

VMTA

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ENGINEERING SOLUTIONS ON A CHIP FROM INTERSIL

Product offerings described in this data book reflect Intersil's commitment to industry leadership as a producer of advanced low-power analog and digital semiconductor components and data acquisition systems.

These components are fabricated using a wide variety of process technologies and are intended to provide state-of-the-art performance and maximum cost effectiveness.

Product areas in which Intersil demonstrates its innovative approach to providing engineering solutions on a chip include:

- **FIELD EFFECT AND DUAL MATCHED BIPOLAR TRANSISTORS**

A complete line of high-performance junction FETs, dual JFETs, MOSFETs and matched dual bipolar devices.

- **DIGITAL**

Very low-power CMOS ROMs and EPROMs, as well as high-speed HMOS ROMs; CMOS microprocessors, peripherals and UARTs.

- **ANALOG SWITCHES AND MULTIPLEXERS**

The industry's broadest offering of highest-performance switches, including a video-RF switch with excellent isolation at 100 MHz, and multiplexers featuring the least error as well as unprecedented input overload protection.

- **ANALOG-TO-DIGITAL AND DIGITAL-TO-ANALOG CONVERTERS**

3½- and 4½-digit display output (DVM) analog-to-digital converters; 12-, 14- and 16-bit microprocessor-compatible analog-to-digital converters; and high-speed precision digital-to-analog converters up to 14 bits.

- **LINEAR**

A new set of low-power devices with unequalled performance—1- μ V offset voltage op amps, 4- μ A quiescent current regulators and supply monitors, 95-per-cent-efficient voltage converters and 1ppm/°C voltage references; a complete family of CMOS op amps; and a wide variety of special analog function circuits.

- **TIMERS, COUNTERS AND DISPLAY DRIVERS**

A wide range of low-power counters, timers and multidigit LED, LCD and vacuum fluorescent display decoder/drivers, including those with full alphanumeric capability.

General Information

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EXPLANATION OF TERMS, INDICES AND SPECIAL SUBSECTIONS

A

PRODUCTION DATA SHEET

This is a full, final data sheet, and describes a mature product in full production. Although Intersil reserves the right to make changes in specifications contained in these data sheets at any time without notice, such changes are not common and are usually minor, generally relating to yield and processing improvements. These data sheets are not marked; others are marked preliminary.

PRELIMINARY DATA SHEET

A preliminary data sheet is issued in advance of the availability of production samples and generally indicates that at the time of printing, the device had not been fully characterized. In the case of a second-source part, the specifications are already determined, and a "preliminary" designation indicates the anticipated availability of the device.

ALPHANUMERIC INDEX

This part number index is arranged first by alpha sequence, (ie: ADCxxxx, DGxxx, Gxxx, ICLxxxx, ICMxxxx, etc.) then by numeric sequence (ie: LM100, LM101A, LM102, LM105, etc.) and ignoring package/temperature/pin number suffixes. The basic numbering sequence, is sorted by reading the part number characters from left to right. Reading the left character first (which is usually an alpha character), then the next character to the right and so forth.

BASE NUMBER INDEX

If only the basic part number is known, use the Base Number Index as a locator aid. The Base Number Index is organized in numeric sequence (with alpha prefixes appearing in bold type and numeric characters set in medium type). Devices are arranged in this index according to the numeric value of the first digit on the left, then the value of the second digit, then the third, and so on. For example, device number ICM7218 precedes ICL741, no package/temperature/pin number suffixes are included, but these may be obtained from the specific product data sheet.

FUNCTION INDEX

This is an index of Intersil device types categorized by product grouping and function. The first major subsection, DISCRETES, is further subdivided into categories for JFETs and Special Function devices.

All remaining major subsections (ANALOG SWITCHES/MULTIPLEXERS, DATA ACQUISITION, LINEAR, TIMERS/COUNTERS, TIMEKEEPING/DTMF, MEMORIES and MICROPROCESSORS/PERIPHERALS)

are organized alphabetically by function. The Functional Index appears in its entirety in section A, and an appropriate subindex appears at the beginning of each major product section.

CROSS-REFERENCE GUIDES

Two cross-reference guides are provided: one for Discrete Devices and one for Integrated Circuits.

The Discrete Cross-Reference Guide indicates whether Intersil can provide the industry-standard type, or an Intersil preferred part instead.

The IC Alternate Source Cross-Reference Guide lists competitive manufacturer device types for which Intersil makes pin-for-pin replacements. In the left-hand column, the competitive device part number is organized alphabetically by manufacturer. The Intersil pin-for-pin replacement appears in the right hand column.

SELECTOR GUIDES

Selector guide tables appear at the front of each major product category subsection and provides a quick reference of key parameters for devices contained in that section.

DEVICE FUNCTION/PACKAGE CODES

Package dimensions and diagrams explaining device prefix and suffix codes appear in Appendix B.

DIE SELECTION CRITERIA

Many of Intersil's semiconductor products are available in die form. This subsection of Appendix B contains general information on criteria for transistor and integrated circuit die selection, including physical parameters, packaging for shipment, assembly, testing and purchase options.

HIGH-RELIABILITY PROCESSING

This subsection of Appendix B defines Intersil's commitment to 100 percent compliance with MIL-STD-883, MIL-STD-750, MIL-M-38510 and MIL-S-19500 specifications. It also outlines Intersil's programs for quality conformance, quality testing and limited use qualification and includes a glossary of military/aerospace Hi-Rel terms.

Intersil reserves the right to make changes in circuitry or specifications contained herein at any time without notice.

Intersil assumes no responsibility for the use of any circuits described herein and makes no representations that they are free patent infringement.

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For the purposes of this policy, critical components in life support systems and/or devices are defined as:

1. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.
2. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.

Intersil cannot assume responsibility for use of any circuitry described other than circuitry entirely embodied in an Intersil product. No circuit patent licenses are implied. Intersil reserves the right to change the circuitry and specifications without notice at any time.

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*Not recommended for new designs. Use ICL8211/12 or ICL7665.

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OBSOLETE PRODUCTS

The products listed below have been designed into circuits in the past, but are no longer likely to be the most economic choice for new designs.

These products are still available for use in existing designs. Data sheets for these products are available upon request.

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| ICL8052/7101 | μ A748 |
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| ICL8068/71C03 | IH5101 |
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| IH401 | μ A733 |
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| LD110/111 | LM110/310 |
| LD114 | LH2110/2310 |
| MM450/550 | LH2111/2311 |
| MM451/551 | LM111/311 |
| MM452/552 | LM100/300 |
| MM455/555 | LM105/305 |
| VCR5P | μ A723 |
| LH0042 | ICM7201 |

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AMI

S68332
S68364

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AD503
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Intersil

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LM302
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µA733
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µA748

Intersil

IM7332
IM7364

Intersil

LM101
LM108
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DAC7533
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WG-8038
VR-8069

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E1151

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XR8038
XRL555
XRL556
XR2242

Fairchild

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µA107
µA108
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µA302
µA305
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µA310
µA311
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Intersil

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| MP7521KN | AD7521KN |
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| LH2110 | LH2110 |
| LH2111 | LH2111 |
| LH2301 | LH2301 |
| LH2308 | LH2308 |
| LH2310 | LH2310 |
| LH2311 | LH2311 |
| LM100 | LM100 |
| LM101 | LM101 |
| LM102 | LM102 |
| LM105 | LM105 |
| LM107 | LM107 |
| LM108 | LM108 |
| LM110 | LM110 |
| LM111 | LM111 |
| LM300 | LM300 |
| LM301 | LM301 |
| LM302 | LM302 |
| LM305 | LM305 |
| LM307 | LM307 |
| LM308 | LM308 |
| LM310 | LM310 |
| LM311 | LM311 |
| LM4250 | LM4250 |
| LM723 | μA723 |
| LM733 | μA733 |
| LM740 | μA740 |
| LM741 | μA741 |
| LM742 | μA742 |
| LM748 | μA748 |
| MM52132 | IM7332 |
| MM52164 | IM7364 |
| MM74C946 | ICM7224 |

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| NEC | Intersil |
| μPD816C | ICM7038B |
| μPD820C | ICM1115B |
| μPD833G | ICM7223 |
| μPD1963G | ICM7050 |
| μPD2332 | IM7332 |
| μPD2364 | IM7364 |
| NPC | Intersil |
| SM5510 | ICM1115B |
| OKI | Intersil |
| MSM503 | AD503 |
| Panasonic/Matsushita | Intersil |
| MN6091 | ICM7038B |
| MN6093 | ICM7051A |
| Phillips/Fasalec | Intersil |
| MB7B | ICM7245U |
| MB101 | ICM7245B |
| MB103 | ICM7245E |
| MB105 | ICM7245U |
| MB107 | ICM7245D |
| MB108 | ICM7245E |
| MB143 | ICM7245A |
| MB144 | ICM7245F |
| MB510 | ICM1115B |
| Plessey | Intersil |
| SC748 | μA748 |
| PMI | Intersil |
| PM308 | LM308 |
| SSS741 | μA741 |
| Raytheon | Intersil |
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| LH2301 | LH2301 |
| LH2311 | LH2311 |
| LH2311 | LH2311 |
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| LM105 | LM105 |
| LM107 | LM107 |
| LM108 | LM108 |
| LM301 | LM301 |
| LM305 | LM305 |
| LM307 | LM307 |
| LM308 | LM308 |
| LM311 | LM311 |
| RC723 | μA723 |
| RC733 | μA733 |
| RC741 | μA741 |
| RC748 | μA748 |
| RM723 | μA723 |
| RM741 | μA741 |
| RM748 | μA748 |
| RCA | Intersil |
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| CA111 | LM111 |
| CA301 | LM301 |
| CA307 | LM307 |
| CA308 | LM308 |
| CA311 | LM311 |
| CA723 | μA723 |
| CA741 | μA741 |
| CA748 | μA748 |
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| CPD6402 | IM6402 |
| Samsung | Intersil |
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| KS5240B01J | ICM7245A |
| KS5240B01H | ICM7245B |
| KS5240B10H | ICM7245D |
| KS5240B12H | ICM7245E |
| KS5240B20H | ICM7245F |
| Sanyo | Intersil |
| LC7523 | AD7523 |
| Signetics | Intersil |
| μA723 | μA723 |
| μA733 | μA733 |
| μA740 | μA740 |
| μA741 | μA741 |
| μA748 | μA748 |
| LH2101 | LH2101 |
| LH2108 | LH2108 |
| LH2301 | LH2301 |
| LH2308 | LH2308 |

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 TMM2364

Intersil
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 ICM7038B
 ICM1115B
 ICM7038D
 2114
 IM7332
 IM7364

DISCRETE CROSS REFERENCE



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| 100S | 2N5458 | 2N2606 | 2N2607 | 2N3331 | 2N5270 | 2N3814 | IT132 |
| 100U | 2N3684 | 2N2607 | 2N2807 | 2N3332 | 2N5265 | 2N3815 | IT132 |
| 102M | 2N5996 | 2N2608 | 2N2808 | 2N3333 | IT132 | 2N3816 | IT130 |
| 102S | 2N5457 | 2N2609 | 2N2609 | 2N3334 | IT132 | 2N3816A | IT130A |
| 103M | 2N5457 | 2N2609JAN | 2N2609JAN | 2N3335 | IT132 | 2N3817 | IT130 |
| 103S | 2N5459 | 2N2639 | IT120 | 2N3336 | IT132 | 2N3817A | IT130A |
| 104M | 2N5455 | 2N2640 | IT122 | 2N3347 | IT137 | 2N3819 | 2N5484 |
| 105M | 2N5455 | 2N2641 | IT122 | 2N3348 | IT138 | 2N3820 | 2N2608 |
| 105U | 2N4340 | 2N2642 | IT120 | 2N3349 | IT139 | 2N3821 | 2N3821 |
| 106M | 2N5485 | 2N2643 | IT122 | 2N3350 | IT137 | 2N3822 | 2N3822 |
| 107M | 2N5485 | 2N2644 | IT122 | 2N3351 | IT138 | 2N3823 | 2N3823 |
| 110U | 2N3685 | 2N2652 | IT120 | 2N3352 | IT139 | 2N3824 | 2N3824 |
| 120U | 2N3686 | 2N2652A | IT120 | 2N3355 | 2N4340 | 2N3827 | IT120 |
| 125U | 2N4339 | 2N2720 | IT120 | 2N3366 | 2N4338 | 2N3828 | IT120 |
| 1277A | 2N3822 | 2N2721 | IT122 | 2N3367 | 2N4338 | 2N3829 | 2N2609 |
| 1278A | 2N3821 | 2N2722 | IT120 | 2N3368 | 2N4341 | 2N3909A | 2N2609 |
| 1279A | 2N3821 | 2N2802 | IT139 | 2N3369 | 2N4339 | 2N3821 | 2N3821 |
| 1280A | 2N4224 | 2N2803 | IT139 | 2N3370 | 2N4339 | 2N3822 | 2N3822 |
| 1281A | 2N3822 | 2N2804 | IT139 | 2N3376 | 2N2608 | 2N3845 | IT132 |
| 1282A | 2N4341 | 2N2805 | IT139 | 2N3378 | 2N2608 | 2N3850 | IT132 |
| 1283A | 2N4340 | 2N2906 | IT139 | 2N3380 | 2N2609 | 2N3954 | 2N3954 |
| 1284A | 2N4222 | 2N2907 | IT139 | 2N3382 | 2N3994 | 2N3954A | 2N3954A |
| 1285A | 2N3821 | 2N2911 | 2N2607 | 2N3384 | 2N3993 | 2N3955 | 2N3955 |
| 1289A | 2N4220 | 2N2942 | 2N2607 | 2N3385 | 2N5114 | 2N3955A | 2N3955A |
| 130U | 2N3687 | 2N2843 | 2N2607 | 2N3409 | IT122 | 2N3955 | 2N3956 |
| 1325A | 2N4222 | 2N2844 | 2N2607 | 2N3410 | IT122 | 2N3957 | 2N3957 |
| 135U | 2N4339 | 2N2903 | IT122 | 2N3411 | IT122 | 2N3966 | 2N4416 |
| 14T | 2N4224 | 2N2903A | IT120 | 2N3423 | IT122 | 2N3967 | 2N4221 |
| 155U | 2N4416 | 2N2910 | IT122 | 2N3424 | IT122 | 2N3967A | 2N4221 |
| 1714A | 2N4340 | 2N2913 | IT122 | 2N3425 | IT122 | 2N3968 | 2N3685 |
| 182S | 2N4391 | 2N2914 | IT120 | 2N3436 | 2N4341 | 2N3968A | 2N3685 |
| 183S | 2N3823 | 2N2915 | IT120 | 2N3437 | 2N4340 | 2N3689 | 2N3688 |
| 187S | 2N4338 | 2N2915A | IT120 | 2N3438 | 2N4338 | 2N3969A | 2N3688 |
| 188S | 2N4340 | 2N2916 | IT120 | 2N3452 | 2N4220 | 2N3970 | 2N3970 |
| 196S | 2N4341 | 2N2916A | IT120 | 2N3453 | 2N4338 | 2N3971 | 2N3971 |
| 2000M | 2N3823 | 2N2917 | IT122 | 2N3454 | 2N4338 | 2N3972 | 2N3972 |
| 2001M | 2N3823 | 2N2918 | IT122 | 2N3455 | 2N4340 | 2N3993 | 2N3993 |
| 200S | 2N4392 | 2N2919 | IT120 | 2N3456 | 2N4338 | 2N3993A | 2N3993 |
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| 201S | 2N4391 | 2N2920 | 2N2920 | 2N3458 | 2N4341 | 2N3994A | 2N3994 |
| 202S | 2N4392 | 2N2920A | 2N2920 | 2N3459 | 2N4339 | 2N4009 | IT132 |
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| 204S | 2N3821 | 2N2937 | IT120 | 2N3513 | IT122 | 2N4011 | IT132 |
| 2078A | 2N3955 | 2N2972 | IT122 | 2N3514 | IT122 | 2N4015 | IT139 |
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| 2080A | 2N3955A | 2N2974 | IT120 | 2N3516 | IT122 | 2N4017 | IT139 |
| 2081A | 2N3955A | 2N2975 | IT120 | 2N3517 | IT122 | 2N4018 | IT139 |
| 2093M | 2N3687 | 2N2976 | IT120 | 2N3521 | IT122 | 2N4019 | IT139 |
| 2084M | 2N3686 | 2N2977 | IT120 | 2N3522 | IT122 | 2N4020 | IT139 |
| 2085M | 2N3686 | 2N2978 | IT120 | 2N3574 | 2N2607 | 2N4021 | IT139 |
| 2088A | 2N3954 | 2N2979 | IT120 | 2N3575 | 2N2607 | 2N4022 | IT139 |
| 2099A | 2N3955A | 2N2980 | IT121 | 2N3578 | 2N2608 | 2N4023 | IT137 |
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| 2134U | 2N3955 | 2N3044 | IT122 | 2N3684 | 2N3684 | 2N4038 | 2N4351 |
| 2136U | 2N3957 | 2N3045 | IT122 | 2N3684A | 2N3684 | 2N4039 | 2N4351 |
| 2138U | 2N3958 | 2N3046 | IT121 | 2N3685 | 2N3685 | 2N4066 | 3N163 |
| 2139U | 2N3958 | 2N3047 | IT122 | 2N3685A | 2N3685 | 2N4066 | 3N166 |
| 2147U | 2N3958 | 2N3048 | IT122 | 2N3686 | 2N3686 | 2N4067 | 3N166 |
| 2148U | 2N3958 | 2N3049 | IT139 | 2N3686A | 2N3686 | 2N4082 | 2N3954 |
| 2149U | 2N3958 | 2N3050 | IT139 | 2N3687 | 2N3687 | 2N4083 | 2N3955 |
| 231S | 2N3954 | 2N3051 | IT139 | 2N3687A | 2N3687 | 2N4084 | 2N3954 |
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| 233S | 2N3955 | 2N3059 | IT139 | 2N3727 | IT130 | 2N4091 | 2N4091 |
| 234S | 2N3957 | 2N3066 | 2N4340 | 2N3728 | IT122 | 2N4091A | 2N4091 |
| 235S | 2N3959 | 2N3067 | 2N4338 | 2N3729 | IT121 | 2N4091JAN | 2N4091JAN |
| 241U | 2N4369 | 2N3068 | 2N4338 | 2N3800 | IT132 | 2N4091JANTX | 2N4091JANTX |
| 250U | 2N4091 | 2N3069 | 2N4341 | 2N3801 | IT132 | 2N4091JANTXV | 2N4091JANTXV |
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| 2N2060 | IT120 | 2N3071 | 2N4338 | 2N3803 | IT132 | 2N4092A | 2N4092 |
| 2N2060A | IT121 | 2N3084 | 2N4339 | 2N3804 | IT130 | 2N4092JAN | 2N4092JAN |
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| 2N2499 | 2N2609 | 2N3329 | 2N5267 | 2N3812 | IT132 | 2N4118A | 2N4118A |
| 2N2500 | 2N2609 | 2N3330 | 2N5268 | 2N3813 | IT132 | 2N4119 | 2N4119 |

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| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
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|---|--|---|---|---|---|--|---|
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| 3N189 3N190 3N191 3N207 3N208 | 3N189 3N190 3N191 3N190 3N188 | BF245 BF245A BF245B BF245C BF246 | 2N5466 2N4416 2N4416 2N4416 2N5485 | BFY81 BFY82 BFY83 BFY84 BFY85 | IT122 IT122 IT122 IT122 IT122 | CM880 CMX740 CP640 CP643 CP650 | 2N4868A 2N5432 2N4091 2N5494 2N5492 |
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| A198 A199 A5T3821 A5T3822 A5T3823 | ITE4392 ITE4393 2N5484 2N5484 2N4416 | BF818 BFQ10 BFQ11 BFQ12 BFQ13 | 2N4858 U401 U401 U402 U403 | CB691 CB692 CB73 CB74 CB80 | 2N4341 2N4339 2N4341 2N4341 2N4338 | D2T2905 D2T2905A D2T918 DA102 DA402 | IT139 IT139 IT129 2N5196 2N5196 |
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| ALTERNATE SOURCE PRODUCT | | ALTERNATE SOURCE PRODUCT | | ALTERNATE SOURCE PRODUCT | | ALTERNATE SOURCE PRODUCT | |
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| INTERSIL EQUIVALENT | | INTERSIL EQUIVALENT | | INTERSIL EQUIVALENT | | INTERSIL EQUIVALENT | |
| E105 | J105 | FF400 | 2N5457 | IT127 | IT127 | ITE2977 | IT120 |
| E106 | J106 | FM1100 | 2N3954A | IT128 | IT128 | ITE2978 | IT120 |
| E107 | J107 | FM1100A | 2N5906 | IT129 | IT129 | ITE2979 | IT120 |
| E108 | J105 | FM1101A | 2N5906 | IT130 | IT130 | ITE3065 | 2N3685 |
| E109 | J106 | FM1102 | 2N3954 | IT130A | IT130A | ITE3067 | 2N3686 |
| E110 | J107 | FM1102A | 2N5906 | IT131 | IT131 | ITE3068 | 2N3687 |
| E111 | J111 | FM1103 | 2N3955 | IT132 | IT132 | ITE3347 | IT137 |
| E111A | J111 | FM1103A | 2N5908 | IT135 | IT135 | ITE3348 | IT138 |
| E112 | J112 | FM1104 | 2N3957 | IT137 | IT137 | ITE3349 | IT139 |
| E112A | J112 | FM1104A | 2N5909 | IT138 | IT138 | ITE3350 | IT137 |
| E113 | J113 | FM1105 | 2N3954A | IT139 | IT139 | ITE3351 | IT138 |
| E113A | J113 | FM1105A | IT500 | IT140 | IT140 | ITE3680 | IT120 |
| E114 | J204 | FM1106 | 2N3954A | IT1700 | IT1700 | ITE3680 | IT132 |
| E1174 | J174 | FM1106A | IT500 | IT1701 | 3N172 | ITE3802 | IT132 |
| E1175 | J175 | FM1107 | 2N3954 | IT1702 | 3N163 | ITE3804 | IT130 |
| E176 | J176 | FM1107A | IT500 | IT1750 | IT1750 | ITE3806 | IT132 |
| E177 | J177 | FM1108 | 2N3955 | IT2700 | 3N165 | ITE3807 | IT132 |
| E201 | J201 | FM1108A | IT502 | IT2701 | 3N165 | ITE3808 | IT132 |
| E202 | J202 | FM1109 | 2N3957 | IT400 | 2N4392 | ITE3809 | IT132 |
| E203 | J203 | FM1109A | IT503 | IT500 | IT500 | ITE3810 | IT130 |
| E204 | J204 | FM1110 | 2N3955 | IT500P | IT500 | ITE3811 | IT130 |
| E210 | 2N5397 | FM1110A | 2N5908 | IT501 | IT501 | ITE3907 | IT120 |
| E211 | 2N5397 | FM1111 | 2N3957 | IT501P | IT501 | ITE3908 | IT120 |
| E212 | 2N5397 | FM1111A | 2N5909 | IT502 | IT502 | ITE4017 | IT139 |
| E230 | 2N4867 | FM1112 | 2N5196 | IT502P | IT502 | ITE4018 | IT139 |
| E231 | 2N4868 | FM1200 | 2N3954 | IT503 | IT503 | ITE4019 | IT139 |
| E232 | 2N4669 | FM1201 | 2N3954 | IT503P | IT503 | ITE4020 | IT139 |
| E270 | J270 | FM1202 | 2N3954 | IT504 | IT504 | ITE4021 | IT139 |
| E271 | J271 | FM1203 | 2N3955A | IT505 | IT505 | ITE4022 | IT139 |
| E300 | 2N5397 | FM1204 | 2N3955 | IT550 | IT550 | ITE4023 | IT137 |
| E304 | 2N5486 | FM1205 | 2N3954 | IT5911 | IT5911 | ITE4024 | IT137 |
| E305 | 2N5484 | FM1206 | 2N3954 | IT5912 | IT5912 | ITE4025 | IT137 |
| E308 | J308 | FM1207 | 2N3954 | ITC2972 | IT122 | ITE4091 | ITE4091 |
| E309 | J309 | FM1208 | 2N3955A | ITC2973 | IT122 | ITE4092 | ITE4092 |
| E310 | J310 | FM1209 | 2N3955 | ITC2974 | IT120 | ITE4093 | ITE4093 |
| E311 | J310 | FM1210 | 2N3955A | ITC2975 | IT120 | ITE4117 | 2N4117 |
| E312 | 2N5397 | FM1211 | IT5911 | ITC2976 | IT120 | ITE4118 | 2N4118 |
| E400 | 2N3955 | FM3954 | 2N3954 | ITC2977 | IT120 | ITE4119 | 2N4119 |
| E401 | 2N3955 | FM3954A | 2N3954A | ITC2978 | IT120 | ITE4338 | 2N4338 |
| E402 | 2N3957 | FM3955 | 2N3955 | ITC2979 | IT120 | ITE4339 | 2N4339 |
| E410 | 2N3955 | FM3955A | 2N3955A | ITC3347 | IT137 | ITE4340 | 2N4340 |
| E411 | IT5911 | FM3956 | 2N3956 | ITC3348 | IT138 | ITE4341 | 2N4341 |
| E412 | IT5911 | FM3957 | 2N3957 | ITC3349 | IT139 | ITE4391 | ITE4391 |
| E413 | 2N5454 | FM3958 | IT5911 | ITC3350 | IT137 | ITE4392 | ITE4392 |
| E414 | 2N3956 | FP4339 | 2N4339 | ITC3351 | IT138 | ITE4393 | ITE4393 |
| E415 | 2N3957 | FP4340 | 2N4340 | ITC3352 | IT139 | ITE4416 | ITE4416 |
| E420 | IT5911 | FT0854A | 2N5486 | ITC3900 | IT132 | ITE4857 | 2N4857 |
| E421 | IT5912 | FT0854B | 2N5486 | ITC3902 | IT132 | ITE4858 | 2N4858 |
| E430 | J309(X2) | FT0854C | 2N4221 | ITC3904 | IT136 | ITE4859 | 2N4859 |
| E431 | J310(X2) | FT0854D | 2N4221 | ITC3906 | IT132 | J100 | 2N5458 |
| ESM25 | U401 | FT3920 | 2N5019 | ITC3907 | IT132 | J101 | 2N4338 |
| ESM25A | U401 | FT3920 | 2N5480 | ITC3908 | IT132 | J102 | 2N5457 |
| ESM4091 | 2N4091 | FT3909 | 2N5019 | ITC3909 | IT132 | J103 | 2N5459 |
| ESM4092 | 2N4092 | FT703 | 3N161 | ITC3910 | IT130 | J105 | J105 |
| ESM4093 | 2N4093 | FT704 | 3N163 | ITC3911 | IT130 | J105-1B | J105 |
| ESM4302 | 2N5457 | GET5457 | 2N5457 | ITC4017 | IT139 | J106 | J106 |
| ESM4303 | 2N5458 | GET5458 | 2N5458 | ITC4018 | IT139 | J106-1B | J106 |
| ESM4304 | 2N5458 | GET5459 | 2N5459 | ITC4019 | IT139 | J107 | J107 |
| ESM4445 | 2N5432 | HA7807 | IT132 | ITC4020 | IT139 | J107-1B | J107 |
| ESM4446 | 2N5434 | HA7809 | IT132 | ITC4021 | IT139 | J108 | J105 |
| ESM4447 | 2N5432 | HOIG1030 | 3N163 | ITC4022 | IT139 | J108-1B | J105 |
| ESM4448 | 2N5434 | HEP801 | 2N3922 | ITC4023 | IT137 | J109 | J106 |
| FE0654A | 2N4386 | HEP802 | 2N5484 | ITC4024 | IT137 | J109-1B | J106 |
| FE0654B | 2N5485 | HEP803 | 2N5019 | ITC4025 | IT137 | J110 | J107 |
| FE100 | 2N3921 | HEPF0021 | 2N5484 | ITE2453 | IT120 | J110-1B | J107 |
| FE100A | 2N3921 | HEPF1035 | J176 | ITE2639 | IT120 | J111 | J111 |
| FE102 | 2N4119 | HEPF2004 | 2N5484 | ITE2840 | IT122 | J111-1B | J111 |
| FE102A | 2N4119 | HEPF2005 | 2N5459 | ITE2841 | IT122 | J111A | J111 |
| FE104 | 2N4119 | ID100 | ID100 | ITE2842 | IT120 | J111A-1B | J111 |
| FE104A | 2N4119 | ID101 | ID101 | ITE2843 | IT122 | J112 | J112 |
| FE1600 | 2N4092 | IMF3954 | 2N3954 | ITE2944 | IT122 | J112-1B | J112 |
| FE200 | 2N3921 | IMF3954A | 2N3954A | ITE2720 | IT120 | J112A | J112 |
| FE202 | 2N3921 | IMF3955 | 2N3955 | ITE2721 | IT122 | J112A-1B | J112 |
| FE204 | 2N3921 | IMF3955A | 2N3955A | ITE2722 | IT120 | J113 | J113 |
| FE300 | 2N3922 | IMF3956 | 2N3956 | ITE2903 | IT122 | J113-1B | J113 |
| FE302 | 2N3921 | IMF3957 | 2N3957 | ITE2913 | IT122 | J113A | J113 |
| FE304 | 2N3921 | IMF3958 | 2N3958 | ITE2914 | IT122 | J113A-1B | J113 |
| FE3619 | 2N5484 | IMF5911 | IMF5911 | ITE2915 | IT120 | J114 | 2N5555 |
| FE4302 | 2N5457 | IMF5912 | IMF5912 | ITE2916 | IT120 | J1401 | IT501 |
| FE4303 | 2N5458 | IMF6485 | IMF6485 | ITE2917 | IT122 | J1402 | IT502 |
| FE4304 | 2N5458 | IT100 | IT100 | ITE2918 | IT122 | J1403 | IT503 |
| FE5245 | 2N4416 | IT101 | IT101 | ITE2919 | IT120 | J1404 | IT503 |
| FE5246 | 2N5484 | IT108 | ITE4416 | ITE2920 | IT120 | J1405 | IT504 |
| FE5247 | 2N5486 | IT109 | ITE4418 | ITE2936 | IT120 | J1406 | IT505 |
| FE5457 | 2N5457 | IT120 | IT120 | ITE2937 | IT120 | J174 | J174 |
| FE5458 | 2N5458 | IT120A | IT120A | ITE2972 | IT122 | J174-1B | IT503 |
| FE5459 | 2N5459 | IT121 | IT121 | ITE2973 | IT122 | J175 | J175 |
| FE5464 | 2N5484 | IT122 | IT122 | ITE2974 | IT120 | J175-1B | J175 |
| FE5465 | 2N5485 | IT124 | IT124 | ITE2975 | IT120 | J176 | J176 |
| FE5466 | 2N5486 | IT126 | IT126 | ITE2976 | IT120 | J176-1B | J176 |

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| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
|--------------------------|---------------------|--------------------------|---------------------|--------------------------|---------------------|--------------------------|---------------------|
| J177 | J177 | K309-18 | J309 | LS5105 | 2N5486 | MD70026 | IT122 |
| J177-18 | J177 | K310-18 | J310 | LS5245 | ITE4416 | MD7003 | IT132 |
| J201 | J201 | KE3684 | 2N3684 | LS5246 | 2N5484 | MD7003A | IT132 |
| J201-18 | J201 | KE3685 | 2N3685 | LS5247 | 2N5486 | MD7003B | IT132 |
| J202 | J202 | KE3686 | 2N3686 | LS5248 | 2N5486 | MD7004 | IT129 |
| J202-18 | J202 | KE3687 | 2N3687 | LS5358 | J204 | MD7007 | IT129 |
| J203 | J203 | KE3623 | 2N3623 | LS5359 | J204 | MD7007A | IT129 |
| J203-18 | J203 | KE3970 | ITE4391 | LS5360 | J202 | MD7007B | IT129 |
| J204 | J204 | KE3971 | ITE4392 | LS5361 | J202 | MD708 | IT129 |
| J204-18 | J204 | KE3972 | ITE4393 | LS5362 | J203 | MD708A | IT129 |
| J210 | 2N5387 | KE4091 | ITE4091 | LS5363 | J203 | MD7086 | IT129 |
| J211 | 2N5397 | KE4092 | ITE4092 | LS5364 | J203 | MD6001 | IT120 |
| J212 | 2N5397 | KE4093 | ITE4093 | LS5391 | 2N4867A | MD6002 | IT120 |
| J230 | 2N4867 | KE4220 | 2N5437 | LS5392 | 2N4868A | MD6003 | IT122 |
| J231 | 2N4868 | KE4221 | 2N5439 | LS5393 | 2N4869A | MD918 | IT122 |
| J232 | 2N4869 | KE4222 | 2N5459 | LS5394 | 2N4869A | MD918A | IT122 |
| J270 | J270 | KE4223 | J204 | LS5395 | 2N4869A | MD819B | IT122 |
| J270-18 | J270 | KE4391 | ITE4391 | LS5396 | 2N4869A | MD882 | IT139 |
| J271 | J271 | KE4392 | ITE4392 | LS5457 | 2N5457 | MD984 | IT139 |
| J271-18 | J271 | KE4393 | ITE4393 | LS5458 | 2N5458 | MEF103 | 2N5457 |
| J300 | 2N5397 | KE4416 | ITE4416 | LS5459 | 2N5459 | MEF104 | 2N5459 |
| J304 | 2N5486 | KE4856 | ITE4391 | LS5484 | 2N5484 | MEF3069 | 2N4341 |
| J305 | 2N5484 | KE4857 | ITE4392 | LS5485 | 2N5485 | MEF3070 | 2N4339 |
| J308 | J308 | KE4858 | ITE4393 | LS5486 | 2N5486 | MEF3458 | 2N4341 |
| J309 | J309 | KE4859 | ITE4391 | LS5556 | 2N3685 | MEF3459 | 2N4339 |
| J310 | J310 | KE4860 | ITE4392 | LS5557 | 2N3684 | MEF3460 | 2N4338 |
| J315 | 2N5397 | KE4861 | ITE4393 | LS5558 | 2N3684 | MEF3684 | 2N3684 |
| J316 | U308 | KE510 | ITE4393 | LS5638 | 2N5638 | MEF3685 | 2N3685 |
| J317 | U310 | KE5103 | J204 | LS5639 | 2N5639 | MEF3686 | 2N3686 |
| J3970 | ITE4391 | KE5104 | ITE4416 | LS5640 | 2N5640 | MEF3687 | 2N3687 |
| J3971 | ITE4392 | KE5105 | ITE4416 | M103 | 3N161 | MEF3821 | 2N3821 |
| J3972 | ITE4393 | KE511 | ITE4392 | M104 | 3N161 | MEF3822 | 2N3822 |
| J401 | IT501 | KH5198 | 2N5198 | M106 | 3N166 | MEF3823 | 2N3823 |
| J402 | IT502 | KH5197 | 2N5197 | M107 | 3N189 | MEF3954 | 2N3954 |
| J403 | IT503 | KH5199 | 2N5199 | M108 | 3N191 | MEF3955 | 2N3955 |
| J404 | IT503 | KH5199 | 2N5199 | M113 | 3N161 | MEF3956 | 2N3956 |
| J405 | IT504 | LDP603 | 2N4221 | M114 | 3N161 | MEF3957 | 2N3957 |
| J406 | IT505 | LDP604 | 2N4221 | M116 | M116 | MEF3958 | 2N3958 |
| J4091 | ITE4091 | LDP605 | 2N4221 | M117 | 2N4351 | MEF4223 | 2N4223 |
| J4092 | ITE4092 | LM114 | IT120 | M119 | 3N161 | MEF4224 | 2N4224 |
| J4093 | ITE4093 | LM114A | IT120A | M163 | 3N163 | MEF4391 | ITE4391 |
| J410 | IT502 | LM114AH | IT120A | M164 | 3N154 | MEF4392 | ITE4392 |
| J411 | IT503 | LM114H | IT120 | M511 | 3N172 | MEF4393 | ITE4393 |
| J412 | IT503 | LM115 | IT120 | M511A | 3N172 | MEF4416 | ITE4416 |
| J420 | IT5911 | LM115A | IT120A | M517 | 3N163 | MEF4856 | 2N4856 |
| J421 | IT5912 | LM115AH | IT120A | MA7807 | IT132 | MEF4857 | 2N4857 |
| J4220 | J204 | LM115H | IT120 | MA7809 | IT132 | MEF4858 | 2N4858 |
| J4221 | J202 | LM194 | IT120A | MAT-01AH | IT140 | MEF4859 | 2N4859 |
| J4222 | J203 | LM394 | IT120A | MAT-01FH | IT140 | MEF4860 | 2N4860 |
| J4223 | J202 | LS3069 | 2N5458 | MAT-01GH | IT140 | MEF4861 | 2N4861 |
| J4224 | J202 | LS3070 | 2N5458 | MAT-01H | IT140 | MEF5103 | ITE4416 |
| J430 | J309(X2) | LS3071 | 2N5458 | MD1120 | IT122 | MEF5104 | ITE4416 |
| J4302 | 2N4302 | LS3458 | J204 | MD1121 | IT122 | MEF5105 | ITE4416 |
| J4303 | 2N5459 | LS3459 | J204 | MD1122 | IT122 | MEF5245 | ITE4416 |
| J4304 | 2N5458 | LS3460 | J204 | MD1123 | IT139 | MEF5246 | 2N5484 |
| J431 | J310(X2) | LS3684 | 2N3684 | MD1129 | IT129 | MEF5247 | 2N5486 |
| J433 | 2N5457 | LS3685 | 2N3685 | MD1130 | IT139 | MEF5248 | 2N5486 |
| J433B | 2N5457 | LS3686 | 2N3686 | MD2218 | IT129 | MEF5249 | 2N5484 |
| J4339 | 2N5457 | LS3687 | 2N3687 | MD2219A | IT129 | MEF5285 | 2N5485 |
| J4391 | ITE4391 | LS3819 | 2N5484 | MD2219 | IT129 | MEF5286 | 2N5486 |
| J4392 | ITE4392 | LS3821 | 2N5457 | MD2219A | IT129 | MEF5561 | U401 |
| J4393 | ITE4393 | LS3822 | 2N5458 | MD2369 | IT129 | MEF5562 | U402 |
| J4416 | ITE4416 | LS3823 | 2N5458 | MD2369A | IT129 | MEF5563 | U403 |
| J4856 | ITE4856 | LS3921 | 2N3921 | MD2369B | IT122 | MEM511 | 3N172 |
| J4857 | ITE4857 | LS3922 | 2N3922 | MD2904 | IT139 | MEM511A | 3N172 |
| J4858 | ITE4858 | LS3966 | ITE4416 | MD2905 | IT139 | MEM511C | 3N172 |
| J4859 | ITE4859 | LS3967 | ITE4416 | MD2906 | IT139 | MEM517A | 3N172 |
| J4860 | ITE4860 | LS3968 | ITE4416 | MD2905A | IT138 | MEM517B | 3N172 |
| J4861 | ITE4861 | LS3969 | ITE4416 | MD2974 | IT120 | MEM517A | 3N172 |
| J4867 | 2N4867 | LS4220 | J204 | MD2975 | IT120 | MEM517C | 3N172 |
| J4867A | 2N4867A | LS4221 | J202 | MD2978 | IT120 | MEM530 | 3N189 |
| J4867RR | 2N4867 | LS4222 | J203 | MD2979 | IT120 | MEM550C | 3N189 |
| J4869 | 2N4869 | LS4223 | J202 | MD3008 | IT120 | MEM550F | 3N189 |
| J4869A | 2N4869A | LS4224 | J202 | MD3250 | IT132 | MEM551 | 3N190 |
| J4869RR | 2N4869 | LS4338 | 2N5457 | MD3250A | IT131 | MEM551C | 3N189 |
| J4869 | 2N4869 | LS4339 | 2N5457 | MD3251 | IT132 | MEM555 | 3N172 |
| J4869A | 2N4869A | LS4340 | 2N5457 | MD3251A | IT131 | MEM556C | 3N172 |
| J4869RR | 2N4869 | LS4341 | 2N5458 | MD3409 | IT129 | MEM560 | 3N161 |
| J5103 | 2N5484 | LS4381 | ITE4391 | MD3410 | IT129 | MEM560C | 3N161 |
| J5104 | 2N5485 | LS4392 | ITE4392 | MD3467 | IT139 | MEM561C | 3N163 |
| J5105 | 2N5486 | LS4393 | ITE4393 | MD3725 | IT129 | MEM561C | 3N163 |
| J6163 | 2N5486 | LS4416 | ITE4416 | MD3762 | IT139 | MEM562 | 2N4351 |
| K114-18 | 2N5555 | LS4856 | ITE4091 | MD4857 | IT132 | MEM562C | 2N4351 |
| K210-18 | 2N5397 | LS4857 | ITE4092 | MD5000 | IT132 | MEM563 | 2N4351 |
| K211-18 | 2N5397 | LS4858 | ITE4093 | MD5000A | IT132 | MEM563C | 2N4351 |
| K212-18 | 2N5397 | LS4859 | ITE4091 | MD5000B | IT132 | MEM711 | M116 |
| K300-18 | 2N5397 | LS4860 | ITE4092 | MD7000 | IT129 | MEM712 | M116 |
| K304-18 | 2N5486 | LS4861 | ITE4093 | MD7001 | IT139 | MEM712A | M116 |
| K305-18 | 2N5484 | LS5103 | 2N5484 | MD7002 | IT122 | MEM713 | 3N170 |
| K309-18 | J309 | LS5104 | 2N5485 | MD7002A | IT122 | MEM806 | 3N163 |

DISCRETE CROSS REFERENCE (cont.)

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| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
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| MEM906A MEM907 MEM907A MEM814 MEM816 | 3N183 3N172 3N172 3N161 3N172 | MPB40 MPB41 MPB42 MPF102 MPF103 | 2N5520 2N5521 2N5523 2N5486 2N5457 | NKT80111 NKT80112 NKT80113 NKT80211 NKT80212 | 2N4220 2N4220 2N3821 2N4339 2N4339 | SA2718 SA2719 SA2720 SA2721 SA2722 | IT122 IT120 IT121 IT122 IT120 |
| MEM817 MEM823 MEM954 MEM954A MEM954B | 3N172 MFE923 3N188 3N188 3N188 | MPF104 MPF105 MPF106 MPF107 MPF108 | 2N5458 2N5459 2N5485 2N5486 2N5486 | NKT80213 NKT80214 NKT80215 NKT80216 NKT80421 | 2N4339 2N4339 2N4339 2N4339 2N4220 | SA2723 SA2724 SA2726 SA2727 SA2738 | IT121 IT122 IT122 IT122 IT120A |
| MEM955 MEM955A MEM955B MF510 MF903 | 3N190 3N190 3N190 2N4092 2N4338 | MPF109 MPF111 MPF112 MPF161 MPF20B | 2N5484 2N5459 2N5459 2N5398 2N3921 | NKT80422 NKT80423 NKT80424 NPC108 NPC211N | 2N4220 2N4220 2N4220 2N5484 2N4338 | SA2739 SDF1001 SDF1002 SDF1003 SDF500 | IT120 2N5432 2N5433 2N5434 2N5430 |
| MF818 MFE2000 MFE2001 MFE2004 MFE2005 | 2N4858 2N4416 2N4416 2N4093 2N4092 | MPF209 MPF255 MPF4391 MPF4392 MPF4393 | 2N3821 IT4416 IT4391 IT4392 IT4393 | NPC212N NPC213N NPC214N NPC215N NPC216N | 2N4338 2N4338 2N4339 2N4339 2N4339 | SDF901 SDF502 SDF503 SDF504 SDF505 | 2N5520 2N5520 2N5520 2N5520 2N5520 |
| MFE2006 MFE2007 MFE2008 MFE2009 MFE2010 | 2N4091 2N4860 2N4859 2N4859 2N4859 | MPF820 MPF970 MPF971 MTF101 MTF102 | J310 J175 J175 2N5484 2N5484 | NPD5554 NPD5565 NPD5566 NPD8301 NPD8302 | IT550 IT550 IT550 2N3954 2N3955 | SDF506 SDF507 SDF508 SDF509 SDF510 | 2N5520 2N5520 2N5520 2N5520 2N3954 |
| MFE2011 MFE2012 MFE2012 MFE2012 MFE2093 MFE2094 | 2N5433 2N5433 2N5434 2N4338 2N4339 | MTF103 MTF104 NDS700 NDS701 NDS702 | 2N5457 2N5459 IT120A IT120A IT120 | NPD8303 DT3 P1004 P1005 P1027 | 2N3956 2N4338 2N5116 2N5115 2N5267 | SDF512 SDF513 SDF514 SDF561 SDF562 | 2N3954 2N3954 2N3954 IT122 IT122 |
| MFE2095 MFE2133 MFE2912 MFE3002 MFE3003 | 2N4340 2N4860 2N5433 3N170 3N164 | NDF9401 NDF9402 NDF9403 NDF9404 NDF9405 | IT500 IT501 IT502 IT503 IT504 | P1028 P1028 P1088E P1086E P1087E | 2N5270 2N5270 2N5509 2N5115 2N5518 | SDF663 SES3919 SFT801 SFT802 SFT603 | IT122 2N5494 2N4338 2N4338 2N4339 |
| MFE3020 MFE3021 MFE4007 MFE4008 MFE4008 | 3N186 3N166 2N3686 2N3686 2N3686 | NDF9406 NDF9407 NDF9408 NDF9409 NDF9410 | IT500 IT501 IT502 IT503 IT504 | P1117E P1118E P1119E PF510 PF5101 | 2N5640 2N5641 2N5640 2N5115 2N4867 | SFT604 SL301AT SL301BT SL301CT SL301ET | 2N4339 IT129 IT129 IT129 IT129 |
| MFE4010 MFE4011 MFE4012 MFE923 MK10 | 2N2508 2N2508 2N2509 IT1700 2N4416 | NF3819 NF4302 NF4303 NF4304 NF4445 | 2N5484 2N5457 2N5459 2N5458 2N5432 | PF5102 PF5103 PF511 PF5301 PF5301-1 | 2N4857 2N4057 2N5114 2N4118A 2N4117A | SL360C SL362C SU2000 SU2020 SU2021 | IT129 IT129 2N4340 2N3954 2N3954 |
| MMF1 MMF2 MMF3 MMF4 MMF5 | 2N5197 2N3921 2N5198 2N3922 2N5199 | NF4446 NF4447 NF4448 NF500 NF501 | 2N5433 2N5433 2N5433 2N4224 2N4224 | PF5301-2 PF5301-3 PL1091 PL1092 PL1093 | 2N4118A 2N4118A 2N3823 2N3823 2N3823 | SU2022 SU2023 SU2024 SU2025 SU2026 | 2N3954 2N3954 2N3954 2N3954 2N3954 |
| MMF6 MMT3923 MP301 MP302 MP303 | 2N3955A 2N3823 IT124 IT124 IT124 | NF506 NF5101 NF5102 NF5103 NF511 | 2N4416 2N4867 2N4867 2N4867 2N4860 | PL1094 PN3664 PN3665 PN3666 PN3667 | 2N3823 2N3684 2N3685 2N3686 2N3687 | SU2027 SU2028 SU2029 SU2029 SU2030 | 2N3954 2N3954 2N3954 2N5197 2N3954 |
| MP310 MP311 MP312 MP313 MP316 | 2N4045 2N4045 2N4044 IT124 IT120A | NF5163 NF520 NF521 NF522 NF523 | 2N4341 2N3684 2N3685 2N3686 2N3685 | PN4091 PN4092 PN4093 PN4220 PN4221 | IT4091 IT4092 IT4093 J204 J202 | SU2030 SU2031 SU2031 SU2032 SU2033 | 2N3955 2N3954 2N5198 2N3954 2N3954 |
| MP350 MP351 MP352 MP353 MP350 | IT132 IT130 IT130 IT130A IT132 | NF530 NF5301 NF5301-1 NF5301-2 NF5301-3 | 2N4341 2N4118A 2N4117A 2N4118A 2N4118A | PN4222 PN4223 PN4224 PN4342 PN4360 | J203 J204 J202 2N5461 2N5460 | SU2034 SU2034 SU2035 SU2035 SU2074 | 2N3954 2N3955 2N3954 2N3955 2N3954 |
| MP361 MP362 MP3954 MP3954A MP3955 | IT130A IT130A 2N3954 2N3954A 2N3955 | NF531 NF532 NF533 NF5457 NF5458 | 2N4339 2N4341 2N4339 2N5457 2N5458 | PN4391 PN4392 PN4416 PN4856 PN4857 | IT4391 IT4392 IT4415 2N4858 2N4857 | SU2075 SU2076 SU2077 SU2077 SU2078 | 2N3954 2N3954 2N3954 2N3955 2N3955 |
| MP3956 MP3957 MP3958 MP5905 MP5906 | 2N3956 2N3957 2N3958 2N5905 2N5906 | NF5459 NF5484 NF5485 NF5486 NF5555 | 2N5459 2N5484 2N5485 2N5486 2N5484 | PN4858 PN4859 PN4860 PN4861 PN5033 | 2N4858 2N4859 2N4860 2N4861 2N5480 | SU2078 SU2080 SU2081 SU2088 SU2098A | 2N3956 U404 U404 2N5197 2N5197 |
| MP5907 MP5908 MP5909 MP5911 MP5912 | 2N5907 2N5908 2N5909 2N5911 2N5912 | NF5636 NF5639 NF5640 NF5653 NF5654 | 2N5639 2N5639 2N5640 2N4860 2N4861 | PTC151 PTC152 SA2253 SA2254 SA2255 | 2N5484 2N5485 IT122 IT122 IT122 | SU2098B SU2099 SU2099A SU2365 SU2365A | 2N5198 2N5197 2N5197 2N3954 2N3954 |
| MP804 MP830 MP831 MP832 MP833 | 2N5520 2N5520 2N5521 2N5522 2N5523 | NF580 NF581 NF582 NF583 NF584 | 2N5432 2N5432 2N5433 2N5434 2N5433 | SA2644 SA2648 SA2710 SA2711 SA2712 | IT120 IT120 IT120 IT120 IT121 | SU2366 SU2366A SU2367 SU2367A SU2368 | 2N3955 2N3955 2N3955 2N3955 2N3956 |
| MP835 MP836 MP837 MP838 MP839 | 2N3954 2N3955 2N3955 2N3956 2N3957 | NF685 NF6451 NF6452 NF6453 NF6454 | 2N4859 U310 U310 U310 U310 | SA2713 SA2714 SA2715 SA2716 SA2717 | IT121 IT122 IT120 IT120 IT121 | SU2368A SU2369 SU2369A SU2410 SU2411 | 2N3956 2N3957 2N3957 2N5907 2N5908 |

**CONSULT FACTORY

DISCRETE CROSS REFERENCE (cont.)



| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
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| SU2412 | 2N5908 | TD5909A | 2N5909 | U183 | 2N3824 | U405 | U405 |
| SU2552 | U401 | TD5911 | IT5911 | U1837E | 2N5456 | U406 | U406 |
| SU2552M | U401 | TD5911A | IT5911 | U184 | 2N5397 | U410 | 2N3955 |
| SU2653 | U401 | TD5912 | IT5912 | U1897E | U1897 | U411 | 2N3955 |
| SU2653M | U401 | TD5912A | IT5912 | U1898E | U1898 | U412 | 2N3955 |
| SU2554 | U401 | TD700 | IT122 | U1899E | U1899 | U421 | 2N5908 |
| SU2554M | U401 | TD701 | IT122 | U197 | 2N4338 | U422 | 2N5908 |
| SU2555 | U402 | TD708 | IT122 | U198 | 2N4340 | U423 | 2N5909 |
| SU2555M | U402 | TD710 | IT122 | U199 | 2N4341 | U424 | 2N5908 |
| SU2656 | U404 | TD711 | IT122 | U1994E | 2N4416 | U425 | 2N5908 |
| SU2556M | U404 | TD713 | IT122 | U200 | 2N4661 | U426 | 2N5909 |
| SX3919 | 2N5484 | TIS14 | 2N4340 | U201 | 2N4860 | U430 | J309(X2) |
| SX3920 | 2N2608 | TIS25 | 2N3954 | U202 | 2N4858 | U431 | J310(X2) |
| TD100 | IT129 | TIS26 | 2N3954 | U2047E | 2N4416 | U440 | IT5911 |
| TD101 | IT129 | TIS27 | 2N3955 | U221 | 2N4381 | U441 | IT5912 |
| TD102 | IT129 | TIS34 | 2N5486 | U222 | 2N4391 | UC100 | 2N3684 |
| TD200 | IT129 | TIS41 | 2N4959 | U231 | U231 | UC110 | 2N3685 |
| TD201 | IT129 | TIS42 | 2N4393 | U232 | U232 | UC115 | 2N4340 |
| TD202 | IT129 | TIS58 | 2N5494 | U233 | U233 | UC120 | 2N3685 |
| TD2219 | IT129 | TIS59 | 2N5486 | U234 | U234 | UC130 | 2N3687 |
| TD224 | IT122 | TIS68 | 2N3955A | U235 | U235 | UC155 | 2N4416 |
| TD225 | IT122 | TIS69 | 2N3955A | U240 | 2N5432 | UC1700 | 3N163 |
| TD226 | IT122 | TIS70 | 2N3956 | U241 | 2N5433 | UC1764 | 3N163 |
| TD227 | IT122 | TIS73 | ITE4391 | U242 | 2N5432 | UC20 | 2N3686 |
| TD228 | IT122 | TIS74 | ITE4392 | U243 | 2N5433 | UC200 | 2N3824 |
| TD229 | IT122 | TIS75 | ITE4393 | U244 | 2N5433 | UC201 | 2N3824 |
| TD230 | IT121 | TIS88 | 2N4416 | U248 | 2N5902 | UC21 | 2N3687 |
| TD231 | IT121 | TIS88A | 2N4416 | U248A | 2N5906 | UC210 | 2N4416 |
| TD232 | IT122 | TIX533 | 2N4392 | U249 | 2N5903 | UC2130 | 2N5452 |
| TD233 | IT122 | TIX535 | 2N4857 | U249A | 2N5907 | UC2132 | 2N5453 |
| TD234 | IT122 | TIX536 | 2N4391 | U250 | 2N5904 | UC2134 | 2N5454 |
| TD235 | IT122 | TIX541 | 2N4859 | U250A | 2N5908 | UC2148 | 2N5454 |
| TD236 | IT122 | TIX542 | 2N5639 | U251 | 2N5905 | UC2138 | 2N5454 |
| TD237 | IT122 | TIX559 | 2N5459 | U251A | 2N5909 | UC2139 | 2N3958 |
| TD238 | IT122 | TIX578 | 2N4341 | U252 | IT5911 | UC2147 | 2N3958 |
| TD239 | IT122 | TIX579 | 2N4341 | U253 | IT5912 | UC2148 | 2N3958 |
| TD240 | IT121 | TN4117 | 2N4117 | U254 | 2N4859 | UC220 | 2N3958 |
| TD241 | IT121 | TN4117A | 2N4117A | U255 | 2N4860 | UC220 | 2N3822 |
| TD242 | IT120A | TN4118 | 2N4118 | U256 | 2N4861 | UC240 | 2N4889 |
| TD243 | IT120A | TN4118A | 2N4118A | U257 | U257 | UC241 | 2N4889 |
| TD244 | IT129 | TN4119 | 2N4119 | U257/TO-71 | U257/TO-71 | UC250 | 2N4091 |
| TD245 | IT129 | TN4119A | 2N4119A | U266 | 2N4856 | UC251 | 2N4392 |
| TD246 | IT129 | TN4338 | 2N4338 | U273 | 2N4118A | UC2755 | 3N165 |
| TD247 | IT129 | TN4339 | 2N4339 | U273A | 2N4118A | UC300 | 2N2608 |
| TD248 | IT129 | TN4340 | 2N4340 | U274 | 2N4118A | UC310 | 2N2607 |
| TD250 | IT120A | TN4341 | 2N4341 | U274A | 2N4119A | UC320 | 2N2607 |
| TD2905 | IT139 | TN5277 | 2N4341 | U275 | 2N4118A | UC330 | 2N2607 |
| TD400 | IT139 | TN5278 | 2N4341 | U275A | 2N4119A | UC340 | 2N2607 |
| TD401 | IT139 | TP5114 | 2N5114 | U280 | 2N5452 | UC40 | 2N2608 |
| TD402 | IT139 | TP5115 | 2N5115 | U281 | 2N5453 | UC400 | 2N5270 |
| TD500 | IT139 | TP5116 | 2N5116 | U282 | 2N5453 | UC401 | 2N5116 |
| TD501 | IT139 | U110 | 2N2608 | U283 | 2N5453 | UC41 | 2N2608 |
| TD502 | IT139 | U111 | 2N2608 | U284 | 2N5454 | UC410 | 2N5268 |
| TD503 | IT132 | U112 | 2N2608 | U285 | 2N5454 | UC420 | 2N5267 |
| TD510 | IT132 | U113 | 2N2608 | U290 | 2N5432 | UC450 | 2N5114 |
| TD511 | IT132 | U114 | 2N2608 | U291 | 2N5434 | UC451 | 2N5116 |
| TD512 | IT132 | U1177 | 2N4220 | U295 | 2N5432 | UC588 | 2N4416 |
| TD513 | IT132 | U1179 | 2N3921 | U296 | 2N5434 | UC703 | 2N4220 |
| TD514 | IT132 | U1179 | 2N3921 | U300 | 2N5114 | UC704 | 2N4220 |
| TD517 | IT132 | U1180 | 2N4221 | U3000 | 2N4341 | UC705 | 2N4224 |
| TD518 | IT132 | U1181 | 2N4220 | U3001 | 2N4339 | UC707 | 2N4860 |
| TD519 | IT132 | U1182 | 2N3921 | U3002 | 2N4338 | UC714 | 2N3822 |
| TD520 | IT139 | U1277 | 2N3684 | U301 | 2N5115 | UC714E | 2N4341 |
| TD521 | IT139 | U1278 | 2N3685 | U3010 | 2N4341 | UC734 | 2N4416 |
| TD522 | IT139 | U1279 | 2N3686 | U3011 | 2N4340 | UC734E | 2N4416 |
| TD523 | IT139 | U1280 | 2N3684 | U3012 | 2N4338 | UC751 | 2N4340 |
| TD524 | IT139 | U1281 | 2N3822 | U304 | U304 | UC752 | 2N4340 |
| TD525 | IT132 | U1282 | 2N4341 | U305 | U305 | UC753 | 2N4341 |
| TD526 | IT132 | U1283 | 2N4340 | U306 | U306 | UC754 | 2N4340 |
| TD527 | IT131 | U1284 | 2N4341 | U308 | U308 | UC755 | 2N4341 |
| TD528 | IT131 | U1285 | 2N4220 | U309 | U309 | UC756 | 2N4340 |
| TD5432 | 2N5432 | U1286 | 2N4341 | U310 | U310 | UC805 | 2N5270 |
| TD5433 | 2N5433 | U1287 | 2N4092 | U311 | U311 | UC807 | 2N5115 |
| TD5434 | 2N5434 | U1321 | 2N4860 | U312 | 2N5397 | UC814 | 2N5270 |
| TD550 | IT129 | U1322 | 2N3922 | U314 | 2N5555 | UC851 | 2N2608 |
| TD5902 | 2N5902 | U1323 | 2N3922 | U315 | 2N5397 | UC853 | 2N2608 |
| TD5902A | 2N5902 | U1324 | 2N3687 | U316 | U309 | UC854 | 2N2608 |
| TD5903 | 2N5903 | U1325 | 2N3686 | U317 | U310 | UC855 | 2N2609 |
| TD5903A | 2N5903 | U133 | 2N2608 | U320 | 2N5433 | UT100 | 2N5397 |
| TD5904 | 2N5904 | U1420 | 2N3821 | U321 | 2N5434 | UT101 | 2N5397 |
| TD5904A | 2N5904 | U1421 | 2N3822 | U322 | 2N5433 | UXC2910 | IT128 |
| TD5905 | 2N5905 | U1422 | 2N3822 | U328 | ** | VCR10N | 2N4889 |
| TD5905A | 2N5905 | U146 | 2N2608 | U329 | ** | VCR11N | VNR11N |
| TD5906 | 2N5906 | U147 | 2N2608 | U330 | ** | VCR12N | 2N3958 |
| TD5906A | 2N5906 | U148 | 2N2608 | U331 | ** | VCR13N | 2N3958 |
| TD5907 | 2N5907 | U149 | 2N2609 | U350 | ** | VCR20N | 2N4341 |
| TD5907A | 2N5907 | U169 | 2N2609 | U401 | U401 | VCR2N | VCR2N |
| TD5908 | 2N5908 | U1714 | 2N4340 | U402 | U402 | VCR3P | VCR3P |
| TD5908A | 2N5908 | U1715 | 2N4340 | U403 | U403 | VCR4N | VCR4N |
| TD5909 | 2N5909 | U182 | 2N4857 | U404 | U404 | VCR5P | VCR5P |

ANALOG SWITCH CROSS REFERENCE



| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
|---|---|--|---|---|---|--|---|
| AD7508/COM/CHIPS AD7508/MIL/CHIPS AD7506JD AD7506JD/883B AD7506JN | IH6116C/D IH6116M/D IH6116C/J IH6116CJ/883B IH6116CPI | AH5010CN AH5012CN AH5013CN AH5014CN AH5015CN | IH5010CPD IH5012CPE IH5013CPD IH5014CPD IH5015CPE | DG180AP DG180BA DG180BP DG181AA DG181AA | DG180AK DG180BA DG180BK DG181AA DGM181AA | DG200AK DG200AL DG200AP DG200BA DG200BK | DG200AK DG200AL DG200AK DG200BA DG200BK |
| AD7506KD AD7506KD/883B AD7506KN AD7506SD AD7506SD/883B | IH6116C/J IH6116CJ/883B IH6116CPI IH6116MJ IH6116MJ/883B | AH5016CN AM5011CN D123AL D123AP D123BP | IH5016CPE IH5011CPE D123AL D123AK D123BJ | DG181AL DG181AP DG181AP DG181AP DG181BA | DG181AL DGM181AL DG181AK DGM181AK DG181BA | DG200BP DG200CJ DG201AK DG201AP DG201BK | DG200BK DG200CJ DG201AK DG201AK DG201BK |
| AD7506TD AD7506TD/883B AD7507/COM/CHIPS AD7507/MIL/CHIPS AD7507JD | IH6116MJ IH6116MJ/883B IH6216C/D IH6216M/D IH6216C/J | D123BP D125AL D125AP D125BP D129AL | D123BK D125AL D125AP D125BK D129AL | DG181BA DG181BP DG181BP DG181BP DG182AA | DGM181BA DG181BK DGM181BK DGM181CJ DG182AA | DG201CJ DG210BP DG211AA DG281AP DG281BA | DG201CJ DG201BK IH182MTW IH182MJD IH182CTW |
| AD7507JD/883B AD7507JN AD7507KD AD7507KD/883B AD7507KN | IH6216CJ/883B IH6216CPI IH6216C/J IH6216CJ/883B IH6216CPI | D129AP D129BP DG123AL DG123AP DG123BP | D129AK D129BK DG123AK DG123BK DG123BK | DG182AA DG182AL DG182AL DG182AL DG182AP | DGM182AA DG182AL DGM182AL DG182AK DGM182AK | DG281BP DG284AP DG284BP DG287AA DG287AP | IH182CJD IH185MJE IH185CJE IH188MTW IH188MJD |
| AD7507SD AD7507SD/883B AD7507TD AD7507TD/883B AH0126CD | IH6216M/D IH6216MJ/883B IH6216MJ IH6216MJ/883B DG126BK | DG125AL DG125AP DG125BP DG125AK DG125AL | DG125AL DG125AK DG125BK DG126AK DG126AL | DG182BA DG182BA DG182BK DG182BK DG182BP | DGM182BA DGM182BA DG182BK DGM182BK DGM182CJ | DG287BA DG287BP DG290AP DG290BP DG381AA | IH188CTW IH188CJD IH191MJE IH191CJE DGM182AA |
| AH0126D AH0126D/883 AH0129CD AH0129D AH0129D/883 | DG126AK DG126AK/883B DG129BK DG129AK DG129AK/883B | DG125BP DG129AL DG129AP DG129BP DG133AL | DG126BK DG129AL DG129AK DG129BK DG133AL | DG183AL DG183AP DG183BP DG184AL DG184AL | DG183AL DG183AK DG183BK DG184AL DGM184AL | DG381AK DG381AP DG381BA DG381BK DG381BP | DGM182AK DGM182AK DGM181BA DGM181BK DGM181BK |
| AH0133CD AH0133D AH0133D/883 AH0134CD AH0134D | DG133BK DG133AK DG133AK/883B DG134BK DG134AK | DG133AP DG133BP DG134AL DG134AP DG134BP | DG133AK DG133BK DG134AL DG134AK DG134BK | DG184AP DG184AP DG184BP DG184BP DG184BP | DGM184AK DGM184AK DG184BK DGM184BK DGM184CJ | DG381CJ DG384AK DG384AP DG384BK DG384BP | DGM181CJ DGM185AK DGM185AK DGM184BK DGM184BK |
| AH0134D/883 AH0133CD AH0133D AH0133D/883 AH0140CD | DG134AK/883B DG139BK DG139AK DG139AK/883B DG140BK | DG139AL DG139AP DG139BP DG140AL DG140AP | DG139AL DG139AK DG139BK DG140AL DG140AK | DG185AL DG185AL DG185AP DG185AP DG185BP | DG185AL DGM185AL DG185AK DGM185AK DG185BK | DG384CJ DG387AA DG387AK DG387AP DG387BA | DGM184CJ DGM189AA DGM188AK DGM188AK DGM187BA |
| AH0140D AH0140D/883 AH0141CD AH0141D AH0141D/883 | DG140AK DG140AK/883B DG141BK DG141AK DG141AK/883B | DG140BP DG141AL DG141AP DG141BP DG142AL | DG140BK DG141AL DG141AK DG141BK DG142AL | DG185BP DG185BP DG185AK DG185AL DG186AP | DGM185BK DGM185CJ DG185AK DG185AL DG186AK | DG387BK DG387BP DG390AK DG390AP DG390BK | DGM187BK DGM187BK DGM191AK DGM191AK DGM190BK |
| AH0142CD AH0142D AH0142D/883 AH0143CD AH0143D | DG142BK DG142AK DG142AK/883B DG143BK DG143AK | DG142AP DG142BP DG143AL DG143AP DG143BP | DG142AK DG142BK DG143AL DG143AK DG143BK | DG186BA DG186BP DG187AA DG187AA DG187AL | DG186BA DG186BK DG187AA DGM187AA DG187AL | DG390BP DG390CJ DG504AK DG504AL DG504CJ | DGM190BK DGM190CJ IH5040MJE IH5040MFD IH5040CPE |
| AH0143D/883 AH0144CD AH0144D AH0144D/883 AH0145CD | DG143AK/883B DG144BK DG144AK DG144AK/883B DG145BK | DG144AL DG144AP DG144BP DG145AL DG145AP | DG144AL DG144AK DG144BK DG145AL DG145AK | DG187AL DG187AP DG187AP DG187BA DG187BA | DGM187AL DG187AK DGM187AK DG187BA DGM187BA | DG5040CK DG5041AA DG5041AK DG5041AL DG5041CJ | IH5040CJE IH5041MTW IH5041MJE IH5041MFD IH5041CPE |
| AH0145D AH0145D/883 AH0145CD AH0145D AH0145D/883 | DG145AK DG145AK/883B DG145BK DG145AK DG145AK/883B | DG145BP DG146AL DG146AP DG146BP DG151AL | DG145BK DG146AL DG146AK DG146BK DG151AL | DG187BP DG187BP DG188AA DG188AA DG188AL | DGM187BK DGM187BK DG188AA DGM188AA DG188AL | DG5041CK DG5042AA DG5042AK DG5042AL DG5042CJ | IH5041CJE IH5042MTW IH5042MJE IH5042MFD IH5042CPE |
| AH0151CD AH0151D/883 AH0152CD AH0152D AH0152D/883 | DG151BK DG151AK/883B DG152BK DG152AK DG152AK/883B | DG151AP DG151BP DG152AL DG152AP DG152BP | DG151AK DG151BK DG152AL DG152AK DG152BK | DG188AL DG188AP DG188AP DG188AP DG188BA | DGM188AL DG188AK DGM188AK DGM188BK DGM188BA | DG5042CK DG5043AK DG5043AL DG5043CJ DG5043CK | IH5042CJE IH5043MJE IH5043MFD IH5043CPE IH5043CJE |
| AH0153CD AH0153D AH0153D/883 AH0154CD AH0154D | DG153BK DG153AK DG153AK/883B DG154BK DG154AK | DG153AL DG153AP DG153BP DG154AL DG154AP | DG153AK DG153AK DG153BK DG154AL DG154AK | DG188BA DG188BP DG189AL DG189AP DG189BP | DGM188BA DG188BK DG189AL DGM190AK DG189BK | DG5044AA DG5044AK DG5044AL DG5044CJ DG5044CK | IH5044MTW IH5044MJE IH5044MFD IH5044CPE IH5044CJE |
| AH0154D/883 AH0155D AH0161CD AH0161D AH0161D/883 | DG154AK/883B DG151AK DG161BK DG161AK DG161AK/883B | DG154BP DG161AL DG161AP DG161BP DG162AL | DG154BK DG161AL DG161AK DG161BK DG162AL | DG190AL DG190AL DG190AP DG190AP DG190BP | DGM190AL DGM190AL DG190AK DGM190AK DG190BK | DG5045AK DG5045AL DG5045CJ DG5045CK DG505AR | IH5045MJE IH5045MFD IH5045CPE IH5045CJE IH6116MJ |
| AH0162CD AH0162D AH0162D/883B AH0163CD AH0163D | DG162BK DG162AK DG162AK/883B DG163BK DG163AK | DG162AP DG162BP DG163AL DG163AP DG163BP | DG162AK DG162BK DG163AL DG163AK DG163BK | DG190BP DG190BP DG191AL DG191AL DG191AP | DGM190BK DGM190CJ DG191AL DGM191AL DG191AK | DG506BR DG506CJ DG507AR DG507BR DG507CJ | IH6116CJ IH6116CPI IH6216MJ IH6216CJ IH6216CPI |
| AH0163D/883 AH0164CD AH0164D AH0164D/883 AH5009CN | DG163AK/883B DG164BK DG164AK DG164AK/883B IH5009CPO | DG164AL DG164AP DG164BP DG164AP DG160AL | DG164AL DG164AK DG164BK DG164AK DG160AL | DG191AP DG191BP DG191BP DG191BP DG200AA | DGM191AK DGM191BK DGM191BK DGM191CJ DG200AA | DG508AP DG508BP DG508CJ DG508AP DG509BP | IH6108MJE IH6108CJE IH6108CPE IH5208MJE IH6208CJE |

**CONSULT FACTORY

ANALOG SWITCH CROSS REFERENCE (cont.)

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| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
|---|---|---|---|---|---|--------------------------|---------------------|
| DG509CJ DGM111AL DGM111AP DGM118P G115AP | IH6208CPE DG111AL DG111AK DG111BK G115AK | H11-5041-5 H11-5041-8 H11-5042-2 H11-5042-5 H11-5042-8 | IH5041CJE IH5041MJE/883B IH5042MJE IH5042CJE IH5142MJE/883B | TL182CN TL182L TL182IN TL182ML TL185CJ | DGM182CJ DGM182BA DGM182CJ DGM182AA IH5045CJE | | |
| G1158P G1158P G1158L G116AP G116BP | G115BJ G115BK G115AL G116AK G1158J | H11-5043-2 H11-5043-5 H11-5043-8 H11-5044-2 H11-5044-5 | IH5143MJE IH5143CJE IH5143MJE/883B IH5144MJE IH5144CJE | TL185CN TL185UJ TL185IN TL185MJ TL185CL | IH6D45CPE IH6D45CJE IH5045CPE IH6D45MJE IH6D42CTW | | |
| G116BP G117AL G118AL G118AP G119AL | G116BK G117AL G118AL G118AK G119AL | H11-5044-8 H11-5045-2 H11-5045-5 H11-5045-8 H11-5046-2 | IH5144MJE/883B IH5145MJE IH5145CJE IH5145MJE/883B IH5046MJE | TL188CN TL188L TL188IN TL188ML TL191CJ | IH5042CPE IH5042CTW IH5042CPE IH5042MTW IH5043CJE | | |
| G123AL G123AP HIQ-0201-6 HIQ-0381-6 HIQ-0384-6 | G123AL G123AK DG201C/D DGM181C/D DGM184C/D | H11-5046-5 H11-5046-8 H11-5047-2 H11-5047-5 H11-5047-8 | IH5046CJE IH5046MJE/883B IH6D47MJE IH6D47CJE IH5047MJE/883B | TL191CN TL191J TL191IN TL191MJ | IH5043CPE IH5043CJE IH5043CPE IH6D43MJE | | |
| HIQ-0387-6 HIQ-0390-6 HIQ-0506-6 HIQ-0508A-6 HIQ-0507-6 | DGM187C/D DGM190C/D IH6118C/D IH5118C/D IH6218C/D | H11-5049-2 H11-5049-5 H11-5049-8 H11-5050-2 H11-5050-5 | IH5149MJE IH5149CJE IH5149MJE/883B IH5150MJE IH5150CJE | | | | |
| HIQ-0507A-6 HIQ-0508-6 HIQ-0508A-6 HIQ-0509-6 HIQ-0509A-6 | IH5216C/D IH6108C/D IH5108C/D IH6208C/D IH5208C/D | H11-5050-8 H11-5051-2 H11-5051-5 H11-5051-8 H12-0200-2 | IH5150MJE/883B IH5151MJE IH5151CJE IH5151MJE/883B DG200AA | | | | |
| HIQ-5040-6 HIQ-5041-6 HIQ-5042-6 HIQ-5043-6 HIQ-5044-6 | IH5140C/D IH5141C/D IH5142C/D IH5143C/D IH5144C/D | HI2-0200-4 HI2-0200-5 HI2-0200-8 HI2-0381-2 HI2-0381-5 | DG200BA DG200BA DG200AA/883B DGM182AA DGM181BA | | | | |
| HIQ-5045-6 HIQ-5046-6 HIQ-5047-6 HIQ-5048-6 HIQ-5050-6 | IH5145C/D IH5046C/D IH5047C/D IH5148C/D IH5150C/D | HI2-0381-8 HI2-0387-2 HI2-0387-5 HI2-0387-8 HI3-0200-5 | DGM181AA/883B DGM188AA DGM187BA DGM188AA/883B DG200CJ | | | | |
| HIQ-5051-6 HI1-0200-2 HI1-0200-4 HI1-0200-5 HI1-0200-6 | IH5051C/D DG200AK DG200BK DG200BK DG200C/D | HI3-0201-5 HI3-0381-5 HI3-0384-5 HI3-0380-5 HI3-0506-5 | DG201CJ DGM181CJ DGM184CJ DGM190CJ IH5116CPI | | | | |
| HI1-0200-8 HI1-0201-2 HI1-0201-4 HI1-0201-5 HI1-0201-8 | DG200AK/883B DG201AK DG201BK DG201BK DG201AK/883B | HI3-0506A-5 HI3-0507-5 HI3-0507A-5 HI3-0508-5 HI3-0508A-5 | IH5116CPI IH6216CPI IH5216CPI IH6108CPE IH5108CPE | | | | |
| HI1-0381-2 HI1-0381-5 HI1-0381-8 HI1-0384-2 HI1-0384-5 | DGM182AK DGM181BK DGM182AK/883B DGM185AK DGM184BK | HI3-0508-5 HI3-0509A-5 LF11201D LF11201D/883B LF11202D | IH6208CPE IH5208CPE DG201AK DG201AK/883B IH202MJE | | | | |
| HI1-0384-8 HI1-0387-2 HI1-0387-5 HI1-0387-8 HI1-0390-2 | DGM185AK/883B DGM188AK DGM187BK DGM188AK/883B DGM191AK | LF11202D/883B LF11508D LF11508D/883B LF11509D LF11509D/883B | IH202MJE/883B IH6109MJE IH6108MJE/883B IH6208MJE IH6208MJE/883B | | | | |
| HI1-0390-5 HI1-0390-8 HI1-0506-2 HI1-0506-5 HI1-0506-8 | DGM190BK DGM191AK/883B IH6116MJ IH6116CJ IH6116MJ/883B | LF13201D LF13201N LF13202D LF13508D LF13508N | DG201BK DG201CJ IH202CJE IH6108CJE IH6108CPE | | | | |
| HI1-0506A-2 HI1-0506A-5 HI1-0506A-8 HI1-0507-2 HI1-0507-5 | IH5116MJ IH5116J IH5116MJ/883B IH6216MJ IH6216CJ | LF13509D LF13508N MM450H MM451H MM452D | IH6208CJE IH6208CPE MM450H MM451H MM452J | | | | |
| HI1-0507-8 HI1-0507A-2 HI1-0507A-5 HI1-0507A-8 HI1-0508-2 | IH6216MJ/883B IH5216MJ IH5216J IH5216MJ/883B IH6108MJE | MM452F MM455H MM550H MM551H MM552D | MM452F MM455H MM550H MM551H MM552J | | | | |
| HI1-0508-5 HI1-0508-8 HI1-0508A-2 HI1-0508A-5 HI1-0508A-8 | IH6108CJE IH6108MJE/883B IH5108MJE IH5108J IH5108MJE/883B | MM552F MM555H SJM181BCC SJM181BIC SJM182BCC | MM552F MM555H JM38510/111018CC JM38510/111018IC JM38510/111028CC | | | | |
| HI1-0509-2 HI1-0509-5 HI1-0509-8 HI1-0509A-2 HI1-0509A-5 | IH6208MJE IH6208CJE IH6208MJE/883B IH5208MJE IH5208J | SJM182BIC SJM184BEC SJM185BEC SJM187BCC SJM187BIC | JM38510/111028IC JM38510/111038BEC JM38510/111048BEC JM38510/111058BCC JM38510/111058IC | | | | |
| HI1-0509A-8 HI1-5040-2 HI1-5040-5 HI1-5040-8 HI1-5041-2 | IH5208MJE/883B IH5040MJE IH5040CJE IH5040MJE/883B IH5041MJE | SJM188BCC SJM188BIC SJM190BEC SJM191BEC TL182CL | JM38510/111068BCC JM38510/111068BIC JM38510/111078BEC JM38510/111088BEC DGM182BA | | | | |

DATA ACQUISITION CROSS REFERENCE



| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
|--|--|--|--|--------------------------|---------------------|--------------------------|---------------------|
| AD7520JD AD7520JN AD7520KD AD7520KN AD7520LD | AD7520JD AD7520JN AD7520KD AD7520KN AD7520LD | MP7521LN MP7521SD MP7521TD MP7521UD MP7523JN | AD7521LN AD7521SD AD7521TD AD7521UD AD7523JN | | | | |
| AD7520LN AD7520SD AD7520TD AD7520UD AD7521JD | AD7520LN AD7520SD AD7520TD AD7520UD AD7521JD | MP7523KN MP7523LN MP7521AD MP7521BD MP7521JN | AD7523KN AD7523LN AD7541AD AD7541BD AD7541JN | | | | |
| AD7521JN AD7521KD AD7521KN AD7521LD AD7521LN | AD7521JN AD7521KD AD7521KN AD7521LD AD7521LN | MP7521KN MP7521SD MP7521TD | AD7541KN AD7541SD AD7541TD | | | | |
| AD7521SD AD7521TD AD7521UD AD7523AD AD7523BD | AD7521SD AD7521TD AD7521UD AD7523AD AD7523BD | | | | | | |
| AD7523CD AD7523JN AD7523KN AD7523LN AD7523SD | AD7523CD AD7523JN AD7523KN AD7523LN AD7523SD | | | | | | |
| AD7523TD AD7523UD AD7530JD AD7530JN AD7530KD | AD7523TD AD7523UD AD7530JD AD7530JN AD7530KD | | | | | | |
| AD7530KN AD7530LD AD7530LN AD7531JD AD7531JN | AD7530KN AD7530LD AD7530LN AD7531JD AD7531JN | | | | | | |
| AD7531KD AD7531KN AD7531LD AD7531LN AD7533AD | AD7531KD AD7531KN AD7531LD AD7531LN AD7533AD | | | | | | |
| AD7533BD AD7533CD AD7533JN AD7533KN AD7533LN | AD7533BD AD7533CD AD7533JN AD7533KN AD7533LN | | | | | | |
| AD7533SD AD7533TD AD7533UD AD7541AD AD7541BD | AD7533SD AD7533TD AD7533UD AD7541AD AD7541BD | | | | | | |
| AD7541JN AD7541KN AD7541SD AD7541TD DAC1020LCD | AD7541JN AD7541KN AD7541SD AD7541TD AD7520LD | | | | | | |
| DAC1020LD DAC1021LCD DAC1021LD DAC1022LCD DAC1022LD | AD7520UD AD7520KD AD7520TD AD7520JD AD7520SD | | | | | | |
| DAC1218LCD DAC1218LCD DAC1218LCD DAC1219LCD DAC1219LCD | AD7541BD AD7541KN AD7541LN AD7541AD AD7541JN | | | | | | |
| DAC1220LCD DAC1220LD DAC1221LCD DAC1221LD DAC1222LCD | AD7521LD AD7521UD AD7521KD AD7521TD AD7521JD | | | | | | |
| DAC1222LD MP7520JD MP7520JN MP7520KD MP7520KN | AD7521SD AD7520JD AD7520JN AD7520KD AD7520KN | | | | | | |
| MP7520LD MP7520LN MP7520SD MP7520TD MP7520UD | AD7520LD AD7520LN AD7520SD AD7520TD AD7520UD | | | | | | |
| MP7521JD MP7521JN MP7521KD MP7521KN MP7521LD | AD7521JD AD7521JN AD7521KD AD7521KN AD7521LD | | | | | | |

**CONSULT FACTORY

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WATCH & CLOCK CROSS REFERENCE

| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
|---|--|--------------------------|---------------------|--------------------------|---------------------|--------------------------|---------------------|
| CD22001H CD22015E E1115 E1151 E1426 | ICM1424C ICM7051A ICM1115A ICM1115B ICM7050U | | | | | | |
| HD43871 HD43871 KSS183 KSS240B01H KSS240B01J | ICM7050G ICM7050H ICM7269 ICM7245B ICM7245A | | | | | | |
| KSS240B10H KSS240B12H KSS240B20H KSS240U01E M5001 | ICM7245D ICM7245E ICM7245F ICM7245U ICM7269 | | | | | | |
| M58434P M58435P M58436-001P M58437-001P MB101 | ICM7038D ICM1115B ICM7050G ICM7070L ICM7245B | | | | | | |
| MB103 MB105 MB107 MB108 MB143 | ICM7245E ICM7245U ICM7245D ICM7245E ICM7245A | | | | | | |
| MB144 MB510 MB511 MB512 MB513 | ICM7245F ICM1115B ICM7050H ICM7050H ICM7050G | | | | | | |
| MB521 MB522 MB531 MB533 MB541 | ITS9068 ITS9066 ICM7050H ICM7050H ICM7052 | | | | | | |
| MBS42 MB7B MCC14440 MCC14463 MJ41 | ICM7052 ICM7245U ICM1424C ICM7210 ICM1424C | | | | | | |
| MJ6 MN6091 MN6092A MN6093 MN6252 | ICM7220 ICM7038B ICM7038E ICM7051A ICM7050G | | | | | | |
| MSM5001 MSM5011 MSM5977 S1424 SCL54301 | ICM7269 ICM1424C ICM1424C ICM1424C ICM1424C | | | | | | |
| SCL5478 SM5011 SM5510 SM5530B TC8031P | ICM7269 ICM7050G ICM1115B ICM7070P ICM7038A | | | | | | |
| TC8032P TC8051P TC8052P TC8058PA TC8057P | ICM7038F ICM7038B ICM7038E ICM1115B ICM7038D | | | | | | |
| UCN-4111M UCN-4112M UCN-4113M UPD1852P UPD1862C | ICM7038C ICM7051A ICM7038B ICM7220MFA ICM7050G | | | | | | |
| UPD1963C UPD816C UPD816C UPD820C UPD833G | ICM7050 ICM7038E ICM7038B ICM1115B ICM7223 | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |
| | | | | | | | |

***CONSULT FACTORY



LINEAR CROSS REFERENCE

| ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT | ALTERNATE SOURCE PRODUCT | INTERSIL EQUIVALENT |
|--|---|--|---|--------------------------|---------------------|--------------------------|---------------------|
| 723 733 741 748 AD101 | UA723 UA733 UA741 UA748 LM101 | MC1741 MC1748 MHW590 MP55010 NE590 | UA741 UA748 AD590 ICL8069 AD590 | | | | |
| AD108 AD301 AD808 AD503 AD532 | LM108 LM301 LM308 AD503 AD532 | NE592 DP-05 DP-07 DP-08 PM308 | NE592 OP-05 OP-07 OP-08 LM308 | | | | |
| AD534 AD550 AD741 AM2502 AM2503 | AD534 AD550 UA741 AM2502 AM2503 | RC723 RC733 RC741 RC748 RM723 | UA723 UA733 UA741 UA748 UA723 | | | | |
| AM2504 AM5402 AM5402 CA101 CA107 | AM2504 HA2505 HA2525 LM101 LM107 | RM741 RM748 SC748 SG101 SG105 | UA741 UA748 UA748 LM101 LM105 | | | | |
| CA111 CA301 CA307 CA308 CA311 | LM111 LM301 LM307 LM308 LM311 | SG107 SG108 SG110 SG111 SG2502 | LM107 LM108 LM110 LM111 AM2502 | | | | |
| CA723 CA741 CA748 DG503 DM2502 | UA723 UA741 UA748 AD503 AM2502 | SG2503 SG301 SG305 SG307 SG308 | AM2503 LM301 LM305 LM307 LM308 | | | | |
| DM2503 DM2504 HA2500 HA2502 HA2505 | AM2503 AM2504 HA2500 HA2502 HA2505 | SG311 SG4250 SG723 SG733 SG741 | LM311 LM4250 UA723 UA733 UA741 | | | | |
| HA2507 HA2510 HA2512 HA2515 HA2517 | HA2507 HA2510 HA2512 HA2515 HA2517 | SG748 SS5741 SU536 TL503 TL592 | UA748 UA741 SU536 AD503 NE592 | | | | |
| HA2520 HA2522 HA2525 HA2527 HA2500 | HA2520 HA2522 HA2525 HA2527 HA2500 | TT-590 UA101 UA102 UA105 UA107 | AD590 LM101 LM102 LM105 LM107 | | | | |
| HA2602 HA2605 HA2607 HA2620 HA2622 | HA2602 HA2605 HA2607 HA2620 HA2622 | UA108 UA110 UA111 UA301 UA302 | LM108 LM110 LM111 LM301 LM302 | | | | |
| HA2625 HA2627 HA2720 LH0042 LH2101 | HA2625 HA2627 ICL8021 LH0042 LH2101 | UA305 UA307 UA308 UA310 UA311 | LM305 LM307 LM308 LM310 LM311 | | | | |
| LH2108 LH2110 LH2111 LH2301 LH2308 | LH2108 LH2110 LH2111 LH2301 LH2308 | UA723 UA733 UA740 UA741 UA748 | UA723 UA733 UA740 UA741 UA748 | | | | |
| LH2310 LH2311 LM100 LM101 LM102 | LH2310 LH2311 LM100 LM101 LM102 | UA777 UHP-503 VR-8069 WG-8038 XR6038 | UA777 AD503 ICL8069 ICL8038 ICL8038 | | | | |
| LM105 LM107 LM108 LM110 LM111 | LM105 LM107 LM108 LM110 LM111 | | | | | | |
| LM300 LM301 LM302 LM305 LM307 | LM300 LM301 LM302 LM305 LM307 | | | | | | |
| LM308 LM310 LM311 LM4250 LM723 | LM308 LM310 LM311 LM4250 UA723 | | | | | | |
| LM733 LM740 LM741 LM748 MC1723 | UA733 UA740 UA741 UA748 UA723 | | | | | | |

**CONSULT FACTORY

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DISCRETE PRODUCT REFERENCE GUIDE

Switches — Junction FET

| Ordering Information | | r _{DS(on)} max Ω | V _p min/max V | I _{SS} max pA | BV _{SS} min V | I _{D(off)} max pA | I _{SS} min/max mA | t _{total} max ns | C _{iss} max pF | C _{rss} max pF | | |
|---|---------|---------------------------------|--------------------------------|------------------------------|------------------------------|----------------------------------|----------------------------------|---------------------------------|-------------------------------|-------------------------------|---------|----------|
| Preferred Part Number | Package | | | | | | | | | | | |
| N-channel: Generally requires driver circuit to translate the popular logic levels to voltages required to drive the JFET. | | | | | | | | | | | | |
| 2N3970 | TO-18 | 30 | -4.0 | -10.0 | (-250) | -40 | 250 | 50 | 150 | 50 | 25 | 6.0 |
| 2N3971 | TO-18 | 60 | -2.0 | -5.0 | (-250) | -40 | 250 | 25 | 75 | 90 | 25 | 6.0 |
| 2N3972 | TO-18 | 100 | -0.5 | -3.0 | (-250) | -40 | 250 | 5 | 30 | 180 | 25 | 6.0 |
| 2N4091 | TO-18 | 30 | -5.0 | -10.0 | -200 | -40 | 200 | 30 | | 65 | 16 | 5.0 |
| 2N4092 | TO-18 | 50 | -2.0 | -7.0 | -200 | -40 | 200 | 15 | | 95 | 16 | 5.0 |
| 2N4093 | TO-18 | 80 | -1.0 | -5.0 | -200 | -40 | 200 | 8 | | 140 | 16 | 5.0 |
| 2N4391 | TO-18 | 30 | -4.0 | -10.0 | -100 | -40 | 100 | 50 | 150 | 55 | 14 | 3.5 |
| 2N4392 | TO-18 | 60 | -2.0 | -5.0 | -100 | -40 | 100 | 25 | 75 | 75 | 14 | 3.5 |
| 2N4393 | TO-18 | 100 | -0.5 | -3.0 | -100 | -40 | 100 | 5 | 30 | 100 | 14 | 3.5 |
| 2N4856 | TO-18 | 25 | -4.0 | -10.0 | -250 | -40 | 250 | 50 | | 34 | 18 | 8.0 |
| 2N4857 | TO-18 | 40 | -2.0 | -6.0 | -250 | -40 | 250 | 20 | 100 | 60 | 18 | 8.0 |
| 2N4858 | TO-18 | 60 | -0.8 | -4.0 | -250 | -40 | 250 | 8 | 80 | 120 | 18 | 8.0 |
| 2N4859 | TO-18 | 25 | -4.0 | -10.0 | -250 | -30 | 250 | 50 | | 34 | 18 | 8.0 |
| 2N4860 | TO-18 | 40 | -2.0 | -6.0 | -250 | -30 | 250 | 20 | 100 | 60 | 18 | 8.0 |
| 2N4861 | TO-18 | 60 | -0.8 | -4.0 | -250 | -30 | 250 | 8 | 80 | 120 | 18 | 8.0 |
| 2N5432 | TO-52 | 5 | -4.0 | -10.0 | -200 | -25 | 200 | 150 | | 41 | 30 | 15.0 |
| 2N5433 | TO-52 | 7 | -3.0 | -9.0 | -200 | -25 | 200 | 100 | | 41 | 30 | 15.0 |
| 2N5434 | TO-52 | 10 | -1.0 | -4.0 | -200 | -25 | 200 | 30 | | 41 | 30 | 15.0 |
| 2N5638 | TO-92 | 30 | | -12.0 | -1nA | -30 | 1nA | 50 | | 24 | 10 | 4.0 |
| 2N5639 | TO-92 | 60 | | -8.0 | -1nA | -30 | 1nA | 25 | | 44 | 10 | 4.0 |
| 2N5640 | TO-92 | 100 | | -6.0 | -1nA | -30 | 1nA | 5 | | 63 | 10 | 4.0 |
| ITE4091 | TO-92 | 30* | -5.0 | -10.0 | -200 | -40 | 200 | 30 | | 65 | 16 | 5.0 |
| ITE4092 | TO-92 | 50 | -2.0 | -7.0 | -200 | -40 | 200 | 15 | | 95 | 16 | 5.0 |
| ITE4093 | TO-92 | 80 | -1.0 | -5.0 | -200 | -40 | 200 | 8 | | 140 | 16 | 5.0 |
| ITE4391 | TO-92 | 30 | -4.0 | -10.0 | -100 | -40 | 100 | 50 | 150 | 55 | 14 | 3.5 |
| ITE4392 | TO-92 | 60 | -2.0 | -5.0 | -100 | -40 | 100 | 25 | 75 | 75 | 14 | 3.5 |
| ITE4393 | TO-92 | 100 | -0.5 | -3.0 | -100 | -40 | 100 | 5 | 30 | 100 | 14 | 3.5 |
| J105 | TO-92 | 3 | -4.5 | -10.0 | -3nA | -25 | 3nA | 500 | | 60 | (70) | (3.5) |
| J106 | TO-92 | 6 | -2.0 | -6.0 | -3nA | -25 | 3nA | 200 | | 60 | (70) | (3.5) |
| J107 | TO-92 | 8 | -0.5 | -4.5 | -3nA | -25 | 3nA | 100 | | 60 | (70) | (3.5) |
| J111 | TO-92 | 30 | -3.0 | -10.0 | -1nA | -35 | 1nA | 20 | | 48 | (16) | (5.0) |
| J112 | TO-92 | 50 | -1.0 | -5.0 | -1nA | -35 | 1nA | 5 | | 48 | (16) | (5.0) |
| J113 | TO-92 | 100 | -0.5 | -3.0 | -1nA | -35 | 1nA | 2 | | 48 | (16) | (5.0) |
| P-channel: | | | | | | | | | | | | |
| 2N3993 | TO-72 | 150 | 4.0 | 9.5 | 1.2nA | 25 | 1.2nA | -10.0 | | | 16 | 4.5 |
| 2N3994 | TO-72 | 300 | 1.0 | 5.5 | 1.2nA | 25 | 1.2nA | -2.0 | | | 16 | 4.5 |
| 2N5114 | TO-18 | 75 | 5.0 | 10.0 | 500 | 30 | 500 | -30.0 | -90 | 37 | 25 | 7.0 |
| 2N5115 | TO-18 | 100 | 3.0 | 6.0 | 500 | 30 | 500 | -15.0 | -60 | 68 | 25 | 7.0 |
| 2N5116 | TO-18 | 150 | 1.0 | 4.0 | 500 | 30 | 500 | -5.0 | -25 | 102 | 25 | 7.0 |
| IT100 | TO-18 | 75 | 2.0 | 4.5 | 200 | 35 | 100 | -10.0 | | | 35 | 12.0 |
| IT101 | TO-18 | 60 | 4.0 | 10.0 | 200 | 35 | 100 | -20.0 | | | 35 | 12.0 |
| J174 | TO-92 | 85 | 5.0 | 10.0 | 1nA | 30 | -1nA | -20.0 | -100 | 22 | (25) | (8.0) |
| J175 | TO-92 | 125 | 3.0 | 6.0 | 1nA | 30 | -1nA | -7.0 | -60 | 45 | (25) | (8.0) |
| J176 | TO-92 | 250 | 1.0 | 4.0 | 1nA | 30 | -1nA | -2.0 | -25 | 70 | (25) | (8.0) |
| J177 | TO-92 | 300 | 0.8 | 2.25 | 1nA | 30 | -1nA | -1.5 | -20 | 90 | (25) | (8.0) |
| J270 | TO-92 | — | 0.5 | 2.0 | 200 | 30 | — | -2.0 | -15 | — | 32 typ. | 4.0 typ. |
| J271 | TO-92 | — | 1.5 | 4.5 | 200 | 30 | — | -6.0 | -50 | — | 32 typ. | 4.0 typ. |
| P1086 | TO-92 | 75 | — | 10.0 | 2nA | 30 | -10nA | -10.0 | — | 100 | 45 | 10.0 |
| P1087 | TO-92 | 150 | — | 5.0 | 2nA | 30 | -10nA | -5.0 | — | 215 | 45 | 10.0 |

() Approximate Value

Switches and Amplifiers — MOSFET

| Ordering Information | | $V_{GS(TH)}$ | | BV_{GSS} min V | I_{DSS} max pA | I_{GSS} max pA | G_{fs} min μ mho | $r_{DS(ON)}$ max Ω | I_D $I_{Q(ON)}$ min/max mA | |
|---|---------|-------------------------------|------|------------------------|------------------------|------------------------|------------------------------|---------------------------------|---------------------------------------|----------------------|
| Preferred Part Number | Package | $V_{GS(OFF)}$ min/max V | V | | | | | | | |
| P-Channel Enhancement: Gen. used where max isolation between signal source and logic drive required; sw: "On" resistance varies with signal amplitude. | | | | | | | | | | |
| 3N161 | TO-72 | -1.5 | -5.0 | -25 | -10nA | -100.0 | 3500.0 | (125) | -40 | -120 Diode Protected |
| 3N163 | TO-72 | -2.0 | -5.0 | -40 | -200 | -10.0 | 2000.0 | 250 | -5 | -30 |
| 3N164 | TO-72 | -2.0 | -5.0 | -30 | -400 | -10.0 | 2000.0 | 300 | -3 | -30 |
| 3N172 | TO-72 | -2.0 | -5.0 | -40 | -400 | -200.0 | (2000.0) | 250 | -5 | -30 Diode Protected |
| 3N173 | TO-72 | -2.0 | -5.0 | -30 | -10nA | -500.0 | (1000.0) | 350 | -5 | -30 Diode Protected |
| IT1700 | TO-72 | -2.0 | -5.0 | -40 | -200 | -10.0 | 2000.0 | 400 | -2 | - |
| N-Channel Enhancement: Can switch positive signals directly from TTL logic; gen. requires driver or translator circuit to switch bipolar signals. | | | | | | | | | | |
| 2N4351 | TO-72 | 1.0 | 5.0 | 25 | 10nA | 10.0 | 1000.0 | 300 | 3 | - |
| 3N170 | TO-72 | 1.0 | 2.0 | 25 | 10nA | 10.0 | 1000.0 | 200 | 10 | - |
| 3N171 | TO-72 | 1.5 | 3.0 | 25 | 10nA | 10.0 | 1000.0 | 200 | 10 | - |
| IT1750 | TO-72 | 0.5 | 3.0 | 25 | 10nA | 10.0 | 3000.0 | 50 | 10 | 100 |
| M116 | TO-72 | 1.0 | 5.0 | 30 | (10nA) | 100.0 | (1000.0) | 100 | - | Diode Protected |

Amplifiers — N-Channel Junction FET

| Ordering Information | | G_{fs} min μ mho | I_{DSS} min/max mA | V_p min/max V | I_{GSS} max pA | BV_{GSS} min V | C_{iss} max pF | C_{rss} max pF | θ_n max nv/ \sqrt Hz | | |
|-----------------------|---------|------------------------------|----------------------------|-----------------------|------------------------|------------------------|------------------------|------------------------|-------------------------------------|-----|----------------|
| Preferred Part Number | Package | | | | | | | | | | |
| 2N3684 | TO-72 | 2000 | 2.5 | 7.5 | -2.0 | -5.0 | -100 | -50 | 4 | 1.2 | 140 @ 100Hz |
| 2N3685 | TO-72 | 1500 | 1.0 | 3.0 | -1.0 | -3.5 | -100 | -50 | 4 | 1.2 | 140 @ 100Hz |
| 2N3686 | TO-72 | 1000 | 0.4 | 1.2 | -0.6 | -2.0 | -100 | -50 | 4 | 1.2 | 140 @ 100Hz |
| 2N3687 | TO-72 | 500 | 0.1 | 0.5 | -0.3 | -1.2 | -100 | -50 | 4 | 1.2 | 140 @ 100Hz |
| 2N3821 | TO-72 | 1500 | 0.5 | 2.5 | - | -4.0 | -100 | -50 | 6 | 3.0 | 200 @ 10Hz |
| 2N3822 | TO-72 | 3000 | 2.0 | 10.0 | - | -6.0 | -100 | -50 | 6 | 3.0 | 200 @ 10Hz |
| 2N3823 | TO-72 | 3500 | 4.0 | 20.0 | - | -8.0 | -500 | -30 | 6 | 2.0 | - |
| 2N3824 | TO-72 | - | - | - | - | (-8.0) | -100 | -50 | 6 | 3.0 | - |
| 2N4117 | TO-72 | 70 | 0.03 | 0.09 | -0.6 | -1.8 | -10 | -40 | 3 | 1.5 | - |
| 2N4117A | TO-72 | 70 | 0.03 | 0.09 | -0.6 | -1.8 | -1 | -40 | 3 | 1.5 | - |
| 2N4118 | TO-72 | 80 | 0.08 | 0.24 | -1.0 | -3.0 | -10 | -40 | 3 | 1.5 | - |
| 2N4118A | TO-72 | 80 | 0.08 | 0.24 | -1.0 | -3.0 | -1 | -40 | 3 | 1.5 | - |
| 2N4119 | TO-72 | 100 | 0.2 | 0.6 | -2.0 | -6.0 | -10 | -40 | 3 | 1.5 | - |
| 2N4119A | TO-72 | 100 | 0.2 | 0.6 | -2.0 | -6.0 | -1 | -40 | 3 | 1.5 | - |
| 2N4220 | TO-72 | 1000 | 0.5 | 0.3 | - | -4.0 | -100 | -30 | 6 | 2.0 | - |
| 2N4221 | TO-72 | 2000 | 2.0 | 6.0 | - | -6.0 | -100 | -30 | 6 | 2.0 | - |
| 2N4222 | TO-72 | 2500 | 5.0 | 15.0 | - | -8.0 | -100 | -30 | 6 | 2.0 | - |
| 2N4223 | TO-72 | 3000 | 3.0 | 18.0 | -0.1 | -8.0 | -250 | -30 | 6 | 2.0 | - |
| 2N4224 | TO-72 | 2000 | 2.0 | 20.0 | -0.1 | -8.0 | -500 | -30 | 6 | 2.0 | - |
| 2N4338 | TO-18 | 600 | 0.2 | 0.6 | -0.3 | -1.0 | -100 | -50 | 7 | 3.0 | 65 @ 1kHz |
| 2N4339 | TO-18 | 800 | 0.5 | 1.5 | -0.6 | -1.8 | -100 | -50 | 7 | 3.0 | 65 @ 1kHz |
| 2N4340 | TO-18 | 1300 | 1.2 | 3.6 | -1.0 | -3.0 | -100 | -50 | 7 | 3.0 | 65 @ 1kHz |
| 2N4341 | TO-18 | 2000 | 3.0 | 9.0 | -2.0 | -6.0 | -100 | -50 | 7 | 3.0 | 65 @ 1kHz |
| 2N4416 | TO-72 | 4500 | 5.0 | 15.0 | - | -6.0 | -100 | -30 | 4 | 2.0 | - |
| 2N4867 | TO-72 | 700 | 0.4 | 1.2 | -0.7 | -2.0 | -250 | -40 | 25 | 5.0 | 10 @ 1kHz |
| 2N4867A | TO-72 | 700 | 0.4 | 1.2 | -0.7 | -2.0 | -250 | -40 | 25 | 5.0 | 5 @ 1kHz |
| 2N4868 | TO-72 | 1000 | 1.0 | 3.0 | -1.0 | -3.0 | -250 | -40 | 25 | 5.0 | 10 @ 1kHz |
| 2N4868A | TO-72 | 1000 | 1.0 | 3.0 | -1.0 | -3.0 | -250 | -40 | 25 | 5.0 | 5 @ 1kHz |
| 2N4869 | TO-72 | 1300 | 2.5 | 7.5 | -1.8 | -5.0 | -250 | -40 | 25 | 5.0 | 10 @ 1kHz |
| 2N4869A | TO-72 | 1300 | 2.5 | 7.5 | -1.8 | -5.0 | -250 | -40 | 25 | 5.0 | 5 @ 1kHz |
| 2N5397 | TO-72 | 6000 | 10.0 | 30.0 | -1.0 | -6.0 | -100 | -25 | 5 | 1.2 | 3.5dB @ 450MHz |
| 2N5398 | TO-72 | 5500 | 5.0 | 40.0 | -1.0 | -6.0 | -100 | -25 | 5.5 | 1.3 | - |
| 2N5457 | TO-92 | 1000 | 1.0 | 5.0 | -0.1 | -6.0 | -1nA | -25 | 7 | 3.0 | - |
| 2N5458 | TO-92 | 1500 | 2.0 | 9.0 | -1.0 | -7.0 | -1nA | -25 | 7 | 3.0 | - |
| 2N5459 | TO-92 | 2000 | 4.0 | 16.0 | -2.0 | -8.0 | -1nA | -25 | 7 | 3.0 | - |

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Amplifiers — N-Channel Junction FET (continued)

| Ordering Information | | g _{fs} min μmho | I _{GSS} min/max mA | | V _p min/max V | | I _{GSS} max pA | BV _{GSS} min V | C _{iss} max pF | C _{rss} max pF | e _n max nv/√Hz |
|-----------------------|---------|--------------------------------|-----------------------------------|------|--------------------------------|-------|-------------------------------|-------------------------------|-------------------------------|-------------------------------|---------------------------------|
| Preferred Part Number | Package | | | | | | | | | | |
| 2N5484 | TO-92 | 3000 | 1.0 | 5.0 | -0.3 | -3.0 | -1nA | -25 | 5 | 1.0 | 120 @ 1kHz |
| 2N5485 | TO-92 | 3500 | 4.0 | 10.0 | -0.5 | -4.0 | -1nA | -25 | 5 | 1.0 | 120 @ 1kHz |
| 2N5486 | TO-92 | 4000 | 8.0 | 20.0 | -2.0 | -6.0 | -1nA | -25 | 5 | 1.0 | 120 @ 1kHz |
| ITE4416 | TO-92 | 4500 | 5.0 | 15.0 | | -6.0 | -100 | -30 | 4 | 2.0 | — |
| J201 | TO-92 | 500 | 0.2 | 1.0 | -0.3 | -1.5 | -100 | -40 | 4 | 1.0 | 5 @ 1kHz |
| J202 | TO-92 | 1000 | 0.9 | 4.5 | -0.8 | -4.0 | -100 | -40 | 4 | 1.0 | 5 @ 1kHz |
| J203 | TO-92 | 1500 | 4.0 | 20.0 | -2.0 | -10.0 | -100 | -40 | 4 | 1.0 | 5 @ 1kHz |
| J204 | TO-92 | 1500 | 1.2 | typ. | -0.5 | -2.0 | -100 | -25 | 4 | 1.0 | 10 @ 1kHz |
| J308 | TO-92 | 8000 | 12.0 | 60.0 | -1.0 | -6.5 | -1nA | -25 | (8) | (5.0) | — |
| J309 | TO-92 | 10,000 | 12.0 | 30.0 | -1.0 | -4.0 | -1nA | -25 | (8) | (5.0) | — |
| J310 | TO-92 | 8000 | 24.0 | 60.0 | -2.0 | -6.5 | -1nA | -25 | (8) | (5.0) | — |
| U308 | TO-52 | 10,000 | 12.0 | 60.0 | -1.0 | -6.0 | -150 | -25 | 7 typ. | 4.0 typ. | 10 @ 100Hz typ. |
| U309 | TO-52 | 10,000 | 12.0 | 30.0 | -1.0 | -4.0 | -150 | -25 | 7 typ. | 4.0 typ. | 10 @ 100Hz typ. |
| U310 | TO-52 | 10,000 | 24.0 | 60.0 | -2.5 | -6.0 | -150 | -25 | 7 typ. | 4.0 typ. | 10 @ 100Hz typ. |

Amplifiers — P-Channel Junction FET

| Ordering Information | | g _{fs} min μmho | I _{GSS} min/max mA | | V _p min/max V | | I _{GSS} max nA | BV _{GSS} min V | C _{iss} max pF | C _{rss} max pF | e _n max nv/√Hz |
|-----------------------|---------|--------------------------------|-----------------------------------|-------|--------------------------------|------|-------------------------------|-------------------------------|-------------------------------|-------------------------------|---------------------------------|
| Preferred Part Number | Package | | | | | | | | | | |
| 2N2607 | TO-18 | 330 | -0.3 | -1.5 | 1.0 | 4.0 | 3 | 30 | 10 | — | 400 @ 1kHz |
| 2N2608 | TO-18 | 1000 | -0.9 | -4.5 | 1.0 | 4.0 | 10 | 30 | 17 | — | 140 @ 1kHz |
| 2N2609 | TO-18 | 2500 | -2.0 | -10.0 | 1.0 | 4.0 | 30 | 30 | 30 | — | 140 @ 1kHz |
| 2N5460 | TO-92 | 1000 | -1.0 | -5.0 | 0.75 | 6.0 | 5 | 40 | 7 | 2 | 115 @ 100Hz |
| 2N5461 | TO-92 | 1500 | -2.0 | -9.0 | 1.0 | 7.5 | 5 | 40 | 7 | 2 | 115 @ 100Hz |
| 2N5462 | TO-92 | 2000 | -4.0 | -16.0 | 1.8 | 9.0 | 5 | 40 | 7 | 2 | 115 @ 100Hz |
| 2N5463 | TO-92 | 1000 | -1.0 | -5.0 | 0.75 | 6.0 | 5 | 60 | 7 | 2 | 115 @ 100Hz |
| 2N5464 | TO-92 | 1500 | -2.0 | -9.0 | 1.0 | 7.5 | 5 | 60 | 7 | 2 | 115 @ 100Hz |
| 2N5465 | TO-92 | 2000 | -4.0 | -16.0 | 1.8 | 9.0 | 5 | 60 | 7 | 2 | 115 @ 100Hz |
| U304 | TO-18 | — | -30.0 | -90.0 | 5.0 | 10.0 | .5 | 30 | 27 | 7 | — |
| J305 | TO-18 | — | -15.0 | -60.0 | 3.0 | 6.0 | .5 | 30 | 27 | 7 | — |
| U306 | TO-18 | — | -5.0 | -25.0 | 1.0 | 4.0 | .5 | 30 | 27 | 7 | — |

Differential Amplifiers — Dual Monolithic N-Channel Junction FET

| Preferred Part Number | Package | V _{GS1-2} max mV | ΔV _{GS} max μV/°C | I _G max pA | BV _{GSS} min V | V _P min/max V | g _{fs} min/max μmho | | I _{DSS} min/max mA | e _n max nV/√Hz |
|-----------------------|---------|---------------------------|----------------------------|-----------------------|-------------------------|--------------------------|------------------------------|-------------|-----------------------------|---------------------------|
| 2N3921 | TO-71 | 5 | 10 | -250 | -50 | - | -3.0 | 1500 7500 | 1.0 10.0 | - |
| 2N3922 | TO-71 | 5 | 25 | -250 | -50 | - | -3.0 | 1500 7500 | 1.0 10.0 | - |
| 2N3954 | TO-71 | 5 | 10 | -50 | -50 | -1.0 | -4.5 | 1000 3000 | 0.5 5.0 | 160 @ 100Hz |
| 2N3954A | TO-71 | 5 | 5 | -50 | -50 | -1.0 | -4.5 | 1000 3000 | 0.5 5.0 | 160 @ 100Hz |
| 2N3955 | TO-71 | 10 | 25 | -50 | -50 | -1.0 | -4.5 | 1000 3000 | 0.5 5.0 | 160 @ 100Hz |
| 2N3955A | TO-71 | 15 | 15 | -50 | -50 | -1.0 | -4.5 | 1000 3000 | 0.5 5.0 | 160 @ 100Hz |
| 2N3956 | TO-71 | 15 | 50 | -50 | -50 | -1.0 | -4.5 | 1000 3000 | 0.5 5.0 | 160 @ 100Hz |
| 2N3957 | TO-71 | 20 | 75 | -50 | -50 | -1.0 | -4.5 | 1000 3000 | 0.5 5.0 | 160 @ 100Hz |
| 2N3958 | TO-71 | 25 | 100 | -50 | -50 | -1.0 | -4.5 | 1000 3000 | 0.5 5.0 | 160 @ 100Hz |
| 2N5196 | TO-71 | 5 | 5 | -15 | -50 | -0.7 | -4.0 | 700 @ 200μA | 0.7 7.0 | 20 @ 1kHz |
| 2N5197 | TO-71 | 5 | 10 | -15 | -50 | -0.7 | -4.0 | 700 @ 200μA | 0.7 7.0 | 20 @ 1kHz |
| 2N5198 | TO-71 | 10 | 20 | -15 | -50 | -0.7 | -4.0 | 700 @ 200μA | 0.7 7.0 | 20 @ 1kHz |
| 2N5199 | TO-71 | 15 | 40 | -15 | -50 | -0.7 | -4.0 | 700 @ 200μA | 0.7 7.0 | 20 @ 1kHz |
| 2N5452 | TO-71 | 5 | 5 | IGSS-100 | -50 | -1.0 | -4.5 | 1000 4000 | 0.5 5.0 | 20 @ 1kHz |
| 2N5453 | TO-71 | 10 | 10 | IGSS-100 | -50 | -1.0 | -4.5 | 1000 4000 | 0.5 5.0 | 20 @ 1kHz |
| 2N5454 | TO-71 | 15 | 25 | IGSS-100 | -50 | -1.0 | -4.5 | 1000 4000 | 0.5 5.0 | 20 @ 1kHz |
| 2N5515 | TO-71 | 5 | 5 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 30 @ 10Hz |
| 2N5516 | TO-71 | 5 | 10 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 30 @ 10Hz |
| 2N5517 | TO-71 | 10 | 20 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 30 @ 10Hz |
| 2N5518 | TO-71 | 15 | 40 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 30 @ 10Hz |
| 2N5519 | TO-71 | 15 | 80 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 30 @ 10Hz |
| 2N5520 | TO-71 | 5 | 5 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 15 @ 10Hz |
| 2N5521 | TO-71 | 5 | 10 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 15 @ 10Hz |
| 2N5522 | TO-71 | 10 | 20 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 15 @ 10Hz |
| 2N5523 | TO-71 | 15 | 40 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 15 @ 10Hz |
| 2N5524 | TO-71 | 15 | 80 | -100 | -40 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 15 @ 10Hz |
| 2N5902 | TO-99 | 5 | 5 | -3 | -40 | -0.6 | -4.5 | 70 250 | 0.3 0.5 | 200 @ 1kHz |
| 2N5903 | TO-99 | 5 | 10 | -3 | -40 | -0.6 | -4.5 | 70 250 | 0.03 0.05 | 200 @ 1kHz |
| 2N5904 | TO-99 | 10 | 20 | -3 | -40 | -0.6 | -4.5 | 70 250 | 0.03 0.05 | 200 @ 1kHz |
| 2N5905 | TO-99 | 15 | 40 | -3 | -40 | -0.6 | -4.5 | 70 250 | 0.03 0.05 | 200 @ 1kHz |
| 2N5906 | TO-99 | 5 | 5 | -1 | -40 | -0.6 | -4.5 | 70 250 | 0.03 0.05 | 100 @ 1kHz |
| 2N5907 | TO-99 | 5 | 10 | -1 | -40 | -0.6 | -4.5 | 70 250 | 0.03 0.05 | 100 @ 1kHz |
| 2N5908 | TO-99 | 10 | 20 | -1 | -40 | -0.6 | -4.5 | 70 250 | 0.03 0.05 | 100 @ 1kHz |
| 2N5909 | TO-99 | 15 | 40 | -1 | -40 | -0.6 | -4.5 | 70 250 | 0.03 0.05 | 100 @ 1kHz |
| 2N5911 | TO-99 | 10 | 20 | -100 | -25 | -1.0 | -5.0 | 5/10 @ 5 mA | 7.0 40.0 | 20 @ 10kHz |
| 2N5912 | TO-99 | 15 | 40 | -100 | -25 | -1.0 | -5.0 | 5/10 @ 5 mA | 7.0 40.0 | 20 @ 10kHz |
| 2N6483 | TO-71 | 5 | 5 | -100 | -50 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 10 @ 10Hz |
| 2N6484 | TO-71 | 10 | 10 | -100 | -50 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 10 @ 10Hz |
| 2N6485 | TO-71 | 15 | 25 | -100 | -50 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 10 @ 10Hz |
| IMF6485 | TO-71 | 25 | 40 | -100 | -50 | -0.7 | -4.0 | 1000 4000 | 0.5 7.5 | 15 @ 10Hz |
| IT500 | TO-52 | 5 | 5 | -5 | -50 | -0.7 | -4.0 | 700 1600 | 0.7 7.0 | 35 @ 10Hz |
| IT501 | TO-52 | 5 | 10 | -5 | -50 | -0.7 | -4.0 | 700 1600 | 0.7 7.0 | 35 @ 10Hz |
| IT502 | TO-52 | 10 | 20 | -5 | -50 | -0.7 | -4.0 | 700 1600 | 0.7 7.0 | 35 @ 10Hz |
| IT503 | TO-52 | 15 | 40 | -5 | -50 | -0.7 | -4.0 | 700 1600 | 0.7 7.0 | 35 @ 10Hz |
| IT504 | TO-52 | 25 | 100 | -5 | -50 | -0.7 | -4.0 | 700 1600 | 0.7 7.0 | 35 @ 10Hz |
| IT505 | TO-52 | 50 | 200 | -5 | -50 | -0.7 | -4.0 | 700 1600 | 0.7 7.0 | 35 @ 10Hz |
| IT5911 | TO-71 | 10 | 20 | -100 | -25 | -1.0 | -5.0 | 5/10 @ 5 mA | 7.0 40.0 | 20 @ 10kHz |
| IT5912 | TO-71 | 15 | 40 | -100 | -25 | -1.0 | -5.0 | 5/10 @ 5 mA | 7.0 40.0 | 20 @ 10kHz |
| U257 | TO-99 | 100 | - | IGSS-100 | -25 | -1.0 | -5.0 | 5000 10000 | 5.0 40.0 | 30 @ 10kHz |
| U401 | TO-71 | 5 | 10 | -15 | -50 | -0.5 | -2.5 | 2000 7000 | 0.5 10.0 | 20 @ 10Hz |
| U402 | TO-71 | 10 | 10 | -15 | -50 | -0.5 | -2.5 | 2000 7000 | 0.5 10.0 | 20 @ 10Hz |
| U403 | TO-71 | 10 | 25 | -15 | -50 | -0.5 | -2.5 | 2000 7000 | 0.5 10.0 | 20 @ 10Hz |
| U404 | TO-71 | 15 | 25 | -15 | -50 | -0.5 | -2.5 | 2000 7000 | 0.5 10.0 | 20 @ 10Hz |
| U405 | TO-71 | 20 | 40 | -15 | -50 | -0.5 | -2.5 | 2000 7000 | 0.5 10.0 | 20 @ 10Hz |
| U406 | TO-71 | 40 | 80 | -15 | -50 | -0.5 | -2.5 | 2000 7000 | 0.5 10.0 | 20 @ 10Hz |
| U421 | TO-99 | 10 | 10 | 0.1 | -60 | -0.4 | -2.0 | 300 800 | 60-1000μA | 20 @ 10Hz |
| U422 | TO-99 | 15 | 25 | 0.1 | -60 | -0.4 | -2.0 | 300 800 | 60-1000μA | 20 @ 10Hz |
| U423 | TO-99 | 25 | 40 | 0.1 | -60 | -0.4 | -2.0 | 300 800 | 60-1000μA | 20 @ 10Hz |
| U424 | TO-99 | 10 | 10 | 0.5 | -60 | -0.4 | -3.0 | 300 1000 | 60-1000μA | 20 @ 10Hz |
| U425 | TO-99 | 15 | 25 | 0.5 | -60 | -0.4 | -3.0 | 300 1000 | 60-1000μA | 20 @ 10Hz |
| U426 | TO-99 | 25 | 40 | 0.5 | -60 | -0.4 | -3.0 | 300 1000 | 60-1000μA | 20 @ 10Hz |

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Differential Amplifiers — Dual Monolithic P-Channel MOSFETS (Enhancement)

| Ordering Information | | $V_{GS(TH)}$ | | BV_{DSS} | I_{DSS} | I_{GSS} | G_{fs} | $I_{DS(ON)}$ | | $r_{DS(ON)}$ | $V_{GS\ 1-2}$ |
|----------------------|---------|--------------|-----|------------|-----------|-----------|-----------|--------------|-----|--------------|---------------------|
| Preferred Part | Package | min/max | max | min/max | max | max | min | min/max | max | max | max |
| Number | | V | | V | μA | μA | μmho | mA | | Ω | mV |
| 3N165 | TO-99 | -2 | -5 | -40 | -200 | -10 | 1500 | -5.0 | -30 | 300 | 100 |
| 3N166 | TO-99 | -2 | -5 | -40 | -200 | -10 | 1500 | -5.0 | -30 | 300 | |
| 3N188 | TO-99 | -2 | -5 | -40 | -200 | -200 | 1500 | -5.0 | -30 | 300 | 100 Zener Protected |
| 3N189 | TO-99 | -2 | -5 | -40 | -200 | -200 | 1500 | -5.0 | -30 | 300 | Zener Protected |
| 3N190 | TO-99 | -2 | -5 | -40 | -200 | -200 | 1500 | -5.0 | -30 | 300 | 100 Zener Protected |
| 3N191 | TO-99 | -2 | -5 | -40 | -200 | -200 | 1500 | -5.0 | -30 | 300 | |

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Differential Amplifiers — Dual NPN Bipolar Transistors

| Ordering Information | | $V_{BE\ 1-2}$ | ΔV_{BE} | h_{FE}° | $I_B\ 1-2$ | BV_{CEO} | I_{CBO} | Noise | f_t | C_{obo} | Structure |
|----------------------|-------------|---------------|-------------------|------------------|------------------------|------------|-----------|--------|-------------------|-----------|---------------|
| Preferred Part | Package | mV | $\mu V/^{\circ}C$ | $I_C = 10\mu A$ | $I_C = 10\mu A$ | V | nA | dB | MHz@ I_C | pF | |
| Number | | max | max | $V_{CE} = 5V$ | $V_{CE} = 5V$ | min | max | max | min | max | |
| 2N4044 | TO-78 | 3 | 3 | 200 | 5 | 60 | .1 | 2 | 200 @ 1mA | 0.8 | Dielec. Isol. |
| 2N4045 | TO-78 | 5 | 10 | 80 | 25 | 45 | .1 | 3 | 150 @ 1mA | 0.8 | Dielec. Isol. |
| 2N4100 | TO-78 | 5 | 5 | 150 | 10 | 55 | .1 | 3 | 150 @ 1mA | 0.8 | Dielec. Isol. |
| 2N4878 | TO-71 | 3 | 3 | 200 | 5 | 60 | .1 | 2 | 200 @ 1mA | 0.8 | Dielec. Isol. |
| 2N4879 | TO-71 | 5 | 5 | 150 | 10 | 55 | .1 | 3 | 150 @ 1mA | 0.8 | Dielec. Isol. |
| 2N4880 | TO-71 | 5 | 10 | 80 | 25 | 45 | .1 | 3 | 150 @ 1mA | 0.8 | Dielec. Isol. |
| IT120 | TO-78 TO-71 | 2 | 5 | 200 | 5 | 45 | 1 | 2 typ. | 220 @ 1mA | 2 | Junc. Isol. |
| IT120A | TO-78 TO-71 | 1 | 3 | 200 | 2.5 | 45 | 1 | 2 typ. | 220 @ 1mA | 2 | Junc. Isol. |
| IT121 | TO-78 TO-71 | 3 | 10 | 80 | 25 | 45 | 1 | 2 typ. | 180 @ 1mA | 2 | Junc. Isol. |
| IT122 | TO-78 TO-71 | 5 | 20 | 80 | 25 | 45 | 1 | 2 typ. | 180 @ 1mA | 2 | Junc. Isol. |
| IT124 | TO-78 | 5 | 15 | 1500 | 0.6 @ $V_{CE} = 1V$ | 2 | .1 | 3 | 100 @ 100 μA | 0.8 | Junc. Isol. |
| IT126 | TO-78 TO-71 | 1 | 3 | 200 | 2.5 | 60 | .1 | 1 typ. | 250 @ 10mA | 4 | Dielec. Isol. |
| IT127 | TO-78 TO-71 | 2 | 5 | 200 | 5 | 60 | .1 | 1 typ. | 250 @ 10mA | 4 | Dielec. Isol. |
| IT128 | TO-78 TO-71 | 3 | 10 | 150 | 10 | 45 | .1 | 1 typ. | 200 @ 10mA | 4 | Dielec. Isol. |
| IT129 | TO-78 TO-71 | 5 | 20 | 100 | 20 | 45 | .1 | 1 typ. | 150 @ 10mA | 4 | Dielec. Isol. |

Differential Amplifiers — Dual PNP Bipolar Transistors

| Ordering Information | | $V_{BE\ 1-2}$ mV max | ΔV_{BE} $\mu V/^\circ C$ max | h_{FE} @ $I_C = 10\mu A$ $V_{CE} = 5V$ min | $I_C = 10\mu A$ $V_{CE} = 5V$ nA max | BV_{CEO} V min | I_{CBO} nA max | Noise dB max | f_t MHz @ I_C min | C_{obo} pF max | Structure |
|-----------------------|-------------|----------------------------|--|---|---|------------------------|------------------------|--------------------|-----------------------------|------------------------|---------------|
| Preferred Part Number | Package | | | | | | | | | | |
| 2N5117 | TO-78 | 3 | 3 | 100 | 10 | 45 | .1 | 4 | 100 @ 0.5mA | .8 | Dielec. Isol. |
| 2N5118 | TO-78 | 5 | 5 | 100 | 15 | 45 | .1 | 4 | 100 @ 0.5mA | .8 | Dielec. Isol. |
| 2N5119 | TO--78 | 5 | 10 | 50 | 40 | 45 | .1 | 4 | 100 @ 0.5mA | .8 | Dielec. Isol. |
| IT130 | TO-78 TO-71 | 2 | 5 | 200 | 5 | -45 | 1 | 2 typ. | 110 @ 1mA | 2 | Junc. Isol. |
| IT130A | TO-78 TO-71 | 1 | 3 | 200 | 2.5 | -60 | 1 | 2 typ. | 110 @ 1mA | 2 | Junc. Isol. |
| IT131 | TO-78 TO-71 | 5 | 10 | 80 | 10 | -45 | † | 2 typ. | 90 @ 1mA | 2 | Junc. Isol. |
| IT132 | TO-78 TO-71 | 10 | 20 | 80 | 25 | -45 | 1 | 2 typ. | 90 @ 1mA | 2 | Junc. Isol. |
| IT136 | TO-78 TO-71 | 1 | 3 | 150 | 2.5 | -60 | .1 | 2 typ. | 150 @ 10mA | 4 | Dielec. Isol. |
| IT137 | TO-78 TO-71 | 2 | 5 | 150 | 5 | -60 | .1 | 2 typ. | 150 @ 10mA | 4 | Dielec. Isol. |
| IT138 | TO-78 TO-71 | 3 | 10 | 120 | 10 | -55 | .1 | 2 typ. | 180 @ 10mA | | Dielec. Isol. |
| IT139 | TO-78 TO-71 | 5 | 20 | 70 | 20 | -45 | .1 | 2 typ. | 100 @ 10mA | 4 | Dielec. Isol. |

Specialty Items

ID-100 This product is a diode combination used to protect those P-channel MOSFET duals which are not diode protected. Their chief characteristic is < 1 pA leakage when voltage across them is less than 5 mV. If voltage across diodes is adjusted to 0V \pm 0.1mV, leakage is less than 0.01 pA.

VCR2N

VCR3P

VCR4N

VCR5P

VCR7N

VCR11N (Dual)

The VCR family consists of three terminal variable resistors where the resistance value between two of the terminals is controlled by the voltage potential applied to the third.

Note: Intersil offers the following military qualified devices:*

| N-channel switches | N-channel amplifiers | P-channel switches | P-channel amplifiers |
|---------------------------|---------------------------|---------------------------|----------------------|
| 2N4091 JAN, JANTX, JANTXV | 2N3821 JAN, JANTX, JANTXV | 2N5114 JAN, JANTX, JANTXV | 2N2609 JAN |
| 2N4092 JAN, JANTX, JANTXV | 2N3823 JAN, JANTX, JANTXV | 2N5115 JAN, JANTX, JANTXV | |
| 2N4093 JAN, JANTX, JANTXV | | 2N5116 JAN, JANTX, JANTXV | |
| 2N4856 JAN, JANTX, JANTXV | | | |
| 2N4857 JAN, JANTX, JANTXV | | | |
| 2N4858 JAN, JANTX, JANTXV | | | |

*JAN processing consists of a sample Group B pulled from the production run.

JANTX processing consists of JAN processing plus 100% electrical read and record, and 100% burn-in.

JANTXV processing consists of JANTX processing plus 100% pre-cap visual and on-shore assembly.

DISCRETE SELECTOR GUIDE

1

| | Detailed Application | Important Parameters | Recommended Part Numbers | | | | | | | |
|---------------------------|--|----------------------------|-------------------------------------|---------------------------|---------------------|-------------------------|-------------------------|-----------------------|------------------|---------------------------------|
| | | | Single N-Channel JFET | Single P-Channel JFET | Dual N-Channel JFET | Single N-Channel MOSFET | Single P-Channel MOSFET | Dual P-Channel MOSFET | Dual NPN Bipolar | Dual PNP Bipolar |
| Amplifiers | Audio | low noise | 2N4220, 2N3821 | 2N2607 2N5460 | 2N3958 1T505 | 2N4351 3N170-1 | 3N163 3N164 | 3N165 | 2N4044 2N4878 | 1T130 |
| | Buffer | low leakage, high gain | 2N4221 | 2N2609 2N5462 | 2N5905 1T505 | M116 1T1750 | 3N172 1T1700 | | 1T120 1T136 | |
| | Differential | good matching & drift | — | — | 2N3954 U401 2N5515 | — | — | | 1T126 2N3810 | |
| | Fet Input Op Amp | — | — | — | — | — | — | | — | |
| | High Impedance | low leakage | 2N4117A | 1T100 J176 2N5116 | 2N5905 1T505 U426 | 1T1750 | 1T1700 | | — | |
| | High Frequency | high gain, low capacitance | U308 2N5397 | J176 | 1T5912 | 2N4351 | 3N163 | | 3N188 | 2N4044 2N4878 1T120 1T136 1T140 |
| | Low Supply Voltage | low pinch-off voltage | 2N4338 2N3687 | 2N5265 J177 | U406 2N3958 | 3N170-1 | 3N164 | | — | |
| | Low Noise | low noise | 2N4867A | 2N5116 J176 | 2N5519 2N5199 | M116 | 3N172 | | — | |
| | Preamplifier | high gain | 2N5397 U310 | 2N5116 J176 | 1T550 U406 | — | — | | — | |
| | Video | high gain, low capacitance | 2N4393 1T4393 | 1T100 | 1T5912 2N5912 | — | — | | — | |
| Mixers | VHF | RF parameters, | U310 2N5397 | 1T100 J174 | 2N6485 | — | — | — | | |
| | UHF | high g_{fs}/C_{iss} | J310 2N5484 | 2N5114 | 1T5912 2N5912 | — | — | — | | |
| Switches | Commutators | low C_{rss} | 2N4391 1T4391 | 2N3993-4 1T100-1 2N5114-6 | 1T550 | 1T1750 | 1T1700 | 3N163 3N165 | — | |
| | Sample and Hold | — | — | — | — | — | — | — | | |
| | Analog Gates | fast switching, | 2N4091-3 2N4391-3 1T4391-3 2N5432-4 | 2N5114-6 | 2N5912 | — | — | — | | |
| | Digital | low $r_{DS(on)}$ | 1T4391-3 2N5432-4 | J174-7 1T100-1 | 1T5912 | 3N170-1 | 3N164 3N172 | 3N188 | — | |
| | Chopper | — | — | — | — | — | — | — | | |
| Integrator Reset | low $r_{DS(on)}$, high I_{pss} | J111-3 J105-7 | — | — | — | — | — | — | | |
| Voltage Control Resistors | Gain Control Amplitude Stability Attenuators | high $V_{GS(off)}$ | VCR2N VCR4N VCR7N | VCR3P | VCR11N | — | — | — | — | |
| Protection Diodes | Signal Clipping and Clamping | low leakage current | — | — | — | — | — | ID100-1 1T139 | | |

2N2607-2N2609 2N2609 JAN P-Channel JFET


1
APPLICATIONS

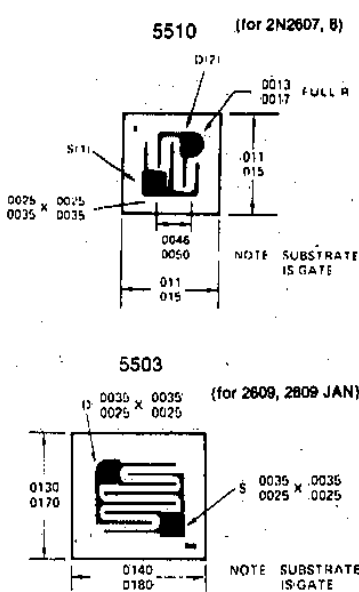
- Low-level Choppers
- Data Switches
- Commutators

ABSOLUTE MAXIMUM RATINGS

 (T_A = 25°C unless otherwise noted)

| | |
|--------------------------------------|-----------------|
| Gate-Source Voltage | 30 V |
| Gate-Drain Voltage | 30 V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10-sec) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 2 mW/°C |

PIN CONFIGURATION


CHIP TOPOGRAPHY


ORDERING INFORMATION*

| TO-18 | WAFER | DICE |
|------------|----------|----------|
| 2N2607 | 2N2607/W | 2N2607/D |
| 2N2608 | 2N2608/W | 2N2608/D |
| 2N2609 | 2N2609/W | 2N2609/D |
| 2N2609 JAN | — | — |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise noted)

| PARAMETER | | 2N2607 | | 2N2608 | | 2N2609 | | Unit | Test Conditions | |
|-------------------|---|--------|-------|--------|-------|--------|-----------------------|------|--|------------------------|
| | | Min | Max | Min | Max | Min | Max | | | |
| I _{GSSR} | Gate Reverse Current | | 3 | | 10 | | 30 | nA | V _{GS} = 30 V, V _{DS} = 0 | |
| | | | 3 | | 10 | | 30 | μA | V _{GS} = 5 V, V _{DS} = 0, T _A = 150°C | |
| BV _{GSS} | Gate-Drain Breakdown Voltage | 30 | | 30 | | 30 | | V | I _G = 1 μA, V _{DS} = 0 | |
| V _P | Gate-Source Pinch-Off Voltage | 1 | 4 | 1 | 4 | 1 | 4 | V | V _{DS} = -5 V, I _D = -1 μA | |
| I _{DSS} | Drain Current at Zero Gate Voltage | -0.30 | -1.50 | -0.90 | -4.50 | -2 | -10 | mA | V _{DS} = -5 V, V _{GS} = 0 | |
| g _{fs} | Small-Signal Common-Source Forward Transconductance | 330 | | 1000 | | 2500 | | μmho | V _{DS} = -5 V, V _{GS} = 0, f = 1 kHz | |
| C _{iss} | Common-Source Input Capacitance | | 10 | | 17 | | 30 | pF | V _{DS} = -5 V, V _{GS} = 1 V, f = 140 kHz | |
| NF | Noise Figure | | 3 | | | | | dB | V _{DS} = -5 V, V _{GS} = 0, f = 1 kHz | R _G = 10 MΩ |
| | | | | | 3 | 3 | R _G = 1 MΩ | | | |

FEATURES

- Low Noise
- High Input Impedance
- Low Capacitance

1

APPLICATIONS

- Low Level Choppers
- Data Switches
- Multiplexers
- Low Noise Amplifiers

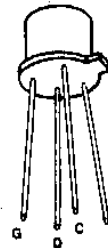
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

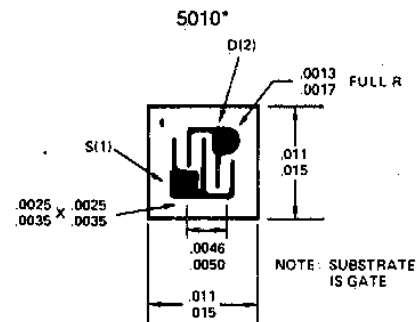
| | |
|---------------------------------------|-----------------|
| Gate-Source or Gate-Drain Voltage | -50V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

PIN CONFIGURATION

TO-72



CHIP TOPOGRAPHY



*DICE WITH 4 MIL BONDING PADS, AVAILABLE. CONSULT FACTORY FOR DETAILS.

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N3684 | 2N3684/W | 2N3684/D |
| 2N3685 | 2N3685/W | 2N3685/D |
| 2N3686 | 2N3686/W | 2N3686/D |
| 2N3687 | 2N3687/W | 2N3687/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N3684 | | 2N3685 | | 2N3686 | | 2N3687 | | UNITS | TEST CONDITIONS |
|--|---------------------------|------|--------|------|--------|------|--------|------|------------------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | |
| BV_{GSS} Gate to Source Breakdown Voltage | -50 | | -50 | | -50 | | -50 | | V | $V_{DS} = 0, I_G = 1.0 \mu\text{A}$ |
| V_p Pinch-Off Voltage | 2.0 | 5.0 | 1.0 | 3.5 | 0.6 | 2.0 | 0.3 | 1.2 | | $V_{DS} = 20 \text{ V}, I_D = 0.001 \mu\text{A}$ |
| I_{GSS} Total Gate Leakage Current | | -0.1 | | -0.1 | | -0.1 | | -0.1 | nA | $V_{GS} = -30 \text{ V}, V_{DS} = 0$ |
| | $T_A = 150^\circ\text{C}$ | | -0.5 | | -0.5 | | -0.5 | | μA | |
| I_{DSS} Saturation Current, Drain-to-Source | 2.5 | 7.5 | 1.0 | 3.0 | 0.4 | 1.2 | 0.1 | 0.5 | mA | $V_{GS} = 0, V_{DS} = 20 \text{ V}$ |
| $ Y_{fs} $ Forward Transmittance | 2000 | 3000 | 1500 | 2500 | 1000 | 2000 | 600 | 1500 | μmhos | $V_{DS} = 20 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$ |
| G_{os} Common Source Output Conductance | | 50 | | 25 | | 10 | | 5 | μmhos | |
| C_{iss} Common Source Input Capacitance | | 4.0 | | 4.0 | | 4.0 | | 4.0 | pF | |
| C_{rss} Common Source Short Circuit Reverse Transfer Capacitance | | 1.2 | | 1.2 | | 1.2 | | 1.2 | pF | |
| $r_{DS(on)}$ On Resistance | | 600 | | 800 | | 1200 | | 2400 | Ohms | $V_{DS} = 0, V_{GS} = 0$ |
| NF Noise Figure | | 0.5 | | 0.5 | | 0.5 | | 0.5 | dB | $f = 100 \text{ Hz}, R_G = 10 \text{ M}\Omega$ $NBW = 6 \text{ Hz}, V_{DS} = 10 \text{ V}$ $V_{GS} = 0 \text{ V}$ |



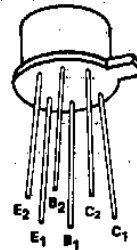
2N3810/A, 2N3811/A Monolithic Dual Matched PNP Transistor

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

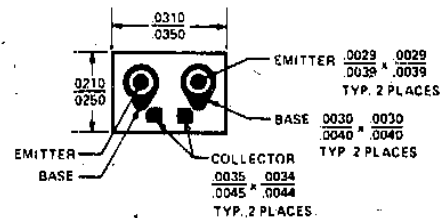
| | |
|--|---|
| Emitter-Base Voltage (Note 1) | -5V |
| Collector-Base or Collector-Emitter Voltage (Note 1) | -60V |
| Collector Current (Note 1) | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | ONE SIDE 500 mW BOTH SIDES 600 mW |
| Derate above 25°C | 2.9 mW/°C 3.4 mW/°C |

PIN CONFIGURATION TO-78



4501

CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-78 | WAFER | DICE |
|---------|----------|----------|
| 2N3810 | 2N3810/W | 2N3810/D |
| 2N3810A | | |
| 2N3811 | 2N3811/W | 2N3811/D |
| 2N3811A | | |

ELECTRICAL CHARACTERISTICS

*When ordering wafer/dice refer to Appendix B-23.

TEST CONDITIONS: 25°C Ambient Temperature unless otherwise noted

| SYMBOL | PARAMETER | 2N3810/A | | 2N3811/A | | UNITS | TEST CONDITIONS |
|---------------|--|----------|-------|----------|-------|-----------------|--|
| | | MIN | MAX | MIN | MAX | | |
| BV_{CBO} | Collector-Base Breakdown Voltage | -60 | | -60 | | | $I_C = -10 \mu\text{A}, I_E = 0$ |
| BV_{CEO} | Collector-Emitter Breakdown Voltage (Note 2) | -60 | | -60 | | V | $I_C = -10 \text{ mA}, I_B = 0$ |
| BV_{EBO} | Emitter-Base Breakdown Voltage | -5 | | -5 | | | $I_E = -10 \mu\text{A}, I_C = 0$ |
| $I_{C(off)}$ | Collector Cutoff Current | | -10 | | -10 | nA | $V_{CB} = -50\text{V}, I_E = 0$ |
| | | | -10 | | -10 | μA | |
| | | | -20 | | -20 | nA | $V_{BE} = 4\text{V}, I_C = 0$ |
| $I_{E(off)}$ | Emitter Cutoff Current | | -20 | | -20 | nA | |
| h_{FE} | Static Forward Current Transfer Ratio (Note 2) | 100 | 450 | 225 | 900 | | $V_{CE} = -5\text{V}$ |
| | | 150 | 450 | 300 | 900 | | $I_C = -10 \mu\text{A}$ |
| | | 125 | | 250 | | | $I_C = -100 \mu\text{A to } -1 \text{ mA}$ |
| | | 75 | | 150 | | | $I_C = 10 \text{ mA}$ |
| | | | | | | | $I_C = 100 \mu\text{A}$ |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage (Note 2) | | -0.7 | | -0.7 | V | $V_{CE} = -5\text{V}, I_B = -10 \mu\text{A}$ |
| | | | -0.8 | | -0.8 | | $I_C = -100 \mu\text{A}, I_B = -100 \mu\text{A}$ |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage (Note 2) | | -0.2 | | -0.2 | V | $I_B = -10 \mu\text{A}, I_C = -100 \mu\text{A}$ |
| | | | -0.25 | | -0.25 | | $I_B = -100 \mu\text{A}, I_C = -1 \text{ mA}$ |
| h_{ie} | Input Impedance | 3 | 30 | 10 | 40 | k Ω | $V_{CE} = -10\text{V}$ |
| h_{fe} | Forward Current Transfer Ratio | 150 | 600 | 300 | 900 | | $I_C = -1 \text{ mA}$ |
| h_{re} | Reverse Voltage Transfer Ratio | | 0.25 | | 0.25 | | $f = 1 \text{ KHz}$ |
| h_{oe} | Output Admittance | 5 | 60 | 5 | 60 | μmho | |
| $ h_{fe} $ | Magnitude of small signal current gain | 1 | 5 | 1 | 5 | | $V_{CE} = -5\text{V}$ |
| | | 1 | | 1 | | | $I_C = -1 \text{ mA}, f = 100 \text{ MHz}$ |
| | | | | | | | $I_C = -500 \mu\text{A}, f = 30 \text{ MHz}$ |

NOTES:

- Per transistor.
- Pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2.0\%$.

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2N3810/A, 2N3811/A



ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C Ambient Temperature unless otherwise noted

1

| SYMBOL | PARAMETER | 2N3810/A | | 2N3811/A | | UNITS | TEST CONDITIONS | |
|---|--|-----------|------|----------|------|--------------------|--|--|
| | | MIN | MAX | MIN | MAX | | | |
| C_{obo} | Output Capacitance | | 4 | | 4 | pF | $V_{CB} = -5V, I_E = 0, f = 100 \text{ MHz}$ | |
| C_{ibo} | Input Capacitance | | 8 | | 8 | | $V_{CB} = -0.5V, I_C = 0, f = 100 \text{ KHz}$ | |
| h_{FE1} / h_{FE2} | DC Current Gain Ratio | 0.9 | 1.0 | 0.9 | 1.0 | | $V_{CE} = -5V, I_C = 100 \mu A$ | |
| | A devices | 0.95 | 1.0 | 0.95 | 1.0 | | | |
| $ V_{BE1} - V_{BE2} $ | Base-Emitter Voltage Differential | | -5 | | -5 | mV | $V_{CE} = -5V$ | |
| | | A devices | -2.5 | | -2.5 | | | $I_C = 10 \mu A \text{ to } 10 \text{ mA}$ |
| | | A devices | -3 | | -3 | | | $I_C = 100 \mu A$ |
| $\frac{\Delta V_{BE1} - V_{BE2}}{\Delta T}$ | Base-Emitter Voltage Differential Gradient | | 10 | | 10 | $\mu V / ^\circ C$ | $V_{CE} = -5, I_C = 100 \mu A$ | |
| | | A devices | 5 | | 5 | | | |
| NF | Spot Noise Figure | | 7 | | 4 | dB | $V_{CE} = -10V, I_C = -100 \mu A, R_G = 3k\Omega, f = 100 \text{ Hz}, \text{ Noise Bandwidth} = 20\text{Hz}$ | |
| | | | 3 | | 1.5 | | $V_{CE} = -10V, I_C = -100 \mu A, R_G = 3k\Omega, f = 1\text{kHz}, \text{ Noise Bandwidth} = 200 \text{ kHz}$ | |
| | | | 2.5 | | 1.5 | | $V_{CE} = -10V, I_C = -100 \mu A, R_G = 3k\Omega, f = 10 \text{ kHz}, \text{ Noise Bandwidth} = 2 \text{ kHz}$ | |
| | | | 3.5 | | 2.5 | | $V_{CE} = -10V, I_C = -100 \mu A, R_G = 3k\Omega, \text{ Noise Bandwidth} = 15.7 \text{ kHz (Note 3)}$ | |

NOTES:

3 3 dB down at 10 Hz and 10 kHz.

2N3821, 2N3822 N-Channel JFET

FEATURES

- Low Capacitance
- Up to 6500 μmho Transconductance

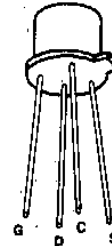
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---|-----------------|
| Gate-Source Voltage | -50V |
| Gate-Drain Voltage | -50V |
| Gate Current | 10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

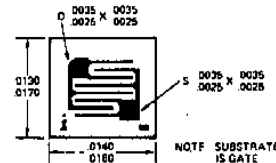
PIN CONFIGURATION

TO-72



CHIP TOPOGRAPHY

5003



ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N3821 | 2N3821/W | 2N3821/D |
| 2N3822 | 2N3822/W | 2N3822/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | 2N3821 | | 2N3822 | | UNIT | TEST CONDITIONS | |
|---------------|---|---------------------------|------|--------|------|--------------------------------------|---|--|
| | | MIN | MAX | MIN | MAX | | | |
| I_{GSS} | Gate Reverse Current | $T_A = 150^\circ\text{C}$ | | | | nA | $V_{GS} = -30\text{ V}, V_{DS} = 0$ | |
| | | | -0.1 | -0.1 | -0.1 | μA | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -50 | | -50 | | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | | -4 | | -6 | V | $V_{DS} = 15\text{ V}, I_D = 0.5\ \text{nA}$ | |
| V_{GS} | Gate-Source Voltage | -0.5 | -2 | | | V | $V_{DS} = 15\text{ V}, I_D = 50\ \mu\text{A}$ | |
| I_{DSS} | Saturation Drain Current | 0.5 | 2.5 | 2 | 10 | mA | $V_{DS} = 15\text{ V}, V_{GS} = 0$ | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 1500 | 4500 | 3000 | 6500 | μmho | $V_{DS} = 15\text{ V}, V_{GS} = 0$ | |
| $ y_{fs} $ | Common-Source Forward Transadmittance | 1500 | | 3000 | | | $f = 1\ \text{kHz}$ | |
| g_{os} | Common-Source Output Conductance (Note 1) | | 10 | | 20 | μF | $V_{DS} = 15\text{ V}, V_{GS} = 0$ | |
| C_{iss} | Common-Source Input Capacitance | | 6 | | 6 | | $f = 1\ \text{MHz}$ | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 3 | | 3 | dB | $V_{DS} = 15\text{ V}, V_{GS} = 0,$ $R_{gen} = 1\ \text{meg}, BW = 5\ \text{Hz}$ | |
| NF | Noise Figure | | 5 | | 5 | | $f = 10\ \text{Hz}$ | |
| E_n | Equivalent Input Noise Voltage | | 200 | | 200 | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ | $V_{DS} = 15\text{ V}, V_{GS} = 0, BW = 5\ \text{Hz}$ | |

Note 1: These parameters are measured during a 2 msec interval 100 msec after DC power is applied.

FEATURES

- Low Noise
- Low Capacitance
- Transductance up to 6500 μmho

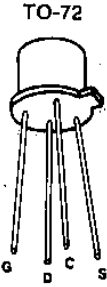
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ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|---------------------------------------|-------|-----------------|
| Gate-Source or Gate-Drain Voltage | | -30V |
| Gate Current | | 10 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | | +300°C |
| Power Dissipation | | 300 mW |
| Derate above 25°C | | 1.7 mW/°C |

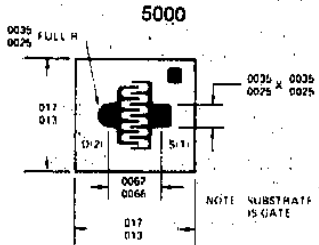
PIN CONFIGURATION



TO-72

G
D
C
S

CHIP TOPOGRAPHY



5000

0025 FULL R
0025

017 013

0067 0066

017 013

0025 x 0025
0025 0025

NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N3823 | 2N3823/W | 2N3823/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | MIN | MAX | UNIT | TEST CONDITIONS | |
|---------------|--|-------|-------|-----------------|--|------------------------------|
| I_{GSS} | Gate Reverse Current | | -0.5 | nA | $V_{GS} = -20V, V_{DS} = 0$ | |
| | | | -0.5 | μA | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -30 | | | $I_G = 1 \mu\text{A}, V_{DS} = 0$ | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | | -8 | V | $V_{DS} = 15V, I_D = 0.5 \text{ nA}$ | |
| V_{GS} | Gate-Source Voltage | -1.0 | -7.5 | | $V_{DS} = 15V, I_D = 400 \mu\text{A}$ | |
| I_{DSS} | Saturation Drain Current | 4 | 20 | mA | $V_{DS} = 15V, V_{GS} = 0$ | |
| g_{fs} | Common-Source Forward Transconductance | 3,500 | 6,500 | μmho | $V_{DS} = 15V, V_{GS} = 0$ | |
| $ Y_{fs} $ | Common-Source Forward Transadmittance | 3,200 | | | | $f = 1 \text{ kHz (Note 1)}$ |
| g_{os} | Common-Source Output Transconductance | | 35 | | | $f = 100 \text{ MHz}$ |
| g_{iss} | Common-Source Input Conductance | | 800 | | | $f = 1 \text{ kHz (Note 1)}$ |
| g_{oss} | Common-Source Output Conductance | | 200 | | | $f = 200 \text{ MHz}$ |
| C_{iss} | Common-Source Input Capacitance | | 6 | pF | $f = 1 \text{ MHz}$ | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 2 | | | |
| NF | Noise Figure | | 2.5 | dB | $V_{DS} = 15V, V_{GS} = 0$ $R_G = 1 \text{ k}\Omega$ $f = 100 \text{ MHz}$ | |

NOTE 1: These parameters are measured during a 2 msec interval 100 msec after DC power is applied.

FEATURES

- $r_{ds} < 250$ ohms
- $I_{D(off)} < 0.1$ nA

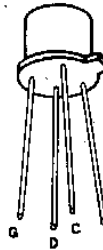
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Source or Gate-Drain Voltage | -50V |
| Gate Current | 10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Load Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

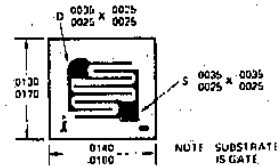
PIN CONFIGURATION

TO-72



CHIP TOPOGRAPHY

5003



ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N3824 | 2N3824/W | 2N3824/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted

| PARAMETER | | MIN | MAX | UNIT | TEST CONDITIONS |
|---------------------|--|---------------------------|------|---------------|---|
| I _{GSS} | Gate Reverse Current | $T_A = 150^\circ\text{C}$ | -0.1 | nA | $V_{GS} = -30\text{V}, V_{DS} = 0$ |
| | | | -0.1 | μA | |
| BV _{GSS} | Gate-Source Breakdown Voltage | -50 | | V | $I_G = 1 \mu\text{A}, V_{DS} = 0$ |
| I _{D(off)} | Drain Cutoff Current | $T_A = 150^\circ\text{C}$ | 0.1 | nA | $V_{DS} = 15\text{V}, V_{GS} = -8\text{V}$ |
| | | | 0.1 | μA | |
| $r_{ds(on)}$ | Drain-Source ON Resistance | | 250 | Ω | $V_{GS} = 0\text{V}, I_D = 0$ $f = 1 \text{ kHz}$ |
| C _{iss} | Common-Source Input Capacitance | | 6 | pF | $V_{DS} = 15\text{V}, V_{GS} = 0$ $f = 1 \text{ MHz}$ |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | 3 | | $V_{GS} = -8\text{V}, V_{DS} = 0$ |

2N3921, 2N3922 Monolithic Dual N-Channel JFET

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FEATURES

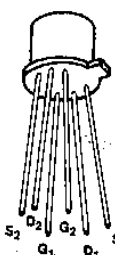
- Low Drain Current
- High Output Impedance
- Matched V_{GS} , ΔV_{GS} , and g_{fs}

ABSOLUTE MAXIMUM RATINGS

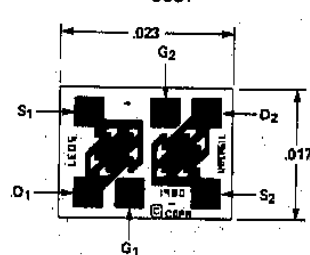
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--|-----------------|
| Gate-Source or Gate-Drain Voltage (Note 1) | -50V |
| Gate Current (Note 1) | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Load Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

PIN CONFIGURATION
TO-71



CHIP TOPOGRAPHY
6037



ALL BOND PADS ARE 4 x 4 MIL.

ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|--------|----------|----------|
| 2N3921 | 2N3921/W | 2N3921/D |
| 2N3922 | 2N3922/W | 2N3922/D |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: (25°C unless otherwise noted)

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | | MIN | MAX | UNIT | TEST CONDITIONS |
|---------------|---|------|------|-----------------|--|
| I_{GSSR} | Gate Reverse Current | | -1 | nA | $V_{GS} = -30V, V_{DS} = 0$ |
| BV_{DGO} | Drain-Gate Breakdown Voltage | 50 | -1 | μA | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | | -3 | V | $I_D = 1 \mu\text{A}, I_S = 0$ |
| V_{GS} | Gate-Source Voltage | -0.2 | -2.7 | | $V_{DS} = 10V, I_D = 1 \text{ nA}$ |
| I_G | Gate Operating Current | | -250 | pA | $V_{DG} = 10V, I_D = 700 \mu\text{A}$ |
| | | | -25 | nA | |
| I_{DSS} | Saturation Drain Current (Note 1) | 1 | 10 | mA | $V_{DS} = 10V, V_{GS} = 0$ |
| g_{fs} | Common-Source Forward Transconductance (Note 2) | 1500 | 7500 | μmho | $V_{DS} = 10V, V_{GS} = 0$ $f = 1 \text{ kHz}$ |
| g_{os} | Common-Source Output Conductance | | 35 | | |
| C_{iss} | Common-Source Input Capacitance | | 18 | pF | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 6 | | |
| g_{fs} | Common-Source Forward Transconductance | 1500 | | μmho | $V_{DG} = 10V, I_D = 700 \mu\text{A}, f = 1 \text{ kHz}$ |
| g_{oss} | Common-Source Output Conductance | | 20 | | |
| NF | Spot Noise Figure | | 2 | dB | $V_{DS} = 10V, V_{GS} = 0$ $f = 1 \text{ kHz}, R_G = 1 \text{ meg}$ |

| MATCHING CHARACTERISTICS | | 2N3921 | | 2N3922 | | UNIT | TEST CONDITIONS |
|---|--|--------|-----|--------|-----|------------------------------|--|
| | | MIN | MAX | MIN | MAX | | |
| $ V_{GS1} - V_{GS2} $ | Differential Gate-Source Voltage | | 5 | | 5 | mV | $V_{DG} = 10V, I_D = 700 \mu\text{A}$ $T_A = 0^\circ\text{C}$ $T_B = 100^\circ\text{C}$ $f = 1 \text{ kHz}$ |
| $\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$ | Gate-Source Differential Voltage Change with Temperature | | 10 | | 25 | $\mu\text{V}/^\circ\text{C}$ | |
| g_{fs2} | Transconductance Ratio | 0.95 | 1.0 | 0.95 | 1.0 | | |

- NOTES: 1. Per transistor.
2. Pulse test duration = 2 ms.

2N3954-2N3958 Monolithic Dual N-Channel JFET

FEATURES

- Low Offset and Drift
- Low Capacitance
- Low Noise
- Superior Tracking Ability
- Low Output Conductance

ABSOLUTE MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted)

Gate-Source or Gate-Drain

Breakdown Voltage (Note 1) 50V

Any Pin to Case Voltage 100V

Gate Current (Note 1) 50 mA

Storage Temperature .. -65°C to +200°C

Operating Temperature -55°C to +150°C

Lead Temperature

(Soldering, 10 sec.) +300°C

ONE SIDE BOTH SIDES

Power Dissipation 250 mW 500 mW

Derate above 25°C 2.8 mW/°C 4.3 mW/°C

PIN CONFIGURATION

TO-71

CHIP TOPOGRAPHY

6037

ALL BOND PADS ARE 4 x 4 MIL.

ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|---------|-----------|-----------|
| 2N3954 | 2N3954/W | 2N3954/D |
| 2N3954A | 2N3954A/W | 2N3954A/D |
| 2N3955 | 2N3955/W | 2N3955/D |
| 2N3955A | 2N3955A/W | 2N3955A/D |
| 2N3956 | 2N3956/W | 2N3956/D |
| 2N3957 | 2N3957/W | 2N3957/D |
| 2N3958 | 2N3958/W | 2N3958/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N3954 | | 2N3954A | | 2N3955 | | 2N3955A | | 2N3956 | | 2N3957 | | 2N3958 | | UNIT | TEST CONDITIONS | |
|---|--|-----|---------|-----|--------|-----|---------|-----|--------|-----|--------|-----|--------|-----|------|--|--|
| | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | | |
| I _{GSSR} | Gate Reverse Current | | -100 | | -100 | | -100 | | -100 | | -100 | | -100 | | pA | V _{GS} = -30 V, V _{DS} = 0 | |
| | T _A = 125°C | | -500 | | -500 | | -500 | | -500 | | -500 | | -500 | | | | |
| BV _{GSS} | Gate-Source Breakdown Voltage | | -50 | | -50 | | -50 | | -50 | | -50 | | -50 | | V | V _{DS} = 0 I _G = -1 μA | |
| V _{GS(off)} | Gate-Source Cutoff Voltage | | -1.0 | | -1.0 | | -1.0 | | -1.0 | | -1.0 | | -1.0 | | | | V _{DS} = 20 V, I _D = 1 nA |
| V _{GS(f)} | Gate-Source Forward Voltage | | 2.0 | | 2.0 | | 2.0 | | 2.0 | | 2.0 | | 2.0 | | | | |
| V _{GS} | Gate-Source Voltage | | -4.2 | | -4.2 | | -4.2 | | -4.2 | | -4.2 | | -4.2 | | nA | V _{DS} = 20 V, I _D = 50 μA I _D = 200 μA | |
| | T _A = 125°C | | -0.5 | | -0.5 | | -0.5 | | -0.5 | | -0.5 | | -0.5 | | | | |
| I _G | Gate Operating Current | | -50 | | -50 | | -50 | | -50 | | -50 | | -50 | | nA | V _{DS} = 20 V, I _D = 200 μA | |
| I _{DSS} | Saturation Drain Current | | 0.5 | | 0.5 | | 0.5 | | 0.5 | | 0.5 | | 0.5 | | mA | V _{DS} = 20 V, V _{GS} = 0 | |
| | T _A = 125°C | | -250 | | -250 | | -250 | | -250 | | -250 | | -250 | | | | |
| g _{fs} | Common-Source Forward Transconductance | | 1000 | | 1000 | | 1000 | | 1000 | | 1000 | | 1000 | | μmho | V _{DS} = 20 V, V _{GS} = 0 | |
| | f = 1 kHz | | 3000 | | 3000 | | 3000 | | 3000 | | 3000 | | 3000 | | | | |
| g _{os} | Common-Source Output Conductance | | 35 | | 35 | | 35 | | 35 | | 35 | | 35 | | pF | f = 1 MHz | |
| | f = 200 MHz | | 1000 | | 1000 | | 1000 | | 1000 | | 1000 | | 1000 | | | | |
| C _{iss} | Common-Source Input Capacitance | | 4.0 | | 4.0 | | 4.0 | | 4.0 | | 4.0 | | 4.0 | | pF | V _{DS} = 10 V, I _S = 0 | |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | 1.2 | | 1.2 | | 1.2 | | 1.2 | | 1.2 | | 1.2 | | | | |
| C _{dgo} | Drain-Gate Capacitance | | 1.5 | | 1.5 | | 1.5 | | 1.5 | | 1.5 | | 1.5 | | dB | V _{DS} = 20 V V _{GS} = 0 R _G = 10 MΩ | |
| NF | Common-Source Spot Noise Figure | | 0.5 | | 0.5 | | 0.5 | | 0.5 | | 0.5 | | 0.5 | | | | |
| I _{G1} -I _{G2} | Differential Gate Current | | 10 | | 10 | | 10 | | 10 | | 10 | | 10 | | nA | V _{DS} = 20 V, I _D = 200 μA T = 125°C | |
| I _{DSS1} /I _{DSS2} | Drain Saturation Current Ratio | | 0.95 | | 0.95 | | 0.95 | | 0.95 | | 0.95 | | 0.95 | | mV | V _{DS} = 20 V, I _D = 200 μA | |
| V _{GS1} -V _{GS2} | Differential Gate-Source Voltage | | 5.0 | | 5.0 | | 10.0 | | 5.0 | | 15 | | 20 | | | | |
| ΔV _{GS1} -V _{GS2} /ΔT | Gate-Source Differential Voltage Change with Temperature | | 0.8 | | 0.4 | | 2.0 | | 1.2 | | 4.0 | | 6.0 | | mV | T = 25°C to -55°C T = 25°C to 125°C | |
| | f = 1 kHz | | 1.0 | | 0.5 | | 2.5 | | 1.5 | | 5.0 | | 7.5 | | | | |
| g _{fs1} /g _{fs2} | Transconductance Ratio | | 0.97 | | 0.97 | | 0.97 | | 0.95 | | 0.95 | | 0.95 | | nA | f = 1 kHz | |

NOTE 1: Per transistor.

1

1

FEATURES

- Low $r_{DS(on)}$
- $I_{D(off)} < 250 \text{ pA}$
- Fast Switching

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Source or Gate-Drain Voltage | -40V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 1.8W |
| Derate above 25°C | 10 mW/°C |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted

| PARAMETER | 2N3970 | | 2N3971 | | 2N3972 | | UNIT | TEST CONDITIONS |
|--|--------|---------------------------|--------|-----|--------|-----|----------|--|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| BV_{GSS} Gate Reverse Breakdown Voltage | -40 | | -40 | | -40 | | V | $I_G = -1\mu\text{A}, V_{DS} = 0$ |
| I_{DGO} Drain Reverse Current | | 250 | | 250 | | 250 | pA | $V_{DG} = 20\text{V}, I_S = 0$ |
| | | $T_A = 150^\circ\text{C}$ | | 500 | | 500 | nA | |
| $I_{D(off)}$ Drain Cutoff Current | | 250 | | 250 | | 250 | pA | $V_{DG} = 20\text{V}, V_{GS} = -12\text{V}$ |
| | | $T_A = 150^\circ\text{C}$ | | 500 | | 500 | nA | |
| $V_{GS(off)}$ Gate-Source Cutoff Voltage | -4 | -10 | -2 | -5 | -0.5 | -3 | V | $V_{DS} = 20\text{V}, I_D = 1 \text{ nA}$ |
| I_{DSS} Saturation Drain Current (Pulse width 300 μs , duty cycle $\leq 3\%$) | 50 | 150 | 25 | 75 | 5 | 30 | mA | $V_{DS} = 20\text{V}, V_{GS} = 0$ |
| $V_{DS(on)}$ Drain-Source ON Voltage | | | | 1.5 | | | V | $V_{GS} = 0$ |
| | | 1 | | | | | | $I_D = 5 \text{ mA}$ $I_D = 10 \text{ mA}$ $I_D = 20 \text{ mA}$ |
| $r_{DS(on)}$ Static Drain-Source ON Resistance | | 30 | | 60 | | 100 | Ω | $V_{GS} = 0, I_D = 1 \text{ mA}$ |
| $r_{ds(on)}$ Drain-Source ON Resistance | | 30 | | 60 | | 100 | Ω | $V_{GS} = 0, I_D = 0$ |
| C_{iss} Common-Source Input Capacitance | | 25 | | 25 | | 25 | pF | $V_{DS} = 20\text{V}, V_{GS} = 0$ |
| C_{rss} Common-Source Reverse Transfer Capacitance | | 6 | | 6 | | 6 | pF | $V_{DS} = 0, V_{GS} = -12\text{V}$ |
| t_d Turn-On Delay Time | | 10 | | 15 | | 40 | ns | $V_{DD} = 10\text{V}, V_{GS(on)} = 0$ $I_{D(on)} \quad V_{GS(off)} \quad R_L$ |
| t_r Rise Time | | 10 | | 15 | | 40 | ns | |
| t_{off} Turn-Off Time | | 30 | | 60 | | 100 | ns | |
| | | | | | | | | 2N3970 20 mA -10V 450 Ω 2N3971 10 mA -5V 850 Ω 2N3972 5 mA -3V 1.6K Ω |

PIN CONFIGURATION

TO-18

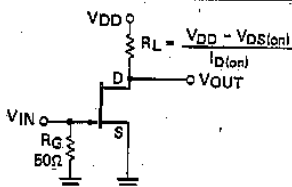
CHIP TOPOGRAPHY

5001

ORDERING INFORMATION*

| TO-18 | WAFER | DICE |
|--------|----------|----------|
| 2N3970 | 2N3970/W | 2N3970/D |
| 2N3971 | 2N3971/W | 2N3971/D |
| 2N3972 | 2N3972/W | 2N3972/D |

*When ordering wafer/dice refer to Appendix B-23.



INPUT PULSE
 RISE TIME 0.25 ns
 FALL TIME 0.75 ns
 PULSE WIDTH 200 ns
 PULSE RATE 550 pps

SAMPLING SCOPE
 RISE TIME 0.4 ns
 INPUT RESISTANCE 10 M
 INPUT CAPACITANCE 1.5 pF

2N3993, 2N3994 P-Channel JFET

FEATURES

- Low $r_{DS(on)}$
- High Y_{fs}/C_{ISS} Ratio (High-Frequency Figure-of-Merit)

APPLICATIONS

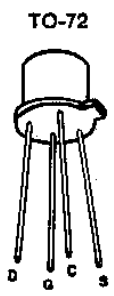
Used in high-speed commutator and chopper applications. Also ideal for "Virtual Gnd" switching; needs no ext. translator circuit to switch ± 10 VAC. Can be driven direct from T²L or CMOS logic.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Drain-Gate Voltage | -25V |
| Drain-Source Voltage | -25V |
| Continuous Forward Gate Current | -10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

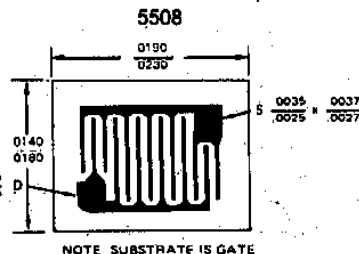
PIN CONFIGURATION



TO-72

D G C S

CHIP TOPOGRAPHY



5508

0190
0230

0140
0180

0037
0027

0035
0025

0037
0027

NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N3993 | 2N3993/W | 2N3993/D |
| 2N3994 | 2N3994/W | 2N3994/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS @ 25°C free-air temperature (unless otherwise noted)

| SYMBOL | PARAMETER | 2N3993 | | 2N3994 | | UNIT | TEST CONDITIONS (Note 3) |
|----------------------|--|--------|------|--------|------|---------------|--|
| | | MIN | MAX | MIN | MAX | | |
| BV _{GSS} | Gate-Source Breakdown Voltage | 25 | | 25 | | V | $I_G = 1 \mu\text{A}$, $V_{DS} = 0$ |
| I _{DGO} | Drain Reverse Current | | -1.2 | | -1.2 | nA | $V_{DG} = -15 \text{ V}$, $I_S = 0$ |
| I _{DSS} | Zero-Gate-Voltage Drain Current | -10 | | -2 | | mA | $V_{DS} = -10 \text{ V}$, $V_{GS} = 0$, (See Note 1) |
| I _{D(off)} | Drain Cutoff Current | | | | -1.2 | nA | $V_{DS} = -10 \text{ V}$, $V_{GS} = 6 \text{ V}$ |
| | | | | | -1 | μA | $V_{DS} = -10 \text{ V}$, $V_{GS} = 6 \text{ V}$, $T_A = 150^\circ\text{C}$ |
| | | | -1.2 | | | nA | $V_{DS} = -10 \text{ V}$, $V_{GS} = 10 \text{ V}$ |
| | | | -1 | | | μA | $V_{DS} = -10 \text{ V}$, $V_{GS} = 10 \text{ V}$, $T_A = 150^\circ\text{C}$ |
| V _{GS(off)} | Gate-Source Voltage | 4 | 9.5 | 1 | 5.5 | V | $V_{DS} = -10 \text{ V}$, $I_D = -1 \mu\text{A}$ |
| r _{ds(on)} | Small-Signal Drain-Source On-State Resistance | | 150 | | 300 | Ω | $V_{GS} = 0$, $I_D = 0$, $f = 1 \text{ kHz}$ |
| y _{fs} | Small-Signal Common-Source Forward Transfer Admittance | 6 | 12 | 4 | 10 | mmho | $V_{DS} = -10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ kHz}$, (See Note 1) |
| C _{iss} | Common-Source Short-Circuit Input Capacitance | | 16 | | 16 | pF | $V_{DS} = -10 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$, (See Note 2) |
| C _{rss} | Common-Source Short-Circuit Reverse Transfer Capacitance | | | | 5 | pF | $V_{DS} = 0$, $V_{GS} = 6 \text{ V}$, $f = 1 \text{ MHz}$ |
| | | | 4.5 | | | pF | $V_{DS} = 0$, $V_{GS} = 10 \text{ V}$, $f = 1 \text{ MHz}$ |

NOTES: 1. These parameters must be measured using pulse techniques. $t_p = 100 \text{ ms}$, duty cycle $\leq 10\%$.

2. This parameter must be measured with bias voltage applied for less than 5 seconds to avoid overheating.

3. The case should be connected to the source for all measurements.



2N4044, 2N4045, 2N4100, 2N4878, 2N4879, 2N4880 Dielectrically Isolated Dual NPN Transistor

1

FEATURES

- High Gain at Low Current
- Low Output Capacitance
- Good h_{FE} Match
- Tight V_{BE} Tracking
- Dielectrically Isolated Matched Pairs for Differential Amplifiers.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Collector-Base or Collector-Emitter Voltage (Note 1)

2N4044, 2N4878 60V

2N4100, 2N4879 55V

2N4045, 2N4880 45V

Collector-Collector Voltage 100V

Emitter-Base Voltage (Note 2) 7V

Collector Current (Note 1) 10 mA

Storage Temperature Range -65°C to $+200^\circ\text{C}$

Operating Temperature Range -55°C to $+150^\circ\text{C}$

Lead Temperature (Soldering, 10 sec.) $+300^\circ\text{C}$

| | TO-71 | | TO-78 | |
|--|----------|------------|----------|------------|
| | ONE SIDE | BOTH SIDES | ONE SIDE | BOTH SIDES |
| Power Dissipation .. | 300 mW | 500 mW | 400 mW | 750 mW |
| Derate above 25°C ($\text{mW}/^\circ\text{C}$) | 1.7 | 2.9 | 2.3 | 4.3 |

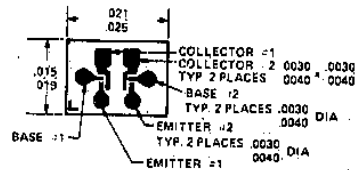
PIN CONFIGURATION

TO-71
TO-78



CHIP TOPOGRAPHY

4000



ORDERING INFORMATION*

| TO-78 | TO-71 | WAFER | DICE |
|--------|--------|----------|----------|
| 2N4044 | 2N4878 | 2N4044/W | 2N4044/D |
| 2N4045 | 2N4879 | 2N4045/W | 2N4045/D |
| 2N4100 | 2N4880 | 2N4100/W | 2N4100/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N4044 2N4878 | | 2N4100 2N4879 | | 2N4045 2N4880 | | UNIT | TEST CONDITIONS | | |
|---------------|------------------------------|-----|------------------|------|------------------|------|------|-----------------|---------------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | | | | |
| h_{FE} | DC Current Gain | | 200 | 600 | 150 | 600 | 80 | 800 | V | $I_C = 10 \mu\text{A}, V_{CE} = 5\text{V}$ $I_C = 1.0 \text{mA}, V_{CE} = 5\text{V}$ $I_C = 10 \mu\text{A}, V_{CE} = 5\text{V}$ |
| | | | 225 | | 175 | | 100 | | | |
| | | | 75 | | 50 | | 30 | | | |
| $V_{BE(on)}$ | Emitter-Base On Voltage | | | 0.7 | | 0.7 | | 0.7 | V | $I_C = 1.0 \text{mA}, I_B = 0.1 \text{mA}$ $I_E = 0, V_{CB} = 45\text{V}, 30\text{V}^*$ |
| $V_{CE(sat)}$ | Collector Saturation Voltage | | | 0.35 | | 0.35 | | 0.35 | | |
| I_{CBO} | Collector Cutoff Current | | | 0.1 | | 0.1 | | 0.1* | nA | $I_C = 0, V_{EB} = 5\text{V}$ $I_E = 0, V_{CB} = 5\text{V}$ |
| | | | | 0.1 | | 0.1 | | 0.1* | μA | |
| I_{EBO} | Emitter Cutoff Current | | | 0.1 | | 0.1 | | 0.1 | nA | |
| C_{obo} | Output Capacitance | | | 0.8 | | 0.8 | | 0.8 | pF | |

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N4044 2N4878 | | 2N4100 2N4879 | | 2N4045 2N4880 | | UNIT | TEST CONDITIONS |
|------------------------|------------------|-----|------------------|-----|------------------|-----|------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| C _{te} | 1 | | 1 | | 1 | | pF | I _C = 0, V _{EB} = 0.5V |
| C _{C1, C2} | 0.8 | | 0.8 | | 0.8 | | pF | V _{CC} = 0 |
| I _{C1, C2} | 5 | | 5 | | 5 | | pA | V _{CC} = ±100V |
| V _{CEO(sust)} | 60 | | 55 | | 45 | | V | I _C = 1mA, I _B = 0 |
| f _t | 200 | | 150 | | 150 | | MHZ | I _C = 1mA, V _{CE} = 10V |
| f _t | 20 | | 15 | | 15 | | MHZ | I _C = 10μA, V _{CE} = 10V |
| NF | | 2 | | 3 | | 3 | dB | I _C = 10μA, V _{CE} = 5V, f = 1KHz R _G = 10 kohms, BW = 200 Hz |
| BV _{CB0} | 60 | | 55 | | 45 | | V | I _C = 10μA, I _E = 0 |
| BV _{EB0} | 7 | | 7 | | 7 | | V | I _E = 10μA, I _C = 0 |

MATCHING CHARACTERISTICS (25°C unless otherwise noted)

| | | | | | | | | | |
|---|--|-----|-----|------|-----|-----|----|-------|--|
| h _{FE1} /h _{FE2} | DC Current Gain Ratio (Note 3) | 0.9 | 1 | 0.85 | 1 | 0.8 | 1 | | I _C = 10μA to 1mA, V _{CE} = 5V |
| V _{BE1} -V _{BE2} | Base Emitter Voltage Differential | | 3 | | 5 | | 5 | mV | I _C = 10μA, V _{CE} = 5V |
| I _{B1} -I _{B2} | Base Current Differential | | 5 | | 10 | | 25 | nA | I _C = 10μA, V _{CE} = 5V |
| Δ(V _{BE1} -V _{BE2})/ΔT | Base Emitter Voltage Differential Change with Temperature | | 3 | | 5 | | 10 | μV/°C | I _C = 10μA, V _{CE} = 5V T _A = -55°C to +125°C |
| Δ(I _{B1} -I _{B2})/ΔT | Base Current Differential Change with Temperature | | 0.3 | | 0.5 | | 1 | nA/°C | |

SMALL SIGNAL CHARACTERISTICS

| PARAMETER | TYPICAL VALUE | UNIT | TEST CONDITIONS |
|-----------------|---------------|--------------------|--|
| h _{ib} | 28 | ohms | I _C = 1mA, V _{CB} = 5V |
| h _{rb} | 43 | x 10 ⁻³ | |
| h _{fe} | 250 | | |
| h _{ob} | 60 | μmhos | I _C = 1mA, V _{CE} = 5V |
| h _{ie} | 9.6 | k ohms | |
| h _{re} | 42 | x 10 ⁻³ | |
| h _{oe} | 12 | μmhos | |

NOTES:

1. Per transistor.
2. The reverse base-emitter voltage must never exceed 7.0 volts and the reverse base-emitter current must never exceed 10 μamps.
3. The lowest of two h_{FE} readings is taken as h_{FE1} for purposes of this ratio.

1

ITE4091-ITE4093 2N4091-2N4093, JANTX* N-Channel JFET

1

FEATURES

- Low $r_{DS(on)}$
- $I_{D(OFF)} < 100$ pA (JANTX Types)
- Fast Switching

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|---------------------------------------|-------|-----------------|
| Gate-Source or Gate-Drain Voltage | | -40V |
| Gate Current | | 10 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | | +300°C |

| | | |
|-------------------|-----------------|-----------------|
| | TO-18 | TO-92 |
| Power Dissipation | 1.8W | 360 mW |
| Derate above 25°C | 1.7 mW/°C | 3.0 mW/°C |

PIN CONFIGURATIONS

CHIP TOPOGRAPHY

ORDERING INFORMATION*

| TO-92 | TO-18† | WAFER | DICE |
|-----------|---------|----------|----------|
| ITE 4091 | 2N4091 | 2N4091/W | 2N4091/D |
| ITE 4091A | 2N4091A | | |
| ITE 4092 | 2N4092 | 2N4092/W | 2N4092/D |
| ITE 4092A | 2N4092A | | |
| ITE 4093 | 2N4093 | 2N4093/W | 2N4093/D |
| ITE 4093A | 2N4093A | | |

†add JANTX to these part numbers if JANTX processing is desired.

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N/ITE 4091 | | 2N/ITE 4092 | | 2N/ITE 4093 | | Unit | Test Conditions | |
|----------------------------------|--|------|-------------|------|-------------|------|-----------------------|--|---|
| | Min. | Max. | Min. | Max. | Min. | Max. | | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | | -40 | | -40 | | V | $I_G = -1\mu\text{A}, V_{DS} = 0$ | |
| $I_{D(OFF)}$ | Drain Reverse Current | | | 200 | | 200 | pA | $V_{GS} = -20\text{V}, I_S = 0$ | |
| | (Not JANTX Specified) $T_A = 150^\circ\text{C}$ | | | 400 | | 400 | nA | | |
| I_{GSS} | Gate Reverse Current | | | -100 | | -100 | pA | $V_{GS} = -20\text{V}, V_{DS} = 0$ | |
| | (JANTX, ITE devices only); $T_A = 150^\circ\text{C}$ | | | -200 | | -200 | nA | | |
| $I_{D(OFF)}$ | -JANTX; $T_A = 25^\circ\text{C}$ | | | 100 | | 100 | pA | $V_{DS} = 20\text{V}$ $V_{GS} = -12\text{V}$ (4091) $V_{GS} = -8\text{V}$ (4092) $V_{GS} = -6\text{V}$ (4093) | |
| | Drain Cutoff Current | | | 200 | | 200 | pA | | |
| JANTX, $T_A = 150^\circ\text{C}$ | | | 400 | | 400 | nA | | | |
| Drain Cutoff Current | | | 200 | | 200 | nA | | | |
| V_P | Gate-Source Pinch-Off Voltage | | -5 | -10 | -2 | -7 | -1 | -5 | $V_{DS} = 20\text{V}, I_D = 1\text{ nA}$ |
| I_{DSS} | Drain Current at Zero Gate Voltage | | 30 | | 15 | | 8 | | $V_{DS} = 20\text{V}, V_{GS} = 0$, Pulse Test Duration = 2 ms |
| $V_{DS(ON)}$ | Drain-Source ON Voltage | | | | | | 0.2 | $V_{GS} = 0$ | |
| | | | | | | 0.2 | $I_D = 2.5\text{ mA}$ | | |
| | | | | | | 0.2 | $I_D = 4\text{ mA}$ | | |
| $r_{DS(on)}$ | Static Drain-Source ON Resistance | | | 30 | | 50 | | 80 | $V_{GS} = 0, I_D = 1\text{ mA}$ |
| $r_{DS(on)}$ | Static Drain Source ON Resistance | | | 30 | | 50 | | 80 | $V_{GS} = 0, I_D = 0, f = 1\text{ kHz}$ |
| C_{iss} | Common-Source Input Capacitance | | | 16 | | 16 | | 16 | $V_{DS} = 20\text{V}, V_{GS} = 0, f = 1\text{ MHz}$ |
| C_{rss} | JANTX Only | | | 5 | | .5 | | 5 | $V_{DS} = -0, V_{GS} = -20\text{V}, f = 1\text{ MHz}$ |
| | Common-Source Reverse Transfer Capacitance | | | 5 | | .5 | | 5 | |
| $t_{d(ON)}$ | Turn-ON Delay Time | | | 15 | | 15 | | 20 | $V_{DD} = 3\text{V}, V_{GS(ON)} = 0$ |
| t_r | Rise Time | | | 10 | | 20 | | 40 | |
| t_{off} | Turn-OFF Time | | | 40 | | 60 | | 80 | |
| | | | | | | | | | |



2N4044, 2N4045, 2N4100, 2N4878, 2N4879, 2N4880 Dielectrically Isolated Dual NPN Transistor

FEATURES

- High Gain at Low Current
- Low Output Capacitance
- Good h_{FE} Match
- Tight V_{BE} Tracking
- Dielectrically Isolated Matched Pairs for Differential Amplifiers.

ABSOLUTE MAXIMUM RATINGS

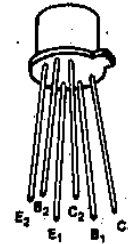
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--|---|
| Collector-Base or Collector-Emitter Voltage (Note 1) | |
| 2N4044, 2N4878 | 60V |
| 2N4100, 2N4879 | 55V |
| 2N4045, 2N4880 | 45V |
| Collector-Collector Voltage | 100V |
| Emitter-Base Voltage (Note 2) | 7V |
| Collector Current (Note 1) | 10 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |

| | TO-71 | | TO-78 | |
|--|----------|------------|----------|------------|
| | ONE SIDE | BOTH SIDES | ONE SIDE | BOTH SIDES |
| Power Dissipation .. | 300 mW | 500 mW | 400 mW | 750 mW |
| Derate above 25°C ($\text{mW}/^\circ\text{C}$) | 1.7 | 2.9 | 2.3 | 4.3 |

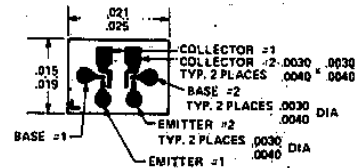
PIN CONFIGURATION

TO-71
TO-78



CHIP TOPOGRAPHY

4000



ORDERING INFORMATION*

| TO-78 | TO-71 | WAFER | DICE |
|--------|--------|----------|----------|
| 2N4044 | 2N4878 | 2N4044/W | 2N4044/D |
| 2N4045 | 2N4879 | 2N4045/W | 2N4045/D |
| 2N4100 | 2N4880 | 2N4100/W | 2N4100/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N4044 2N4878 | | 2N4100 2N4879 | | 2N4045 2N4880 | | UNIT | TEST CONDITIONS |
|--|---------------------------|------|------------------|------|------------------|------|---------------|--|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| h_{FE} DC Current Gain | 200 | 600 | 150 | 600 | 80 | 800 | V | $I_C = 10\ \mu\text{A}, V_{CE} = 5\text{V}$ |
| | 225 | | 175 | | 100 | | | $I_C = 1.0\ \text{mA}, V_{CE} = 5\text{V}$ |
| | $T_A = -55^\circ\text{C}$ | 75 | | 50 | | 30 | | |
| $V_{BE(on)}$ Emitter-Base On Voltage | | 0.7 | | 0.7 | | 0.7 | | $I_C = 1.0\ \text{mA}, I_B = 0.1\ \text{mA}$ |
| $V_{CE(sat)}$ Collector Saturation Voltage | | 0.35 | | 0.35 | | 0.35 | | $I_C = 1.0\ \text{mA}, I_B = 0.1\ \text{mA}$ |
| I_{CBO} Collector Cutoff Current | | 0.1 | | 0.1 | | 0.1* | nA | $I_E = 0, V_{CB} = 45\text{V}, 30\text{V}^*$ |
| | $T_A = 150^\circ\text{C}$ | | | 0.1 | | 0.1* | μA | |
| I_{EBO} Emitter Cutoff Current | | 0.1 | | 0.1 | | 0.1 | nA | $I_C = 0, V_{EB} = 5\text{V}$ |
| C_{obo} Output Capacitance | | 0.8 | | 0.8 | | 0.8 | pF | $I_E = 0, V_{CB} = 5\text{V}$ |

1

ELECTRICAL CHARACTERISTICS (25 °C unless otherwise noted)

| PARAMETER | 2N4044 2N4878 | | 2N4100 2N4879 | | 2N4045 2N4880 | | UNIT | TEST CONDITIONS |
|-----------------|------------------|-----|------------------|-----|------------------|-----|------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| C_{ie} | | 1 | | 1 | | 1 | pF | $I_C = 0, V_{EB} = 0.5V$ |
| $C_{C1, C2}$ | | 0.8 | | 0.8 | | 0.8 | pF | $V_{CC} = 0$ |
| $I_{C1, C2}$ | | 5 | | 5 | | 5 | pA | $V_{CC} = \pm 100V$ |
| $V_{CEO(sust)}$ | 60 | | 55 | | 45 | | V | $I_C = 1mA, I_B = 0$ |
| f_t | 200 | | 150 | | 150 | | MHz | $I_C = 1mA, V_{CE} = 10V$ |
| f_t | 20 | | 15 | | 15 | | MHz | $I_C = 10\mu A, V_{CE} = 10V$ |
| NF | | 2 | | 3 | | 3 | dB | $I_C = 10\mu A, V_{CE} = 5V$ $R_G = 10\text{ kohms}$ $f = 1\text{ kHz}$ $BW = 200\text{ Hz}$ |
| BV_{CBO} | 60 | | 55 | | 45 | | V | $I_C = 10\mu A, I_E = 0$ |
| BV_{EBO} | 7 | | 7 | | 7 | | V | $I_E = 10\mu A, I_C = 0$ |

MATCHING CHARACTERISTICS (25 °C unless otherwise noted)

| | | | | | | | | | |
|--|---|-----|-----|------|-----|-----|----|------------------|---|
| h_{FE1}/h_{FE2} | DC Current Gain Ratio (Note 3) | 0.9 | 1 | 0.85 | 1 | 0.8 | 1 | | $I_C = 10\mu A\text{ to }1mA,$ $V_{CE} = 5V$ |
| $ V_{BE1} - V_{BE2} $ | Base Emitter Voltage Differential | | 3 | | 5 | | 5 | mV | $I_C = 10\mu A, V_{CE} = 5V$ |
| $ I_{B1} - I_{B2} $ | Base Current Differential | | 5 | | 10 | | 25 | nA | $I_C = 10\mu A, V_{CE} = 5V$ |
| $ \Delta(V_{BE1} - V_{BE2})/\Delta T $ | Base Emitter Voltage Differential Change with Temperature | | 3 | | 5 | | 10 | $\mu V/^\circ C$ | $I_C = 10\mu A,$ $V_{CE} = 5V$ $T_A = -55^\circ C\text{ to }+125^\circ C$ |
| $ \Delta(I_{B1} - I_{B2})/\Delta T $ | Base Current Differential Change with Temperature | | 0.3 | | 0.5 | | 1 | $nA/^\circ C$ | |

SMALL SIGNAL CHARACTERISTICS

| PARAMETER | TYPICAL VALUE | UNIT | TEST CONDITIONS |
|-----------|---------------------------|------|--------------------------|
| h_{ib} | Input Resistance | 28 | $I_C = 1mA, V_{CB} = 5V$ |
| h_{rb} | Voltage Feedback Ratio | 43 | |
| h_{fe} | Small Signal Current Gain | 250 | $I_C = 1mA, V_{CE} = 5V$ |
| h_{ob} | Output Conductance | 60 | |
| h_{ie} | Input Resistance | 9.6 | |
| h_{re} | Voltage Feedback Ratio | 42 | |
| h_{oe} | Output Conductance | 12 | |

NOTES:

1. Per transistor.
2. The reverse base-emitter voltage must never exceed 7.0 volts and the reverse base-emitter current must never exceed 10 μ amps.
3. The lowest of two h_{FE} readings is taken as h_{FE1} for purposes of this ratio.

2N4117-19, 2N4117A-19A N-Channel JFET

FEATURES

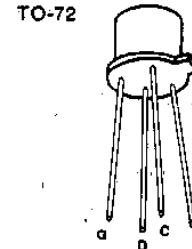
- Low Leakage
- Low Capacitance

ABSOLUTE MAXIMUM RATINGS

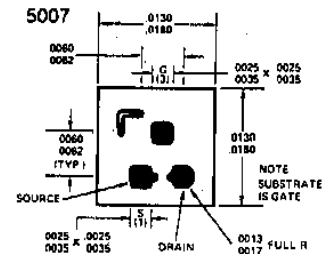
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|---------------------------------------|-------|-----------------|
| Gate-Source or Gate-Drain Voltage | | -40V |
| Gate Current | | 50 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | | +300°C |
| Power Dissipation | | 300 mW |
| Derate above 25°C | | 1.7 mW/°C |

PIN CONFIGURATION



CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-72 | WAFER | CHIP |
|---------|----------|----------|
| 2N4117 | 2N4117/W | 2N4117/D |
| 2N4117A | — | — |
| 2N4118 | 2N4118/W | 2N4118/D |
| 2N4118A | — | — |
| 2N4119 | 2N4119/W | 2N4119/D |
| 2N4119A | — | — |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | 2N4117 | | 2N4118 | | 2N4119 | | UNIT | TEST CONDITIONS |
|----------------------|---|-----------|------|---------|------|---------|------|-----------------|--|
| | | 2N4117A | | 2N4118A | | 2N4119A | | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -40 | | -40 | | -40 | | V | $I_G = -1 \mu\text{A}, V_{DS} = 0$ |
| I_{GSSR} | Gate Reverse Current | | -10 | | -10 | | -10 | pA | $V_{GS} = -20 \text{ V}, V_{DS} = 0$ |
| | | A devices | | -1 | | -1 | | | |
| | $T_A = +100^\circ\text{C}$ | | | -25 | | -25 | | -25 | |
| | A devices | | -2.5 | | -2.5 | | -2.5 | | |
| $V_{GS}(\text{off})$ | Gate-Source Pinch-Off Voltage | -0.6 | -1.8 | -1 | -3 | -2 | -6 | V | $V_{DS} = 10 \text{ V}, I_D = 1 \text{ nA}$ |
| I_{DSS} | Drain Current at Zero Gate Voltage (Note 1) | 0.02 | 0.09 | 0.08 | 0.24 | 0.20 | 0.60 | mA | $V_{DS} = 10 \text{ V}, V_{GS} = 0$ |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 70 | 210 | 80 | 250 | 100 | 330 | μmho | $V_{DS} = 10 \text{ V}, f = 1 \text{ kHz}$ |
| g_{fs} | Common-Source Forward Transconductance | 60 | | 70 | | 90 | | | $V_{GS} = 0, f = 30 \text{ MHz}$ |
| g_{os} | Common-Source Output Conductance | | 3 | | 5 | | 10 | | $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$ |
| C_{iss} | Common-Source Input Capacitance | | 3 | | 3 | | 3 | pF | $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$ |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 1.5 | | 1.5 | | 1.5 | | $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$ |

NOTE: 1. Pulse test: Pulse duration of 2 ms used during test.

2N4220 - 2N4222 N-Channel JFET

FEATURES

- $C_{rss} < 2$ pF
- Moderately High Forward Transconductance

1

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Source or Gate-Drain Voltage | -30V |
| Gate Current | 10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

PIN CONFIGURATION
TO-72

CHIP TOPOGRAPHY
5010*

NOTE: SUBSTRATE IS GATE.

*DICE WITH 4 MIL BONDING PADS AVAILABLE. CONSULT FACTORY FOR DETAILS.

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N4220 | 2N4220/W | 2N4220/D |
| 2N4221 | 2N4221/W | 2N4221/D |
| 2N4222 | 2N4222/W | 2N4222/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | 2N4220 | | 2N4221 | | 2N4222 | | UNIT | TEST CONDITIONS | |
|------------------|---|---------------------------|------|--------|------|--------|------|-----------------|--|-------------|
| | | MIN | MAX | MIN | MAX | MIN | MAX | | | |
| IGSSR | Gate Reverse Current | $T_A = 150^\circ\text{C}$ | | -0.1 | -0.1 | -0.1 | -0.1 | nA | $V_{GS} = -15\text{ V}, V_{DS} = 0$ | |
| | | | | -0.1 | -0.1 | -0.1 | -0.1 | μA | | |
| BVGS | Gate-Source Breakdown Voltage | -30 | | -30 | | -30 | | V | $I_G = -10\ \mu\text{A}, V_{DS} = 0$ | |
| VGS(off) | Gate-Source Cutoff Voltage | | -4 | | -6 | | -8 | V | $V_{DS} = 15\text{ V}, I_D = 0.1\ \text{nA}$ | |
| VGS | Gate-Source Voltage | -0.5 | -2.5 | -1 | -5 | -2 | -6 | V | $V_{DS} = 15\text{ V}$ $I_D = 50\ \mu\text{A}$ (2N4220) $I_D = 200\ \mu\text{A}$ (2N4221) $I_D = 500\ \mu\text{A}$ (2N4222) | |
| I _{DSS} | Saturation Drain Current (Note 3) | 0.5 | 3 | 2 | 6 | 5 | 15 | mA | $V_{DS} = 15\text{ V}, V_{GS} = 0$ | |
| g _{fs} | Common-Source Forward Transconductance (Note 1) | 1000 | 4000 | 2000 | 5000 | 2500 | 6000 | μmho | $V_{DS} = 15\text{ V}, V_{GS} = 0$ | |
| y _{fs} | Common-Source Forward Transadmittance | 750 | | 750 | | 750 | | | | f = 1 kHz |
| g _{os} | Common-Source Output Conductance (Note 1) | | 10 | | 20 | | 40 | | | f = 100 MHz |
| C _{iss} | Common-Source Input Capacitance | | 6 | | 6 | | 6 | pF | f = 1 MHz | |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | 2 | | 2 | | 2 | | | |

NOTE 1: Pulse test duration 2 ms.

FEATURES

- NF = 3 dB Typical at 200 MHz
- $C_{rss} < 2$ pF

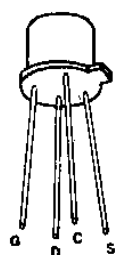
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|---------------------------------------|-------|-----------------|
| Gate-Source or Gate-Drain Voltage | | -30V |
| Gate Current | | 10 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | | +300°C |
| Power Dissipation | | 300 mW |
| Derate above 25°C | | 1.7 mW/°C |

PIN CONFIGURATION

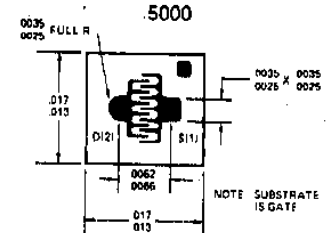
TO-72



a
D
C
S

CHIP TOPOGRAPHY

5000



NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N4223 | 2N4223/W | 2N4223/D |
| 2N4224 | 2N4224/W | 2N4224/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | 2N4223 | | 2N4224 | | UNIT | TEST CONDITIONS |
|------------|--|----------------------------|------|--------|------|-----------------|---|
| | | MIN | MAX | MIN | MAX | | |
| IGSSR | Gate Reverse Current | $T_A = +150^\circ\text{C}$ | | -0.25 | -0.5 | nA | $V_{GS} = -20\text{ V}, V_{DS} = 0$ |
| | | | | -0.25 | -0.5 | μA | |
| BVGSS | Gate-Source Breakdown Voltage | -30 | | -30 | | | $I_G = -10\ \mu\text{A}, V_{DS} = 0$ |
| VGS(off) | Gate-Source Cutoff Voltage | -0.1 | -8 | -0.1 | -8 | V | $V_{DS} = 15\text{ V}$ $I_D = 0.25\ \text{nA}$ (2N4223) $I_D = 0.5\ \text{nA}$ (2N4224) $I_D = 0.3\ \text{mA}$ (2N4223) $I_D = 0.2\ \text{mA}$ (2N4224) |
| VGS | Gate-Source Voltage | -1.0 | -7.0 | -1.0 | -7.5 | | |
| IDSS | Saturation Drain Current (Note 1) | 3 | 18 | 2 | 20 | | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 3000 | 7000 | 2000 | 7500 | μmho | $V_{DS} = 15\text{ V}, V_{GS} = 0$ |
| C_{iss} | Common-Source Input Capacitance (Output Shorted) | | 6 | | 6 | pF | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 2 | | 2 | pF | f = 1 MHz |
| $ y_{fs} $ | Common-Source Forward Transadmittance | 2700 | | 1700 | | μmho | $V_{DS} = 15\text{ V}, V_{GS} = 0$ |
| g_{iss} | Common-Source Input Conductance (Output Shorted) | | 800 | | 800 | | |
| g_{oss} | Common-Source Output Conductance (Input Shorted) | | 200 | | 200 | | |
| G_{ps} | Small Signal Power Gain | 10 | | | | | f = 200 MHz |
| NF | Noise Figure | | 5 | | | dB | $V_{DS} = 15\text{ V}, V_{GS} = 0,$ $R_{gen} = 1\text{ k}\Omega$ |

Note 1: Pulse test, duration 2 msec.

FEATURES

- Exceptionally High Figure of Merit
- Radiation Immunity
- Extremely Low Noise and Capacitance
- High Input Impedance

1

APPLICATIONS

- Low-level Choppers
- Data Switches
- Multiplexers and Low Noise Amplifiers

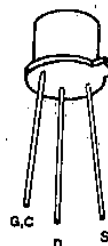
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|---------------------------------------|-------|-----------------|
| Gate-Source or Gate-Drain Voltage | | -50V |
| Gate Current | | 50 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | | +300°C |
| Power Dissipation | | 300 mW |
| Derate above 25°C | | 1.7 mW/°C |

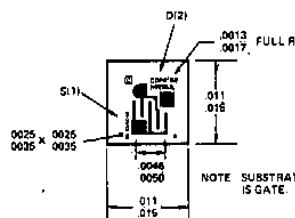
PIN CONFIGURATION

TO-18



CHIP TOPOGRAPHY

5040



*DICE WITH 4 MIL BONDING PADS AVAILABLE. CONSULT FACTORY FOR DETAILS.

ORDERING INFORMATION*

| TO-18 | WAFER | DICE |
|--------|----------|----------|
| 2N4338 | 2N4338/W | 2N4338/D |
| 2N4339 | 2N4339/W | 2N4339/D |
| 2N4340 | 2N4340/W | 2N4340/D |
| 2N4341 | 2N4341/W | 2N4341/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N4338 | | 2N4339 | | 2N4340 | | 2N4341 | | UNITS | TEST CONDITIONS | |
|--|--------|-----------|--------|-----------|--------|-----------|--------|------------|-----------------|--|-------------------|
| | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | | |
| I_{GSS} Gate Reverse Current | | -0.1 | | -0.1 | | -0.1 | | -0.1 | nA | $V_{GS} = -30\text{V}, V_{DS} = 0$ | |
| | | -0.1 | | -0.1 | | -0.1 | | -0.1 | μA | | |
| BV_{GSS} Gate-Source Breakdown Voltage | -50 | | -50 | | -50 | | -50 | | V | $I_G = -1\mu\text{A}, V_{DS} = 0$ $V_{DS} = 15\text{V}, I_D = 0.1\mu\text{A}$ | |
| $V_{GS(off)}$ Gate-Source Cutoff Voltage | -0.3 | -1 | -0.6 | -1.8 | -1 | -3 | -2 | -6 | | | |
| $I_{D(off)}$ Drain Cutoff Current | | 0.05 (-5) | | 0.05 (-5) | | 0.05 (-5) | | 0.07 (-10) | nA (V) | $V_{DS} = 15\text{V}, V_{GS} = ()$ | |
| I_{DSS} Saturation Drain Current | 0.2 | 0.6 | 0.5 | 1.5 | 1.2 | 3.6 | 3 | 9 | mA | $V_{DS} = 15\text{V}, V_{GS} = 0$ | |
| g_{fs} Common-Source Forward Transconductance | 600 | 1800 | 800 | 2400 | 1300 | 3000 | 2000 | 4000 | μmho | $V_{DS} = 15\text{V}, V_{GS} = 0$ | $f = 1\text{kHz}$ |
| g_{os} Common-Source Output Conductance | | 5 | | 15 | | 30 | | 60 | | | |
| $r_{DS(on)}$ Drain-Source ON Resistance | | 2500 | | 1700 | | 1500 | | 800 | ohm | $V_{DS} = 0, I_{DS} = 0$ | |
| C_{iss} Common-Source Input Capacitance | | 7 | | 7 | | 7 | | 7 | pF | $V_{DS} = 15\text{V}, V_{GS} = 0$ | $f = 1\text{MHz}$ |
| C_{rss} Common-Source Reverse Transfer Capacitance | | 3 | | 3 | | 3 | | 3 | | | |
| NF Noise Figure | | 1 | | 1 | | 1 | | 1 | dB | $V_{DS} = 15\text{V}, V_{GS} = 0$ $R_{gen} = 1\text{meg}, BW = 200\text{Hz}$ | $f = 1\text{kHz}$ |

2N4351 N-Channel Enhancement Mode MOS FET

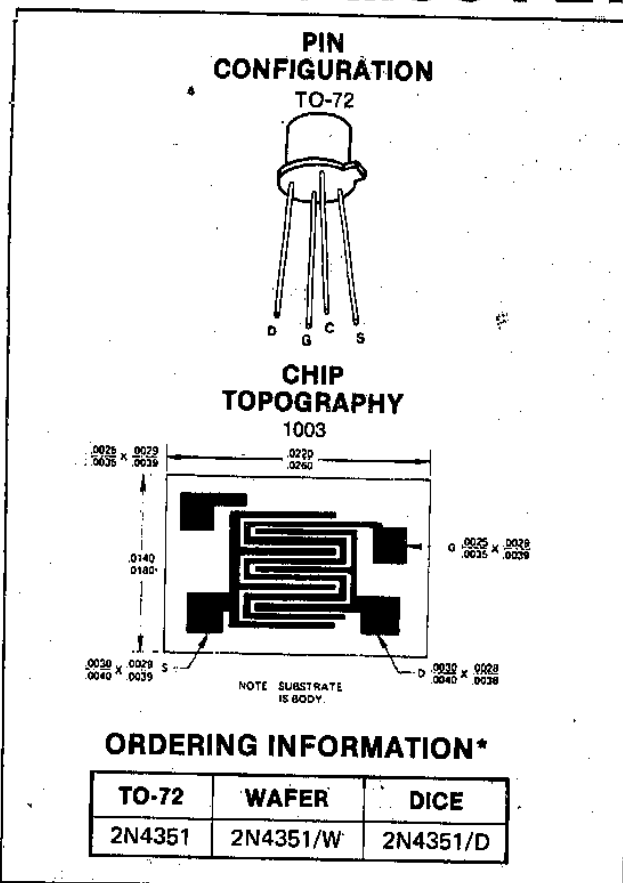
FEATURES

- Low ON Resistance
- Low Capacitance
- High Gain
- High Gate Breakdown Voltage
- Low Threshold Voltage

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--|---|
| Drain-Source Voltage or Drain-Gate Voltage | 25V |
| Peak Gate-Source Voltage (Note 1) | $\pm 125\text{V}$ |
| Drain Current | 100 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 375 mW |
| Derate above 25°C | 3 mW/ $^\circ\text{C}$ |



1

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

Substrate connected to source.

| PARAMETER | MIN | MAX | UNITS | TEST CONDITIONS |
|--------------|------|-----|-----------------|--|
| BV_{DSS} | 25 | | V | $I_D = 10\ \mu\text{A}$, $V_{GS} = 0$ |
| I_{GSS} | | 10 | μA | $V_{GS} = \pm 30\ \text{V}$, $V_{DS} = 0$ |
| I_{DSS} | | 10 | nA | $V_{DS} = 10\ \text{V}$, $V_{GS} = 0$ |
| $V_{GS(th)}$ | 1 | .5 | V | $V_{DS} = 10\ \text{V}$, $I_D = 10\ \mu\text{A}$ |
| $I_{D(on)}$ | 3 | | mA | $V_{GS} = 10\ \text{V}$, $V_{DS} = 10\ \text{V}$ |
| $V_{DS(on)}$ | | 1 | V | $I_D = 2\ \text{mA}$, $V_{GS} = 10\ \text{V}$ |
| $r_{DS(on)}$ | | 300 | ohms | $V_{GS} = 10\ \text{V}$, $I_D = 0$, $f = 1\ \text{kHz}$ |
| $ y_{fs} $ | 1000 | | μmho | $V_{DS} = 10\ \text{V}$, $I_D = 2\ \text{mA}$, $f = 1\ \text{kHz}$ |
| C_{rss} | | 1.3 | pF | $V_{DS} = 0$, $V_{GS} = 0$, $f = 140\ \text{kHz}$ |
| C_{iss} | | 5.0 | | $V_{DS} = 10\ \text{V}$, $V_{GS} = 0$, $f = 140\ \text{kHz}$ |
| $C_{d(sub)}$ | | 5.0 | | $V_{D(SUB)} = 10\ \text{V}$, $f = 140\ \text{kHz}$ |
| $t_{d(on)}$ | | 45 | ns | |
| t_r | | 65 | | |
| $t_{d(off)}$ | | 60 | | |
| t_f | | 100 | | |

Note 1. Device must not be tested at $\pm 125\text{V}$ more than once or longer than 300 ms.

ITE4391-ITE4393 2N4391-2N4393 N-Channel JFET

FEATURES

- $r_{ds(on)} < 30$ ohms (2N4391)
- $I_{D(off)} < 100$ pA
- Switches ± 10 VAC with ± 15 V Supplies (2N4392, 2N4393)

1

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------------|
| Gate-Source or Gate-Drain Voltage | -40V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | TO-18 TO-92 |
| Derate above 25°C | 1.8W / 360 mW |
| | 1.7 mW/°C / 3.0 mW/°C |

PIN CONFIGURATIONS

CHIP TOPOGRAPHY

ORDERING INFORMATION*

| TO-92 | TO-18 | WAFER | DICE |
|----------|--------|----------|----------|
| ITE 4391 | 2N4391 | 2N4391/W | 2N4391/D |
| ITE 4392 | 2N4392 | 2N4392/W | 2N4392/D |
| ITE 4393 | 2N4393 | 2N4393/W | 2N4393/D |

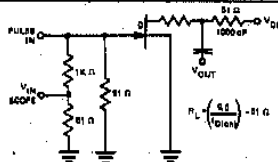
ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | 4391 | | 4392 | | 4393 | | UNIT | TEST CONDITIONS |
|---------------|--|-----|---------------------------|-----|------|------|----------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| I_{GSS} | Gate Reverse Current | | $T_A = 150^\circ\text{C}$ | | -100 | -100 | pA | $V_{GS} = -20\text{ V}, V_{DS} = 0$ |
| BV_{GSS} | Gate-Source Breakdown Voltage | | -40 | -40 | -40 | -40 | V | $I_G = 1\ \mu\text{A}, V_{DS} = 0$ |
| $I_{D(off)}$ | Drain Cutoff Current | | $T_A = 150^\circ\text{C}$ | | 100 | 100 | pA | $V_{DS} = 20\text{ V}$ |
| | | | 200 | 200 | 200 | 200 | nA | $V_{GS} = -5\text{ V (4393)}$ $V_{GS} = -7\text{ V (4392)}$ $V_{GS} = -12\text{ V (4391)}$ |
| $V_{GS(f)}$ | Gate-Source Forward Voltage | | -4 | -10 | -2 | -5 | V | $I_G = 1\text{ mA}, V_{DS} = 0$ |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | | -4 | -10 | -2 | -5 | V | $V_{DS} = 20\text{ V}, I_D = 1\text{ nA}$ |
| I_{DSS} | Saturation Drain Current (Note 1) | | 50 | 150 | 25 | 75 | mA | $V_{DS} = 20\text{ V}, V_{GS} = 0$ |
| $V_{DS(on)}$ | Drain Source ON-Voltage | | 0.4 | 0.4 | 0.4 | 0.4 | V | $V_{GS} = 0$ $I_D = 3\text{ mA (4393)}$ $I_D = 6\text{ mA (4392)}$ $I_D = 12\text{ mA (4391)}$ |
| $r_{DS(on)}$ | Static Drain-Source ON Resistance | | 30 | 60 | 100 | 100 | Ω | $V_{GS} = 0, I_D = 1\text{ mA}$ |
| $r_{ds(on)}$ | Drain-Source ON Resistance | | 30 | 60 | 100 | 100 | Ω | $V_{GS} = 0, I_D = 0$ $f = 1\text{ kHz}$ |
| C_{iss} | Common-Source Input Capacitance | | 14 | 14 | 14 | 14 | pF | $V_{DS} = 20\text{ V}, V_{GS} = 0$ |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 3.5 | 3.5 | 3.5 | 3.5 | pF | $V_{DS} = 0$ $V_{GS} = -5\text{ V}$ $V_{GS} = -7\text{ V}$ $V_{GS} = -12\text{ V}$ $f = 1\text{ MHz}$ |
| t_d | Turn-ON Delay Time | | 15 | 15 | 15 | 15 | ns | $V_{DD} = 10\text{ V}, V_{GS(on)} = 0$ |
| t_r | Rise Time | | 5 | 5 | 5 | 5 | ns | $I_{D(on)}$ $V_{GS(off)}$ |
| t_{off} | Turn-OFF Delay Time | | 20 | 35 | 50 | 50 | ns | 12 mA / -12 V |
| t_f | Fall Time | | 15 | 20 | 30 | 30 | ns | 6 / -7 |
| | | | | | | | | 3 / -5 |

NOTE:

1. Pulse test required, pulse width = 300 μs , duty cycle $\leq 3\%$



INPUT PULSE

RISE TIME < 0.5 ns
FALL TIME < 0.5 ns
PULSE DUTY CYCLE 1%

SAMPLING SCOPE

RISE TIME 0.4 ns
INPUT RESISTANCE 50 Ω

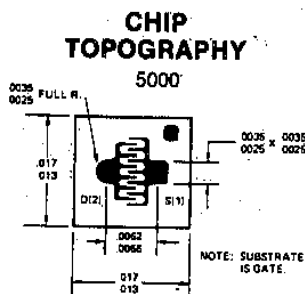
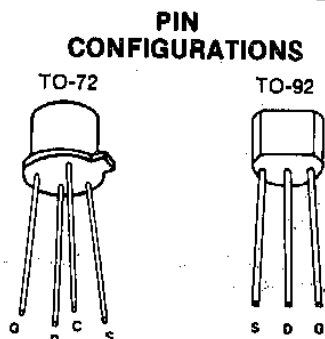
FEATURES

- Low Noise
- Low Feedback Capacitance
- Low Output Capacitance
- High Transconductance
- High Power Gain

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Source or Gate-Drain Voltage | |
| 2N4416, ITE4416 | -30V |
| 2N4416A | -35V |
| Gate Current | 10 mA |
| Storage Temperature Range | |
| 2N4416/2N4416A | -65°C to +200°C |
| ITE4416 | -55°C to +125°C |
| Operating Temperature Range | |
| 2N4416/2N4416A | -65°C to +200°C |
| ITE4416 | -55°C to +125°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate, above 25°C | |
| 2N4416/2N4416A | 1.7 mW/°C |
| ITE4416 | 3.0 mW/°C |



ORDERING INFORMATION*

| TO-92 | TO-72 | WAFER | DICE |
|----------|---------|-----------|-----------|
| ITE 4416 | 2N4416 | 2N4416/W | 2N4416/D |
| — | 2N4416A | 2N4416A/W | 2N4416A/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | MIN | MAX | UNIT | TEST CONDITIONS | | |
|---------------|--|---------------------------|------------|-----------------|---|---------------------|---|
| $V_{GS(f)}$ | Gate-Source Forward Voltage | | 1 | V | $I_G = 1\text{ mA}, V_{DS} = 0$ | | |
| I_{GSS} | Gate Reverse Current | | -0.1 | nA | $V_{GS} = -20\text{ V}, V_{DS} = 0$ | | |
| | | | -0.1 | μA | | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | 2N4416/ITE4416 2N4416A | -30 -35 | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ $V_{DS} = 15\text{ V}, I_D = 1\ \text{nA}$ | | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | 2N4416/ITE4416 2N4416A | -6 -6 | V | | | |
| I_{DSS} | Drain Current at Zero Gate Voltage | 5 | 15 | mA | $V_{DS} = 15\text{ V}, V_{GS} = 0$ | | |
| g_{fs} | Common-Source Forward Transconductance | 4500 | 7500 | μmho | | | |
| g_{os} | Common-Source Output Conductance | | 50 | μmho | | | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 0.8 | pF | | | |
| C_{iss} | Common-Source Input Capacitance | | 4 | pF | | | |
| C_{oss} | Common-Source Output Capacitance | | 2 | pF | | | |
| | | | | | | $f = 1\ \text{kHz}$ | |
| PARAMETER | | 100 MHz | | 400 MHz | | UNIT | TEST CONDITIONS |
| | | MIN | MAX | MIN | MAX | | |
| g_{iss} | Common-Source Input Conductance | | 100 | | 1000 | μmho | $V_{DS} = 15\text{ V}, V_{GS} = 0$ |
| b_{iss} | Common-Source Input Susceptance | | 2500 | | 10,000 | | |
| g_{oss} | Common-Source Output Conductance | | 75 | | 100 | | |
| b_{oss} | Common-Source Output Susceptance | | 1000 | | 4000 | | |
| g_{fs} | Common-Source Forward Transconductance | | | 4000 | | dB | $V_{DS} = 15\text{ V}, I_D = 5\text{ mA}$ $V_{DS} = 15\text{ V}, I_D = 5\text{ mA}, R_G = 1\ \text{k}\Omega$ |
| G_{ps} | Common-Source Power Gain | 18 | | 10 | | | |
| NF | Noise Figure | | 2 | | 4 | | |

1



2N4856-2N4861 2N4856-2N4858 JAN, JTX, JTXV* N-Channel JFET

1

FEATURES

- Low $r_{DS(on)}$
- $I_{D(off)} < 250$ pA
- Switches $\pm 10V$ Signals with $\pm 15V$ Supplies (2N4858, 2N4861)

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ C$ unless otherwise noted)

Gate-Source or Gate-Drain Voltage

2N4856-58 -40V

2N4859-61 -30V

Gate Current 50 mA

Storage Temperature $-65^\circ C$ to $+200^\circ C$

Operating Temperature Range $-55^\circ C$ to $+150^\circ C$

Led Temperature (Soldering, 10 sec.) $+300^\circ C$

Power Dissipation 1.8W

Derate above $25^\circ C$ 10 mW/ $^\circ C$

PIN CONFIGURATION

TO-18

CHIP TOPOGRAPHY

5001

ORDERING INFORMATION*

| TO-18 | WAFER | DICE |
|----------|----------|----------|
| 2N4856 † | 2N4856/W | 2N4856/D |
| 2N4857 † | 2N4857/W | 2N4857/D |
| 2N4858 † | 2N4858/W | 2N4858/D |
| 2N4859 | 2N4859/W | 2N4859/D |
| 2N4860 | 2N4860/W | 2N4860/D |
| 2N4861 | 2N4861/W | 2N4861/D |

† add JAN, JTX, JTXV, to basic part number to specify these devices.

ELECTRICAL CHARACTERISTICS

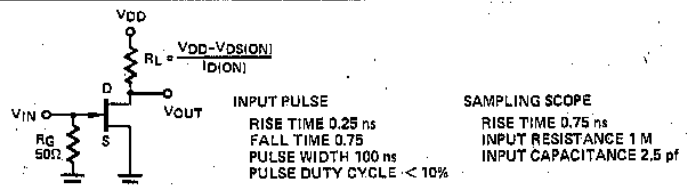
($25^\circ C$ unless otherwise noted)

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | | | 2N4856,59 | | 2N4857,60 | | 2N4858,61 | | UNIT | TEST CONDITIONS |
|----------------------|--|---------------------|-----------|--------------|-----------|--------------|-----------|-------------|-----------|--|
| | | | MIN | MAX | MIN | MAX | MIN | MAX | | |
| BV _{GSS} | Gate-Source Breakdown Voltage | 2N4856-58 | -40 | | -40 | | -40 | | V | $I_G = -1 \mu A, V_{DS} = 0$ |
| | | 2N4859-61 | -30 | | -30 | | -30 | | | |
| GSSR | Gate-Reverse Current | $T_A = 150^\circ C$ | | -250 | | -250 | | -250 | pA | $V_{GS} = -20 V, V_{DS} = 0$ $V_{GS} = -15 V, V_{DS} = 0$ |
| | | | | 250 | | 250 | | 250 | | |
| I _{D(off)} | Drain Cutoff Current | $T_A = 150^\circ C$ | | 500 | | 500 | | 500 | nA | $V_{DS} = 15 V, V_{GS} = -10 V$ |
| | | | | 500 | | 500 | | 500 | | |
| V _{GS(off)} | Gate-Source Cutoff Voltage | | -4 | -10 | -2 | -6 | -0.8 | -4 | V | $V_{DS} = 15 V, I_D = 0.5 mA$ |
| I _{DSS} | Saturation Drain Current (Note 1) | | 50 | | 20 | 100 | 8 | 80 | mA | $V_{DS} = 15 V, V_{GS} = 0$ |
| V _{DS(on)} | Drain-Source ON Voltage | | | 0.75 (20) | | 0.50 (10) | | 0.50 (5) | V (mA) | $V_{GS} = 0, I_D = ()$ |
| r _{ds(on)} | Drain-Source ON Resistance | | | 25 | | 40 | | 60 | ohm | $V_{GS} = 0, I_D = 0$ $f = 1 kHz$ |
| C _{iss} | Common-Source Input Capacitance | | | 18 | | 18 | | 18 | pF | $V_{DS} = 0, V_{GS} = -10 V$ $f = 1 MHz$ |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | | 8 | | 8 | | 8 | | |
| t _d | Turn-ON Delay Time | | | 6 | | 6 | | 10 | ns | $V_{DD} = 10 V, R_L = 464 \Omega$ (2N4856,59) 953Ω (2N4857,60) 1910Ω (2N4858,61) $V_{GS(on)} = 0$ $V_{GS(off)} = -10V, I_D = 20 mA$ (2N4856, 9) $V_{GS(off)} = -6V, I_D = 10 mA$ (2N4857, 60) $V_{GS(off)} = -4V, I_D = 5 mA$ (2N4858, 61) |
| t _r | Rise Time | | | 3 | | 4 | | 10 | | |
| t _{off} | Turn-OFF Time | | | 25 | | 50 | | 100 | | |
| | | | | | | | | | | |

NOTE:

1. Pulse test required, pulsewidth = 100 μs , duty cycle $\leq 10\%$.



FEATURES

- Low Noise Voltage
- Low Leakage
- High Gain

ABSOLUTE MAXIMUM RATINGS

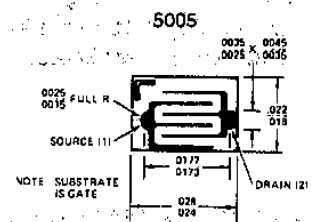
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Source or Gate-Drain Voltage | -40V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

PIN CONFIGURATION



CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|---------|-----------|-----------|
| 2N4867 | 2N4867/W | 2N4867/D |
| 2N4867A | 2N4867A/W | 2N4867A/D |
| 2N4868 | 2N4868/W | 2N4868/D |
| 2N4868A | 2N4868A/W | 2N4868A/D |
| 2N4869 | 2N4869/W | 2N4869/D |
| 2N4869A | 2N4869A/W | 2N4869A/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | 2N4867 2N4867A | | 2N4868 2N4868A | | 2N4869 2N4869A | | UNIT | TEST CONDITIONS | | |
|---------------|---|-------------------|-------|-------------------|-------|-------------------|-------|--------------------|--|------------------------------------|--------------------|
| | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | | | | |
| I_{GSSR} | Gate Reverse Current | | -0.25 | | -0.25 | | -0.25 | nA | $V_{GS} = -30\text{ V}, V_{DS} = 0$ | | |
| | | | -0.25 | | -0.25 | | -0.25 | μA | | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -40 | | -40 | | -40 | | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ | | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | -0.7 | -2 | -1 | -3 | -1.8 | -5 | | $V_{DS} = 20\text{ V}, I_D = 1\ \mu\text{A}$ | | |
| I_{DSS} | Saturation Drain Current (Note 1) | 0.4 | 1.2 | 1 | 3 | 2.5 | 7.5 | mA | $V_{DS} = 20\text{ V}, V_{GS} = 0$ | | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 700 | 2000 | 1000 | 3000 | 1300 | 4000 | μmho | $V_{DS} = 20\text{ V}, V_{GS} = 0$ | | |
| g_{os} | Common-Source Output Conductance | | 1.5 | | 4 | | 10 | | | $f = 1\text{ kHz}$ | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 5 | | 5 | | 5 | pF | | $f = 1\text{ MHz}$ | |
| C_{iss} | Common-Source Input Capacitance | | 25 | | 25 | | 25 | | | | |
| \bar{E}_n | Short Circuit Equivalent Input Noise Voltage | A devices | | 20 | | 20 | | 20 | nV | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | $f = 10\text{ Hz}$ |
| | | | | 10 | | 10 | | 10 | | | $f = 1\text{ kHz}$ |
| | | | | 10 | | 10 | | 10 | | | $f = 10\text{ Hz}$ |
| | | | | 5 | | 5 | | 5 | | | $f = 1\text{ kHz}$ |
| | | | 5 | | 5 | | 5 | $\sqrt{\text{Hz}}$ | | | |
| NF | Spot Noise Figure | | 1 | | 1 | | 1 | dB | $V_{DS} = 10\text{ V}, V_{GS} = 0$ $R_{gen} = 20\text{ K}, (2N4867\text{ Series})$ $R_{gen} = 5\text{ K}, (2N4867A\text{ Series})$ | $f = 1\text{ kHz}$ | |

NOTE: 1. Pulse test duration = 2 ms.



2N4044, 2N4045, 2N4100, 2N4878, 2N4879, 2N4880 Dielectrically Isolated Dual NPN Transistor

1

FEATURES

- High Gain at Low Current
- Low Output Capacitance
- Good h_{FE} Match
- Tight V_{BE} Tracking
- Dielectrically Isolated Matched Pairs for Differential Amplifiers.

ABSOLUTE MAXIMUM RATINGS

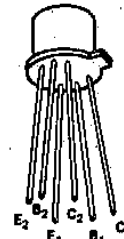
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--|-----------------|
| Collector-Base or Collector-Emitter Voltage (Note 1) | 60V |
| 2N4044, 2N4878 | 55V |
| 2N4100, 2N4879 | 45V |
| 2N4045, 2N4880 | 100V |
| Collector-Collector Voltage | 7V |
| Emitter-Base Voltage (Note 2) | 10 mA |
| Collector Current (Note 1) | -65°C to +200°C |
| Storage Temperature Range | -55°C to +150°C |
| Operating Temperature Range | +300°C |
| Lead Temperature (Soldering, 10 sec.) | |

| | TO-71 | | TO-78 | |
|---------------------------------|----------|------------|----------|------------|
| | ONE SIDE | BOTH SIDES | ONE SIDE | BOTH SIDES |
| Power Dissipation .. | 300 mW | 500 mW | 400 mW | 750 mW |
| Derate above 25°C (mW/°C) | 1.7 | 2.9 | 2.3 | 4.3 |

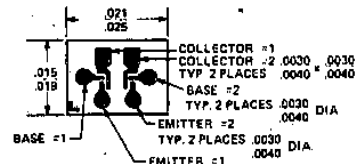
PIN CONFIGURATION

TO-71
TO-78



CHIP TOPOGRAPHY

4000



ORDERING INFORMATION*

| TO-78 | TO-71 | WAFER | DICE |
|--------|--------|----------|----------|
| 2N4044 | 2N4878 | 2N4044/W | 2N4044/D |
| 2N4045 | 2N4879 | 2N4045/W | 2N4045/D |
| 2N4100 | 2N4880 | 2N4100/W | 2N4100/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N4044 2N4878 | | 2N4100 2N4879 | | 2N4045 2N4880 | | UNIT | TEST CONDITIONS |
|---------------|------------------------------|-----|------------------|------|------------------|------|---------------|--|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| h_{FE} | DC Current Gain | | 200 | 600 | 150 | 600 | V | $I_C = 10 \mu\text{A}, V_{CE} = 5\text{V}$ |
| | | | 225 | | 175 | | | $I_C = 1.0\text{mA}, V_{CE} = 5\text{V}$ |
| | $T_A = -55^\circ\text{C}$ | | 75 | | 50 | | | $I_C = 10 \mu\text{A}, V_{CE} = 5\text{V}$ |
| $V_{BE(on)}$ | Emitter-Base On Voltage | | | 0.7 | | 0.7 | | $I_C = 1.0\text{mA}, I_B = 0.1\text{mA}$ |
| $V_{CE(sat)}$ | Collector Saturation Voltage | | | 0.35 | | 0.35 | | $I_E = 0, V_{CB} = 45\text{V}, 30\text{V}^*$ |
| I_{CBO} | Collector Cutoff Current | | | 0.1 | | 0.1* | nA | $I_C = 0, V_{EB} = 5\text{V}$ |
| | $T_A = 150^\circ\text{C}$ | | | 0.1 | | 0.1* | μA | |
| I_{EBO} | Emitter Cutoff Current | | | 0.1 | | 0.1 | nA | $I_E = 0, V_{CB} = 5\text{V}$ |
| C_{obo} | Output Capacitance | | | 0.8 | | 0.8 | pF | |

1

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N4044 2N4878 | | 2N4100 2N4879 | | 2N4045 2N4880 | | UNIT | TEST CONDITIONS |
|------------------------|------------------|-----|------------------|-----|------------------|-----|------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| C _{te} | 1 | | 1 | | 1 | | pF | I _C = 0, V _{EB} = 0.5V |
| C _{C1, C2} | 0.8 | | 0.8 | | 0.8 | | pF | V _{CC} = 0 |
| I _{C1, C2} | 5 | | 5 | | 5 | | pA | V _{CC} = ±100V |
| V _{CEO(sust)} | 60 | | 55 | | 45 | | V | I _C = 1mA, I _B = 0 |
| f _t | 200 | | 150 | | 150 | | MHz | I _C = 1mA, V _{CE} = 10V |
| f _t | 20 | | 15 | | 15 | | MHz | I _C = 10μA, V _{CE} = 10V |
| NF | 2 | | 3 | | 3 | | dB | I _C = 10μA, V _{CE} = 5V, f = 1kHz R _G = 10 kohms, BW = 200 Hz |
| BV _{CBO} | 60 | | 55 | | 45 | | V | I _C = 10μA, I _E = 0 |
| BV _{EBO} | 7 | | 7 | | 7 | | V | I _E = 10μA, I _C = 0 |

MATCHING CHARACTERISTICS (25°C unless otherwise noted)

| | | | | | | | | | |
|---|---|-----|---|------|---|-----|---|-------|---|
| h _{FE1} /h _{FE2} | DC Current Gain Ratio (Note 3) | 0.9 | 1 | 0.85 | 1 | 0.8 | 1 | | I _C = 10μA to 1mA, V _{CE} = 5V |
| V _{BE1} -V _{BE2} | Base Emitter Voltage Differential | 3 | | 5 | | 5 | | mV | I _C = 10μA, V _{CE} = 5V |
| I _{B1} -I _{B2} | Base Current Differential | 5 | | 10 | | 25 | | nA | I _C = 10μA, V _{CE} = 5V |
| (ΔV _{BE1} -V _{BE2})/ΔT | Base Emitter Voltage Differential Change with Temperature | 3 | | 5 | | 10 | | μV/°C | I _C = 10μA, V _{CE} = 5V T _A = -55°C to +125°C |
| (ΔI _{B1} -I _{B2})/ΔT | Base Current Differential Change with Temperature | 0.3 | | 0.5 | | 1 | | nA/°C | |

SMALL SIGNAL CHARACTERISTICS

| PARAMETER | TYPICAL VALUE | UNIT | TEST CONDITIONS |
|-----------------|---------------|--------------------|--|
| h _{ib} | 28 | ohms | I _C = 1mA, V _{CB} = 5V |
| h _{rb} | 43 | x 10 ⁻³ | |
| h _{fe} | 250 | | |
| h _{ob} | 60 | μmhos | I _C = 1mA, V _{CE} = 5V |
| h _{ie} | 9.6 | k ohms | |
| h _{re} | 42 | x 10 ⁻³ | |
| h _{oe} | 12 | μmhos | |

NOTES:

1. Per transistor.
2. The reverse base-emitter voltage must never exceed 7.0 volts and the reverse base-emitter current must never exceed 10 μamps.
3. The lowest of two h_{FE} readings is taken as h_{FE1} for purposes of this ratio.

1

FEATURES

- Low Insertion Loss
- No Offset or Error Voltages Generated by Closed Switch
- Purely Resistive

APPLICATIONS

- Analog Switches
- Commutators
- Choppers

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Gate-Drain or Gate-Source Voltage 30V
 Gate Current 50 mA
 Storage Temperature Range -65°C to $+200^\circ\text{C}$
 Operating Temperature Range ... -55°C to $+150^\circ\text{C}$
 Lead Temperature (Soldering, 10 sec.) ... $+300^\circ\text{C}$
 Power Dissipation 500 mW
 Derate above 25°C 3 mW/ $^\circ\text{C}$

PIN CONFIGURATION

TO-18

D
G
S

CHIP TOPOGRAPHY

5508

NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

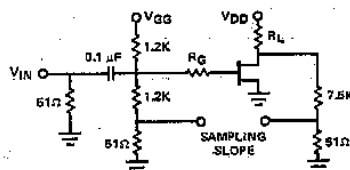
| TO-18 | WAFER | DICE |
|--------|----------|----------|
| 2N5018 | 2N5018/W | 2N5018/D |
| 2N5019 | 2N5019/W | 2N5019/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise noted)

| PARAMETER | | 2N5018 | | 2N5019 | | Unit | Test Conditions |
|----------------------|--|--------|------|--------|------|---------------|--|
| | | Min | Max | Min | Max | | |
| BV _{GSS} | Gate-Source Breakdown Voltage | 30 | | 30 | | V | $I_G = 1 \mu\text{A}, V_{DS} = 0$ |
| I _{GSSR} | Gate Reverse Current | | 2 | | 2 | nA | $V_{GS} = 15 \text{ V}, V_{DS} = 0$ |
| I _{D(off)} | Drain Cutoff Current | | -10 | | -10 | μA | $V_{DS} = -15 \text{ V}, V_{GS} = 12 \text{ V (2N5018)}$ $V_{GS} = 7 \text{ V (2N5019)}$ |
| I _{DGO} | Drain Reverse Current | | -2 | | -2 | nA | $V_{DG} = -15 \text{ V}, I_S = 0$ |
| | | | -3 | | -3 | μA | $T_A = 150^\circ\text{C}$ |
| V _{GS(off)} | Gate-Source Cutoff Voltage | | 10 | | 5 | V | $V_{DS} = -15 \text{ V}, I_D = -1 \mu\text{A}$ |
| I _{DSS} | Saturation Drain Current | -10 | | -5 | | mA | $V_{DS} = -20 \text{ V}, V_{GS} = 0$ |
| V _{DS(on)} | Drain-Source ON Voltage | | -0.5 | | -0.5 | V | $V_{GS} = 0, I_D = -6 \text{ mA (2N5018)}$ $I_D = -3 \text{ mA (2N5019)}$ |
| r _{DS(on)} | Static Drain-Source ON Resistance | | 75 | | 150 | Ω | $I_D = -1 \text{ mA}, V_{GS} = 0$ |
| r _{ds(on)} | Drain-Source ON Resistance | | 75 | | 150 | | $I_D = 0, V_{GS} = 0$ f = 1 kHz |
| C _{iss} | Common-Source Input Capacitance | | 45 | | 45 | pF | $V_{DS} = -15 \text{ V}, V_{GS} = 0$ f = 1 MHz |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | 10 | | 10 | | $V_{DS} = 0, V_{GS} = 12 \text{ V (2N5018)}$ $V_{GS} = 7 \text{ V (2N5019)}$ |
| t _{d(on)} | Turn-ON Delay Time | | 15 | | 15 | | $V_{DD} = -6 \text{ V}, V_{GS(on)} = 0$ |
| t _r | Rise Time | | 20 | | 75 | | |
| t _{d(off)} | Turn-Off Delay Time | | 15 | | 25 | | |
| t _f | Fall Time | | 50 | | 100 | ns | $V_{GS(off)} \quad I_{D(on)} \quad R_L$ 2N5018 12 V -6 mA 910 Ω 2N5019 7V -3 mA 1.8K Ω |

NOTE 1: Due to symmetrical geometry these units may be operated with source and drain leads interchanged.



INPUT PULSE
 RISE TIME < 1 ns
 FALL TIME < 1 ns
 PULSE WIDTH 100 ns
 REPLETION RATE 1 MHz

SAMPLING SCOPE
 RISE TIME 0.4 ns
 INPUT RESISTANCE 10 M Ω
 INPUT CAPACITANCE 1.5 pF

FEATURES

- Low ON Resistance
- $I_{D(off)} < 500 \text{ pA}$
- Switches directly from T²L Logic

GENERAL DESCRIPTION

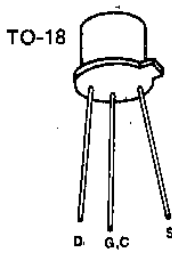
Ideal for inverting switching or "Virtual Gnd" switching into inverting input of Op. Amp. No driver is required and $\pm 10 \text{ VAC}$ signals can be handled using only +5V logic (T²L or CMOS).

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

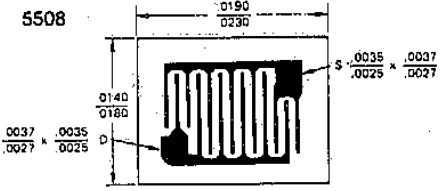
| | |
|---------------------------------------|-----------------|
| Gate-Drain or Gate-Source Voltage | 30V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 500 mW |
| Derate above 25°C | 3 mW/°C |

PIN CONFIGURATION



TO-18
D, G.C, S

CHIP TOPOGRAPHY



5508
0190
0230
0140
0180
0037 x .0027
0035 x .0025
S .0035 x .0037
.0025 x .0027

NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO18 † | WAFER | DICE |
|--------|----------|----------|
| 2N5114 | 2N5114/W | 2N5114/D |
| 2N5115 | 2N5115/W | 2N5115/D |
| 2N5116 | 2N5116/W | 2N5116/D |

†add JAN, JTX to basic part number to specify these devices

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N5114 | | 2N5115 | | 2N5116 | | UNIT | TEST CONDITIONS | | |
|--------------|---|-----|--------|------|--------|------|---------------|---|---|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | | | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | | 30 | | 30 | | V | $I_G = 1 \mu\text{A}, V_{DS} = 0$ | | |
| I_{GSSR} | Gate Reverse Current | | | 500 | | 500 | pA | $V_{GS} = 20 \text{ V}, V_{DS} = 0$ | | |
| | $T_A = 150^\circ\text{C}$ | | | 1.0 | | 1.0 | μA | | | |
| $I_{D(off)}$ | Drain Cutoff Current | | | -500 | | -500 | pA | $V_{DS} = -15 \text{ V}, V_{GS} = 2N5115 = 7 \text{ V}$ $2N5116 = 5 \text{ V}$ | | |
| | $T_A = 150^\circ\text{C}$ | | | -1.0 | | -1.0 | μA | | | |
| V_p | Gate-Source Pinch-Off Voltage | | 5 | 10 | 3 | 6 | V | $V_{DS} = -15 \text{ V}, I_D = -1 \text{ nA}$ | | |
| I_{DSS} | Drain Current at Zero Gate Voltage (Note 1) | | -30 | -90 | -15 | -60 | -5 | -25 | mA | $V_{GS} = 0, V_{DS} = 2N5114 = -18 \text{ V}$ $2N5115 = -15 \text{ V}$ $2N5116 = -15 \text{ V}$ |
| V_{GSSF} | Forward Gate-Source Voltage | | | -1 | | -1 | -1 | V | $I_G = -1 \text{ mA}, V_{DS} = 0$ | |
| $V_{DS(on)}$ | Drain-Source ON Voltage | | | -1.3 | | -0.8 | -0.6 | V | $V_{GS} = 0, I_D = 2N5114 = -15 \text{ mA}$ $2N5115 = -7 \text{ mA}$ $2N5116 = -3 \text{ mA}$ | |
| $r_{DS(on)}$ | Static Drain-Source ON Resistance | | | 75 | | 100 | 150 | Ω | $V_{GS} = 0, I_D = -1 \text{ mA}$ | |
| $r_{ds(on)}$ | Small-Signal Drain-Source ON Resistance | | | 75 | | 100 | 150 | Ω | $V_{GS} = 0, I_D = 0, f = 1 \text{ kHz}$ | |
| | Jan TX only | | | 75 | | 100 | 175 | | | |
| C_{iss} | Common-Source Input Capacitance | | | 25 | | 25 | 25 | pF | $V_{DS} = -15 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | |
| | Jan TX only | | | 25 | | 25 | 27 | | | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | | 7 | | 7 | 7 | pF | $V_{DS} = 0, V_{GS} = 2N5114 = 12 \text{ V}$ $2N5115 = 7 \text{ V}$ $2N5116 = 5 \text{ V}$ $f = 1 \text{ MHz}$ | |

Note 1. Pulse test; duration = 2 ms.

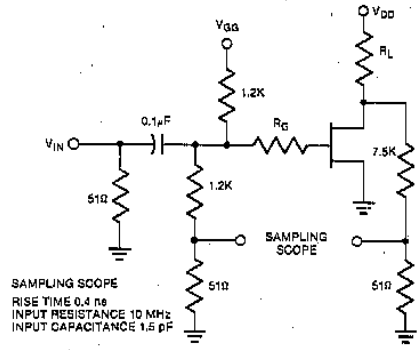
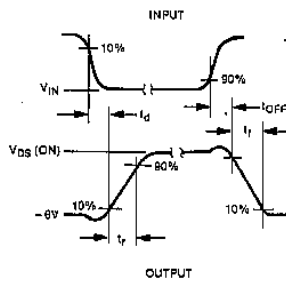
1

SWITCHING CHARACTERISTICS (25°C unless otherwise noted)

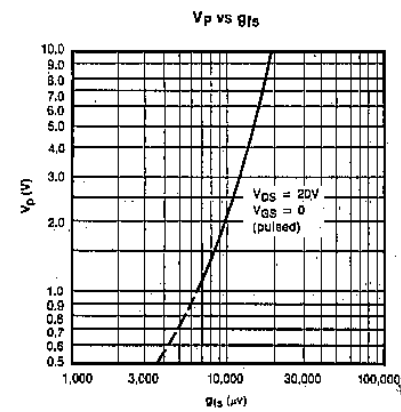
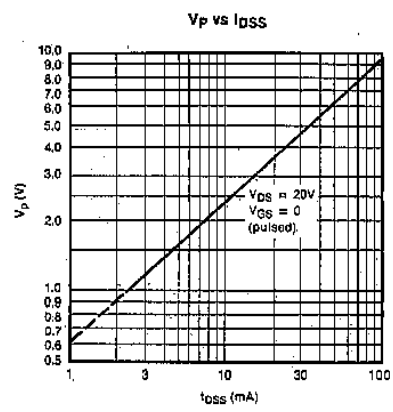
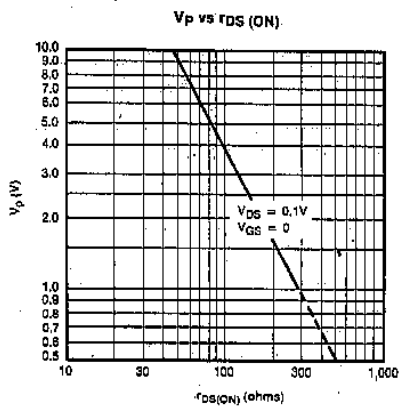
| PARAMETER | 2N5114 | 2N5115 | 2N5116 | JAN TX 2N5114 | JAN TX 2N55115 | JAN TX 2N5116 | UNIT |
|-------------------------------|--------|--------|--------|------------------------|-------------------|------------------|------|
| t_d Turn-ON Delay Time | MAX 6 | MAX 10 | MAX 12 | MAX 6 | MAX 10 | MAX 25 | ns |
| t_r Rise Time | 10 | 20 | 30 | 10 | 20 | 35 | |
| t_{off} Turn-OFF Delay Time | 6 | 8 | 19 | 6 | 8 | 29 | |
| t_f Fall Time | 15 | 30 | 50 | (not JAN TX specified) | | | |

1

| TEST CONDITIONS | | | |
|-----------------|--------|--------|--------|
| | 2N5114 | 2N5115 | 2N5116 |
| V_{DD} | -10V | -6V | -6V |
| V_{GG} | 20V | 12V | 8V |
| R_L | 430Ω | 910Ω | 2 KΩ |
| R_G | 100Ω | 220Ω | 390Ω |
| $I_{D(ON)}$ | -15mA | -7mA | -3mA |
| V_{IN} | -12V | -7V | -5V |



SAMPLING SCOPE
RISE TIME 0.4 ns
INPUT RESISTANCE 10 MΩ
INPUT CAPACITANCE 1.5 pF



2N5117-2N5119 Dielectrically Isolated Dual PNP Transistor

FEATURES

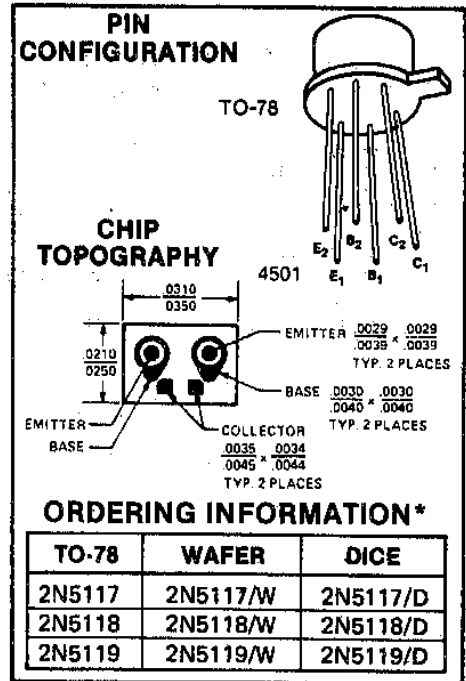
- High Gain at Low Current
- Low Output Capacitance
- Good h_{FE} Match
- Tight V_{BE} Tracking
- Dielectrically Isolated Matched Pairs for Differential Amplifiers.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Collector-Base or Collector-Emitter Voltage (Note 1) 45V
 Emitter-Base Voltage (Notes 1 and 2) 7V
 Collector-Collector Voltage 100V
 Collector Current (Note 1) 10 mA
 Storage Temperature Range -65°C to $+200^\circ\text{C}$
 Operating Temperature Range -55°C to $+150^\circ\text{C}$
 Lead Temperature (Soldering, 10 sec.) $+300^\circ\text{C}$

| | | |
|---------------------------------|--------------------------|--------------------------|
| | ONE SIDE | BOTH SIDES |
| Power Dissipation | 400 mW | 750 mW |
| Derate above 25°C | 2.3 mW/ $^\circ\text{C}$ | 4.3 mW/ $^\circ\text{C}$ |



1

*When ordering wafer/dice refer to Appendix B-23

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | DESCRIPTION | 2N5117 | | 2N5118 | | 2N5119 | | UNIT | TEST CONDITIONS |
|-----------------|--------------------------------------|---------------------------|-----|--------|-----|--------|-----|------|--|
| | | MIN | MAX | MIN | MAX | MIN | MAX | | |
| h_{FE} | DC Current Gain | | 100 | 300 | | 50 | | | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| | | | 100 | | | 50 | | | $I_C = 500 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| | | $T_A = -55^\circ\text{C}$ | 30 | | | 20 | | | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| I_{CBO} | Collector Cutoff Current | | | 0.1 | | 0.1 | | nA | $I_E = 0, V_{CB} = 30 \text{ V}$ |
| | | $T_A = 150^\circ\text{C}$ | | | 0.1 | | 0.1 | | μA |
| I_{EBO} | Emitter Cutoff Current | | | 0.1 | | 0.1 | | nA | $I_C = 0, V_{EB} = 5.0 \text{ V}$ |
| I_{C1-C2} | Collector-Collector Leakage | | | 5.0 | | 5.0 | | pA | $V_{CC} = 100 \text{ V}$ |
| GBW | Current Gain Bandwidth Product | | 100 | | 100 | | | MHz | $I_C = 500 \mu\text{A}, V_{CE} = 10 \text{ V}$ |
| C_{ob} | Output Capacitance | | | 0.8 | | 0.8 | | pF | $I_E = 0, V_{CB} = 5.0 \text{ V}$ |
| C_{te} | Emitter Transition Capacitance | | | 1.0 | | 1.0 | | pF | $I_C = 0, V_{EB} = 0.5 \text{ V}$ |
| C_{C1-C2} | Collector-Collector Capacitance | | | 0.8 | | 0.8 | | pF | $V_{CC} = 0$ |
| $V_{CEO(sust)}$ | Collector-Emitter Sustaining Voltage | 45 | | 45 | | 45 | | V | $I_C = 1.0 \text{ mA}, I_E = 0$ |
| NF | Narrow Band Noise Figure | | | 4.0 | | 4.0 | | dB | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ $BW = 200 \text{ Hz}$ $f = 1 \text{ KHz}, R_G = 10 \text{ K}\Omega$ |
| BV_{CBO} | Collector Base Breakdown Voltage | 45 | | 45 | | 45 | | V | $I_C = 10 \mu\text{A}, I_E = 0$ |
| BV_{EBO} | Emitter Base Breakdown Voltage | 7.0 | | 7.0 | | 7.0 | | V | $I_E = 10 \mu\text{A}, I_C = 0$ |

MATCHING CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | DESCRIPTION | 2N5117 | | 2N5118 | | 2N5119 | | UNIT | TEST CONDITIONS |
|--------------------------------------|---|--------|------|--------|-----|--------|-----|------------------------------|---|
| | | MIN | MAX | MIN | MAX | MIN | MAX | | |
| h_{FE1}/h_{FE2} | DC Current Gain Ratio (Note 3) | 0.9 | 1.0 | 0.85 | 1.0 | 0.8 | 1.0 | | $I_C = 10 \mu\text{A}$ to $500 \mu\text{A}, V_{CE} = 5 \text{ V}$ $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| $V_{BE1} - V_{BE2}$ | Base-Emitter Voltage Differential | | 3.0 | | 5.0 | | 5.0 | mV | $I_C = 10 \mu\text{A}$ to $500 \mu\text{A}, V_{CE} = 5 \text{ V}$ |
| $I_{B1} - I_{B2}$ | Base Current Differential | | 10.0 | | 15 | | 40 | nA | |
| $\Delta(V_{BE1} - V_{BE2})/\Delta T$ | Base Voltage Differential Change with Temperature | | 3.0 | | 5.0 | | 10 | $\mu\text{V}/^\circ\text{C}$ | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ |
| $\Delta(I_{B1} - I_{B2})/\Delta T$ | Base-Current Differential Change with Temperature | | 0.3 | | 0.5 | | 1.0 | $\text{nA}/^\circ\text{C}$ | $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ |

1. Per transistor.
 2. The reverse base-to-emitter voltage must never exceed 7.0 volts and the reverse base-to-emitter current must never exceed $10 \mu\text{A}$.
 3. Lower of two h_{FE} readings is defined as h_{FE1} .

2N5196-2N5199

Dual Monolithic N-Channel JFET

ABSOLUTE MAXIMUM RATINGS

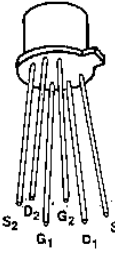
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|--|-------|--|
| Gate-Source or Gate-Drain Voltage (Note 1) | | -50V |
| Gate Current (Note 1) | | 50 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10-sec.) | | +300°C |
| Power Dissipation | | ONE SIDE 250 mW ... BOTH SIDE 500 mW |
| Derate above 25°C | | 2.6 mW/°C ... 4.3 mW/°C |

1

PIN CONFIGURATION

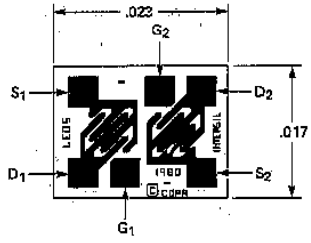
TO-18



S₂ D₂ G₂ S₁
G₁ D₁

CHIP TOPOGRAPHY

6037



ALL BOND PADS ARE 4 x 4 MIL.

ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|--------|----------|----------|
| 2N5196 | 2N5196/W | 2N5196/D |
| 2N5197 | 2N5197/W | 2N5197/D |
| 2N5198 | 2N5198/W | 2N5198/D |
| 2N5199 | 2N5199/W | 2N5199/D |

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | | MIN | MAX | UNIT | TEST CONDITIONS |
|----------------------|--|------|------|--|---|
| I _{GSSR} | Gate Reverse Current | | -25 | µA | V _{GS} = -30 V, V _{DS} = 0 |
| BV _{GSS} | Gate-Source Breakdown Voltage | -50 | | V | I _G = -1 µA, V _{DS} = 0 |
| V _{GS(off)} | Gate-Source Cutoff Voltage | -0.7 | -4 | V | V _{DS} = 20 V, I _D = 1 nA |
| V _{GS} | Gate-Source Voltage | -0.2 | -3.8 | V | |
| I _G | Gate Operating Current | | -15 | µA | V _{DS} = 20 V, I _D = 200 µA |
| I _{DSS} | Saturation Drain Current (Note 2) | 0.7 | 7 | mA | V _{DS} = 20 V, V _{GS} = 0 |
| g _{fs} | Common-Source Forward Transconductance | 1000 | 4000 | µmho | V _{DS} = 20 V, V _{GS} = 0 |
| g _{fs} | Common-Source Forward Transconductance | 700 | 1600 | µmho | V _{DS} = 20 V, I _D = 200 µA |
| g _{os} | Common-Source Output Conductance | | 50 | µmho | V _{DS} = 20 V, V _{GS} = 0 |
| g _{os} | Common-Source Output Conductance | | 4 | µmho | V _{DS} = 20 V, I _D = 200 µA |
| C _{iss} | Common-Source Input Capacitance | | 6 | pF | |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | 2 | pF | |
| NF | Spot Noise Figure | | 0.5 | dB | V _{DS} = 20 V, V _{GS} = 0 |
| e _n | Equivalent Input Noise Voltage | | 20 | $\frac{\mu\text{V}}{\sqrt{\text{Hz}}}$ | f = 1 kHz |

| PARAMETER | 2N5196 | | 2N5197 | | 2N5198 | | 2N5199 | | UNIT | TEST CONDITIONS |
|---|--------|-----|--------|-----|--------|-----|--------|-----|-------|--|
| | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | |
| I _{G1} - I _{G2} | | 5 | | 5 | | 5 | | 5 | nA | V _{DS} = 20 V, I _D = 200 µA, 125°C |
| I _{DSS1} / I _{DSS2} | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | | V _{DS} = 20 V, V _{GS} = 0 V |
| g _{fs1} / g _{fs2} | 0.97 | 1 | 0.97 | 1 | 0.95 | 1 | 0.95 | 1 | | f = 1 kHz |
| V _{GS1} - V _{GS2} | | 5 | | 5 | | 10 | | 15 | mV | V _{DS} = 20 V, I _D = 200 µA |
| $\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$ | | 5 | | 10 | | 20 | | 40 | µV/°C | |
| g _{os1} - g _{os2} | | 1 | | 1 | | 1 | | 1 | µmho | |

- NOTES: 1. Per transistor.
 2. Pulse test required, pulsewidth = 300 µs, duty cycle < 3%.
 3. Measured at endpoints T_A and T_B.

FEATURES

- $G_{ps} = 15$ dB Minimum (Common Gate) at 450 MHz
- Low Noise
- Low Capacitance

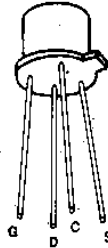
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Drain-Gate Voltage | -25V |
| Drain-Source Voltage | -25V |
| Continuous Forward Gate Current | -10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

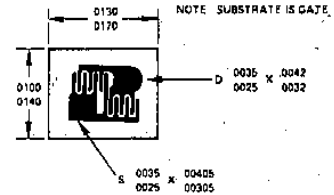
PIN CONFIGURATION

TO-72



CHIP TOPOGRAPHY

5011



ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N5397 | 2N5397/W | 2N5397/D |
| 2N5398 | 2N5398/W | 2N5398/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | 2N5397 | | 2N5398 | | UNIT | TEST CONDITIONS | |
|---------------|---|--------|--------|--------|--------|---|---|-------------|
| | | MIN | MAX | MIN | MAX | | | |
| I_{GSSR} | Gate Reverse Current | | -0.1 | | -0.1 | nA | $V_{GS} = -15\text{ V}, V_{DS} = 0$ | 150°C |
| | | | -0.1 | | -0.1 | μA | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -25 | | -25 | | V | $V_{DS} = 0, I_G = -1\ \mu\text{A}$ | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | -1.0 | -6.0 | -1.0 | -6.0 | | $V_{DS} = 10\text{ V}, I_D = 1\ \text{nA}$ | |
| I_{DSS} | Saturation Drain Current (Note 1) | 10 | 30 | 5 | 40 | mA | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | |
| $V_{GS(f)}$ | Gate-Source Forward Voltage | | 1 | | 1 | V | $V_{DS} = 0, I_G = 1\ \text{mA}$ | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 6000 | 10,000 | | | μmho | $V_{DS} = 10\text{ V}, I_D = 10\ \text{mA}$ | f = 1 kHz |
| | | | | 5500 | 10,000 | | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | |
| g_{oss} | Common-Source Output Conductance | | 200 | | | $V_{DS} = 10\text{ V}, I_D = 10\ \text{mA}$ | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | |
| | | | | | 400 | $V_{DS} = 10\text{ V}, I_D = 10\ \text{mA}$ | | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 1.2 | | | pF | $V_{DS} = 10\text{ V}, I_D = 10\ \text{mA}$ | f = 1 MHz |
| | | | | | 1.3 | | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | |
| C_{iss} | Common-Source Input Capacitance | | 5.0 | | | $V_{DG} = 10\text{ V}, I_D = 10\ \text{mA}$ | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | |
| | | | | | 5.5 | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | | |
| g_{iss} | Common-Source Input Conductance | | 2000 | | | μmho | $V_{DG} = 10\text{ V}, I_D = 10\ \text{mA}$ | f = 450 MHz |
| | | | | | 3000 | | $V_{DG} = 10\text{ V}, V_{GS} = 0$ | |
| g_{oss} | Common-Source Output Conductance | | 400 | | | $V_{DS} = 10\text{ V}, I_D = 10\ \text{mA}$ | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | |
| | | | | | 500 | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 5500 | 9000 | | | $V_{DG} = 10\text{ V}, I_D = 10\ \text{mA}$ | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | |
| | | | | 5000 | 10,000 | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | | |
| G_{ps} | Common-Source Power Gain (neutralized) | 15 | | | | dB | $V_{DG} = 10\text{ V}, I_D = 10\ \text{mA}$ | |
| NF | Common-Source, Spot Noise Figure (neutralized) | | 3.5 | | | | | |

Note 1: Pulse test duration = 2ms

2N5432-2N5434 N-Channel JFET

FEATURES

- Low $r_{ds(on)}$
- Excellent Switching
- Low Cutoff Current

1

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|---|
| Gate-Source Voltage | -25V |
| Gate-Drain Voltage | -25V |
| Gate Current | 100mA |
| Drain Current | 400 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 300 mW |
| Derate above 25°C | 2.3 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION

TO-52

CHIP TOPOGRAPHY

5018

NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

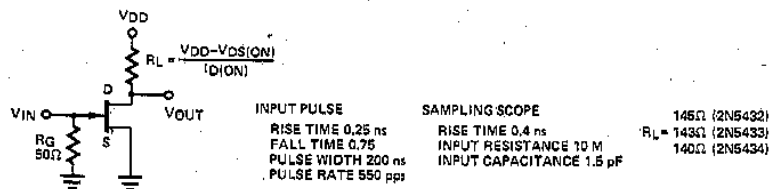
| TO-52 | WAFER | DICE |
|--------|----------|----------|
| 2N5432 | 2N5432/W | 2N5432/D |
| 2N5433 | 2N5433/W | 2N5433/D |
| 2N5434 | 2N5434/W | 2N5434/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N5432 | | 2N5433 | | 2N5434 | | UNIT | TEST CONDITIONS |
|---------------|--|-----|---------------------------|------|--------|------|------|--|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| I_{GSSR} | Gate Reverse Current | | $T_A = 150^\circ\text{C}$ | | | | pA | $V_{GS} = -15\text{ V}, V_{DS} = 0$ |
| | | | -200 | -200 | -200 | -200 | nA | |
| BV_{GSS} | Gate Source Breakdown Voltage | | -25 | -25 | -25 | -25 | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ |
| $I_{D(off)}$ | Drain Cutoff Current | | $T_A = 150^\circ\text{C}$ | | | | pA | $V_{DS} = 5\text{ V}, V_{GS} = -10\text{ V}$ |
| | | | 200 | 200 | 200 | 200 | nA | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | | -4 | -10 | -3 | -9 | V | $V_{DS} = 5\text{ V}, I_D = 3\text{ nA}$ |
| I_{DSS} | Saturation Drain Current (Note 1) | | 150 | 100 | 30 | | mA | $V_{DS} = 15\text{ V}, V_{GS} = 0$ |
| $r_{DS(on)}$ | Static Drain-Source ON Resistance | | 2 | 5 | 7 | 10 | ohm | $V_{GS} = 0, I_D = 10\text{ mA}$ |
| $V_{DS(on)}$ | Drain-Source ON Voltage | | | 50 | 70 | 100 | mV | |
| $r_{ds(on)}$ | Drain-Source ON Resistance | | | 5 | 7 | 10 | ohm | $V_{GS} = 0, I_D = 0$ $f = 1\text{ kHz}$ |
| C_{iss} | Common-Source Input Capacitance | | | 30 | 30 | 30 | pF | $V_{DS} = 0, V_{GS} = -10\text{ V}$ $f = 1\text{ MHz}$ |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | | 15 | 15 | 15 | | |
| t_d | Turn-ON Delay Time | | | 4 | 4 | 4 | ns | $V_{DD} = 1.5\text{ V},$ $V_{GS(on)} = 0,$ $V_{GS(off)} = -12\text{ V},$ $I_{D(on)} = 10\text{ mA}$ |
| t_r | Rise Time | | | 1 | 1 | 1 | | |
| t_{off} | Turn-OFF Delay Time | | | 6 | 6 | 6 | | |
| t_f | Fall Time | | | 30 | 30 | 30 | | |

NOTE: 1. Pulse test required, pulsewidth 300 μs , duty cycle $\leq 3\%$.





2N5452-2N5454 Dual Monolithic N-Channel JFET

FEATURES

- Low Offset Voltage
- Low Drift
- Low Capacitance
- Low Output Conductance

GENERAL DESCRIPTION

Matched FET pairs for differential amplifiers. This family of general purpose FETs is characterized for low and medium frequency differential amplifier applications requiring low drift and low offset voltage.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Gate-Source or Gate Drain

Voltage (Note 1) -50V

Gate Current (Note 1) 50 mA

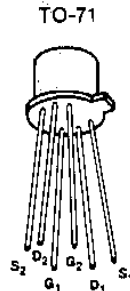
Storage Temperature Range -65°C to $+200^\circ\text{C}$

Operating Temperature Range -55°C to $+150^\circ\text{C}$

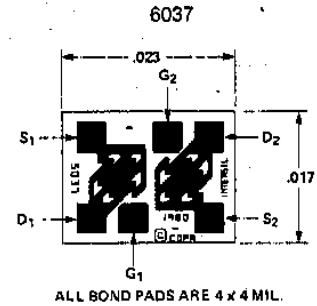
Lead Temperature (Soldering, 10 sec.) $+300^\circ\text{C}$

| | | |
|---------------------------------|--------------------------|--------------------------|
| | ONE SIDE | BOTH SIDES |
| Power Dissipation | 250 mW | 500 mW |
| Derate above 25°C | 2.9 mW/ $^\circ\text{C}$ | 4.3 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION



CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|--------|----------|----------|
| 2N5452 | 2N5452/W | 2N5452/D |
| 2N5453 | 2N5453/W | 2N5453/D |
| 2N5454 | 2N5454/W | 2N5454/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | 2N5452 | | 2N5453 | | 2N5454 | | UNITS | TEST CONDITIONS | |
|---------------------------|--|---------------------------|------|--------|------|--------|------|--------------------------------------|---|---|
| | | MIN | MAX | MIN | MAX | MIN | MAX | | | |
| I_{GSSR} | Gate Reverse Current | $T_A = 150^\circ\text{C}$ | | | | | | | | |
| | | | -100 | | -100 | | -100 | μA | $V_{GS} = -30\text{V}, V_{DS} = 0$ | |
| | | | -200 | | -200 | | -200 | nA | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -50 | | -50 | | -50 | | | $V_{DS} = 0, I_G = -1\mu\text{A}$ | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | -1 | -4.5 | -1 | -4.5 | -1 | -4.5 | V | $V_{DS} = 20\text{V}, I_D = 1\text{nA}$ | |
| V_{GS} | Gate-Source Voltage | -0.2 | -4.2 | -0.2 | -4.2 | -0.2 | -4.2 | | $V_{DS} = 20\text{V}, I_D = 50\mu\text{A}$ | |
| $V_{GS(f)}$ | Gate-Source Forward Voltage | | 2 | | 2 | | 2 | | $V_{DS} = 0, I_G = 1\text{mA}$ | |
| I_{DSS} | Saturation Drain Current | 0.5 | 5.0 | 0.5 | 5.0 | 0.5 | 5.0 | mA | $V_{DS} = 20\text{V}, V_{GS} = 0$ | |
| g_{fs} | Common-Source Forward Transconductance | 1000 | 3000 | 1000 | 3000 | 1000 | 3000 | μmho | $V_{DS} = 20\text{V}, V_{GS} = 0$ | f = 1 kHz |
| | | 1000 | | 1000 | | 1000 | | | | f = 100 MHz |
| g_{os} | Common-Source Output Conductance | | 3.0 | | 3.0 | | 3.0 | μmho | $V_{DS} = 20\text{V}, I_D = 200\mu\text{A}$ | f = 1 kHz |
| | | | 1.0 | | 1.0 | | 1.0 | | | |
| C_{iss} | Common-Source Input Capacitance | | 4.0 | | 4.0 | | 4.0 | pF | $V_{DS} = 20\text{V}, V_{GS} = 0$ | f = 1 MHz |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 1.2 | | 1.2 | | 1.2 | | | |
| C_{dgo} | Drain-Gate Capacitance | | 1.5 | | 1.5 | | 1.5 | | | |
| \bar{e}_n | Equivalent Short Circuit Input Noise Voltage | | 20 | | 20 | | 20 | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ | $V_{DS} = 20\text{V}, V_{GS} = 0$ | f = 1 kHz |
| NF | Common-Source Spot Noise Figure | | 0.5 | | 0.5 | | 0.5 | dB | $V_{DS} = 20\text{V}, V_{GS} = 0$ | f = 100 Hz |
| I_{DSS1}/I_{DSS2} | Drain Saturation Current Ratio | 0.95 | 1.0 | 0.95 | 1.0 | 0.95 | 1.0 | | $V_{DS} = 20\text{V}, V_{GS} = 0$ | |
| $ V_{GS1}-V_{GS2} $ | Differential Gate-Source Voltage | | 5.0 | | 10.0 | | 15.0 | mV | $V_{DS} = 20\text{V}, I_D = 200\mu\text{A}$ | $T = 25^\circ\text{C}$ to -55°C $T = 25^\circ\text{C}$ to $+125^\circ\text{C}$ |
| $\Delta V_{GS1}-V_{GS2} $ | Gate-Source Voltage Differential Change with Temperature | | 0.4 | | 0.8 | | 2.0 | | | |
| g_{fs1}/g_{fs2} | Transconductance Ratio | 0.97 | 1.0 | 0.97 | 1.0 | 0.95 | 1.0 | | | |
| $ g_{os1}-g_{os2} $ | Differential Output Conductance | | 0.25 | | 0.25 | | 0.25 | μmhos | | |
| | | | | | | | | | | |

NOTE: 1. Per transistor.

1



2N5457-2N5459 N-Channel JFET

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|---|
| Drain-Gate Voltage | 25V |
| Drain-Source Voltage | 25V |
| Continuous Forward Gate Current | 10 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/ $^\circ\text{C}$ |

1

PIN CONFIGURATION

TO-92

CHIP TOPOGRAPHY

5010*

*DICE WITH 4 MIL BONDING PADS AVAILABLE. CONSULT FACTORY FOR DETAILS.

ORDERING INFORMATION*

| TO-92 | WAFER | DICE |
|--------|----------|----------|
| 2N5457 | 2N5457/W | 2N5457/D |
| 2N5458 | 2N5458/W | 2N5458/D |
| 2N5459 | 2N5459/W | 2N5459/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|---------------|---------------------------------|---|----------------------|----------------------|----------------------|---|
| BV_{GSS} | Gate-Source Breakdown Voltage | -25 | -60 | | V | $I_G = -10 \mu\text{A}$, $V_{DS} = 0$ |
| I_{GSS} | Gate Reverse Current | | .05 | -1.0 -200 | nA | $V_{GS} = -15 \text{ V}$, $V_{DS} = 0$ $V_{GS} = -15 \text{ V}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$ |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | 2N5457 -0.5 2N5458 -1.0 2N5459 -2.0 | | -6.0 -7.0 -8.0 | V | $V_{DS} = 15 \text{ V}$, $I_D = 10 \text{ nA}$ |
| V_{GS} | Gate-Source Voltage | 2N5457 2N5458 2N5459 | 2.5 3.5 4.5 | | V | $V_{DS} = 15 \text{ V}$, $I_D = 100 \mu\text{A}$ $V_{DS} = 15 \text{ V}$, $I_D = 200 \mu\text{A}$ $V_{DS} = 15 \text{ V}$, $I_D = 400 \mu\text{A}$ |
| I_{DSS} | Zero-Gate-Voltage Drain Current | 2N5457 2N5458 2N5459 | 1.0 2.0 4.0 | 3.0 6.0 9.0 | 5.0 9.0 16 | mA $V_{DS} = 15 \text{ V}$, $V_{GS} = 0$ |
| $ y_{fs} $ | Forward Transfer Admittance | 2N5457 2N5458 2N5459 | 1000 1500 2000 | 3000 4000 4500 | 5000 5500 6000 | μmho $V_{DS} = 15 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ kHz}$ |
| $ y_{os} $ | Output Admittance | | 10 | 50 | μmho | $V_{DS} = 15 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ kHz}$ |
| C_{iss} | Input Capacitance | | 4.5 | 7.0 | pF | $V_{DS} = 15 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$ |
| C_{rss} | Reverse Transfer Capacitance | | 1.5 | 3.0 | pF | $V_{DS} = 15 \text{ V}$, $V_{GS} = 0$, $f = 1 \text{ MHz}$ |
| NF | Noise Figure | | | 3.0 | dB | $V_{DS} = 15 \text{ V}$, $V_{GS} = 0$, $R_G = 1 \text{ M}\Omega$ $BW = 1 \text{ Hz}$, $f = 1 \text{ kHz}$ |

Pulse test required. $PW \leq 630 \text{ ms}$, duty cycle $\leq 10\%$

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|---|
| Drain-Gate or Source-Gate Voltage | |
| 2N5460 - 2N5462 | 40V |
| 2N5463 - 2N5465 | 60V |
| Gate Current | 10 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 310 mW |
| Derate above 25°C | 2.8 mW/ $^\circ\text{C}$ |

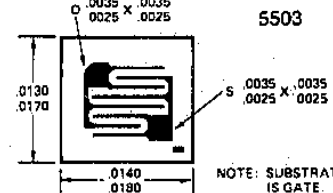
PIN CONFIGURATION

TO-92



S D G

CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-92 | WAFER | DICE |
|--------|----------|----------|
| 2N5460 | 2N5460/W | 2N5460/D |
| 2N5461 | 2N5461/W | 2N5461/D |
| 2N5462 | 2N5462/W | 2N5462/D |
| 2N5463 | 2N5463/W | 2N5463/D |
| 2N5464 | 2N5464/W | 2N5464/D |
| 2N5465 | 2N5465/W | 2N5465/D |

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|---------------|--|--|---------------------------|-------------------|------------------------------|--|
| BV_{GS} | Gate-Source Breakdown Voltage | 2N5460, 2N5461, 2N5462 2N5463, 2N5464, 2N5465 | 40 60 | | V | $I_G = 10 \mu\text{A}$, $V_{DS} = 0$ |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | 2N5460, 2N5463 2N5461, 2N5464 2N5462, 2N5465 | 0.75 1.0 1.8 | 6.0 7.5 9.0 | V | $V_{DS} = 15 \text{ Vdc}$, $I_D = 1.0 \mu\text{A}$ |
| I_{GSSR} | Gate Reverse Current | 2N5460, 2N5461, 2N5462 2N5463, 2N5464, 2N5465 | | 5.0 | nA | $V_{DS} = 0$ |
| | | | $T_A = 100^\circ\text{C}$ | 1.0 | μA | |
| I_{DSS} | Zero-Gate Voltage Drain Current | 2N5460, 2N5463 2N5461, 2N5464 2N5462, 2N5465 | -1.0 | -5.0 | mA | $V_{DS} = -15 \text{ V}$ |
| | | | -2.0 | -9.0 | | |
| | | | -4.0 | -16 | | |
| V_{GS} | Gate-Source Voltage | 2N5460, 2N5463 2N5461, 2N5464 2N5462, 2N5465 | 0.5 | 4.0 | V | $V_{GS} = 0$ |
| | | | 0.8 | 4.5 | | $I_D = 0.1 \text{ mA}$ |
| | | | 1.5 | 6.0 | | $I_D = -0.2 \text{ mA}$ |
| g_{fs} | Forward Transadmittance | 2N5460, 2N5463 2N5461, 2N5464 2N5462, 2N5465 | 1000 | 4000 | μmho | $V_{DS} = -15 \text{ V}$ $V_{GS} = 0 \text{ V}$ |
| | | | 1500 | 5000 | | |
| | | | 2000 | 6000 | | |
| g_{DS} | Output Admittance | | | 75 | μmho | $f = 1.0 \text{ kHz}$ |
| C_{iss} | Input Capacitance | | 5.0 | 7 | pF | |
| C_{rss} | Reverse Transfer Capacitance | | 1.0 | 2.0 | pF | |
| NF | Common-Source Noise Figure | | 1.0 | 2.5 | dB | $f = 100 \text{ Hz}$ $BW = 1.0 \text{ Hz}$ $R_G = 1.0 \text{ M}\Omega$ |
| \bar{e}_n | Equivalent Short-Circuit Input Noise Voltage | | .60 | 115 | $\text{nV}/\sqrt{\text{Hz}}$ | |

FEATURES

- Up to 400 MHz Operation
- Economy Packaging
- $C_{rss} < 1.0$ pF

1

ABSOLUTE MAXIMUM RATINGS

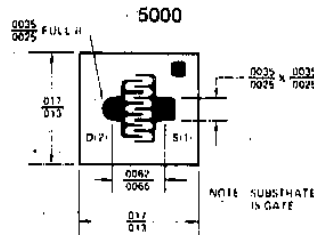
($T_A = 25^\circ\text{C}$ unless otherwise specified)

| | |
|---------------------------------------|---|
| Drain-Gate Voltage | 25V |
| Source Gate Voltage | 25V |
| Drain Current | 30 mA |
| Forward Gate Current | 10 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 310 mW |
| Derate above 25°C | 2.8 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION TO-92



CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-92 | WAFER | DICE |
|--------|----------|----------|
| 2N5484 | 2N5484/W | 2N5484/D |
| 2N5485 | 2N5485/W | 2N5485/D |
| 2N5486 | 2N5486/W | 2N5486/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N5484 | | 2N5485 | | 2N5486 | | UNITS | TEST CONDITIONS | | |
|---------------|--|-----|--------|------|--------|------|-------|---|---|----------------------|
| | MIN | MAX | MIN | MAX | MIN | MAX | | | | |
| I_{GSSR} | Gate Reverse Current $T_A = 100^\circ\text{C}$ | | -1.0 | -200 | -1.0 | -200 | nA | $V_{GS} = -20\text{ V}, V_{DS} = 0$ | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | | -25 | -25 | -25 | -25 | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ | | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | | -0.3 | -3.0 | -0.5 | -4.0 | -2.0 | -6.0 | $V_{DS} = 15\text{ V}, I_D = 10\text{ mA}$ | |
| I_{DSS} | Saturation Drain Current | | 1.0 | 5.0 | 4.0 | 10 | 8.0 | 20 | $V_{DS} = 15\text{ V}, V_{GS} = 0$ (Note 1) | |
| g_{fs} | Common-Source Forward Transconductance | | 3000 | 6000 | 3500 | 7000 | 4000 | 8000 | $V_{DS} = 15\text{ V}, V_{GS} = 0$ | |
| g_{os} | Common-Source Output Conductance | | | 50 | | 60 | | 75 | | $f = 1\text{ kHz}$ |
| $Re(y_{fs})$ | Common-Source Forward Transconductance | | 2500 | | 3000 | | 3500 | | | $f = 100\text{ MHz}$ |
| $Re(y_{os})$ | Common-Source Output Conductance | | | 75 | | 100 | | 100 | | $f = 400\text{ MHz}$ |
| $Re(y_{is})$ | Common-Source Input Conductance | | | 100 | | 1000 | | 1000 | | $f = 100\text{ MHz}$ |
| $Re(y_{is})$ | Common-Source Input Conductance | | | 100 | | 1000 | | 1000 | | $f = 400\text{ MHz}$ |
| C_{iss} | Common-Source Input Capacitance | | | 5.0 | | 5.0 | | 5.0 | $f = 1\text{ MHz}$ | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | | 1.0 | | 1.0 | | 1.0 | | |
| C_{oss} | Common-Source Output Capacitance | | | 2.0 | | 2.0 | | 2.0 | | |
| NF | Noise Figure | | 2.5 | 3.0 | 2.5 | 2.0 | 4.0 | 4.0 | $V_{DS} = 15\text{ V}, V_{GS} = 0, R_G = 1\text{ M}\Omega$ | |
| G_{ps} | Common-Source Power Gain | | | | | | | | $V_{DS} = 15\text{ V}, I_D = 1\text{ mA}, R_G = 1\text{ k}\Omega$ | |
| | | | | | | | | | $V_{DS} = 15\text{ V}, I_D = 4\text{ mA}, R_G = 1\text{ k}\Omega$ | |
| | | | | | | | | | $V_{DS} = 15\text{ V}, I_D = 1\text{ mA}$ | |
| | | | | | | | | $V_{DS} = 15\text{ V}, I_D = 4\text{ mA}$ | | |

NOTE: Pulse test required. Pulse width = 300 μs , duty cycle $\leq 3\%$.

2N5515-2N5524 Monolithic Dual N-Channel JFET

1

FEATURES

- Tight Temperature Tracking
- Tight Matching
- High Common Mode Rejection
- Low Noise

ABSOLUTE MAXIMUM RATINGS

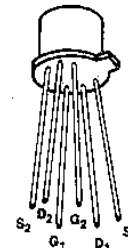
($T_A = 25^\circ\text{C}$ unless otherwise specified)

| | | |
|---------------------------------------|-----------------|--|
| Gate-Source or Gate-Drain Voltage | -40V | |
| Gate Current (Note 1) | 50 mA | |
| Storage Temperature Range | -65°C to +200°C | |
| Operating Temperature Range | -55°C to +150°C | |
| Lead Temperature (Soldering, 10 sec.) | +300°C | |

| | ONE SIDE | BOTH SIDES |
|-------------------|-----------|------------|
| Power Dissipation | 250 mW | 500 mW |
| Derate above 25°C | 3.8 mW/°C | 7.7 mW/°C |

PIN CONFIGURATION

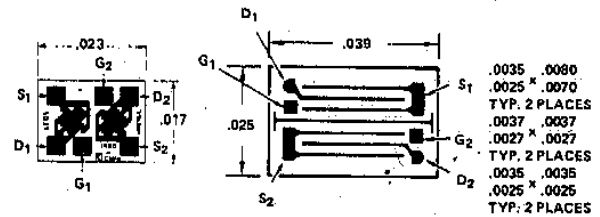
TO-71



CHIP TOPOGRAPHY

(2N5515-19)
6037

(2N5520-24)
6019



ALL BOND PADS ARE 4 x 4 MIL.

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| 2N5515 | 2N5515/W | 2N5515/D |
| 2N5516 | 2N5516/W | 2N5516/D |
| 2N5517 | 2N5517/W | 2N5517/D |
| 2N5518 | 2N5518/W | 2N5518/D |
| 2N5519 | 2N5519/W | 2N5519/D |
| 2N5520 | | |
| 2N5521 | | |
| 2N5522 | | |
| 2N5523 | | |
| 2N5524 | | |

*When ordering wafer/dice refer to Appendix B-23.

NOTE: Per transistor.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

1

| PARAMETER | | MIN | MAX | UNITS | TEST CONDITIONS | |
|-------------------|---|------------------------|------|--------|---|-----------|
| I _{GSSR} | Gate Reverse Current | | -250 | μA | V _{GS} = -30 V, V _{DS} = 0 | |
| | | T _A = 150°C | -250 | nA | | |
| BV _{GSS} | Gate-Source Breakdown Voltage | -40 | | V | I _G = -1 μA, V _{DS} = 0 | |
| V _p | Gate-Source Pinch-Off Voltage | -0.7 | -4 | V | V _{DS} = 20 V, I _D = 1 nA | |
| I _{DSS} | Drain Current at Zero Gate Voltage (Note 1) | 0.5 | 7.5 | mA | V _{DS} = 20 V, V _{GS} = 0 | |
| g _{fs} | Common-Source Forward Transconductance (Note 1) | 1000 | 4000 | μmho | | f = 1 kHz |
| g _{oss} | Common-Source Output Conductance | | 10 | μmho | | f = 1 MHz |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | 5 | pF | | |
| C _{iss} | Common-Source Input Capacitance | | 25 | pF | | |
| ē _n | Equivalent Input Noise Voltage | 2N5515-19 | 30 | nV/√Hz | f = 10 Hz | |
| | | 2N5520-24 | 15 | | f = 1 kHz | |
| | | 2N5515-24 | 10 | | | |
| I _G | Gate Current | | -100 | μA | V _{DG} = 20 V, I _D = 200 μA | |
| | | T _A = 125°C | -100 | nA | | |
| V _{GS} | Gate-Source Voltage | -0.2 | -3.8 | V | | |
| g _{fs} | Common-Source Forward Transconductance (Note 1) | 500 | 1000 | μmho | | f = 1 kHz |
| g _{oss} | Common-Source Output Conductance | | 1 | μmho | | |

MATCHING CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N5515,20 | | 2N5516,21 | | 2N5517,22 | | 2N5518,23 | | 2N5519,24 | | UNIT | TEST CONDITIONS |
|--|-----------|-----|-----------|-----|-----------|-----|-----------|-----|-----------|-----|-------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | |
| I _{DSS1} | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | 0.90 | 1 | | V _{DS} = 20 V, V _{GS} = 0 |
| I _{DSS2} | | | | | | | | | | | | |
| I _{G1} - I _{G2} | | 10 | | 10 | | 10 | | 10 | | 10 | nA | V _{DG} = 20 V, I _D = 200 μA |
| g _{fs1} | 0.97 | 1 | 0.97 | 1 | 0.95 | 1 | 0.95 | 1 | 0.90 | 1 | | V _{DG} = 20 V, I _D = 200 μA |
| g _{fs2} | | | | | | | | | | | | f = 1 kHz |
| g _{oss1} - g _{oss2} | | 0.1 | | 0.1 | | 0.1 | | 0.1 | | 0.1 | μmho | V _{DG} = 20 V, I _D = 200 μA |
| V _{GS1} - V _{GS2} | | 5 | | 5 | | 10 | | 15 | | 15 | mV | f = 1 kHz |
| $\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$ | | 5 | | 10 | | 20 | | 40 | | 80 | μV/°C | V _{DG} = 20 V, I _D = 200 μA |
| CMRR | 100 | | 100 | | 90 | | | | | | dB | V _{DD} = 10 to 20 V, I _D = 200 μA |

NOTES:

1. Pulse duration of 28 ms used during test.
2. CMRR = 20 Log₁₀ΔV_{DD}/Δ|V_{GS1} - V_{GS2}|, (ΔV_{DD} = 10V)

FEATURES

- Economy Packaging
- Fast Switching
- Low Drain-Source 'ON' Resistance

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise specified)

| | |
|---------------------------------------|-----------------|
| Drain-Source Voltage | 30V |
| Drain-Gate Voltage | 30V |
| Source-Gate Voltage | 30V |
| Forward Gate Current | 10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 310 mW |
| Derate above 25°C | 2.8 mW/°C |

PIN CONFIGURATION

TO-92

CHIP TOPOGRAPHY

5001

NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

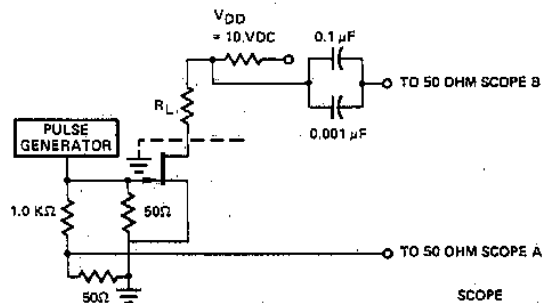
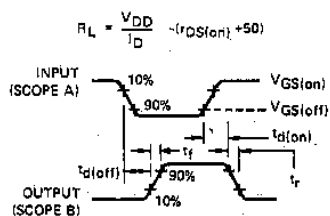
| TO-92 | WAFER | DICE |
|--------|----------|----------|
| 2N5638 | 2N5638/W | 2N5638/D |
| 2N5639 | 2N5639/W | 2N5638/D |
| 2N5640 | 2N5640/W | 2N5640/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | 2N5638 | | 2N5639 | | 2N5640 | | UNIT | TEST CONDITIONS |
|--------------|--------|-----|--------|-----|--------|-----|----------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | | |
| BV_{GSS} | -30 | | -30 | | -30 | | V | $I_G = -10 \mu\text{A}, V_{DS} = 0$ |
| I_{GSSR} | -1.0 | | -1.0 | | -1.0 | | nA | $V_{GS} = -15 \text{ V}, V_{DS} = 0$ |
| $I_{D(off)}$ | 1.0 | | 1.0 | | 1.0 | | nA | $V_{DS} = 15 \text{ V}, V_{GS} = -12 \text{ V}$ (2N5638) |
| I_{DSS} | 50 | | 25 | | 5.0 | | mA | $V_{GS} = -8 \text{ V}$ (2N5639), $V_{GS} = -6 \text{ V}$ (2N5640) |
| $V_{DS(on)}$ | 0.5 | | 0.5 | | 0.5 | | V | $V_{GS} = 0, I_D = 12 \text{ mA}$ (2N5638), $I_D = 6 \text{ mA}$ (2N5639), $I_D = 3 \text{ mA}$ (2N5640) |
| $r_{DS(on)}$ | 30 | | 60 | | 100 | | Ω | $I_D = 1 \text{ mA}, V_{GS} = 0$ |
| $r_{ds(on)}$ | 30 | | 60 | | 100 | | Ω | $V_{GS} = 0, I_D = 0$ |
| C_{iss} | 10 | | 10 | | 10 | | pF | $V_{GS} = -12 \text{ V}, V_{DS} = 0$ |
| C_{rss} | 4.0 | | 4.0 | | 4.0 | | pF | $f = 1 \text{ MHz}$ |
| $t_{d(on)}$ | 4.0 | | 6.0 | | 8.0 | | ns | $V_{DD} = 10 \text{ V}, I_{D(on)} = 12 \text{ mA}$ (2N5638) |
| t_r | 5.0 | | 8.0 | | 10 | | ns | $V_{GS(on)} = 0, I_{D(on)} = 6 \text{ mA}$ (2N5639) |
| t_d | 5.0 | | 10 | | 15 | | ns | $V_{GS(off)} = -10 \text{ V}, I_{D(on)} = 3 \text{ mA}$ (2N5640) |
| t_f | 10 | | 20 | | 30 | | ns | $R_G = 50 \Omega$ |

NOTE: 1. Pulse test; $PW \leq 300 \mu\text{s}$, duty cycle $\leq 3.0\%$.



SCOPE
TEKTRONIX 567A
OR EQUIVALENT

2N5902-2N5909 Monolithic Dual N-Channel JFET

FEATURES

- Tight Tracking
- Good Matching

1

ABSOLUTE MAXIMUM RATINGS

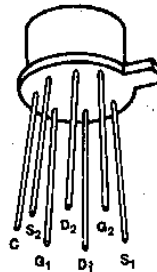
($T_A = 25^\circ\text{C}$ unless otherwise specified)

Gate-Drain or Gate-Source

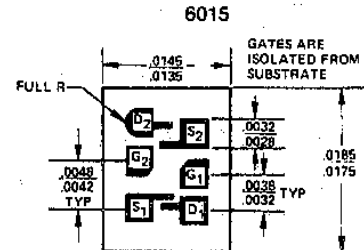
| | |
|---------------------------------------|-----------------|
| Voltage (Note 1) | -40V |
| Gate Current (Note 1) | 10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |

| | | |
|-------------------|-----------------|-------------------|
| Power Dissipation | ONE SIDE | BOTH SIDES |
| | 367 mW | 500 mW |
| Derate above 25°C | 3 mW/°C | 4 mW/°C |

PIN CONFIGURATION TO-99



CHIP TOPOGRAPHY 6015



ORDERING INFORMATION*

| TO-99 | WAFER | DICE | TO-99 | WAFER | DICE |
|--------|----------|----------|--------|----------|----------|
| 2N5902 | 2N5902/W | 2N5902/D | 2N5906 | 2N5906/W | 2N5906/D |
| 2N5903 | 2N5903/W | 2N5903/D | 2N5907 | 2N5907/W | 2N5907/D |
| 2N5904 | 2N5904/W | 2N5904/D | 2N5908 | 2N5908/W | 2N5908/D |
| 2N5905 | 2N5905/W | 2N5905/D | 2N5909 | 2N5905/W | 2N5909/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | 2N5902-5 | | 2N5906-9 | | UNIT | TEST CONDITIONS | | | | |
|--|--|----------|------|----------|------|--|--|----------|-----|------------------------------|--|
| | | MIN | MAX | MIN | MAX | | | | | | |
| I_{GSSR} | Gate Reverse Current | | -5 | | -2 | pA | $V_{GS} = -20\text{ V}, V_{DS} = 0$ | | | | |
| | | | -10 | | -5 | nA | | | | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -40 | | -40 | | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ | | | | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | -0.6 | -4.5 | -0.6 | -4.5 | V | | | | | |
| V_{GS} | Gate Source Voltage | | -4 | | -4 | V | $V_{DG} = 10\text{ V}, I_D = 30\ \mu\text{A}$ | | | | |
| I_G | Gate Operating Current | | -3 | | -1 | pA | | | | | |
| | | | -3 | | -1 | nA | | | | | |
| I_{DSS} | Saturation Drain Current | 30 | 500 | 30 | 500 | μA | | | | | |
| g_{fs} | Common-Source Forward Transconductance | 70 | 250 | 70 | 250 | μmho | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | | | | |
| g_{os} | Common-Source Output Conductance | | 5 | | 5 | μmho | | | | | |
| C_{iss} | Common-Source Input Capacitance | | 3 | | 3 | pF | $f = 1\text{ MHz}$ | | | | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 1.5 | | 1.5 | pF | | | | | |
| g_{fs} | Common-Source Forward Transconductance | 50 | 150 | 50 | 150 | μmho | $V_{DG} = 10\text{ V}, I_D = 30\ \mu\text{A}$ | | | | |
| g_{os} | Common-Source Output Conductance | | 1 | | 1 | μmho | | | | | |
| \bar{e}_n | Equivalent Short Circuit Input Noise Voltage | | 0.2 | | 0.1 | $\frac{\mu\text{V}}{\sqrt{\text{Hz}}}$ | $V_{DS} = 10\text{ V}, V_{GS} = 0$ | | | | |
| NF | Spot Noise Figure | | 3 | | 1 | dB | | | | | |
| | | | | | | | $f = 100\text{ Hz}$ $R_G = 10\text{ M}\Omega$ | | | | |
| PARAMETER | | 2N5902-6 | | 2N5903-7 | | 2N5904-8 | | 2N5905-9 | | UNIT | TEST CONDITIONS |
| | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | |
| $ I_{G1} - I_{G2} $ | Differential Gate Current | | 2.0 | | 2.0 | | 2.0 | | 2.0 | nA | $V_{DG} = 10\text{ V}, I_D = 30\ \mu\text{A}, T_A = 125^\circ\text{C}$ |
| | | | 0.2 | | 0.2 | | 0.2 | | 0.2 | | |
| $\frac{I_{DSS1}}{I_{DSS2}}$ | Saturation Drain Current Ratio | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | | $V_{DS} = 10\text{ V}, V_{GS} = 0$ |
| $\frac{g_{fs1}}{g_{fs2}}$ | Transconductance Ratio | 0.97 | 1 | 0.97 | 1 | 0.95 | 1 | 0.95 | 1 | | |
| $ V_{GS1} - V_{GS2} $ | Differential Gate-Source Voltage | | 5 | | 5 | | 10 | | 15 | mV | $V_{DG} = 10\text{ V}, I_D = 30\ \mu\text{A}$ |
| $\frac{\Delta V_{BS1} - V_{GS2} }{\Delta T}$ | Gate-Source Voltage Differential Drift (Measured at end points T_A and T_B) | | 5 | | 10 | | 20 | | 40 | $\mu\text{V}/^\circ\text{C}$ | |
| $ g_{os1} - g_{os2} $ | Differential Output Conductance | | 0.2 | | 0.2 | | 0.2 | | 0.2 | μmho | |
| | | | | | | | | | | | $f = 1\text{ kHz}$ $T_A = 25^\circ\text{C}$ $T_B = 125^\circ\text{C}$ $T_A = -55^\circ\text{C}$ $T_B = 25^\circ\text{C}$ |

NOTE 1: Per transistor.

2N5911, 2N5912 IT5911, IT5912 Monolithic Dual N-Channel JFET

FEATURES

- Tight Tracking
- Low Insertion Loss
- Good Matching

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Drain or Gate Source Voltage | -25V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |

| | TO-71 | | TO-99 | |
|-------------------|-----------|------------|-----------|------------|
| | ONE SIDE | BOTH SIDES | ONE SIDE | BOTH SIDES |
| Power Dissipation | 300 mW | 500 mW | 300 mW | 500 mW |
| Derate above 25°C | 1.7 mW/°C | 2.9 mW/°C | 3.0 mW/°C | 4.0 mW/°C |

PIN CONFIGURATION

TO-99 TO-71

CHIP TOPOGRAPHY

6022

ORDERING INFORMATION*

| TO-71 | TO-99 | WAFER | DICE |
|--------|--------|----------|----------|
| IT5911 | 2N5911 | 2N5911/W | 2N5911/D |
| IT5912 | 2N5912 | 2N5912/W | 2N5912/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | MIN | MAX | UNIT | TEST CONDITIONS | | |
|--------------------------------------|--|---------------------------|--------|--------------------------------------|----------------------------------|------------------------------|--|
| IGSSR | Gate Reverse Current | | -100 | pA | VGS = -15 V, VDS = 0 | | |
| | | $T_A = 150^\circ\text{C}$ | -250 | nA | | | |
| BVGSS | Gate Reverse Breakdown Voltage | -25 | | V | IG = -1 μA , VDS = 0 | | |
| VGS(off) | Gate-Source Cutoff Voltage | -1 | -5 | V | VDS = 10 V, ID = 1 nA | | |
| VGS | Gate-Source Voltage | -0.3 | -4 | V | | | |
| IG | Gate Operating Current | | -100 | pA | VDG = 10 V, ID = 5 mA | | |
| | | $T_A = 125^\circ\text{C}$ | -100 | nA | | | |
| IDSS | Saturation Drain Current (Pulsewidth 300 μs , duty cycle \leq 3%) | 7 | 40 | mA | VDS = 10 V, VGS = 0 V | | |
| gfs | Common-Source Forward Transconductance | 5000 | 10,000 | μmho | f = 1 kHz | | |
| gfs | Common-Source Forward Transconductance | 5000 | 10,000 | | f = 100 MHz | | |
| gos | Common-Source Output Conductance | | 100 | μmho | f = 1 kHz | | |
| gos | Common-Source Output Conductance | | 150 | | f = 100 MHz | | |
| Ciss | Common-Source Input Capacitance | | 5 | pF | VDG = 10 V, ID = 5 mA | | |
| Crss | Common-Source Reverse Transfer Capacitance | | 1.2 | | | | |
| en | Equivalent Short Circuit Input Noise Voltage | | 20 | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ | f = 10 kHz | | |
| NF | Spot Noise Figure | | 1 | dB | f = 10 kHz RG = 100K Ω | | |
| PARAMETER | | IT, 2N5911 | | IT, 2N5912 | | UNIT | TEST CONDITIONS |
| | | MIN | MAX | MIN | MAX | | |
| IG1-IG2 | Differential Gate Current | | 20 | | 20 | nA | VDG = 10 V, ID = 5 mA, 125°C |
| $\frac{IDSS1}{IDSS2}$ | Saturation Drain Current Ratio | 0.95 | 1 | 0.95 | 1 | | VDS = 10 V, VGS = 0 (Pulsewidth 300 μs , duty cycle \leq 3%) |
| VGS1-VGS2 | Differential Gate-Source Voltage | | 10 | | 15 | mV | |
| $\frac{\Delta VGS1-VGS2 }{\Delta T}$ | Gate-Source Voltage Differential Drift (Measured at end points, TA and TB) | | 20 | | 40 | $\mu\text{V}/^\circ\text{C}$ | TA = 25°C TB = 125°C |
| | | | 20 | | 40 | | TA = -55°C TB = 25°C |
| $\frac{gfs1}{gfs2}$ | Transconductance Ratio | 0.95 | 1 | 0.95 | 1 | | f = 1 kHz |

1

2N6483-2N6485 Monolithic Low Noise Dual N-Channel JFET

FEATURES

- Ultra Low Noise
- High CMRR
- Low Offset
- Tight Tracking

1

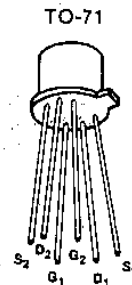
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

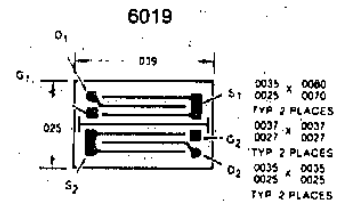
| | | |
|--|-------|---|
| Gate-Source or Gate-Drain Voltage (Note.1) | | -50V |
| Gate-Gate Voltage | | $\pm 50\text{V}$ |
| Gate Current (Note 1) | | 50 mA |
| Storage Temperature Range | | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | | $+300^\circ\text{C}$ |

| | ONE SIDE | BOTH SIDES |
|---------------------------------|--------------------------------|--------------------------------|
| Power Dissipation | 250 mW | 500 mW |
| Derate above 25°C | 3.8 mW/ $^\circ\text{C}$ | 7.7 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION



CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|--------|----------|----------|
| 2N6483 | 2N6483/W | 2N6483/D |
| 2N6484 | 2N6484/W | 2N6484/D |
| 2N6485 | 2N6485/W | 2N6485/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT | TEST CONDITIONS |
|-------------|---|---------------------------|------|------------------------------|--|
| I_{GSS} | Gate Reverse Current | | 200 | μA | $V_{GS} = -30\text{V}, V_{DS} = 0$ |
| | | $T_A = 150^\circ\text{C}$ | 200 | nA | |
| BV_{GSS} | Gate Source Breakdown Voltage | 50 | | V | $I_G = 1\mu\text{A}, V_{DS} = 0$ |
| V_p | Gate Source Pinch Off Voltage | 0.7 | 4.0 | | $V_{DS} = 20\text{V}, I_D = 1\text{nA}$ |
| I_{DSS} | Drain Current at Zero Gate Voltage (Note 2) | 0.5 | 7.5 | mA | $V_{DS} = 20\text{V}, V_{GS} = 0$ |
| g_{fs} | Common Source Forward Transconductance (Note 2) | 1000 | 4000 | μmho | $V_{DS} = 20\text{V}, V_{GS} = 0, f = 1\text{KHz}$ |
| g_{oss} | Common Source Output Conductance | | 10 | | |
| C_{iss} | Common Source Input Capacitance | | 20 | pF | $V_{DS} = 20\text{V}, V_{GS} = 0, f = 1\text{MHz}$ |
| C_{rss} | Common Source Reverse Transfer Capacitance | | 3.5 | | |
| I_G | Gate Current | | 100 | μA | $V_{GD} = 20\text{V}, I_D = 200\mu\text{A}$ |
| | | $T_A = 150^\circ\text{C}$ | 100 | nA | |
| V_{GS} | Gate Source Voltage | 0.2 | 3.8 | V | $V_{DG} = 20\text{V}, I_D = 200\mu\text{A}$ |
| g_{fs} | Common Source Forward Transconductance | 500 | 1500 | μmho | $V_{DG} = 20\text{V}, I_D = 200\mu\text{A}, f = 1\text{KHz}$ |
| g_{os} | Common Source Output Conductance | | 1 | | $V_{DG} = 20\text{V}, I_D = 200\mu\text{A}$ |
| \bar{e}_n | Equivalent Input Noise Voltage | | 10 | $\text{nV}/\sqrt{\text{Hz}}$ | $V_{DS} = 20\text{V}, I_D = 200\mu\text{A}, f = 10\text{Hz}$ |
| | | | 5 | | $V_{DS} = 20\text{V}, I_D = 200\mu\text{A}, f = 1\text{KHz}$ |

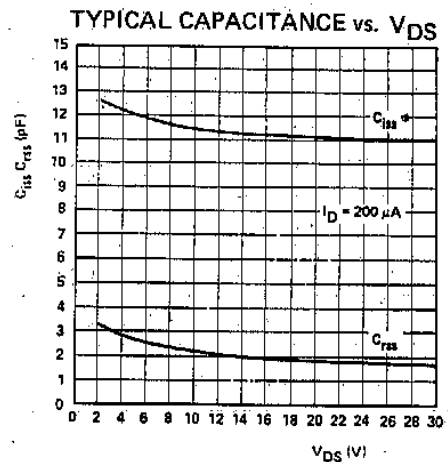
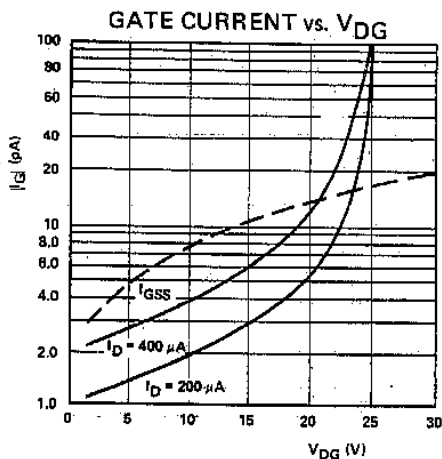
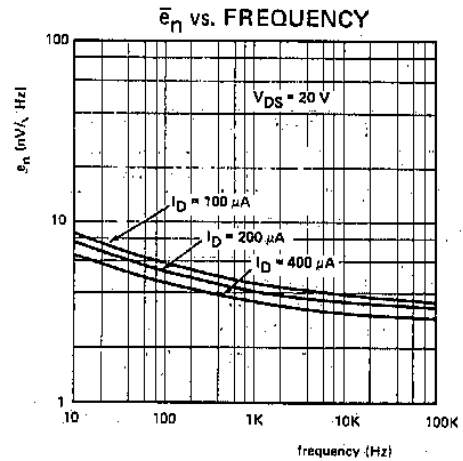
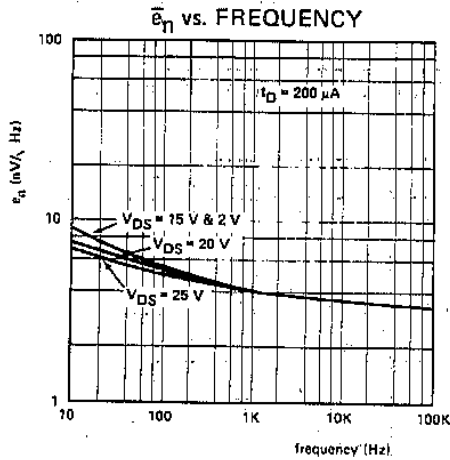
NOTES: 1. Per transistor.
2. Pulse test required; pulse width = 2 ms.

MATCHING CHARACTERISTICS (@ 25°C unless otherwise noted)

| SYMBOL | PARAMETER | 2N6483 | | 2N6484 | | 2N6485 | | UNIT | CONDITIONS |
|---|--|--------|------|--------|------|--------|------|------------------------------|--|
| | | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | | |
| $\frac{I_{DSS1}}{I_{DSS2}}$ | Drain Current Ratio at Zero Gate Voltage | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | | $V_{DS} = 20\text{ V}, V_{GS} = 0$ (Note 2) |
| $ I_{G1} - I_{G2} $ | Differential Gate Current | | 10 | | 10 | | 10 | nA | $V_{DG} = 20\text{ V}, I_D = 200\text{ }\mu\text{A}$ $T_A = +125^\circ\text{C}$ |
| $\frac{g_{fs1}}{g_{fs2}}$ | Transconductance Ratio | 0.97 | 1 | 0.97 | 1 | 0.95 | 1 | | $V_{DG} = 20\text{ V}, I_D = 200\text{ }\mu\text{A}$, $f = 1\text{ KHz}$ (Note 2) |
| $ g_{os1} - g_{os2} $ | Differential Output Conductance | | 0.1 | | 0.1 | | 0.1 | μmho | $V_{DG} = 20\text{ V}, I_D = 200\text{ }\mu\text{A}$, $f = 1\text{ KHz}$ |
| $ V_{GS1} - V_{GS2} $ | Differential Gate-Source Voltage | | 5 | | 10 | | 15 | mV | $V_{DG} = 20\text{ V}, I_D = 200\text{ }\mu\text{A}$ |
| $\frac{\Delta V_{GS1} - V_{GS2}}{\Delta T}$ | Gate-Source Voltage Differential Drift | | 5 | | 10 | | 25 | $\mu\text{V}/^\circ\text{C}$ | $V_{DG} = 20\text{ V}, I_D = 200\text{ }\mu\text{A}$ $T_A = -55^\circ\text{C to } +125^\circ\text{C}$ |
| CMRR | Common Mode Rejection Ratio | 100 | | 100 | | 90 | | dB | $V_{DD} = 10\text{ to } 20\text{ V}$, $I_D = 200\text{ }\mu\text{A}$ (Note 3) |

- NOTES: 1. These ratings are limiting values above which the serviceability of any individual semiconductor device may be impaired.
 2. Pulse duration of 2 ms used during test.
 3. $\text{CMRR} = 20 \log_{10} \Delta V_{DD} / \Delta |V_{GS1} - V_{GS2}|$, ($\Delta V_{DD} = 10\text{ V}$), not included in JEDEC registration

TYPICAL OPERATING CHARACTERISTICS



1

IMF6485 Monolithic Low Noise Dual N-Channel JFET

FEATURES

- Ultra Low Noise
- High CMRR
- Low Offset
- Tight Tracking

1

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--|---|
| Gate-Source or Gate-Drain Voltage (Note 1) | -50V |
| Gate-Gate Voltage | $\pm 50\text{V}$ |
| Gate Current (Note 1) | 50 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |

| | ONE SIDE | BOTH SIDES |
|---------------------------------|--------------------------|--------------------------|
| Power Dissipation | 250 mW | 500 mW |
| Derate above 25°C | 3.8 mW/ $^\circ\text{C}$ | 7.7 mW/ $^\circ\text{C}$ |

GENERAL DESCRIPTION

This N-Channel Junction FET is characterized for ultra low noise applications requiring tightly controlled and specified noise parameters at 10 Hz and 1000 Hz. Tight matching specifications make this device ideal as the input stage for low frequency differential instrumentation amplifiers.

PIN CONFIGURATION
TO-71

CHIP TOPOGRAPHY
6019

ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|---------|-----------|-----------|
| IMF6485 | IMF6485/W | IMF6485/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT | TEST CONDITIONS |
|-------------|---|---------------------------|------|------------------------------|--|
| I_{GSS} | Gate Reverse Current | | -200 | μA | $V_{GS} = -30\text{V}, V_{DS} = 0$ |
| | | $T_A = 150^\circ\text{C}$ | -200 | nA | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -50 | | V | $I_G = -1\mu\text{A}, V_{DS} = 0$ |
| V_P | Gate-Source Pinch-Off Voltage | -0.7 | -4.0 | | $V_{DS} = 20\text{V}, I_D = 1\text{nA}$ |
| I_{DSS} | Drain Current at Zero Gate Voltage (Note 2) | 0.5 | 7.5 | mA | $V_{DS} = 20\text{V}, V_{GS} = 0$ |
| g_{fs} | Common-Source Forward Transconductance (Note 2) | 1000 | 4000 | μmho | $V_{DS} = 20\text{V}, V_{GS} = 0, f = 1\text{KHz}$ |
| g_{oss} | Common-Source Output Conductance | | 10 | | $V_{DS} = 20\text{V}, V_{GS} = 0, f = 1\text{KHz}$ |
| C_{iss} | Common-Source Input Capacitance | | 20 | pF | $V_{DS} = 20\text{V}, V_{GS} = 0, f = 1\text{MHz}$ |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 3.5 | | $V_{DS} = 20\text{V}, V_{GS} = 0, f = 1\text{MHz}$ |
| I_G | Gate Current | | -100 | μA | $V_{DG} = 20\text{V}, I_D = 200\mu\text{A}$ |
| | | $T_A = 150^\circ\text{C}$ | -100 | nA | |
| V_{GS} | Gate-Source Voltage | 0.2 | -3.8 | V | $V_{DG} = 20\text{V}, I_D = 200\mu\text{A}$ |
| g_{fs} | Common-Source Forward Transconductance | 500 | 1500 | μmho | $V_{DG} = 20\text{V}, I_D = 200\mu\text{A}, f = 1\text{KHz}$ |
| g_{os} | Common-Source Output Conductance | | 1 | | $V_{DG} = 20\text{V}, I_D = 200\mu\text{A}$ |
| \bar{e}_n | Equivalent Input Noise Voltage | | 15 | $\text{nV}/\sqrt{\text{Hz}}$ | $V_{DS} = 20\text{V}, I_D = 200\mu\text{A}, f = 10\text{Hz}$ |
| | | | 10 | | $V_{DS} = 20\text{V}, I_D = 200\mu\text{A}, f = 1\text{KHz}$ |

NOTES:

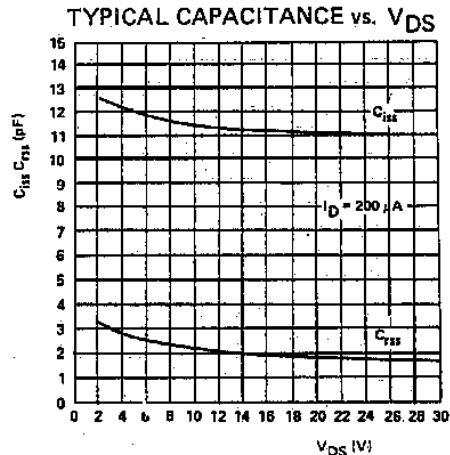
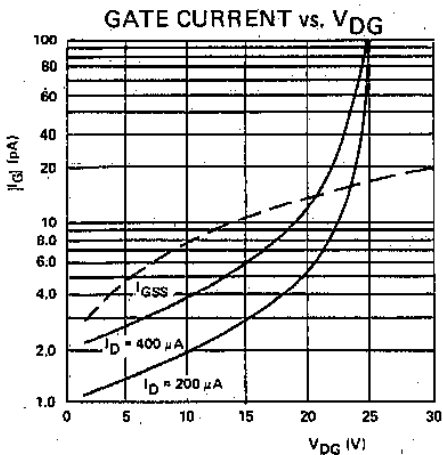
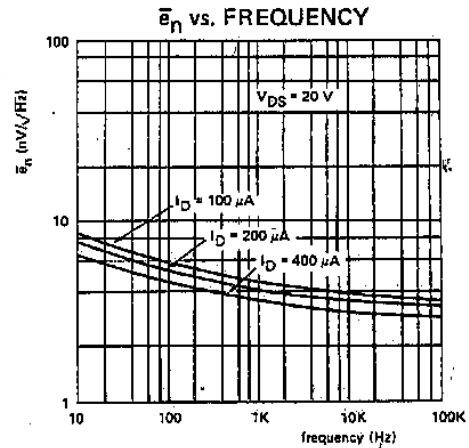
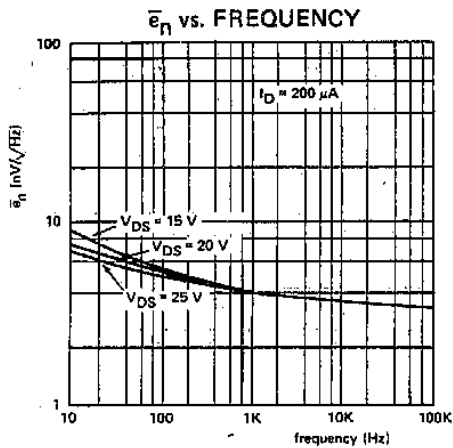
1. Per transistor.
2. Pulse test required; pulse width = 2 ms.

MATCHING CHARACTERISTICS (@ 25° C unless otherwise noted)

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT | CONDITIONS |
|--|--|------|------|------------------------------|---|
| $\frac{I_{DSS1}}{I_{DSS2}}$ | Drain Current Ratio at Zero Gate Voltage | 0.95 | 1 | | $V_{DS} = 20 \text{ V}, V_{GS} = 0$ (Note 2) |
| $ I_{G1} - I_{G2} $ | Differential Gate Current | | 10 | nA | $V_{DG} = 20 \text{ V}, I_D = 200 \mu\text{A}$ $T_A = +125^\circ \text{C}$ |
| $\frac{g_{fs1}}{g_{fs2}}$ | Transconductance Ratio | 0.95 | 1 | | $V_{DG} = 20 \text{ V}, I_D = 200 \mu\text{A}$, $f = 1 \text{ KHz}$ (Note 2) |
| $ g_{os1} - g_{os2} $ | Differential Output Conductance | | 0.1 | μmho | $V_{DG} = 20 \text{ V}, I_D = 200 \mu\text{A}$, $f = 1 \text{ KHz}$ |
| $ V_{GS1} - V_{GS2} $ | Differential Gate-Source Voltage | | 25 | mV | $V_{DG} = 20 \text{ V}, I_D = 200 \mu\text{A}$ |
| $\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$ | Gate-Source Voltage Differential Drift | | 40 | $\mu\text{V}/^\circ\text{C}$ | $V_{CG} = 20 \text{ V}, I_D = 200 \mu\text{A}$ $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ |
| CMRR | Common Mode Rejection Ratio | 90 | | dB | $V_{DD} = 10$ to 20 V , $I_D = 200 \mu\text{A}$ (Note 3) |

- NOTES: 1. These ratings are limiting values above which the serviceability of any individual semiconductor device may be impaired.
 2. Pulse duration of 2 ms used during test.
 3. $\text{CMRR} = 20 \log_{10} \Delta V_{DD} / \Delta |V_{GS1} - V_{GS2}|$. ($\Delta V_{DD} = 10 \text{ V}$)

TYPICAL OPERATING CHARACTERISTICS



1

Diode Protected P-Channel Enhancement Mode MOSFET

FEATURES

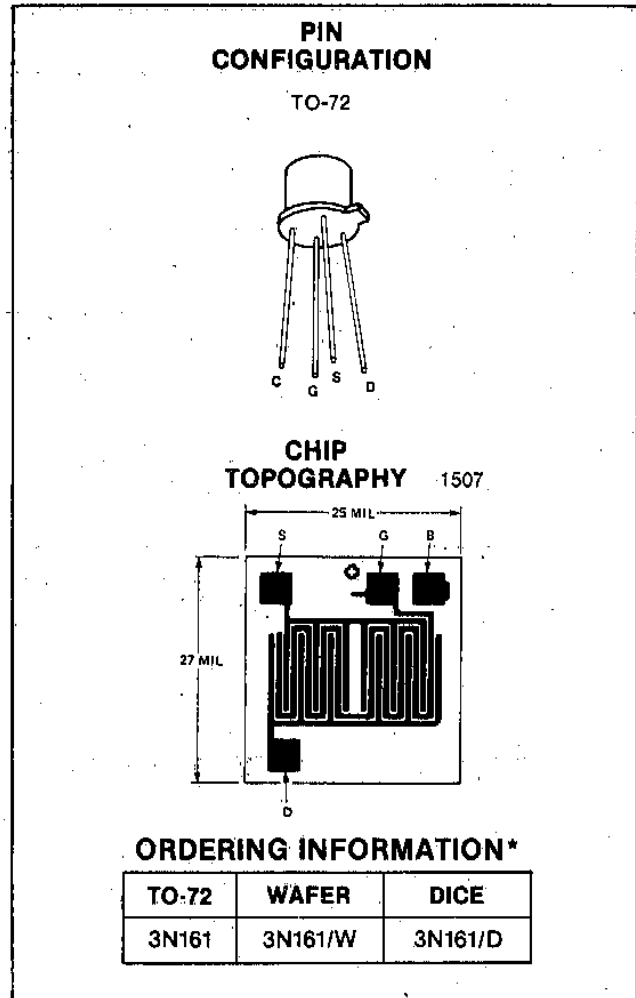
- Channel Cut Off with Zero Gate Voltage
- Square-Law Transfer Characteristic Reduces Distortion
- Independent Substrate Connection Provides Flexibility in Biasing
- Internally Connected Diode Protects Gate from Damage due to Overvoltage

1

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|---|
| Drain-Source or Drain-Gate Voltage | 40V |
| Drain Current | 50 mA |
| Gate Forward Current | 10 μA |
| Gate Reverse Current | 1 mA |
| Storage Temperature | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 375 mW |
| Derate above 25°C | 3.0 mW/ $^\circ\text{C}$ |



*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted).

| PARAMETER | MIN | TYP | MAX | UNIT | TEST CONDITIONS |
|---|------|------|------|-----------------|---|
| I _{GSSF} Forward Gate-Terminal Current | | -100 | | pA | V _{GS} = -25 V, V _{DS} = 0 |
| | | | -1 | nA | |
| BV _{GSS} Forward Gate-Source Break-down Voltage | -25 | | | V | I _G = -0.1 mA, V _{DS} = 0, |
| I _{DSS} Zero-Gate-Voltage Drain Current | | | -10 | nA | V _{DS} = -15 V, V _{GS} = 0 |
| | | | -10 | μA | |
| V _{GS(th)} Gate-Source Threshold Voltage | -1.5 | | -5 | V | V _{DS} = -15 V, I _D = -10 μA |
| V _{GS} Gate-Source Voltage | -4.5 | | -8 | V | V _{DS} = -15 V, I _D = -8 mA |
| I _{D(on)} On-State Drain Current | -40 | | -120 | mA | V _{DS} = -15 V, V _{GS} = -15 V |
| y _{fs} Small-Signal Common-Source Forward Transfer Admittance | 3500 | | 6500 | μmho | V _{DS} = -15 V, I _D = -8 mA |
| y _{os} Small-Signal Common-Source Output Admittance | | | 250 | | |
| C _{iss} Common-Source Short-Circuit Input Capacitance | | | 10 | pF | f = 1 MHz |
| C _{rss} Common-Source Short-Circuit Reverse Transfer Capacitance | | | 4 | | f = 1 MHz |

3N163, 3N164 P-Channel Enhancement Mode MOS FET

FEATURES

- Very High Input Impedance
- High Gate Breakdown
- Fast Switching
- Low Capacitance

ABSOLUTE MAXIMUM RATINGS (Note 1)

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Drain-Source or Drain-Gate Voltage

3N163 40V

3N164 30V

Static Gate-Source Voltage

3N163 $\pm 40\text{V}$

3N164 $\pm 30\text{V}$

Transient Gate-Source Voltage (Note 2)

..... $\pm 125\text{V}$

Drain Current 50 mA

Storage Temperature -65°C to $+200^\circ\text{C}$

Operating Temperature -55°C to $+150^\circ\text{C}$

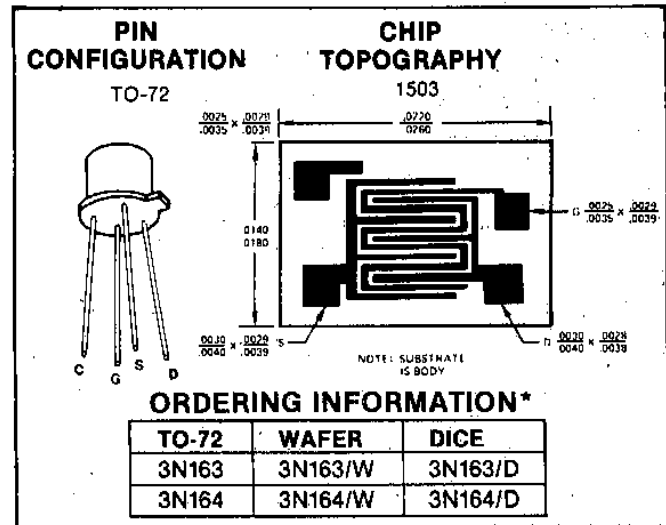
Lead Temperature (Soldering, 10 sec.) $+300^\circ\text{C}$

Power Dissipation 375 mW

Derate above $+25^\circ\text{C}$ 3.0 mW/ $^\circ\text{C}$

NOTES:

1. See handling precautions on 3N170 data sheet.
2. Devices must not be tested at $\pm 125\text{V}$ more than once, nor for longer than 300 ms.



1

*When ordering wafer/dice refer to Appendix B-23.

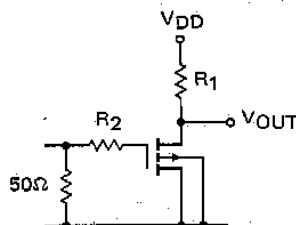
ELECTRICAL CHARACTERISTICS (@ 25°C and $V_{BS} = 0$ unless noted)

| Symbol | Parameter | 3N163 | | 3N164 | | UNITS | TEST CONDITIONS |
|--------------|------------------------------------|-------|----------------------------|-------|-------|------------------|---|
| | | MIN | MAX | MIN | MAX | | |
| I_{GSSR} | Gate Reverse Leakage Current | | 10 | | 10 | pA | $V_{GS} = -40\text{V}$ (3N163) $V_{GS} = -30\text{V}$ (3N164) |
| I_{GSSF} | Gate Forward Current | | -10 | | -10 | | |
| | | | $T_A = +125^\circ\text{C}$ | | -25 | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | -40 | | -30 | | V | $I_D = -10\ \mu\text{A}$, $V_{GS} = 0$ |
| BV_{SDS} | Source Drain Breakdown Voltage | -40 | | -30 | | | $I_S = -10\ \mu\text{A}$, $V_{GD} = 0$, $V_{DB} = 0$ |
| $V_{GS(th)}$ | Threshold Voltage | -2.0 | -5.0 | -2.0 | -5.0 | V | $V_{DS} = V_{GS}$, $I_D = -10\ \mu\text{A}$ |
| $V_{GS(10)}$ | Threshold Voltage | -2.0 | -5.0 | -2.0 | -5.0 | | $V_{DS} = -15\text{V}$, $I_D = -10\ \mu\text{A}$ |
| V_{GS} | Gate Source Voltage | -3.0 | -6.5 | -3.0 | -6.5 | | $V_{DS} = -15\text{V}$, $I_D = -0.5\ \text{mA}$ |
| I_{DSS} | Zero Gate Voltage Drain Current | | 200 | | 400 | pA | $V_{DS} = -15\text{V}$, $V_{GS} = 0$ |
| I_{SDS} | Source Drain Current | | 400 | | 800 | | $V_{SD} = 15\text{V}$, $V_{GS} = V_{DB} = 0$ |
| $r_{DS(on)}$ | Drain-Source on Resistance | | 250 | | 300 | ohms | $V_{GS} = -20\text{V}$, $I_D = -100\ \mu\text{A}$ |
| $I_{D(10)}$ | On Drain Current | -5.0 | -30.0 | -3.0 | -30.0 | mA | $V_{DS} = -15\text{V}$, $V_{GS} = -10\text{V}$ |
| g_{fs} | Forward Transconductance | 2000 | 4000 | 1000 | 4000 | μmhos | $V_{DS} = -15\text{V}$, $I_D = -10\ \text{mA}$, $f = 1\ \text{kHz}$ |
| g_{os} | Output Admittance | | 250 | | 250 | | |
| C_{iss} | Input Capacitance - Output Shorted | | 2.5 | | 2.5 | pF | $V_{DS} = -15\text{V}$, $I_D = -10\ \text{mA}$, $f = 1\ \text{MHz}$ |
| C_{rss} | Reverse Transfer Capacitance | | 0.7 | | 0.7 | | |
| C_{oss} | Output Capacitance Input Shorted | | 3.0 | | 3.0 | | |

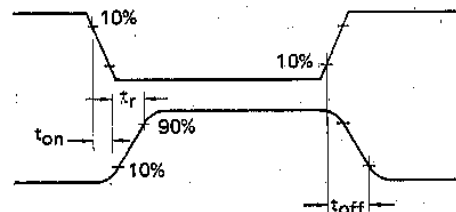
SWITCHING CHARACTERISTICS (@ 25°C and $V_{BS} = 0$)

| | | | | | | | |
|-----------|--------------------|--|----|--|----|----|-----------------------------------|
| t_{on} | Turn-On Delay Time | | 12 | | 12 | ns | $V_{DD} = -15\text{V}$ |
| t_r | Rise Time | | 24 | | 24 | | $I_{D(10)}$ = -10 mA |
| t_{off} | Turn-Off Time | | 50 | | 50 | | $R_G = R_L = 1.4\ \text{k}\Omega$ |

SWITCHING TIME CIRCUIT



SWITCHING WAVEFORM



3N165, 3N166 Dual P-Channel Enhancement Mode MOS FET

FEATURES

- Very High Impedance
- High Gate Breakdown
- Low Capacitance

1

ABSOLUTE MAXIMUM RATINGS (Note 1)

($T_A = 25^\circ\text{C}$ unless otherwise specified)

Drain-Source or Drain-Gate Voltage (Note 2)

3N165 40V

3N166 30V

Transient Gate-Source Voltage (Note 3) $\pm 12\text{V}$

Gate-Gate Voltage $\pm 80\text{V}$

Drain Current (Note 2) 50 mA

Storage Temperature -65°C to $+200^\circ\text{C}$

Operating Temperature -55°C to $+150^\circ\text{C}$

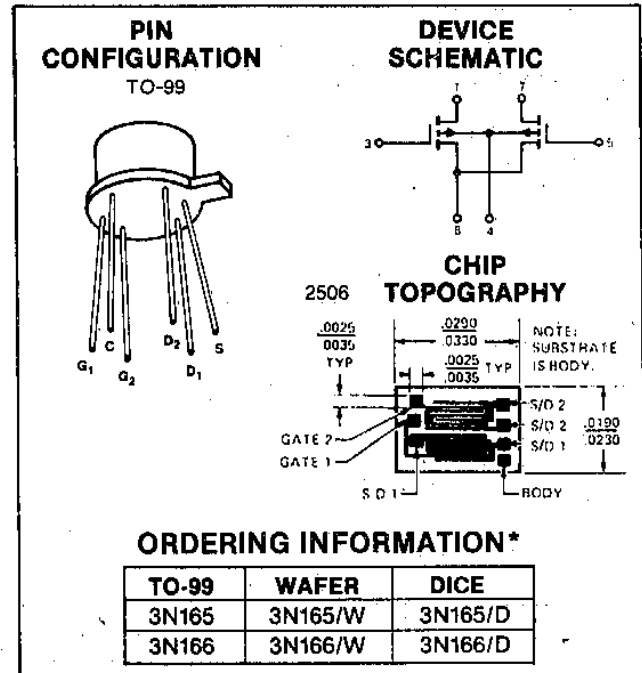
Lead Temperature (Soldering, 10 sec.) $+300^\circ\text{C}$

Power Dissipation

One Side 300 mW

Both Sides 525 mW

Total Derating above 25°C $4.2 \text{ mW}/^\circ\text{C}$



*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (@ 25°C and $V_{GS} = 0$ unless notes)

| PARAMETER | | MIN | MAX | UNITS | TEST CONDITIONS |
|--------------|--|------|------|------------------|---|
| I_{GSSR} | Gate Reverse Leakage Current | | 10 | pA | $V_{GS} = 40\text{V}$ |
| I_{GSSF} | Gate Forward Leakage Current | | -10 | | $V_{GS} = -40\text{V}$ |
| | $T_A = +125^\circ\text{C}$ | | -25 | | |
| I_{DSS} | Drain to Source Leakage Current | | -200 | mA | $V_{DS} = -20\text{V}$ |
| I_{SDS} | Source to Drain Leakage Current | | -400 | | $V_{SD} = -20, V_{DB} = 0$ |
| $I_{D(on)}$ | On Drain Current | -5 | -30 | V | $V_{DS} = -15\text{V}, V_{GS} = -10\text{V}$ |
| $V_{GS(th)}$ | Gate Source Threshold Voltage | -2 | -5 | | $V_{DS} = -15\text{V}, I_D = -10\mu\text{A}$ |
| $V_{GS(th)}$ | Gate Source Threshold Voltage | -2 | -5 | ohms | $V_{DS} = V_{GS}, I_D = -10\mu\text{A}$ |
| $r_{DS(on)}$ | Drain Source ON Resistance | | 300 | | $V_{GS} = -20\text{V}, I_D = -100\mu\text{A}$ |
| g_{fs} | Forward Transconductance | 1500 | 3000 | μmhos | $V_{DS} = -15\text{V}, I_D = -10\text{mA}, f = 1\text{kHz}$ |
| g_{os} | Output Admittance | | 300 | | |
| C_{iss} | Input Capacitance | | 3.0 | pF | $V_{DS} = -15\text{V}, I_D = -10\text{mA}, f = 1\text{MHz}$ |
| C_{rss} | Reverse Transfer Capacitance | | 0.7 | | |
| C_{oss} | Output Capacitance | | 3.0 | | |
| $RE(Y_{fs})$ | Common Source Forward Transconductance | 1200 | | μmhos | $V_{DS} = -15\text{V}, I_D = -10\text{mA}, f = 100\text{MHz}$ |

MATCHING CHARACTERISTICS 3N165

| PARAMETER | | MIN | MAX | UNITS | TEST CONDITIONS |
|-------------------------------------|--|------|-----|------------------------------|---|
| Y_{fs1}/Y_{fs2} | Forward Transconductance Ratio | 0.90 | 1.0 | | $V_{DS} = -15\text{V}, I_D = -1500\mu\text{A}, f = 1\text{kHz}$ |
| V_{GS1-2} | Gate-Source Threshold Voltage Differential | | 100 | mV | $V_{DS} = -15\text{V}, I_D = -500\mu\text{A}$ |
| $\frac{\Delta V_{GS1-2}}{\Delta T}$ | Gate Source Threshold Voltage Differential Change with Temperature | | 100 | $\mu\text{V}/^\circ\text{C}$ | $V_{DS} = -15\text{V}, I_D = -500\mu\text{A}$ $T_A = -55^\circ\text{C}$ to $+25^\circ\text{C}$ |
| | | | 100 | | |

Note 1: See handling precautions on 3N170 data sheet.

Note 2: Per transistor.

Note 3: Devices must not be tested at $\pm 125\text{V}$ more than once, nor for longer than 300 ms.

3N170, 3N171 N-Channel Enhancement Mode MOS FET

FEATURES

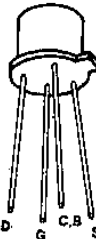
- Low Switching Voltages
- Fast Switching Times
- Low Drain-Source Resistance
- Low Reverse Transfer Capacitance

ABSOLUTE MAXIMUM RATINGS

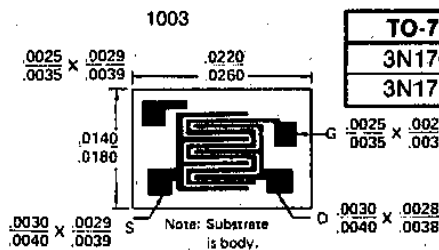
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|---------------------------------|-------|---|
| Drain-Gate Voltage | | $\pm 35\text{V}$ |
| Drain-Source Voltage | | 25V |
| Gate-Source Voltage | | $\pm 35\text{V}$ |
| Drain Current | | 30 mA |
| Storage Temperature | | |
| Range | | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature | | |
| Range | | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature | | |
| (Soldering, 10 sec.) | | $+300^\circ\text{C}$ |
| Power Dissipation | | 300 mW |
| Derate above 25°C | | 1.7 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION



CHIP TOPOGRAPHY



HANDLING PRECAUTIONS

MOS field-effect transistors have extremely high input resistance and can be damaged by the accumulation of excess static charge. To avoid possible damage to the device while wiring, testing, or in actual operation, follow the procedures outlined below.

1. To avoid the build-up of static charge, the leads of the devices should remain shorted together with a metal ring except when being tested or used.
2. Avoid unnecessary handling. Pick up devices by the case instead of the leads.
3. Do not insert or remove devices from circuits with the power on as transient voltages may cause permanent damage to the devices.

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|-------|---------|---------|
| 3N170 | 3N170/W | 3N170/D |
| 3N171 | 3N170/W | 3N170/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted) Substrate connected to source.

| PARAMETER | MIN | MAX | UNITS | TEST CONDITIONS |
|---------------------|------|-----|------------------|--|
| BV _{DSS} | 25 | | V | $I_D = 10 \mu\text{A}$, $V_{GS} = 0$ |
| I _{GSS} | | 10 | pA | $V_{GS} = -35 \text{V}$, $V_{DS} = 0$ |
| I _{DSS} | | 10 | nA | $V_{DS} = 10 \text{V}$, $V_{GS} = 0$ |
| | | 1.0 | μA | |
| V _{GS(th)} | | 1.0 | V | $V_{DS} = 10 \text{V}$, $I_D = 10 \mu\text{A}$ |
| | | 3.0 | | |
| I _{D(on)} | 10 | | mA | $V_{GS} = 10 \text{V}$, $V_{DS} = 10 \text{V}$ |
| V _{DS(on)} | | 2.0 | V | $I_D = 10 \text{mA}$, $V_{GS} = 10 \text{V}$ |
| r _{ds(on)} | | 200 | Ω | $V_{GS} = 10 \text{V}$, $I_D = 0$, $f = 1.0 \text{kHz}$ |
| Y _{fs} | 1000 | | μmhos | $V_{DS} = 10 \text{V}$, $I_D = 2.0 \text{mA}$, $f = 1.0 \text{kHz}$ |
| C _{rss} | | 1.3 | pF | $V_{DS} = 0$, $V_{GS} = 0$, $f = 1.0 \text{MHz}$ |
| C _{iss} | | 5.0 | | $V_{DS} = 10 \text{V}$, $V_{GS} = 0$, $f = 1.0 \text{MHz}$ |
| C _{d(sub)} | | 5.0 | | $V_{D(SUB)} = 10 \text{V}$, $f = 1.0 \text{MHz}$ |
| t _{d(on)} | | 3.0 | ns | $V_{DD} = 10 \text{V}$, $I_{D(on)} = 10 \text{mA}$, $V_{GS(on)} = 10 \text{V}$, $V_{GS(off)} = 0$, $R_G = 50 \Omega$ |
| t _r | | 10 | | |
| t _{d(off)} | | 3.0 | | |
| t _f | | 15 | | |



3N172, 3N173 Diode Protected P-Channel Enhancement Mode MOS FET

FEATURES

- High Input Impedance
- Diode Protected Gate

1

ABSOLUTE MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Drain-Source or Drain-Gate Voltage | |
| 3N172 | 40V |
| 3N173 | 30V |
| Drain Current | 50 mA |
| Gate Forward Current | 10 μA |
| Gate Reverse Current | 1 mA |
| Storage Temperature | -65°C to +200°C |
| Operating Temperature | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 375 mW |
| Derate above 25°C | 3.0 mW/°C |

PIN CONFIGURATION
TO-72

DEVICE SCHEMATIC

CHIP TOPOGRAPHY 1503Z

NOTE: SUBSTRATE IS BODY

ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|-------|---------|---------|
| 3N172 | 3N172/W | 3N172/D |
| 3N173 | 3N173/W | 3N173/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (@ 25°C and V_{BS} = 0 unless noted)

| PARAMETER | | 3N172 | | 3N173 | | UNITS | TEST CONDITIONS |
|---------------------|----------------------------------|-------------------------|------|-------|------|--|--|
| | | MIN | MAX | MIN | MAX | | |
| I _{GSSR} | Gate Reverse Current | | -200 | | -500 | pA | V _{GS} = -20V |
| | | T _A = +125°C | -0.5 | | -1.0 | | |
| BV _{GSS} | Gate Breakdown Voltage | -40 | -125 | -30 | -125 | V | I _D = -10 μA |
| BV _{DSS} | Drain-Source Breakdown Voltage | -40 | | -30 | | | I _D = -10 μA |
| BV _{SDS} | Source-Drain Breakdown Voltage | -40 | | -30 | | | I _S = -10 μA, V _{DB} = 0 |
| V _{GS(th)} | Threshold Voltage | -2.0 | -5.0 | -2.0 | -5.0 | | V _{DS} = V _{GS} , I _D = -10 μA |
| | | -2.0 | -5.0 | -2.0 | -5.0 | V _{DS} = -15V, I _D = -10 μA | |
| V _{GS} | Gate Source Voltage | -3.0 | -6.5 | -2.5 | -6.5 | V _{DS} = -15V, I _D = -500 μA | |
| I _{DSS} | Zero Gate Voltage Drain Current | | -0.4 | | -10 | nA | V _{DS} = -15V, V _{GS} = 0 |
| I _{SDS} | Zero Gate Voltage Source Current | | -0.4 | | -10 | | V _{SD} = -15V, V _{DB} = 0, V _{GD} = 0 |
| r _{DS(on)} | Drain Source On Resistance | | 250 | | 350 | ohms | V _{GS} = -20V, I _D = -100 μA |
| I _{D(on)} | On Drain Current | -5.0 | -30 | -5.0 | -30 | mA | V _{DS} = -15V, V _{GS} = -10V |

3N188-3N191 Dual P-Channel Enhancement Mode MOSFET

FEATURES

- Very High Input Impedance
- High Gate Breakdown 3N190-3N191
- Zener Protected gate 3N188-3N189
- Low Capacitance

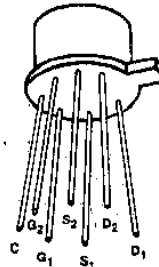
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---|---|
| Drain-Source or Drain-Gate Voltage (Note 1) | |
| 3N188, 3N189 | 40V |
| 3N190, 3N191 | 30V |
| Transient Gate-Source Voltage (Notes 1 and 2) | $\pm 125\text{V}$ |
| Gate-Gate Voltage | $\pm 80\text{V}$ |
| Drain Current (Note 1) | 50 mA |
| Storage Temperature | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10-sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | |
| One Side | 300 mW |
| Both Sides | 525 mW |
| Total Derating above 25°C | $4.2\text{ mW}/^\circ\text{C}$ |

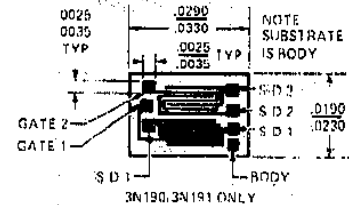
PIN CONFIGURATION

TO-99



CHIP TOPOGRAPHY

2506



NOTE: Body is connected to case.

ORDERING INFORMATION*

| TO-99 | WAFER | DICE |
|-------|---------|---------|
| 3N188 | — | — |
| 3N189 | — | — |
| 3N190 | 3N190/W | 3N190/D |
| 3N191 | 3N191/W | 3N191/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C and $V_{BS} = 0$ unless otherwise noted)

| PARAMETER | DESCRIPTION | 3N188 3N189 | | 3N190 3N191 | | UNITS | TEST CONDITIONS |
|--------------|-----------------------------------|----------------|-------|----------------|-------|------------------|---|
| | | MIN | MAX | MIN | MAX | | |
| I_{GSSR} | Gate Reverse Current | | | | 10 | μA | $V_{GS} = 40\text{V}$ |
| I_{GSSF} | Gate Forward Current | | -200 | | -10 | μA | $V_{GS} = -40\text{V}$ |
| | | | -200 | | -25 | | |
| BV_{DSS} | Drain-Source Breakdown Voltage | -40 | | -40 | | V | $I_D = -10\mu\text{A}$ |
| BV_{SDS} | Source-Drain Breakdown Voltage | -40 | | -40 | | | $I_S = -10\mu\text{A}, V_{BD} = 0$ |
| $V_{GS(th)}$ | Threshold Voltage | -2.0 | -5.0 | -2.0 | -5.0 | | $V_{DS} = -15\text{V}, I_D = -10\mu\text{A}$ |
| | | -2.0 | -5.0 | -2.0 | -5.0 | | $V_{DS} = V_{GS}, I_D = -10\mu\text{A}$ |
| V_{GS} | Gate Source Voltage | -3.0 | -6.5 | -3.0 | -6.5 | | $V_{DS} = -15\text{V}, I_D = -500\mu\text{A}$ |
| I_{DSS} | Zero Gate Voltage Drain Current | | -200 | | -200 | μA | $V_{DS} = -15\text{V}$ |
| I_{SDS} | Source Drain Current | | -400 | | -400 | | $V_{SD} = -15\text{V}, V_{DB} = 0$ |
| $r_{DS(on)}$ | Drain-Source on Resistance | | 300 | | 300 | ohms | $V_{DS} = -20\text{V}, I_D = -100\mu\text{A}$ |
| $I_{D(on)}$ | On Drain Current | -5.0 | -30.0 | -5.0 | -30.0 | mA | $V_{DS} = -15\text{V}, V_{GS} = -10\text{V}$ |
| g_{fs} | Forward Transconductance (Note 3) | 1500 | 4000 | 1500 | 4000 | μmhos | |
| Y_{os} | Output Admittance | | 300 | | 300 | | $V_{DS} = -15\text{V}, I_D = -5\text{mA}$ |
| C_{iss} | Input Capacitance Output Shorted | | 4.5 | | 4.5 | pF | $f = 1\text{kHz}$ |
| C_{rss} | Reverse Transfer Capacitance | | 1.5 | | 1.0 | | $f = 1\text{MHz}$ |
| C_{oss} | Output Capacitance Input Shorted | | 3.0 | | 3.0 | | |

SWITCHING CHARACTERISTICS (@ 25°C and $V_{BS} = 0$ unless noted)

| Parameter | Description | MIN | MAX | UNITS | TEST CONDITIONS |
|-------------|--------------------|-----|-----|-------|---|
| $t_{d(on)}$ | Turn On Delay Time | | 15 | ns | $V_{DD} = -15\text{V}, I_D = -5\text{mA}$ |
| t_r | Rise Time | | 30 | ns | $R_G = R_L = 1.4\text{k}\Omega$ |
| t_{off} | Turn Off Time | | 50 | ns | |

MATCHING CHARACTERISTICS (@ 25°C and $V_{BS} = 0$ unless noted) 3N188 and 3N190

| Parameter | Description | MIN | MAX | UNITS | TEST CONDITIONS |
|-------------------------------------|---|------|-----|------------------------------|--|
| Y_{fs1}/Y_{fs2} | Forward Transconductance Ratio | 0.85 | 1.0 | | $V_{DS} = -15\text{V}, I_D = -500\mu\text{A}, f = 1\text{kHz}$ |
| V_{GS1-2} | Gate Source Threshold Voltage Differential | | 100 | mV | $V_{DS} = -15\text{V}, I_D = -500\mu\text{A}$ |
| $\frac{\Delta V_{GS1-2}}{\Delta T}$ | Gate Source Threshold Voltage Differential Change with Temperature (Note 4) | | 100 | $\mu\text{V}/^\circ\text{C}$ | $V_{DS} = -15\text{V}, I_D = -500\mu\text{A}$ $T = -55^\circ\text{C}$ to $+25^\circ\text{C}$ |
| $\frac{\Delta V_{GS1-2}}{\Delta T}$ | Gate Source Threshold Voltage Differential Change with Temperature (Note 4) | | 100 | $\mu\text{V}/^\circ\text{C}$ | $V_{DS} = -15\text{V}, I_D = -500\mu\text{A}$ $T = +25^\circ\text{C}$ to $+125^\circ\text{C}$ |

NOTES:

1. Per transistor
2. Approximately doubles for every 10°C increase in T_A .

3. Pulse test duration = 300 μsec ; duty cycle $\leq 3\%$.
4. Measured at end points, T_A and T_B .

FEATURES

- $I_R = 0.1 \text{ pA}$ (typical)
- $BV_R > 30 \text{ V}$
- $C_{rss} = 0.75 \text{ pF}$ (typical)

1

GENERAL DESCRIPTION

The ID100 and ID101 are monolithic dual diodes intended for use in applications requiring extremely low leakage currents. Applications include interstage coupling with reverse isolation, signal clipping and clamping and protection of ultra low leakage FET differential dual and operational amplifiers.

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|---|
| Diode Reverse Voltage | 30V |
| Diode to Diode Voltage | $\pm 50\text{V}$ |
| Forward Current | 20 mA |
| Reverse Current | 100 μA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/ $^\circ\text{C}$ |

PIN CONFIGURATIONS

TO-71
TO-78

*These leads must not be tied together nor connected to the circuit in any way.

CHIP TOPOGRAPHY

ORDERING INFORMATION*

| | | | |
|-------|-------|---------|---------|
| TO78 | TO71 | WAFER | CHIP |
| ID100 | ID101 | ID100/W | ID100/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise noted)

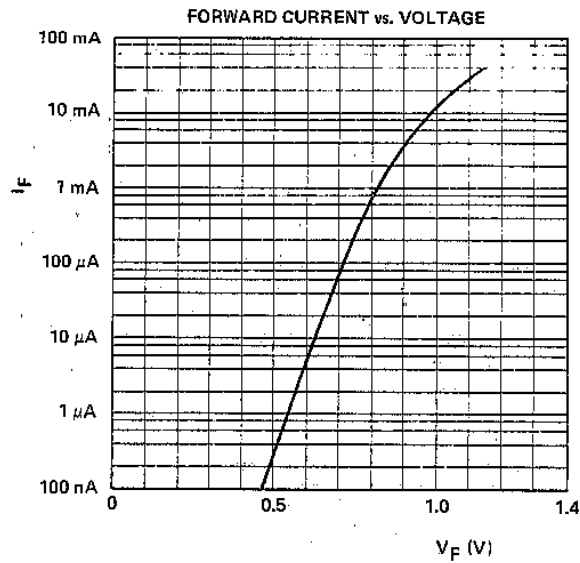
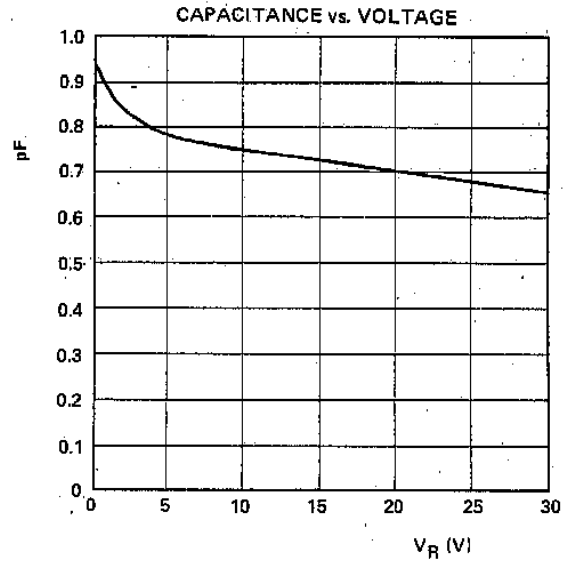
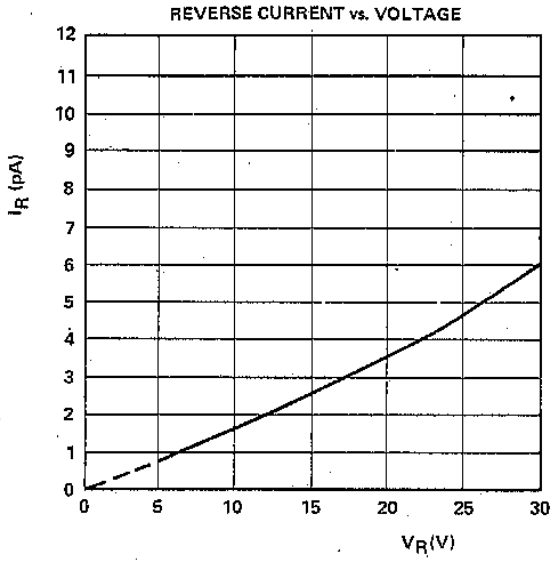
| PARAMETER | ID100, ID101 | | | UNITS | TEST CONDITIONS | |
|---------------------|------------------------------|---------------------------|------|-------|-----------------|---|
| | MIN. | TYP. | MAX. | | | |
| V_F | Forward Voltage Drop | 0.8 | | 1.1 | V | $I_F = 10 \text{ mA}$ |
| BV_R | Reverse Breakdown Voltage | 30 | | | V | $I_R = 1 \mu\text{A}$ |
| I_R | Reverse Leakage Current | | 0.1 | | pA | $V_R = 1 \text{ V}$ |
| | | | 2.0 | 10 | nA | $V_R = 10 \text{ V}$ |
| | | $T_A = 125^\circ\text{C}$ | | | | |
| $ I_{R1} - I_{R2} $ | Differential Leakage Current | | | 3 | pA | |
| C_{rss} | Total Reverse Capacitance | | 0.75 | 1 | pF | $V_R = 10 \text{ V}, f = 1 \text{ MHz}$ |

ID100, ID101



TYPICAL CHARACTERISTICS OF ID100/ID101

1



IT100, IT101 P-Channel JFET

1

FEATURES

- Interfaces Directly w/T²L Logic Elements
- $r_{DS(on)} < 75\Omega$ for 5V Logic Drive
- $I_{D(off)} < 100 \text{ pA}$

GENERAL DESCRIPTION

This P-channel JFET has been designed to directly interface with T²L logic, thus eliminating the need for costly drivers, in analog gate circuitry. Bipolar inputs of $\pm 15 \text{ V}$ can be switched. The FET is OFF for hi level inputs ($+5 \text{ V}$ or $+15 \text{ V}$) and ON for low level inputs ($< 0.5 \text{ V}$ for IT100; $< 1.5 \text{ V}$ for IT101).

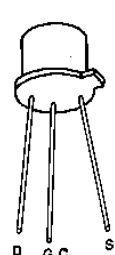
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ \text{C}$ unless otherwise noted)

| | |
|---|---|
| Gate-Source Voltage | 35V |
| Gate-Drain Voltage | 35V |
| Gate Current | 50mA |
| Storage Temperature Range | -65°C to $+200^\circ \text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ \text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ \text{C}$ |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/ $^\circ \text{C}$ |

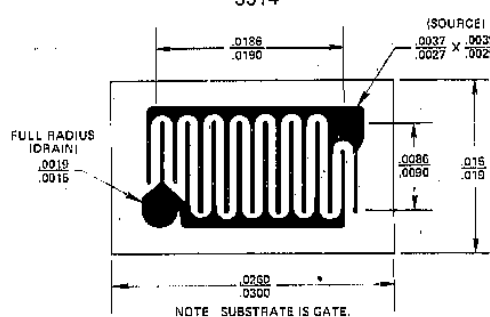
PIN CONFIGURATION

TO-18



CHIP TOPOGRAPHY

5514



NOTE: SUBSTRATE IS GATE.

ORDERING INFORMATION*

| TO-18 | WAFER | DICE |
|-------|---------|---------|
| IT100 | IT100/W | IT100/D |
| IT101 | IT101/W | IT101/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | | IT100 | | IT101 | | UNIT | TEST CONDITIONS |
|--------------|-------------------------------|-------|------|-------|------|----------|---|
| | | MIN | MAX | MIN | MAX | | |
| I_{DSS} | Drain Current | -10 | | -20 | | mA | $V_{GS} = 0, V_{DS} = -15 \text{ V}$ |
| V_p | Pinch Off Voltage | 2 | 4.5 | 4 | 10 | V | $I_D = 1 \text{ nA}, V_{DS} = -15 \text{ V}$ |
| BV_{GSS} | Gate-Source Breakdown Voltage | 35 | | 35 | | | $I_G = 1 \mu\text{A}, V_{DS} = 0$ |
| I_{GSSR} | Gate Reverse Current | | 200 | | 200 | pA | $V_{GS} = 20 \text{ V}, V_{DS} = 0$ |
| g_{fs} | Transconductance | 8 | | 8 | | mmho | $V_{GS} = 0, V_{DS} = -15 \text{ V}$ |
| g_{os} | Output Conductance | | 1 | | 1 | | |
| $I_{D(off)}$ | Drain (OFF) Leakage | | -100 | | -100 | pA | $V_{DS} = -10 \text{ V}, V_{GS} = 15 \text{ V}$ |
| $r_{DS(on)}$ | Drain-Source "ON" Resistance | | 75 | | 60 | Ω | $V_{GS} = 0, V_{DS} = -0.1 \text{ V}$ |
| C_{iss} | Input Capacitance | | 35 | | 35 | pF | $V_{DG} = -20 \text{ V}, V_{GS} = 0$ |
| C_{rss} | Reverse Transfer Capacitance | | 12 | | 12 | | $V_{DG} = -10 \text{ V}, I_S = 0$ |

IT120-IT122 Monolithic Dual NPN Transistor

FEATURES

- High h_{FE} at Low Current
- Low Output Capacitance
- Good Matching
- Tight V_{BE} Tracking

ABSOLUTE MAXIMUM RATINGS

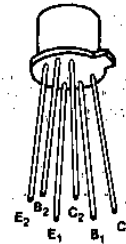
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--------------------------------------|---|
| Collector-Base Voltage (Note 1) | 45V |
| Collector-Emitter Voltage (Note 1) | 45V |
| Emitter Base Voltage (Notes 1 and 2) | 7V |
| Collector Current (Note 1) | 50 mA |
| Collector-Collector Voltage | 60V |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec) | $+300^\circ\text{C}$ |

| | TO-71 | | TO-78 | |
|--------------------------|--------------------------|--------------------------|--------------------------|--------------------------|
| | ONE SIDE | BOTH SIDES | ONE SIDE | BOTH SIDES |
| Power | | | | |
| Dissipation ... | 400 mW | 750 mW | 300 mW | 500 mW |
| Derate Above | | | | |
| 25°C | 1.7 mW/ $^\circ\text{C}$ | 2.9 mW/ $^\circ\text{C}$ | 2.3 mW/ $^\circ\text{C}$ | 4.3 mW/ $^\circ\text{C}$ |

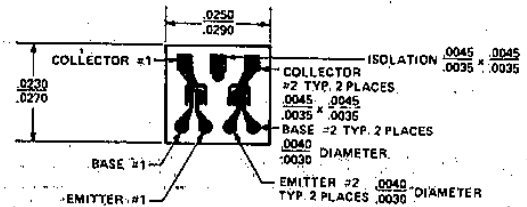
PIN CONFIGURATION

TO-71
TO-78



CHIP TOPOGRAPHY

4003



ORDERING INFORMATION*

| TO-78 | TO-71 | WAFER | DICE |
|-------|------------|---------|---------|
| IT120 | IT120-TO71 | IT120/W | IT120/D |
| IT121 | IT121-TO71 | IT121/W | IT121/D |
| IT122 | IT122-TO71 | IT122/W | IT122/D |

ELECTRICAL CHARACTERISTICS

(25°C unless otherwise noted)

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | | IT120A | | IT120 | | IT121 | | IT122 | | UNIT | TEST CONDITIONS |
|--------------------------------------|---|----------------------------|-----|-------|-----|-------|-----|-------|-----|------------------------------|---|
| | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | |
| h_{FE} | DC Current Gain | | 200 | | 200 | | 80 | | 80 | | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| | | | 225 | | 225 | | 100 | | 100 | | $I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$ |
| | | $T_A = -55^\circ\text{C}$ | 75 | | 75 | | 30 | | 30 | | |
| $V_{BE(ON)}$ | Emitter-Base On Voltage | | 0.7 | | 0.7 | | 0.7 | | 0.7 | V | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| $V_{CE(SAT)}$ | Collector Saturation Voltage | | 0.5 | | 0.5 | | 0.5 | | 0.5 | V | $I_C = 0.5 \text{ mA}, I_B = 0.05 \text{ mA}$ |
| I_{CBO} | Collector Cutoff Current | | 1.0 | | 1.0 | | 1.0 | | 1.0 | nA | $I_E = 0, V_{CB} = 45 \text{ V}$ |
| | | $T_A = +150^\circ\text{C}$ | 10 | | 10 | | 10 | | 10 | μA | |
| I_{EBO} | Emitter Cutoff Current | | 1.0 | | 1.0 | | 1.0 | | 1.0 | nA | $I_C = 0, V_{EB} = 5.0 \text{ V}$ |
| C_{obo} | Output Capacitance | | 2.0 | | 2.0 | | 2.0 | | 2.0 | pF | $I_E = 0, V_{CB} = 5.0 \text{ V}, f = 1 \text{ MHz}$ |
| C_{te} | Emitter Transition Capacitance | | 2.5 | | 2.5 | | 2.5 | | 2.5 | pF | $I_C = 0, V_{EB} = 0.5 \text{ V}, V_{CC} = 0$ |
| $C_{C1, C2}$ | Collector to Collector Capacitance | | 4.0 | | 4.0 | | 4.0 | | 4.0 | pF | $V_{CC} = 0$ |
| $I_{C1, C2}$ | Collector to Collector Leakage Current | | 10 | | 10 | | 10 | | 10 | nA | $V_{CC} = \pm 60 \text{ V}$ |
| $V_{CEO(SUST)}$ | Collector to Emitter Sustaining Voltage | 45 | | 45 | | 45 | | 45 | | V | $I_C = 1.0 \text{ mA}, I_B = 0$ |
| GBW | Current Gain Bandwidth Product | 10 | | 10 | | 7 | | 7 | | MHz | $I_C = 10 \mu\text{A}, V_{CE} = 5 \text{ V}$ |
| | | 220 | | 220 | | 180 | | 180 | | MHz | $I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V}$ |
| $ V_{BE1} - V_{BE2} $ | Base-Emitter Voltage Differential | | 1 | | 2 | | 3 | | 5 | mV | |
| $ I_{B1} - I_{B2} $ | Base Current Differential | | 2.5 | | 5 | | 25 | | 25 | nA | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| $\Delta(V_{BE1} - V_{BE2})/\Delta T$ | Base-Emitter Voltage Differential Change with Temperature | | 3 | | 5 | | 10 | | 20 | $\mu\text{V}/^\circ\text{C}$ | $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |

NOTES: 1. Per transistor.

2. The reverse base-to-emitter voltage must never exceed 7.0 volts and the reverse base-to-emitter current must never exceed 10 μA .

IT124

Monolithic Dual Super-Beta NPN Transistor

1

FEATURES

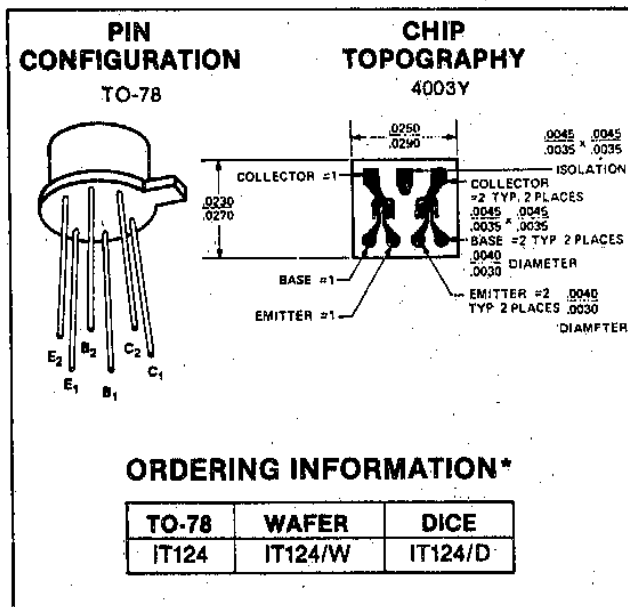
- Very High Gain
- Low Output Capacitance
- Tight V_{BE} Matching
- High GBW

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--------------------------------------|---|
| Collector-Base Voltage (Note 1) | 2V |
| Collector-Emitter Voltage (Note 1) | 2V |
| Emitter-Base Voltage (Notes 1 and 2) | 7V |
| Collector-Current (Note 1) | 10 mA |
| Collector-Collector Voltage | 100V |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec) | $+300^\circ\text{C}$ |

| | | |
|---------------------------------|--------------------------|--------------------------|
| | TO-78 | |
| | ONE SIDE | BOTH SIDES |
| Power Dissipation | 300 mW | 500 mW |
| Derate above 25°C | 1.7 mW/ $^\circ\text{C}$ | 4.3 mW/ $^\circ\text{C}$ |



*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS | CONDITIONS |
|---------------------|--|----------------------------------|-----|-------|---|
| h_{FE} | DC Current Gain | 1500 | | | $I_C = 1\mu\text{A}, V_{CE} = 1\text{V}$ |
| | | $T_A = -55^\circ\text{C}$ 600 | | | $I_C = 10\mu\text{A}, V_{CE} = 1\text{V}$ |
| $V_{BE(ON)}$ | Emitter-Base "ON" Voltage | | 0.7 | V | $I_C = 1\text{mA}, I_B = 0.1\text{mA}$ |
| $V_{CE(SAT)}$ | Collector Saturation Voltage | | 0.5 | | $I_C = 1\text{mA}, I_B = 0.1\text{mA}$ |
| I_{CBO} | Collector Cutoff Current | | 100 | pA | $I_E = 0, V_{CB} = 1\text{V}$ |
| | | | 100 | nA | $T_A = +150^\circ\text{C}$ |
| I_{EBO} | Emitter Cutoff Current | | 100 | pA | $I_C = 0, V_{EB} = 5\text{V}$ |
| C_{obo} | Output Capacitance | | 0.8 | pF | $I_E = 0, V_{CB} = 1\text{V}$ |
| C_{te} | Emitter Transition Capacitance | | 1.0 | | $I_C = 0, V_{EB} = 0.5\text{V}$ |
| C_{C1C2} | Collector to Collector Capacitance | | 0.8 | | $V_{CC} = 0$ |
| I_{C1C2} | Collector to Collector Leakage Current | | 250 | pA | $V_{CC} = \pm 50\text{V}$ |
| GBW | Current Gain Bandwidth Product | 10 | | MHz | $I_C = 10\mu\text{A}, V_{CE} = 1\text{V}$ |
| | | 100 | | | $I_C = 100\mu\text{A}, V_{CE} = 1\text{V}$ |
| NF | Narrow Band Noise Figure | | 3 | dB | $I_C = 10\mu\text{A}, V_{CE} = 3\text{V}$, $f = 1\text{KHz}, R_G = 10\text{Kohms}$, $BW = 200\text{Hz}$ |
| BV_{CBO} | Collector-Base Breakdown Voltage | 2 | | V | $I_C = 10\mu\text{A}, I_E = 0$ |
| BV_{EBO} (Note 2) | Emitter-Base Breakdown Voltage | 7 | | | $I_E = 10\mu\text{A}, I_C = 0$ |
| $V_{CEO(SUST)}$ | Collector-Emitter Sustaining Voltage | 2 | | | $I_C = 1\text{mA}, I_B = 0$ |

MATCHING CHARACTERISTICS @ 25°C (unless otherwise noted)

| SYMBOL | PARAMETER | TYP | MAX | UNITS | CONDITIONS |
|---------------------------------------|---|-----|-----|------------------------------|--|
| $ V_{BE1} - V_{BE2} $ | Base Emitter Voltage Differential | 2 | 5 | mV | $I_C = 10\mu\text{A}, V_{CE} = 1\text{V}$ |
| $\Delta (V_{BE1} - V_{BE2})/\Delta T$ | Base Emitter Voltage Differential Change with Temperature | 5 | 15 | $\mu\text{V}/^\circ\text{C}$ | $I_C = 10\mu\text{A}, V_{CE} = 1\text{V}$ $T = -55^\circ\text{C}$ to $+125^\circ\text{C}$ |
| $ I_{B1} - I_{B2} $ | Base Current Differential | | .6 | nA | $T_C = 10\mu\text{A}, V_{CE} = 1\text{V}$ |

NOTES:

1. Per transistor.
2. The reverse base-to-emitter voltage must never exceed 7.0 volts and the reverse base-to-emitter current must never exceed $10\mu\text{A}$.



IT126-IT129 Monolithic Dual NPN Transistor

FEATURES

- High Gain at Low Current
- Low Output Capacitance
- Tight I_B Match
- Tight V_{BE} Tracking
- Dielectric Isolated Matched Pairs for Differential Amplifiers

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise specified)

| | |
|---------------------------------|-----|
| Collector-Base Voltage (Note 1) | |
| IT126, IT127 | 60V |
| IT128 | 55V |
| IT129 | 45V |

| | |
|------------------------------------|-----|
| Collector-Emitter Voltage (Note 1) | |
| IT126, IT127 | 60V |
| IT128 | 55V |
| IT129 | 45V |

Emitter-Base Voltage (Notes 1 and 2) 7.0V

Collector Current (Note 1) 100 mA

Collector-Collector Voltage 70V

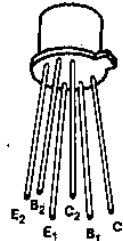
Storage Temperature Range -65°C to $+200^\circ\text{C}$

Operating Temperature Range -55°C to $+150^\circ\text{C}$

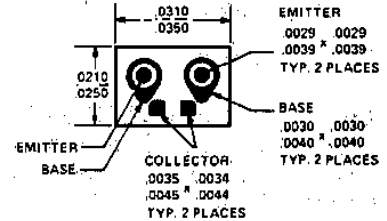
Lead Temperature (Soldering, 10 sec.) $+300^\circ\text{C}$

| Power Dissipation Total Dissipation at 25°C Cast Temperature Derating Factor | TO71 | | TO78 | |
|---|--------------------------|--------------------------|--------------------------|--------------------------|
| | One Side | Both Sides | One Side | Both Sides |
| | 0.3 Watt | 0.5 Watt | 0.4 Watt | 0.75 Watt |
| | 1.7 mW/ $^\circ\text{C}$ | 2.9 mW/ $^\circ\text{C}$ | 2.5 mW/ $^\circ\text{C}$ | 4.3 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION



CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO78 | TO-71 | WAFER | DICE |
|-------|------------|---------|---------|
| IT126 | IT126-TO71 | IT126/W | IT126/D |
| IT127 | IT127-TO71 | IT127/W | IT127/D |
| IT128 | IT128-TO71 | IT128/W | IT128/D |
| IT129 | IT129-TO71 | IT129/W | IT129/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | IT126 | | IT127 | | IT128 | | IT129 | | UNITS | CONDITIONS |
|--|----------------------------|-----|-----------|-----|-----------|-----|-----------|-----|------------------------------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | |
| h_{FE} DC Current Gain | | 150 | 150 | | 100 | | 70 | | | $I_C = 10 \mu\text{A}, V_{CE} = 5\text{V}$ |
| | | 200 | 800 | 200 | 800 | 150 | 800 | 100 | | $I_C = 1.0 \text{ mA}, V_{CE} = 5\text{V}$ |
| | | 230 | | 230 | | 170 | | 115 | | $I_C = 10 \text{ mA}, V_{CE} = 5\text{V}$ |
| | | 100 | | 100 | | 75 | | 50 | | $I_C = 50 \text{ mA}, V_{CE} = 5\text{V}$ |
| | $T_A = -55^\circ\text{C}$ | 75 | | 75 | | 60 | | 40 | | $I_C = 1 \text{ mA}, V_{CE} = 5\text{V}$ |
| $V_{BE(on)}$ Emitter-Base On Voltage | | .9 | .9 | | .9 | | .9 | | V | $I_C = 10 \text{ mA}, V_{CE} = 5\text{V}$ |
| $V_{CE(sat)}$ Collector Saturation Voltage | | 1.0 | 1.0 | | 1.0 | | 1.0 | | | $I_C = 50 \text{ mA}, V_{CE} = 5\text{V}$ |
| | | .3 | .3 | | .3 | | .3 | | | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$ |
| I_{CBO} Collector Cutoff Current | | 1.0 | 1.0 | | 1.0 | | 1.0 | | nA | $I_E = 0, V_{CB} = 45\text{V}, 30\text{V}^*$ |
| | $T_A = +150^\circ\text{C}$ | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 | μA | |
| I_{EBO} Emitter Cutoff Current | | 0.1 | 0.1 | | 0.1 | | 0.1 | | nA | $I_C = 0, V_{EB} = 5\text{V}$ |
| C_{obo} Output Capacitance | | 3 | 3 | | 3 | | 3 | | pF | $I_E = 0, V_{CB} = 20\text{V}$ |
| $BV_{C_1C_2}$ Collector to Collector Breakdown Voltage | ± 100 | | ± 100 | | ± 100 | | ± 100 | | V | $I_C = \pm 1 \mu\text{A}$ |
| $V_{CEO(sust)}$ Collector to Emitter Sustaining Voltage | 60 | | 60 | | 55 | | 45 | | | $I_C = 1 \text{ mA}, I_B = 0$ |
| BV_{CBO} Collector Base Breakdown Voltage | 60 | | 60 | | 55 | | 45 | | | $I_C = 10 \mu\text{A}, I_E = 0$ |
| BV_{EBO} Emitter Base Breakdown Voltage | 7 | | 7 | | 7 | | 7 | | | $I_E = 10 \mu\text{A}, I_C = 0$ |
| MATCHING CHARACTERISTICS | | | | | | | | | | |
| $ V_{BE1} - V_{BE2} $ Base Emitter Voltage Differential | | 1 | 2 | | 3 | | 5 | | mV | $I_C = 1 \text{ mA}, V_{CE} = 5\text{V}$ |
| $\Delta(V_{BE1} - V_{BE2})/\Delta T$ Base Emitter Voltage Differential Change with Temperature | | 3 | 5 | | 10 | | 20 | | $\mu\text{V}/^\circ\text{C}$ | $I_C = 1 \text{ mA}, V_{CE} = 5\text{V}$ $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ |
| $ B_1 - B_2 $ Base Current Differential | | 2.5 | 5 | | 10 | | 20 | | nA | $I_C = 10 \mu\text{A}, V_{CE} = 5\text{V}$ |
| | | .25 | .5 | | 1.0 | | 2.0 | | μA | $I_C = 1 \text{ mA}, V_{CE} = 5\text{V}$ |

NOTES:

1. Per transistor.
2. The reverse base-to-emitter voltage must never exceed 7.0 volts and the reverse base-to-emitter current must never exceed $10 \mu\text{A}$.

1

IT130-IT132 Monolithic Dual PNP Transistor

FEATURES

- High h_{FE} at Low Current
- Low Output Capacitance
- Tight I_B Match
- Tight V_{BE} Tracking

ABSOLUTE MAXIMUM RATINGS

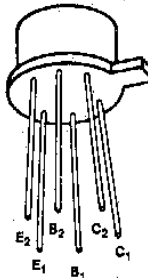
($T_A = 25^\circ\text{C}$ unless otherwise specified)

| | |
|--------------------------------------|---|
| Collector-Base Voltage (Note 1) | 45V |
| Collector-Emitter Voltage (Note 1) | 45V |
| Emitter-Base Voltage (Notes 1 and 2) | 7V |
| Collector Current (Note 1) | 50 mA |
| Collector-Collector Voltage | 60V |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec) | $+300^\circ\text{C}$ |

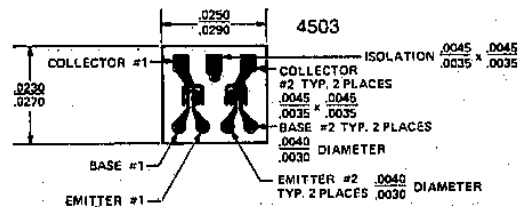
| | TO-71 | | TO-78 | |
|-------------|--------------------------|--------------------------|--------------------------|--------------------------|
| | ONE SIDE | BOTH SIDES | ONE SIDE | BOTH SIDES |
| Power | 400 mW | 750 mW | 300 mW | 500 mW |
| Dissipation | 2.3 mW/ $^\circ\text{C}$ | 4.3 mW/ $^\circ\text{C}$ | 1.7 mW/ $^\circ\text{C}$ | 4.3 mW/ $^\circ\text{C}$ |

PIN CONFIGURATIONS

TO-71
TO-78



CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-78 | TO-71 | WAFER | DICE |
|--------|-------------|----------|----------|
| IT130A | IT130A-TO71 | IT130A/W | IT130A/D |
| IT130 | IT130-TO71 | IT130/W | IT130/D |
| IT131 | IT131-TO71 | IT131/W | IT131/D |
| IT132 | IT132-TO71 | IT132/W | IT132/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | IT130A | | IT130 | | IT131 | | IT132 | | UNIT | TEST CONDITIONS |
|--------------------------------------|---|-----|----------------------------|------|-------|------|-------|------|------------------------------|---|
| | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | |
| h_{FE} | DC Current Gain | 200 | | 200 | | 80 | | 80 | | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| | | 225 | | 225 | | 100 | | 100 | | $I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$ |
| | | | $T_A = -55^\circ\text{C}$ | 75 | | 75 | | 30 | | 30 |
| $V_{BE(ON)}$ | Emitter-Base On Voltage | | | 0.7 | 0.7 | 0.7 | 0.7 | 0.7 | V | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| $V_{CE(SAT)}$ | Collector Saturation Voltage | | | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | | $I_C = 0.5 \text{ mA}, I_B = 0.05 \text{ mA}$ |
| I_{CBO} | Collector Cutoff Current | | -1.0 | -1.0 | -1.0 | -1.0 | -1.0 | -1.0 | nA | $I_E = 0, V_{CB} = 45 \text{ V}$ |
| | | | $T_A = +150^\circ\text{C}$ | -10 | -10 | -10 | -10 | -10 | μA | |
| I_{EBO} | Emitter Cutoff Current | | | -1.0 | -1.0 | -1.0 | -1.0 | -1.0 | nA | $I_C = 0, V_{EB} = 5.0 \text{ V}$ |
| C_{ob} | Output Capacitance | | | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | pF | $I_E = 0, V_{CB} = 5.0 \text{ V}$ |
| C_{te} | Emitter Transition Capacitance | | | 2.5 | 2.5 | 2.5 | 2.5 | 2.5 | pF | $I_C = 0, V_{EB} = 0.5 \text{ V}$ |
| C_{C1-C2} | Collector to Collector Capacitance | | | 4.0 | 4.0 | 4.0 | 4.0 | 4.0 | | $V_{CC} = 0$ |
| I_{C1-C2} | Collector to Collector Leakage Current | | | 10 | 10 | 10 | 10 | 10 | nA | $V_{CC} = \pm 60 \text{ V}$ |
| $V_{CEO(SUST)}$ | Collector to Emitter Sustaining Voltage | | -45 | | -45 | | -45 | | V | $I_C = 1.0 \text{ mA}, I_B = 0$ |
| GBW | Current Gain Bandwidth Product | | 5 | 5 | 4 | 4 | 4 | 4 | MHZ | $I_C = 10 \mu\text{A}, V_{CE} = 5 \text{ V}$ |
| | | | 110 | 110 | 90 | 90 | 90 | 90 | | $I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V}$ |
| $ V_{BE1} - V_{BE2} $ | Base-Emitter Voltage Differential | | | 1 | 2 | 3 | 5 | 5 | mV | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| $ I_{B1} - I_{B2} $ | Base Current Differential | | | 2.5 | 5 | 25 | 25 | 25 | nA | $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |
| $\Delta(V_{BE1} - V_{BE2})/\Delta T$ | Base-Emitter Voltage Differential Change with Temperature | | | 3 | 5 | 10 | 20 | 20 | $\mu\text{V}/^\circ\text{C}$ | $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ $I_C = 10 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ |

NOTES:

1. Per transistor.
2. The reverse base-to-emitter voltage must never exceed 7.0V, and the reverse base-to-emitter current must never exceed 10 μA .

IT136-IT139 Monolithic Dual PNP Transistor

FEATURES

- High Gain at Low Current
- Low Output Capacitance
- Tight I_B Match
- Tight V_{BE} Tracking
- Dielectrically Isolated Matched Pairs for Differential Amplifiers

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Collector-Base Voltage (Note 1)

| | |
|--------------|-----|
| IT136, IT137 | 60V |
| IT138 | 55V |
| IT139 | 45V |

Collector-Emitter Voltage (Note 1)

| | |
|--------------|-----|
| IT136, IT137 | 60V |
| IT138 | 55V |
| IT139 | 45V |

Emitter-Base Voltage (Notes 1 and 2)

Collector Current (Note 1)

Collector-Collector Voltage

Storage Temperature Range

Operating Temperature Range

Lead Temperature (Soldering, 10-sec.)

TO78

| | | |
|--|-------------|---------------|
| | ONE SIDE | BOTH SIDES |
|--|-------------|---------------|

Power Dissipation 0.4 Watt 0.75 Watt

Derate above 25°C 2.3 mW/ $^\circ\text{C}$ 4.3 mW/ $^\circ\text{C}$

TO71

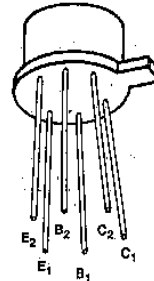
| | | |
|--|-------------|---------------|
| | ONE SIDE | BOTH SIDES |
|--|-------------|---------------|

Power Dissipation 0.3 Watt 0.5 Watt

Derate above 25°C 1.7 mW/ $^\circ\text{C}$ 2.9 mW/ $^\circ\text{C}$

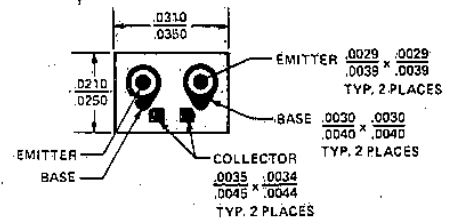
PIN CONFIGURATION

TO-71
TO-78



4501

CHIP TOPOGRAPHY



ORDERING INFORMATION*

| TO-78 | TO-71 | WAFER | DICE |
|-------|------------|---------|---------|
| IT136 | IT136-TO71 | IT136/W | IT136/D |
| IT137 | IT137-TO71 | IT137/W | IT137/D |
| IT138 | IT138-TO71 | IT138/W | IT138/D |
| IT139 | IT139-TO71 | IT139/W | IT139/D |

*When ordering wafer/dice refer to Appendix B-23.

1

ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise noted)

1

| PARAMETER | | IT136 | | IT137 | | IT138 | | IT139 | | UNITS | CONDITIONS | |
|--|---|-------|-----|-------|-----|-------|-----|-------|------|-------|---|---|
| | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | | |
| h _{FE} | DC Current Gain | | | 150 | | 100 | | 70 | | | I _C = 10 μA, V _{CE} = 5V | |
| | | | | 150 | 800 | 150 | 800 | 100 | 800 | 70 | 800 | I _C = 1.0 mA, V _{CE} = 5V |
| | | | | 125 | | 125 | | 80 | | 50 | | I _C = 10 mA, V _{CE} = 5V |
| | | | | 65 | | 60 | | 40 | | 25 | | I _C = 50 mA, V _{CE} = 5V |
| | T _A = 55°C | 75 | | 75 | | 60 | | 40 | | | I _C = 1 mA, V _{CE} = 5V | |
| V _{BE(on)} | Emitter - Base On Voltage | | .9 | | .9 | | .9 | | .9 | V | I _C = 10 mA, V _{CE} = 5V | |
| | | | 1.0 | | 1.0 | | 1.0 | | 1.0 | | I _C = 50 mA, V _{CE} = 5V | |
| V _{CE(sat)} | Collector Saturation Voltage | | .3 | | .3 | | .3 | | .3 | | I _C = 1 mA, I _B = .1 mA | |
| | | | .6 | | .6 | | .6 | | .6 | | I _C = 10 mA, I _B = 1 mA | |
| I _{CBO} | Collector Cutoff Current | | 0.1 | | 0.1 | | 0.1 | | 0.1* | nA | I _E = 0, V _{CB} = 45V, 30V* | |
| | T _A = +150°C | | 1.1 | | 0.1 | | 0.1 | | 0.1* | | | μA |
| I _{EBO} | Emitter Cutoff Current | | 0.1 | | 0.1 | | 0.1 | | 0.1 | nA | I _C = 0, V _{EB} = 5V | |
| C _{obo} | Output Capacitance | | 3 | | 3 | | 3 | | 3 | pF | I _E = 0, V _{CB} = 20V, f = 1 MHz | |
| PARAMETERS | | IT136 | | IT137 | | IT138 | | IT139 | | UNITS | CONDITIONS | |
| | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | | |
| BV _{C₁C₂} | Collector to Collector Breakdown Voltage | ± 100 | | ± 100 | | ± 100 | | ± 100 | | V | I _C = ±1 μA | |
| V _{CEO(sust)} | Collector to Emitter Sustaining Voltage | 60 | | 60 | | 55 | | 45 | | | I _C = 1 mA, I _B = 0 | |
| BV _{CBO} | Collector Base Breakdown Voltage | 60 | | 60 | | 55 | | 45 | | | I _C = 10 μA, I _E = 0 | |
| BV _{EBO} | Emitter Base Breakdown Voltage | 7 | | 7 | | 7 | | 7 | | | I _E = 10 μA, I _C = 0 | |
| PARAMETERS | | IT136 | | IT137 | | IT138 | | IT139 | | UNITS | CONDITIONS | |
| | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | | | |
| V _{BE₁} - V _{BE₂} | Base Emitter Voltage Differential | | 1 | | 2 | | 3 | | 5 | mV | I _C = 1 mA, V _{CE} = 5V | |
| Δ V _{BE₁} - V _{BE₂} ΔT | Base Emitter Voltage Differential Change with Temperature | | 3 | | 5 | | 10 | | 20 | μV/°C | I _C = 1 mA, V _{CE} = 5V T _A = -55°C to +125°C | |
| I _{B₁} - I _{B₂} | Base Current Differential | | 2.5 | | 5 | | 10 | | 20 | nA | I _C = 10 μA, V _{CE} = 5V | |
| | | | .25 | | .5 | | 1.0 | | 2.0 | μA | I _C = 1 mA, V _{CE} = 5V | |

NOTES: 1. Per transistor.
 2. The reverse base-to-emitter voltage must never exceed 7.0 volts and the reverse base-to-emitter current must never exceed 10μA



IT500-IT505 Monolithic Dual Cascoded N-Channel JFET

FEATURES

- $CMRR > 120$ dB
- $I_G < 5$ pA @ 50V_{DG}
- $C_{rss} < 0.5$ pF
- $g_{os} > .025$ μ mhos

ABSOLUTE MAXIMUM RATINGS

(T_A = 25° C unless otherwise specified)

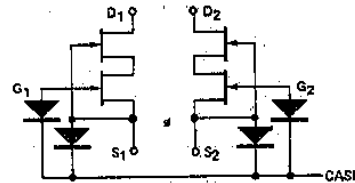
| | |
|---|-------------------|
| Drain-Source and Drain-Gate Voltages (Note 1) | 60V |
| Drain Current (Note 1) | 50 mA |
| Gate-Gate Voltage | ±60V |
| Storage Temperature | -65° C to +200° C |
| Operating Temperature | -55° C to +150° C |
| Lead Temperature (Soldering, 10 sec.) | +300° C |

| | | |
|--------------------|-----------------|-------------------|
| | ONE SIDE | BOTH SIDES |
| Power Dissipation | 250 mW | 500 mW |
| Derate above 25° C | 3.8 mW/° C | 7.7 mW/° C |

GENERAL DESCRIPTION

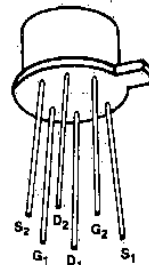
A low noise, low leakage FET that employs a cascode structure to accomplish very low I_G at high voltage levels, while giving high transconductance and very high common mode rejection ratio.

1

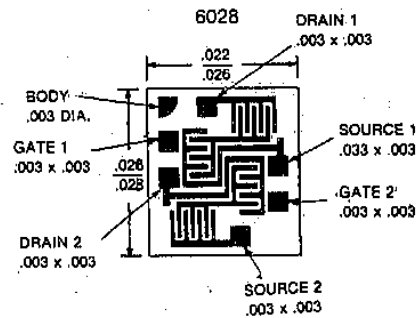


PIN CONFIGURATION

TO-71
low profile



CHIP TOPOGRAPHY (Note 2)



ORDERING INFORMATION*

| TO-78 | WAFER | DICE |
|-------|---------|---------|
| IT500 | IT500/W | IT500/D |
| IT501 | IT501/W | IT501/D |
| IT502 | IT502/W | IT502/D |
| IT503 | IT503/W | IT503/D |
| IT504 | IT504/W | IT504/D |
| IT505 | IT505/W | IT505/D |

NOTE 1. Per transistor.

NOTE 2. Due to the non-symmetrical structure of these devices, the drain and source ARE NOT interchangeable.

*When ordering wafer/dice refer to Appendix B-23.

1

| ELECTRICAL CHARACTERISTICS (@ 25°C unless otherwise specified) | | | | | | | | | | | | | |
|--|---|------|-------|---------------------------|--|--|--|--|--|--|--|--|--|
| Symbol | Characteristics | Min | Max | Unit | Test Conditions | | | | | | | | |
| I_{GSSR} | Gate Reverse Current | | -100 | pA | $V_{GS} = -20V, V_{DS} = 0$ | | | | | | | | |
| | | | -5 | nA | | | | | | | | | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -60 | | V | $I_G = -1 \mu A, V_{DS} = 0$ | | | | | | | | |
| $V_{GS} (off)$ | Gate-Source Cutoff Voltage | -0.7 | -4 | | | | | | | | | | |
| V_{GS} | Gate-Source Voltage | -0.2 | -3.8 | | | | | | | | | | |
| I_G | Gate Operating Current | | -5 | pA | $V_{DG} = 50V, I_D = 200 \mu A$ | | | | | | | | |
| | | | -5 | nA | | | | | | | | | |
| I_{DSS} | Saturation Drain Current (Note 1) | 0.7 | 7 | mA | $V_{DS} = 20V, V_{GS} = 0$ | | | | | | | | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 1000 | 4000 | μmho | $V_{DS} = 20V, V_{GS} = 0$ $V_{DG} = 20V, I_D = 200 \mu A$ $f = 1 kHz$ | | | | | | | | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | 700 | 1600 | | | | | | | | | | |
| g_{os} | Common-Source Output Conductance | | 1 | | | | | | | | | | |
| g_{os} | Common-Source Output Conductance | | 0.025 | | | | | | | | | | |
| C_{g1g2} | Gate to Gate Capacitance | | 3.5 | pF | $V_{G1} = V_{G2} = 10V$ | | | | | | | | |
| C_{iss} | Common-Source Input Capacitance | | 7 | pF | $V_{DS} = 20V, V_{GS} = 0$ $f = 1 MHz$ | | | | | | | | |
| C_{rss} | Common-Source Reverse Transfer Capacitance (Note 3) | | 0.5 | | | | | | | | | | |
| NF | Spot Noise Figure | | 0.5 | | | | | | | | | | |
| e_n | Equivalent Input Noise Voltage | | 0.035 | $\frac{\mu V}{\sqrt{Hz}}$ | $f = 100 Hz, R_G = 10 M\Omega$ $f = 10 Hz$ $f = 1 kHz$ | | | | | | | | |
| | | | 0.010 | $\frac{\mu V}{\sqrt{Hz}}$ | | | | | | | | | |

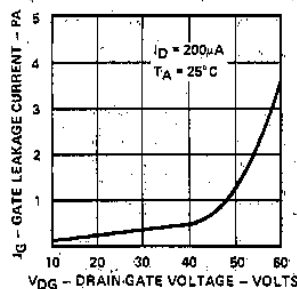
| Symbol | Characteristics | IT500 | | IT501 | | IT502 | | IT503 | | IT504 | | IT505 | | Unit | Test Conditions |
|---|---|-------|-----|-------|-----|-------|-----|-------|-----|-------|-----|-------|-----|------------------|---|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | |
| I_{G1}, I_{G2} | Differential Gate Current | | 5 | 5 | 5 | 5 | 5 | 5 | 5 | 10 | 15 | | | nA | $V_{DG} = 20V, I_D = 200 \mu A, +125^\circ C$ |
| I_{DSS1}, I_{DSS2} | Saturation Drain Current Ratio (Note 1) | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | 0.95 | 1 | 0.9 | 1 | 0.85 | 1 | | $V_{DS} = 20V, V_{GS} = 0V$ |
| g_{fs1}/g_{fs2} | Transconductance Ratio (Note 1) | 0.97 | 1 | 0.97 | 1 | 0.95 | 1 | 0.95 | 1 | 0.90 | 1 | 0.85 | 1 | | $f = 1 kHz$ |
| $V_{GS1} - V_{GS2}$ | Differential Gate-Source Voltage | | 5 | 5 | 10 | 15 | 25 | 50 | | | | | | mV | |
| $\frac{\Delta V_{GS1} - V_{GS2}}{\Delta T}$ | Gate-Source Differential Voltage Change with Temp. (Note 2) | | 5 | 10 | 20 | 40 | 100 | 200 | | | | | | $\mu V/^\circ C$ | $V_{DG} = 20V, I_D = 200 \mu A$ $T_A = 25^\circ C, T_B = 125^\circ C$ $T_A = -55^\circ C, T_B = 25^\circ C$ |
| C_{MRR}^{**} | Common Mode Rejection Ratio | 120 | | 120 | | 120 | | 120 | | 120 | | 120 | | dB | $\Delta V_{DD} = 10V, I_D = 200 \mu A$ |

** $C_{MRR} = 20 \log_{10} \frac{\Delta V_{DD}}{\Delta (V_{GS1} - V_{GS2})}, \Delta V_{DD} = 10 / -20V$

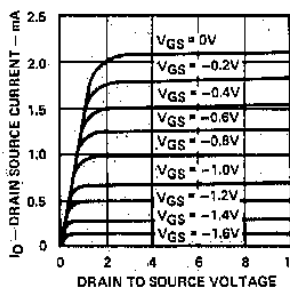
- NOTES: 1. Pulse test required, pulsewidth = 300 μs , duty cycle $\leq 3\%$.
 2. Measured at end points, T_A and T_B .
 3. With case guarded C_{rss} is typically $< 0.15 pF$.

TYPICAL PERFORMANCE CURVES

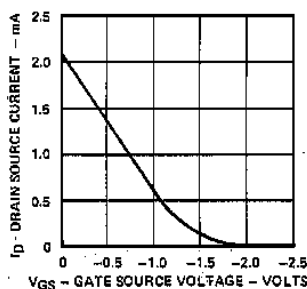
GATE LEAKAGE



OUTPUT CHARACTERISTICS



TYPICAL CAPACITANCE VS. GATE-SOURCE VOLTAGE



A050 Using the IT500 Family to Improve the Input Bias Current of BIFET OPAMPS

1

INTRODUCTION

The LF156 family of BIFET OPAMPS is very popular because of the combination of high slew rate (typically $12V/\mu s$ @ unity gain) and moderate offset voltage (about 2mV). Input bias current, however, varies directly with input voltage, rising from 30pA @ $V_{IN} = -10V$, to 50 pA @ $V_{IN} = 0V$, and finally to 80pA @ $V_{IN} = +10V$. This can be improved markedly by using one of the IT500 series to drive the inputs of the LF156.

The IT500, like the others in its family, is a dual cascoded n-channel JFET pair, featuring a typical input bias current of $<1pA$ with inputs ranging from -15V to +15V; actual I_B is guaranteed to be less than 5pA @ $V_{DG} = 50V$.

Figure 1 shows an IT500 being used to drive the inputs of an LF156. This greatly reduces the input bias current, and in no way affects the already superior slew rate; the offset voltage is not significantly degraded because of the excellent matching of the IT500.

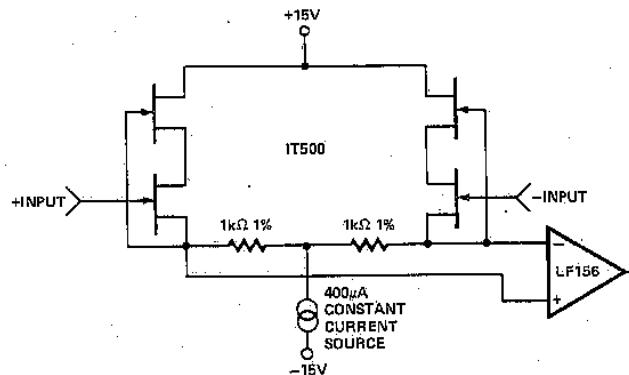


FIGURE 1. INPUT DRIVE CIRCUIT USING IT500

The constant current source can be designed with any transistor pair having a high beta @ $I_C = 400\mu A$. See Figure 2.

An added bonus of the IT500 is its CMRR $> 100dB$, compared to the LF156 CMRR of 85dB.

This configuration is ideal for electrometer circuits, with good measurement accuracy down to 10pA of input current ($< 10\%$ error with 10pA of input current). A $10M\Omega$ glass feedback resistor connected between the -INPUT and OPAMP OUTPUT does the trick. Other possible applications include sample and hold amplifiers, instrumentation amplifiers, etc.

Although this application note has dealt solely with the LF156, all present day BIFET OPAMPS exhibit the same I_{BIAS} vs. V_{IN} dependency, and all will benefit from using the IT500 as a preamplifier.

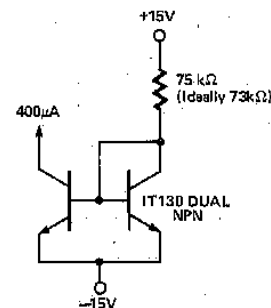


FIGURE 2. CONSTANT CURRENT SOURCE

1

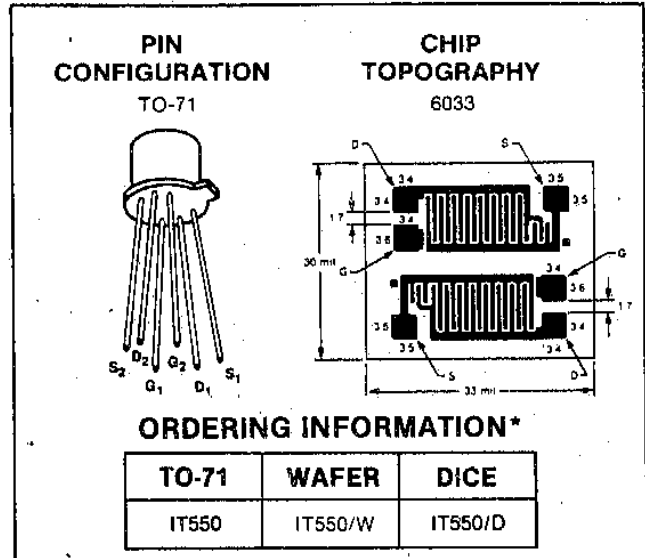
FEATURES

- Specified Matching Characteristics
- High Gain
- Low "ON" Resistance

ABSOLUTE MAXIMUM RATINGS

(25°C Unless otherwise noted)

| | | |
|---------------------------------------|-----------------|------------|
| Gate-Drain or Gate-Source Voltage | -40V | |
| Gate Current | 50 mA | |
| Gate-Gate Voltage | ±80V | |
| Storage Temperature Range | -65°C to +200°C | |
| Operating Temperature Range | -55°C to +150°C | |
| Lead Temperature (Soldering, 10 sec.) | +300°C | |
| Power Dissipation | One Side | Both Sides |
| | 325mW | 650mW |
| Derate above 25°C | 2.2mW/°C | 3.3mW/°C |



*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS (25°C unless otherwise noted)

| SYMBOL | PARAMETERS | TEST CONDITIONS | MIN. | MAX. | UNIT | |
|---------------|---|--|----------------------------------|--------------|------------------------|-----------|
| I_{GSSR} | Gate-Reverse Current | $V_{GS} = -20V, V_{DS} = 0$ $T_A = 150^\circ C$ | | -100 | pA | |
| | | | | -200 | mA | |
| BV_{GSS} | Gate-Source Breakdown Voltage | $I_G = -1\mu A, V_{DS} = 0$ | -40 | | V | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | $V_{DS} = 15V, I_D = 1nA$ | -0.5 | -3 | | |
| $V_{GS(f)}$ | Gate-Source Voltage | $V_{DS} = 0V, I_G = 2mA$ | | 1.0 | | |
| I_{DSS} | Saturation Drain Current (Note 1) | $V_{DS} = 15V, V_{GS} = 0$ | 5 | 30 | mA | |
| $r_{DS(on)}$ | Static Drain Source ON Resistance | $I_D = 1mA, V_{GS} = 0$ | | 100 | Ω | |
| g_{fs} | Common-Source Forward Transconductance (Note 1) | $V_{DG} = 15V, I_D = 2mA$ | $f = 1kHz$ | 7500 | 12,500 | μmho |
| g_{os} | | | Common-Source Output Conductance | $f = 100MHz$ | 7000 | |
| C_{rss} | Common-Source Reverse Transfer Capacitance | $f = 1kHz$ | | 45 | pF | |
| C_{iss} | Common-Source Input Capacitance | $f = 1MHz$ | | 3 | | |
| NF | Spot Noise Figure | $f = 10Hz, R_G = 1M$ | | 12 | dB | |
| e_n | Equivalent Short Circuit Input Noise Voltage | $f = 10Hz$ | | 50 | $\frac{nV}{\sqrt{Hz}}$ | |

| SYMBOL | PARAMETERS | CONDITIONS | IT550 | | UNIT |
|---|---|--|-------|------|------------------|
| | | | MIN. | MAX. | |
| $\frac{I_{DSS1}}{I_{DSS2}}$ | Saturation Drain Current Ratio (Notes 1 and 2) | $V_{DS} = 15V, V_{GS} = 0$ | 0.95 | 1 | — |
| $ V_{GS1} - V_{GS2} $ | Differential Gate-Source Voltage | $V_{DS} = 15V, I_D = 2mA$ | | 50 | mV |
| $\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$ | Gate-Source Voltage Differential Drift (Note 3) | $(T_A = -55^\circ C \text{ to } +125^\circ C)$ | | 100 | $\mu V/^\circ C$ |
| $\frac{g_{fs1}}{g_{fs2}}$ | Transconductance Ratio (Notes 1 and 2) | $V_{DS} = 15V, I_D = 2mA, f = 1kHz$ | 0.90 | 1 | — |

NOTES:

1. Pulse test required; pulse width 300 μs , duty cycle $\leq 3\%$.
2. Assumes smaller value in numerator
3. Measured at end points T_A and T_B

FEATURES

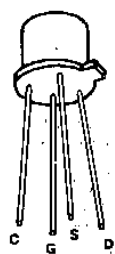
- Low ON-Resistance
- High Gain
- Low Noise Voltage
- High Input Impedance
- Low Leakage

ABSOLUTE MAXIMUM RATINGS

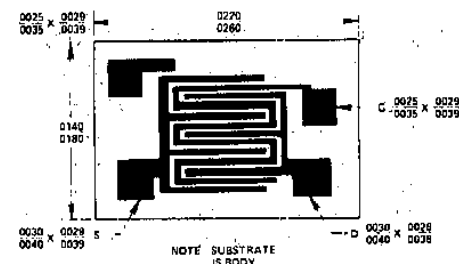
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--------------------------------------|---|
| Drain-Source and Gate-Source Voltage | -40 V |
| Peak Gate-Source Voltage (Note 1) | ± 125 V |
| Drain Current | 50 mA |
| Storage Temperature | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec) | $+300^\circ\text{C}$ |
| Power Dissipation | 375 mW |
| Derate above 25°C | 3 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION
TO-72



CHIP TOPOGRAPHY
1503



ORDERING INFORMATION*

| TO-72 | WAFER | DICE |
|--------|----------|----------|
| IT1700 | IT1700/W | IT1700/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted), $V_{BS} = 0$ unless otherwise noted.

| PARAMETER | MIN | MAX | UNITS | TEST CONDITIONS | |
|------------------------------|---|--------------|-------|------------------|---|
| BV_{DSS} | Drain to Source Breakdown Voltage | -40 | | V | $V_{GS} = 0, I_D = -10 \mu\text{A}$ |
| BV_{SDS} | Source to Drain Breakdown Voltage | -40 | | V | $V_{GS} = 0, I_D = -10 \mu\text{A}$ |
| I_{GSS} | Gate Leakage Current | (See note 2) | | | |
| I_{DSS} | Drain to Source Leakage Current | | 200 | μA | $V_{GS} = 0, V_{DS} = -20 \text{ V}$ |
| $I_{DSS}(150^\circ\text{C})$ | Drain to Source Leakage Current | | 0.4 | μA | |
| I_{SDS} | Source to Drain Leakage Current | | 400 | μA | |
| $I_{SDS}(150^\circ\text{C})$ | Source to Drain Leakage Current | | 0.8 | μA | |
| $V_{GS(th)}$ | Gate Threshold Voltage | -2 | -5 | V | $V_{GS} = V_{DS}, I_D = -10 \mu\text{A}$ |
| $r_{DS(on)}$ | Static Drain to Source "on" Resistance | | 400 | ohms | $V_{GS} = -10 \text{ V}, V_{DS} = 0$ |
| $I_{DS(on)}$ | Drain to Source "on" Current | 2 | | mA | $V_{GS} = -10 \text{ V}, V_{DS} = -15 \text{ V}$ |
| g_{fs} | Forward Transconductance Common Source | 2000 | 4000 | μmhos | $V_{DS} = -15 \text{ V}, I_D = -10 \text{ mA}$ $f = 1 \text{ kHz}$ |
| C_{iss} | Small Signal, Short Circuit, Common Source, Input Capacitance | | 5 | pF | $V_{DS} = -15 \text{ V}, I_D = -10 \text{ mA}$ $f = 1 \text{ MHz}$ |
| C_{rss} | Small Signal, Short Circuit, Common Source, Reverse Transfer Capacitance | | 1.2 | pF | $V_{DG} = -15 \text{ V}, I_D = 0$ $f = 1 \text{ MHz}$ |
| C_{oss} | Small Signal, Short Circuit, Common Source, Output Capacitance | | 3.5 | pF | $V_{DS} = -15 \text{ V}, I_D = -10 \text{ mA}$ $f = 1 \text{ MHz}$ |

- NOTES:** 1. Device must not be tested at $\pm 125\text{V}$ more than once nor longer than 300 ms.
 2. Actual gate current is immeasurable. Package suppliers are required to guarantee a package leakage of $< 10 \mu\text{A}$. External package leakage is the dominant mode which is sensitive to both transient and storage environment, which cannot be guaranteed.

IT1750 N-Channel Enhancement Mode MOSFET

FEATURES

- Low ON Resistance
- Low C_{dg}
- High Gain
- Low Threshold Voltage

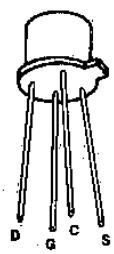
1
ABSOLUTE MAXIMUM RATINGS

 (T_A = 25°C unless otherwise noted)

| | | |
|---------------------------------------|-------|-----------------|
| Drain-Source and Gate-Source Voltage | | 25V |
| Peak Gate-Source Voltage (Note 1) | | ±125V |
| Drain Current | | 100 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | | +300°C |
| Power Dissipation | | 375 mW |
| Derate above 25°C | | 3 mW/°C |

PIN CONFIGURATION

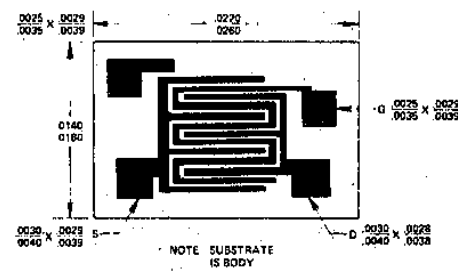
TO-72



D G C S

CHIP TOPOGRAPHY

1003



NOTE: SUBSTRATE IS BODY

ORDERING INFORMATION*

| | | |
|--------------|--------------|-------------|
| TO-72 | WAFER | DICE |
| IT1750 | IT1750/W | IT1750/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (T_A = 25°C, Body connected to Source and V_{BS} = 0 unless otherwise noted)

| PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS | |
|---------------------|----------------------------------|-------------|-----|-------|-----------------|--|
| V _{GS(th)} | Gate to Source Threshold Voltage | 0.50 | 1.5 | 3.0 | V | V _{DS} = V _{GS} , I _D = 10 μA |
| I _{DSS} | Drain Leakage Current | | 0.1 | 10 | nA | V _{DS} = 10 V, V _{GS} = 0 |
| I _{GSS} | Gate Leakage Current | See note 2. | | | | |
| BV _{DSS} | Drain Breakdown Voltage | 25 | | | V | I _D = 10 μA, V _{GS} = 0 |
| r _{DS(on)} | Drain To Source on Resistance | | 25 | 50 | ohms | V _{GS} = 20 V |
| I _{D(on)} | Drain Current | 10 | 50 | | mA | V _{DS} = V _{GS} = 10 V |
| Y _{fs} | Forward Transadmittance | 3,000 | | | μmhos | V _{DS} = 10 V, I _D = 10 mA, f = 1 KHz |
| C _{iss} | Total Gate Input Capacitance | | 5.0 | 6.0 | pF | I _D = 10 mA, V _{DS} = 10 V, f = 1 MHz |
| C _{dg} | Gate to Drain Capacitance | | 1.3 | 1.6 | pF | V _{DG} = 10 V, f = 1 MHz |

NOTES:

1. Devices must not be tested at ±125V more than once nor longer than 300 ms.
2. Actual gate current is immeasurable. Package suppliers are required to guarantee a package leakage of < 10pA. External package leakage is the dominant mode which is sensitive to both transient and storage environment, which cannot be guaranteed.

FEATURES

- Low $r_{DS(on)}$

APPLICATIONS

- Analog Switches
- Choppers
- Commutators

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Gate-Drain or Gate-Source Voltage -25V

Gate Current 50 mA

Storage Temperature Range .. -65°C to +200°C

Operating Temperature Range -55°C to +150°C

Lead Temperature (Soldering, 10 sec.)...+300°C

Power Dissipation 360 mW

Derate above 25°C 3.3 mW/°C

**PIN
CONFIGURATION
TO-92**



ORDERING INFORMATION*

| | |
|------|------------|
| J105 | TO-92 only |
| J106 | TO-92 only |
| J107 | TO-92 only |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted *When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | DESCRIPTION | J105 | | | J106 | | | J107 | | | UNIT | TEST CONDITIONS |
|-----------------------------------|--|------|-----|-----|------|-----|-----|------|-----|------|----------|---|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | | |
| I_{GSS} | Gate-Reverse Current (Note 1) | | | -3 | | | -3 | | | -3 | nA | $V_{DS}=0V, V_{GS}=-15V$ |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | -4.5 | | -10 | | | -6 | | | -4.5 | V | $V_{DS}=5V, I_D=1\mu A$ |
| BV_{GSS} | Gate-Source Breakdown Voltage | -25 | | | -25 | | | | | -25 | | $V_{DS}=0V, I_G=-1\mu A$ |
| I_{DSS} | Drain Saturation Current (Note 2) | 500 | | | 200 | | | 100 | | | mA | $V_{DS}=15V, V_{GS}=0V$ |
| $I_{D(off)}$ | Drain Cutoff Current (Note 1) | | | 3 | | | 3 | | | 3 | nA | $V_{DS}=5V, V_{GS}=-10V$ |
| $r_{DS(on)}$ | Drain source ON Resistance | | | 3 | | | 6 | | | 8 | Ω | $V_{DS}\leq 0.1V, V_{GS}=0V$ |
| $C_{dg(off)}$ | Drain Gate OFF Capacitance | | | 35 | | | 35 | | | 35 | | $V_{DS}=0V, V_{GS}=-10V$ $f=1\text{ MHz}$ |
| $C_{sg(off)}$ | Source Gate OFF Capacitance | | | 35 | | | 35 | | | 35 | | |
| $C_{dg(on)}$ + $C_{sg(on)}$ | Drain Gate plus Source Gate ON Capacitance | | | 160 | | | 160 | | | 160 | pF | |
| $t_{d(on)}$ | Turn On Delay Time | | 15 | | | 15 | | | 15 | | ns | Switching Time Test Conditions: J105 J106 J107 V_{DD} 1.5V 1.5V 1.5V $V_{GS(off)}$ -12V -7V -5V R_L 50 Ω 50 Ω 50 Ω |
| t_r | Rise Time | | 20 | | | 20 | | | 20 | | | |
| $t_{d(off)}$ | Turn Off Delay Time | | 15 | | | 15 | | | 15 | | | |
| t_f | Fall Time | | 20 | | | 20 | | | 20 | | | |

- NOTES:** 1. Approximately doubles for every 10°C increase in T_A .
2. Pulse test duration = 300 μs ; duty cycle $\leq 3\%$.

1

1

FEATURES

- Low Cost
- Automated Insertion Package
- Low Insertion Loss
- No Offset or Error Voltage Generated by Closed Switch
- Purely Resistive High Isolation Resistance from Driver
- Fast Switching
- Short Sample and Hold Aperture Time

APPLICATIONS

- Analog Switches
- Choppers
- Commutators

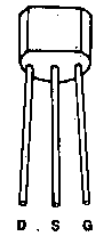
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Drain or Gate-Source Voltage | -35V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Power Dissipation | 310 mW |
| Derate Above 25°C | 2.8 mW/°C |

PIN CONFIGURATION

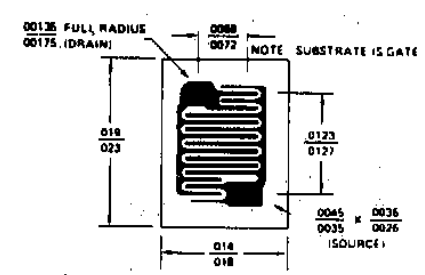
TO-92



D S G

CHIP TOPOGRAPHY

5001



NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO-92 | WAFER | DICE |
|-------|--------|--------|
| J111 | J111/W | J111/D |
| J112 | J112/W | J112/D |
| J113 | J113/W | J113/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted

| PARAMETERS | J111 | | | J112 | | | J113 | | | UNIT | TEST CONDITIONS |
|---------------|--|-----|-----|------|-----|-----|------|-----|-----|----------|---|
| | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | | |
| I_{GSSR} | Gate Reverse Current (Note 1) | | | | | | | | | nA | $V_{DS} = 0V, V_{GS} = -15V$ |
| $V_{GS(off)}$ | Gate Source Cutoff Voltage | | | | | | | | | V | $V_{DS} = 5V, I_D = 1\mu A$ |
| BV_{GSS} | Gate Source Breakdown Voltage | | | | | | | | | V | $V_{DS} = 0V, I_G = -1\mu A$ |
| I_{DSS} | Drain Saturation Current (Note 2) | | | | | | | | | mA | $V_{DS} = 15V, V_{GS} = 0V$ |
| $I_D(off)$ | Drain Cutoff Current (Note 1) | | | | | | | | | nA | $V_{DS} = 5V, V_{GS} = -10V$ |
| $r_{DS(on)}$ | Drain Source ON Resistance | | | | | | | | | Ω | $V_{DS} = 0.1V, V_{GS} = 0V$ |
| $C_{dg(off)}$ | Drain Gate OFF Capacitance | | | | | | | | | pF | $f = 1\text{ MHz}$ |
| $C_{sg(off)}$ | Source Gate OFF Capacitance | | | | | | | | | | |
| $C_{dg(on)}$ | Drain Gate Plus Source Gate ON Capacitance | | | | | | | | | | |
| $t_{d(on)}$ | Turn On Delay Time | | | | | | | | | ns | Switching Time Test Conditions |
| t_r | Rise Time | | | | | | | | | | |
| $t_{d(off)}$ | Turn Off Delay Time | | | | | | | | | | |
| t_f | Fall Time | | | | | | | | | | |
| | | 7 | | 7 | | | 7 | | | | V_{DD} 10V 10V 10V |
| | | 6 | | 6 | | | 6 | | | | $V_{GS(off)}$ -12V -7V -5V |
| | | 20 | | 20 | | | 20 | | | | R_L 0.8k Ω 1.6k Ω 3.2k Ω |
| | | 15 | | 15 | | | 15 | | | | |

NOTES:

1. Approximately doubles for every 10°C increase in T_A .
2. Pulse Test duration 300 μs ; duty cycle $\leq 3\%$.

FEATURES


- Low Insertion Loss
- No Offset or Error Generated by Closed Switch
 - Purely Resistive
 - High Isolation Resistance from Driver
- Short Sample and Hold Aperture Time
- Fast Switching

APPLICATIONS

- Analog Switches
- Choppers
- Commutators

PIN CONFIGURATION

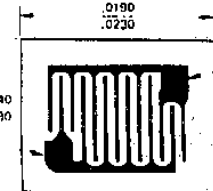
TO-92



D G S

CHIP TOPOGRAPHY (Note 1)

5508



NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO-92 | WAFER | DICE |
|-------|--------|--------|
| J17X | J17X/W | J17X/D |

*When ordering wafer/dice refer to Appendix B-23.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

| | |
|--|-----------------|
| Gate-Drain or Gate-Source Voltage (Note 1) | 30V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | 300°C |
| Power Dissipation | 350 mW |
| Derate above 25°C | 3.5 mW/°C |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted

| PARAMETERS | J174 | | | J175 | | | J176 | | | J177 | | | UNIT | TEST CONDITIONS |
|---|--|-----|-----|------|-----|-----|------|-----|------|------|-----|---------------------------------------|------|---|
| | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | | |
| I _{GSSR} | Gate Reverse Current (Note 2) | | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | nA | V _{DS} = 0, V _{GS} = 20V |
| V _{GS(off)} | Gate-Source Cutoff Voltage | | 5 | 10 | 3 | 6 | 1 | 4 | 0.8 | 2.25 | | | V | V _{DS} = -15V, I _D = -10nA |
| BV _{GSS} | Gate-Source Breakdown Voltage | | 30 | | 30 | | 30 | | 30 | | | | | V _{DS} = 0, I _G = 1μA |
| I _{DSS} | Saturation Drain Current (Note 3) | | -20 | -100 | -7 | -60 | -2 | -25 | -1.5 | -20 | | | mA | V _{DS} = -15V, V _{GS} = 0 |
| I _{D(off)} | Drain Cutoff Current (Note 2) | | | -1 | | -1 | | -1 | | -1 | | | nA | V _{DS} = -15V, V _{GS} = 10V |
| r _{DS(on)} | Drain-Source ON Resistance | | | 85 | | 125 | | 250 | | 300 | | | Ω | V _{GS} = 0, V _{DS} = -0.1V |
| C _{DG(off)} | Drain-Gate OFF Capacitance | | 5.5 | | 5.5 | | 5.5 | | 5.5 | | | | pF | V _{DS} = 0, V _{GS} = 10V f = 1 MHz |
| C _{SG(off)} | Source-Gate OFF Capacitance | | 5.5 | | 5.5 | | 5.5 | | 5.5 | | | | | |
| C _{DG(on)} + C _{SG(on)} | Drain-Gate Plus Source Gate ON Capacitance | | 40 | | 40 | | 40 | | 40 | | | V _{DS} = V _{GS} = 0 | | |
| t _{D(on)} | Turn On Delay Time | | 2 | | 5 | | 15 | | 20 | | | | ns | Switching Time Test Conditions |
| t _r | Rise Time | | 5 | | 10 | | 20 | | 25 | | | | | J174 |
| t _{D(off)} | Turn Off Delay Time | | 5 | | 10 | | 15 | | 20 | | | | | J175 |
| t _f | Fall Time | | 10 | | 20 | | 20 | | 25 | | | | | J176 |
| | | | | | | | | | | | | | | J177 |

NOTES:

1. Geometry is symmetrical. Units may be operated with source and drain leads interchanged.
2. Approximately doubles for every 10°C increase in T_A.
3. Pulse test duration ~300μs; duty cycle ≤ 3%.

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FEATURES

- High Input Impedance
- Low I_{GSS}

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)
 Gate-Source or Gate-Drain Voltage -40V
 Gate Current 50 mA
 Storage Temperature Range ... -65°C to +200°C
 Operating Temperature Range -55°C to +150°C
 Lead Temperature (Soldering, 10 sec.)... +300°C
 Power Dissipation 360 mW
 Derate above 25°C 3.3mW/°C

PIN CONFIGURATION
TO-92

CHIP TOPOGRAPHY
5010*

NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO-92 | WAFER | DICE |
|-------|--------|--------|
| J201 | J201/W | J201/D |
| J202 | J202/W | J202/D |
| J203 | J203/W | J203/D |
| J204 | J204/W | J204/D |

*DICE WITH 4 MIL BONDING PADS AVAILABLE. CONSULT FACTORY FOR DETAILS.

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted

| PARAMETERS | J201 | | | J202 | | | J203 | | | J204 | | | UNIT | TEST CONDITIONS | |
|--|------|------|------|-------|-----|------|-------|-----|-------|-------|-----|------|------------------------|---|-----------|
| | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | | | |
| I_{GSS} Gate Reverse Current (Note 2) | | | -100 | | | -100 | | | -100 | | | -100 | pA | $V_{DS} = 0, V_{GS} = -20V$ | |
| $V_{GS(off)}$ Gate-Source Cutoff Voltage | -0.3 | | -1.5 | -0.8 | | -4.0 | -2.0 | | -10.0 | -0.5 | | -2.0 | V | $V_{DS} = 20V, I_D = 10\ \mu A$ | |
| BV_{GSS} Gate-Source Breakdown Voltage | -40 | | | -40 | | | -40 | | | -25 | | | | $V_{DS} = 0, I_G = -1\ \mu A$ | |
| I_{DSS} Saturation Drain Current (Note 3) | 0.2 | | 1.0 | 0.9 | | 4.5 | 4.0 | | 20 | 1.2 | | | mA | $V_{DS} = 20V, V_{GS} = 0$ | |
| I_G Gate Current (Note 1) | | -3.5 | | -3.5 | | | -3.5 | | | -3.5 | | | pA | $V_{DG} = 20V, I_D = 200\ \mu A$ | |
| g_{fs} Common-Source Forward Transconductance (Note 2) | 500 | | | 1,000 | | | 1,500 | | | 1,500 | | | μmho | $V_{DS} = 20V, V_{GS} = 0$ | |
| g_{os} Common Source Output Conductance | | 1 | | | 3.5 | | | 10 | | | 2.5 | | | | f = 1 kHz |
| C_{iss} Common-Source Input Capacitance | | 4 | | | 4 | | | 4 | | | 4 | | | | |
| C_{rss} Common-Source Reverse Transfer Capacitance | | 1 | | | 1 | | | 1 | | | 1 | | | | |
| \bar{e}_n Equivalent Short-Circuit Input Noise Voltage | | 5 | | | 5 | | | 5 | | | 10 | | $\frac{nV}{\sqrt{Hz}}$ | $V_{DS} = 10V, V_{GS} = 0$ f = 1 kHz | |

NOTES: 1. Approximately doubles for every 10°C increase in T_A .
 2. Pulse test duration = 2ms.

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETERS | | J204 | | | UNIT | TEST CONDITIONS | |
|---------------------------------|---------------|--|----------------------------------|------|-----------------|--|--|
| | | MIN | TYP | MAX | | | |
| S T A T I C | I_{GSS} | Gate Reverse Current (Note 2) | | -100 | pA | $V_{DS} = 0, V_{GS} = -20V$ | |
| | $V_{GS(off)}$ | -0.5 | Gate-Source Cutoff Voltage | | V | $V_{DS} = 20V, I_D = 10nA$ | |
| | BV_{GSS} | -25 | Gate-Source Breakdown Voltage | | | $V_{DS} = 0, I_G = -\mu A$ | |
| | I_{DSS} | Saturation Drain Current (Note 3) | | 1.2 | mA | $V_{DS} = 20V, V_{GS} = 0$ | |
| | I_G | Gate Current (Note 1) | | -3.5 | pA | $V_{DG} = 20V, I_D 200\mu A$ | |
| D Y N A M I C | g_{fs} | Common-Source Forward Transconductance (Note 2) | | 1500 | μmho | $V_{DS} = 20V, V_{GS} = 0$ | |
| | g_{os} | Common Source Output Conductance | | 2.5 | | | |
| | C_{iss} | Common-Source Input Capacitance | | 4 | pF | f = 1MHz | |
| | C_{rss} | Common-Source Reverse Transfer Capacitance | | 1 | | | |
| | e_n | Equivalent Short-Circuit Input Noise Voltage | | 10 | $\frac{nV}{Hz}$ | $V_{DS} = 10V, V_{GS} = 0$ f = 1kHz | |

FEATURES

- Industry Standard Part in Low Cost Plastic Package
- High Power Gain
- Low Noise
- Dynamic Range Greater than 100 dB
- Easily Matched to 75Ω Input

1

APPLICATIONS

- VHF/UHF Amplifiers
- Oscillators
- Mixers

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Drain-Gate Voltage | -25V |
| Drain-Source Voltage | -25V |
| Continuous Forward Gate Current | -10 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering; 10 sec.) | +300°C |
| Power Dissipation | 300 mW |
| Derate above 25°C | 1.7 mW/°C |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted

| PARAMETER | | J308 | | | J309 | | | J310 | | | UNIT | TEST CONDITIONS | |
|----------------------|--|-------|--------|--------|--------|--------|--------|--------|-----|--------|-------|---|------------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | | | |
| BV _{GSS} | Gate-Source Breakdown Voltage | -25 | | | -25 | | | -25 | | | V | $I_G = -1\mu\text{A}, V_{DS} = 0$ | |
| I _{GSSR} | Gate Reverse Current | | | -1.0 | | | -1.0 | | | -1.0 | nA | $V_{GS} = -15\text{V}, V_{DS} = 0$ | |
| V _{GS(off)} | Gate-Source Cutoff Voltage | -1.0 | | -6.5 | -1.0 | | -4.0 | -2.0 | | -6.5 | μA | $V_{DS} = 10\text{V}, I_D = 1\text{nA}$ | |
| I _{DSS} | Saturation Drain Current (Note 1) | 12 | | 60 | 12 | | 30 | 24 | | 60 | mA | $V_{DS} = 10\text{V}, V_{GS} = 0$ | |
| V _{GS(f)} | Gate-Source Forward Voltage | | | 1.0 | | | 1.0 | | | 1.0 | V | $V_{DS} = 0, I_G = 1\text{ mA}$ | |
| g _{fs} | Common-Source Forward Transconductance | 8,000 | | 20,000 | 10,000 | | 20,000 | 8,000 | | 18,000 | | $V_{DS} = 10\text{V}, I_D = 10\text{ mA}$ | |
| g _{os} | Common-Source Output Conductance | | | 200 | | | 200 | | | 200 | | | f = 1 kHz |
| g _{fg} | Common-Gate Forward Transconductance | | 13,000 | | | 13,000 | | 12,000 | | | μmhos | | |
| g _{og} | Common Gate Output Conductance | | 150 | | | 150 | | 150 | | | | f = 1 MHz | |
| C _{gd} | Gate-Drain Capacitance | | 1.8 | 2.5 | | 1.8 | 2.5 | | 1.8 | 2.5 | | | pF |
| C _{gs} | Gate-Source Capacitance | | 4.3 | 5.0 | | 4.3 | 5.0 | | 4.3 | 5.0 | | nV/√Hz | |
| e _n | Equivalent Short-Circuit Input Noise Voltage | | 10 | | | 10 | | 10 | | | | | f = 100 Hz |
| Re(v _{fs}) | Common-Source Forward Transconductance | | 12 | | | 12 | | 12 | | | | mmho | |
| Re(v _{fg}) | Common-Gate Input Conductance | | 14 | | | 14 | | 14 | | | | | |
| Re(v _{is}) | Common-Source Input Conductance | | 0.4 | | | 0.4 | | 0.4 | | | | | |
| Re(v _{os}) | Common-Source Output Conductance | | 0.15 | | | 0.15 | | 0.15 | | | | | |
| G _{pg} | Common-Gate Power Gain at Noise Match | | 16 | | | 16 | | 16 | | | | | |
| NF | Noise Figure | | 1.5 | | | 1.5 | | 1.5 | | | | dB | |
| G _{pg} | Common-Gate Power Gain at Noise Match | | 11 | | | 11 | | 11 | | | | | |
| NF | Noise Figure | | 2.7 | | | 2.7 | | 2.7 | | | | f = 450 MHz | |

NOTE: 1. Pulse test PW 300 μs, duty cycle ≤ 3%.

PIN CONFIGURATION

TO-92

S D G

CHIP TOPOGRAPHY

5021

NOTE: SUBSTRATE IS GATE

TYP. 2 PLACES

ORDERING INFORMATION*

| TO-92 | WAFER | DICE |
|-------|--------|--------|
| J30X | J30X/W | J30X/D |

*When ordering wafer/dice refer to Appendix B-23.



LM114/H, LM114A/AH Monolithic Dual NPN Transistor

1

GENERAL DESCRIPTION

These devices contain a pair of junction-isolated NPN transistors fabricated on a single silicon substrate. This monolithic structure makes possible extremely tight parameter matching at low cost. Further, advanced processing techniques yield exceptionally high current gains at low collector currents, virtual elimination of "popcorn noise," low leakages and improved long-term stability.

Although designed primarily for high breakdown voltage and exceptional DC characteristics, these transistors have surprisingly good high-frequency performance. The gain-bandwidth product is 300MHz with 1mA collector current and 5V collector-base voltage and 22MHz with 10 μ A collector current. Typical collector-base capacitance is only 1.6 pF at 5V.

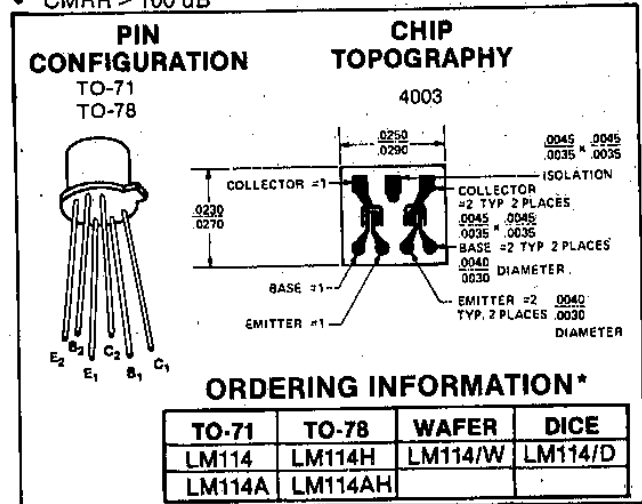
ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|---|
| Collector-Base Voltage (1) | 45V |
| Collector-Emitter Voltage (1) | 45V |
| Collector-Collector Voltage | 45V |
| Emitter-Base Voltage (1) | 6V |
| Collector Current (1) | 20mA |
| Storage Temperature Range | -65 $^\circ\text{C}$ to +200 $^\circ\text{C}$ |
| Operating Temperature Range | -55 $^\circ\text{C}$ to +150 $^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | +300 $^\circ\text{C}$ |
| Power Dissipation | 800mW |
| Derate above 25 $^\circ\text{C}$ | 14mW/ $^\circ\text{C}$ |

FEATURES

- Low offset voltage
- Low drift
- High current gain
- Tight beta match
- High breakdown voltage
- Matching guaranteed over a 0V to 45V collector-base voltage range
- CMRR > 100 dB



ELECTRICAL CHARACTERISTICS (Note 2)

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETER | MAXIMUM LIMITS | | UNITS | CONDITIONS |
|-------------------------------------|---------------------------|----------|------------------------------|--|
| | LM114A, AH | LM114, H | | |
| Offset Voltage | 0.5 | 2.0 | mV | $1\mu\text{A} \leq I_C \leq 100\mu\text{A}$ |
| Offset Current | 2.0 | 10 | nA | $I_C = 10\mu\text{A}$ |
| Bias Current | 0.5 | 40 | nA | $I_C = 1\mu\text{A}$ |
| | 20 | | | $I_C = 10\mu\text{A}$ |
| | 3.0 | | | $I_C = 1\mu\text{A}$ |
| Offset Voltage Change | 0.2 | 1.5 | mV | $0V \leq V_{CB} \leq V_{MAX}$, $I_C = 10\mu\text{A}$ |
| Offset Current Change | 1.0 | 4.0 | nA | |
| Offset Voltage Drift | 2.0 | 10 | $\mu\text{V}/^\circ\text{C}$ | |
| Offset Current | 12 | 50 | nA | $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, $I_C = 10\mu\text{A}$ |
| Bias Current | 60 | 150 | | |
| Collector-Base Leakage Current | 10 | 50 | pA | $V_{CB} = V_{MAX}$ |
| | $T_A = 125^\circ\text{C}$ | 50 | nA | |
| Collector-Emitter Leakage Current | 50 | 200 | pA | $V_{CE} = V_{MAX}$, $V_{EB} = 0V$ |
| | $T_A = 125^\circ\text{C}$ | 200 | nA | |
| Collector-Collector Leakage Current | 100 | 300 | pA | $V_{CC} = V_{MAX}$ |
| | $T_A = 125^\circ\text{C}$ | 300 | nA | |

Note 1: Per transistor.

Note 2: These specifications apply for $T_A = +25^\circ\text{C}$ and $0V \leq V_{CB} \leq V_{MAX}$, unless otherwise specified. For the LM114 and LM114A, $V_{MAX} = 30V$.

M116 Diode Protected N-Channel Enhancement Mode MOSFET

FEATURES

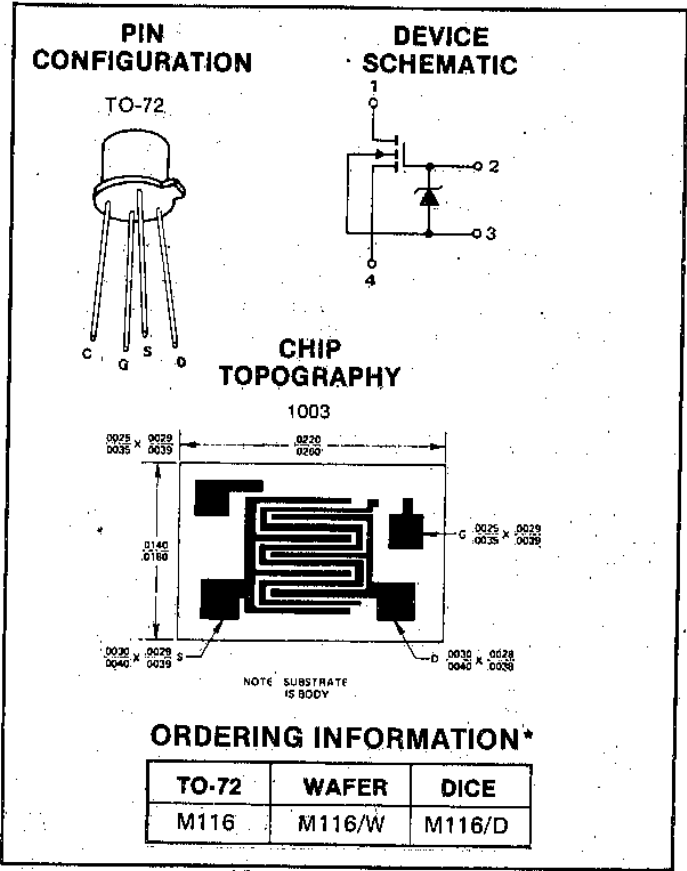
- Low I_{GSS}
- Integrated Zener Clamp for Gate Protection

1

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|---------------------------------------|---|
| Drain to Source Voltage | 30V |
| Gate to Drain Voltage | 30V |
| Drain Current | 50 mA |
| Gate Zener Current | ± 0.1 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 300 mW |
| Derate above 25°C | $2.2 \text{ mW}/^\circ\text{C}$ |



*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | M116 | | UNITS | TEST CONDITIONS |
|--------------|------------|-----|----------|--|
| | MIN | MAX | | |
| $r_{DS(on)}$ | 100 200 | | Ω | $V_{GS} = 20 \text{ V}, I_D = 100 \mu\text{A}, V_{BS} = 0$ $V_{GS} = 10 \text{ V}, I_D = 100 \mu\text{A}, V_{BS} = 0$ |
| $V_{GS(th)}$ | 1 | 5 | V | $V_{GS} = V_{DS}, I_D = 10 \mu\text{A}, V_{BS} = 0$ |
| BV_{DSS} | 30 | | | $I_D = 1 \mu\text{A}, V_{GS} = V_{BS} = 0$ |
| BV_{SDS} | 30 | | | $I_S = 1 \mu\text{A}, V_{GD} = V_{BD} = 0$ |
| BV_{GBS} | 30 | 60 | | $I_G = 10 \mu\text{A}, V_{SB} = V_{DB} = 0$ |
| $I_{D(OFF)}$ | | 10 | nA | $V_{DS} = 20 \text{ V}, V_{GS} = V_{BS} = 0$ |
| $I_{S(OFF)}$ | | 10 | | $V_{SD} = 20 \text{ V}, V_{GD} = V_{BD} = 0$ |
| I_{GSS} | | 100 | pA | $V_{GS} = 20 \text{ V}, V_{DS} = V_{BS} = 0$ |
| C_{gs} | | 2.5 | pF | $V_{GB} = V_{DB} = V_{SB} = 0, f = 1 \text{ MHz}$ Body Guarded |
| C_{gd} | | 2.5 | | $V_{GB} = 0, V_{DB} = 10 \text{ V}, f = 1 \text{ MHz}$ |
| C_{db} | | 7 | | $V_{GB} = 0, V_{DB} = 10 \text{ V}, V_{BS} = 0$ |
| C_{iss} | | 10 | | $f = 1 \text{ MHz}$ |

FEATURES

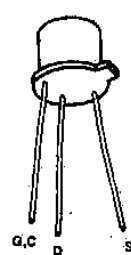
- Low Insertion Loss
- Good OFF Isolation

APPLICATIONS

- Analog Switches
- Commutators
- Choppers

PIN CONFIGURATION

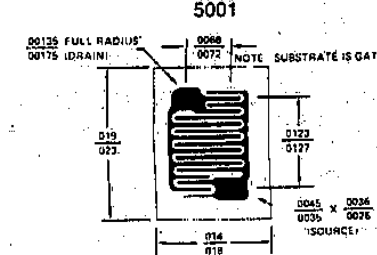
TO-18



G, C
D
S

CHIP TOPOGRAPHY

5001



00135 FULL RADIUS
00175 (DRAIN) 00068
00072 NOTE SUBSTRATE IS GATE

0119 023 0123 0127

0114 018 0045 0035 X 0026 0026
"SOURCE"

ORDERING INFORMATION*

| TO-18 | WAFER | DICE |
|-------|--------|--------|
| U200 | U200/W | U200/D |
| U201 | U201/W | U201/D |
| U202 | U202/W | U202/D |

*When ordering wafer/dice refer to Appendix B-23.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

| | |
|---------------------------------------|-----------------|
| Gate-Drain or Gate-Source Voltage | -30V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | +300°C |
| Total Device Dissipation | 1.8W |
| Derate above 25°C | 10 mW/°C |

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| Parameter | U200 | | U201 | | U202 | | Unit | Test Conditions |
|----------------------|------|-----|------|-----|------|-----|------|---|
| | Min | Max | Min | Max | Min | Max | | |
| I _{GSS} | -1 | | -1 | | -1 | | nA | V _{GSS} = 20 V, V _{DS} = 0 |
| | -1 | | -1 | | -1 | | μA | |
| BV _{GSS} | -30 | | -30 | | -30 | | V | I _G = 1 μA, V _{DS} = 0 |
| V _{GS(off)} | -0.5 | | -1.5 | | -3.5 | | | V _{DS} = 20 V, I _D = 10 nA |
| I _{D(off)} | 1 | | 1 | | 1 | | nA | V _{DS} = 10 V, V _{GS} = -12 V |
| | 1 | | 1 | | 1 | | μA | |
| I _{DSS} | 3 | | 15 | | 30 | | mA | V _{DS} = 20 V, V _{GS} = 0 |
| r _{ds(on)} | 150 | | 75 | | 50 | | ohm | V _{GS} = 0, I _D = 0 f = 1 kHz |
| C _{iss} | 30 | | 30 | | 30 | | pF | V _{DS} = 20 V, V _{GS} = 0 f = 1 MHz |
| C _{rss} | 8 | | 8 | | 8 | | | V _{DS} = 0, V _{GS} = -12 V |

NOTE 1: Pulse test required, pulsewidth = 300 μsec, duty cycle ≤ 3%.

U231-U235 Monolithic Dual N-Channel JFET

FEATURES

- Good Matching Characteristics

APPLICATIONS

- Differential Amplifiers
- Low and Maximum Frequency Amplifiers

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|--|-------|-----------------|
| Gate-Source or Gate-Drain Voltage (Note 1) | | -50V |
| Gate Current (Note 1) | | 50 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Load Temperature (Soldering, 10 sec.) | | +300°C |
| Power Dissipation | | 300 mW |
| Derate above 25°C | | 1.7 mW/°C |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted.

PIN CONFIGURATION

TO-71

CHIP TOPOGRAPHY

6037

ALL BOND PADS ARE 4 x 4 MIL.

ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|-------|--------|--------|
| U23X | U23X/W | U23X/D |

*When ordering wafer/dice refer to Appendix B-23.

| Parameter | Min | Max | Unit | Test Conditions |
|--|------|------|-------------------------------|--------------------------------------|
| I_{GSSR} Gate Reverse Current | | -100 | pA | $V_{GS} = -30V, V_{DS} = 0$ |
| | | -500 | nA | $T_A = 150^\circ\text{C}$ |
| BV_{GSS} Gate-Source Breakdown Voltage | -50 | | V | $I_G = 1\mu\text{A}, V_{DS} = 0$ |
| $V_{GS(off)}$ Gate-Source Cutoff Voltage | -0.5 | -4.5 | V | $V_{DS} = 20V, I_D = 1\text{ nA}$ |
| V_{GS} Gate-Source Voltage | -0.3 | -4.0 | V | |
| I_G Gate Operating Current | | -50 | pA | $V_{DG} = 20V, I_D = 200\mu\text{A}$ |
| | | -250 | nA | $T_A = 125^\circ\text{C}$ |
| I_{DSS} Saturation Drain Current (Note 2) | 0.5 | 5.0 | mA | $V_{DS} = 20V, V_{GS} = 0$ |
| g_{fs} Common-Source Forward Transconductance (Note 1) | 1000 | 3000 | μmho | $V_{DS} = 20V, V_{GS} = 0$ |
| | 1000 | | | $f = 1\text{ kHz}$ |
| | | | | $f = 100\text{ MHz}$ |
| g_{fs} Common-Source Forward Transconductance (Note 1) | 600 | 1600 | μmho | $V_{DG} = 20V, I_D = 200\mu\text{A}$ |
| g_{os} Common-Source Output Capacitance | | 35 | pF | $V_{DS} = 20V, V_{GS} = 0$ |
| g_{os} Common-Source Output Conductance | | 10 | μmho | $V_{DG} = 20V, I_D = 200\mu\text{A}$ |
| C_{iss} Common-Source Input Capacitance | | 6 | pF | |
| C_{rss} Common-Source Reverse Transfer Capacitance | | 2 | pF | $V_{DS} = 20V, V_{GS} = 0$ |
| \bar{e}_n Equivalent Short Circuit Input Noise Voltage | | 80 | $\frac{nV}{\sqrt{\text{Hz}}}$ | $f = 1\text{ MHz}$ |
| | | | | $f = 100\text{ Hz}$ |

| Matching Characteristics | U231 Max | U232 Max | U233 Max | U234 Max | U235 Max | Unit | Test Conditions |
|--|----------|----------|----------|----------|----------|------------------------------|--|
| $ I_{G1} - I_{G2} $ Differential Gate Current | 10 | 10 | 10 | 10 | 10 | nA | $V_{DG} = 20V, I_D = 200\mu\text{A}, 125^\circ\text{C}$ |
| $\frac{ I_{DSS1} - I_{DSS2} }{I_{DSS1}}$ Saturation Drain Current Match (Note 2) | 5 | 5 | 5 | 10 | 15 | % | $V_{DS} = 20V, V_{GS} = 0$ |
| $ V_{GS1} - V_{GS2} $ Differential Gate-Source Voltage | 5 | 10 | 15 | 20 | 25 | mV | |
| $\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$ Gate-Source Voltage Differential Drift (Note 3) | 10 | 25 | 50 | 75 | 100 | $\mu\text{V}/^\circ\text{C}$ | $T_A = 25^\circ\text{C}$ $T_B = 125^\circ\text{C}$ $T_A = -55^\circ\text{C}$ $T_B = 25^\circ\text{C}$ |
| $\frac{ g_{fs1} - g_{fs2} }{g_{fs1}}$ Transconductance Match (Note 2) | 3 | 5 | 5 | 10 | 15 | % | $V_{DG} = 20V, I_D = 200\mu\text{A}$ |
| $ g_{os1} - g_{os2} $ Differential Output Conductance | 5 | 5 | 5 | 5 | 5 | μmho | $f = 1\text{ kHz}$ |

NOTES:

1. Per transistor.
2. Pulse test required, pulse width = 300 μs , duty cycle $\leq 3\%$.
3. Measured at end points, T_A and T_B .

U257 Monolithic Dual N-Channel JFET

FEATURES

- $g_{fs} > 5000 \mu\text{mho}$ from DC to 100 MHz
- Matched V_{GS} , g_{fs} and g_{os}

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|--|-------|-----------------|
| Gate-Drain or Gate-Source Voltage (Note 1) | | -25V |
| Gate Current (Note 1) | | 50 mA |
| Storage Temperature Range | | -65°C to +200°C |
| Operating Temperature Range | | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | | +300°C |

| | ONE SIDE | BOTH SIDES |
|-------------------|-----------------|------------|
| Power Dissipation | 250 mW | 500 mW |
| Derate above 25°C | 3.8 mW/°C | 7.7 mW/°C |

PIN CONFIGURATION

TO-99

CHIP TOPOGRAPHY

6022

G_1 .0037 x .0037
.0027 x .0027
(TYP. 2 PLACES)

D_1 .0037 x .0037
.0027 x .0027
(TYP. 2 PLACES)

S_1 .0037 x .0037
.0027 x .0027
(TYP. 2 PLACES)

ORDERING INFORMATION*

| TO-99 | WAFER | DICE |
|-------|--------|--------|
| U257 | U257/W | U257/D |

*When ordering wafer/dice refer to Appendix B-23.

1

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| | PARAMETER | MIN | MAX | UNIT | TEST CONDITIONS |
|-----------------------------|---|---------------------------|--------|--------------------------------------|---|
| I_{GSSR} | Gate Reverse Current | | -100 | pA | $V_{GS} = 15\text{ V}, V_{DS} = 0$ |
| | | $T_A = 150^\circ\text{C}$ | -250 | nA | |
| BV_{GSS} | Gate-Source Breakdown Voltage | -25 | | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ |
| $V_{GS}(\text{off})$ | Gate-Source Cutoff Voltage | -1 | -5 | | $V_{DS} = 10\text{ V}, I_D = 1\ \text{nA}$ |
| I_{DSS} | Saturation Drain Current (Note 2) | 5 | 40 | mA | $V_{DS} = 10\text{ V}, V_{GS} = 0$ |
| g_{fs} | Common-Source Forward Transconductance | 5000 | 10,000 | μmho | $V_{DS} = 10\text{ V}, I_D = 5\text{ mA}, f = 1\text{ kHz}$ |
| g_{fs} | Common-Source Forward Transconductance | 5000 | 10,000 | | $V_{DG} = 10\text{ V}, I_D = 5\text{ mA}, f = 100\text{ MHz}$ |
| g_{os} | Common-Source Output Conductance | | 150 | μmho | $V_{DS} = 10\text{ V}, I_D = 5\text{ mA}, f = 1\text{ kHz}$ |
| g_{oss} | Common-Source Output Conductance | | 150 | | $V_{DG} = 10\text{ V}, I_D = 5\text{ mA}, f = 100\text{ MHz}$ |
| C_{iss} | Common-Source Input Capacitance | | 5 | pF | $V_{DG} = 10\text{ V}, I_D = 5\text{ mA}$ |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 1.2 | | |
| \bar{e}_n | Equivalent Input Noise Voltage | | 30 | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ | $f = 10\text{ kHz}$ |
| $\frac{I_{DSS1}}{I_{DSS2}}$ | Drain Current Ratio at Zero Gate Voltage (Note 2) | 0.85 | 1 | | $V_{DS} = 10\text{ V}, V_{GS} = 0$ |
| $ V_{GS1} - V_{GS2} $ | Differential Gate-Source Voltage | | 100 | mV | |
| $\frac{g_{fs1}}{g_{fs2}}$ | Transconductance Ratio | 0.85 | 1 | | $V_{DG} = 10\text{ V}, I_D = 5\text{ mA}, f = 1\text{ kHz}$ |
| $ g_{os1} - g_{os2} $ | Differential Output Conductance | | 20 | μmho | |

NOTES:

1. Per transistor.
2. Pulse test required, pulse width = 300 μs , duty cycle $\leq 3\%$.

FEATURES

- Low ON Resistance
- $I_{D(off)} < 500$ pA
- Switches directly from T²L Logic (U306)

1

APPLICATIONS

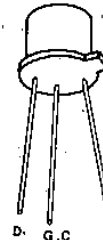
- Analog Switches
- Commutators
- Choppers

ABSOLUTE MAXIMUM RATINGS

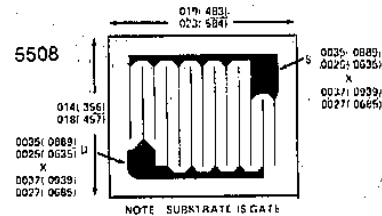
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--|-----------------|
| Gate-Drain or Gate-Source Voltage (Note 1) | 30V |
| Gate Current | 50 mA |
| Storage Temperature Range | -65°C to +200°C |
| Operating Temperature Range | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | 300°C |
| Power Dissipation | 350 mW |
| Derate above 25°C | 2.8 mW/°C |

PIN CONFIGURATION TO-18



CHIP TOPOGRAPHY (Note 1)



ORDERING INFORMATION*

| TO-18 | WAFER | DICE |
|-------|--------|--------|
| U304 | U304/W | U304/D |
| U305 | U305/W | U305/D |
| U306 | U306/W | U306/D |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25°C unless otherwise noted.

*When ordering wafer/dice refer to Appendix B-23.

| Parameter | U304 | | U305 | | U306 | | Unit | Test Conditions |
|--|------|------|------|------|------|------|---------------|--|
| | Min | Max | Min | Max | Min | Max | | |
| I_{GSSR} Gate Reverse Current $T_A = 150^\circ\text{C}$ | | 500 | | 500 | | 500 | pA | $V_{GS} = 20V, V_{DS} = 0$ |
| BV_{GSS} Gate-Source Breakdown Voltage | 30 | 1.0 | 30 | 1.0 | 30 | 1.0 | μA | $I_G = 1 \mu\text{A}, V_{DS} = 0$ |
| $V_{GS(off)}$ Gate-Source Cutoff Voltage | 5 | 10 | 3 | 6 | 1 | 4 | V | $V_{DS} = -15V, I_D = -1 \mu\text{A}$ |
| $V_{DS(on)}$ Drain-Source ON Voltage | | -1.3 | | -0.8 | | -0.6 | V | $V_{GS} = 0, I_D = -15\text{mA (U304)},$ $I_D = -7\text{mA (U305)},$ $I_D = -3\text{mA (U306)}$ |
| I_{DSS} Saturation Drain Current (Note 2) | -30 | -90 | -15 | -60 | -5 | -25 | mA | $V_{DS} = -15V, V_{GS} = 0$ |
| $I_{D(off)}$ Drain Cutoff Current $T_A = 150^\circ\text{C}$ | | -500 | | -500 | | -500 | pA | $V_{DS} = -15V, V_{GS} = 12V \text{ (U304)}$ $V_{GS} = 7V \text{ (U305)}$ $V_{GS} = 5V \text{ (U306)}$ |
| $r_{DS(on)}$ Static Drain-Source ON Resistance | | 85 | | 110 | | 175 | Ω | $V_{GS} = 0V, I_D = -1\text{mA}$ |
| $r_{DS(on)}$ Drain-Source ON Resistance | | 85 | | 110 | | 175 | Ω | $V_{GS} = 0V, I_D = 0$ |
| C_{iss} Common-Source Input Capacitance | | 27 | | 27 | | 27 | pF | $V_{DS} = -15V, V_{GS} = 0$ |
| C_{rss} Common-Source Reverse Transfer Capacitance | | 7 | | 7 | | 7 | pF | $V_{DS} = 0, V_{GS} = 12V \text{ (U304)}$ $V_{GS} = 7V \text{ (U305)},$ $V_{GS} = 5V \text{ (U306)}$ |
| $t_{d(on)}$ Turn-ON Delay Time | | 20 | | 25 | | 25 | ns | U304 U305 U306 $V_{DD} -10V -6V -6V$ $V_{GS(off)} 12V 7V 5V$ $R_L 580\Omega 743\Omega 1800\Omega$ $V_{GS(on)} 0 0 0$ $I_{D(on)} -15\text{mA} -7\text{mA} -3\text{mA}$ |
| t_r Rise Time | | 15 | | 25 | | 35 | ns | |
| $t_{d(off)}$ Turn-OFF Delay Time | | 10 | | 15 | | 20 | ns | |
| t_f Fall Time | | 25 | | 40 | | 60 | ns | |

NOTES:

1. Due to symmetrical geometry these units may be operated with source and drain leads interchanged.
2. Pulse test pulsewidth = 300 μs , duty cycle $\leq 3\%$.

FEATURES

- Industry Standard Part in Low Cost Plastic Package
- High Power Gain
- Low Noise
- Dynamic Range Greater than 100 dB
- Easily Matched to 75Ω Input

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--------------------------------------|---|
| Gate-Drain or Gate-Source Voltage | -25V |
| Gate Current | 20 mA |
| Storage Temperature | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Led Temperature (Soldering, 10 sec.) | $+300^\circ\text{C}$ |
| Power Dissipation | 500 mW |
| Derate above 25°C | 4mW/ $^\circ\text{C}$ |

PIN CONFIGURATIONS

TO-52

G.C D S

CHIP TOPOGRAPHY

5021

NOTE: SUBSTRATE IS GATE

TYP. 2 PLACES

ORDERING INFORMATION*

| TO-52 | WAFER | DICE |
|-------|--------|--------|
| U308 | U308/W | U308/D |
| U309 | U309/W | U309/D |
| U310 | U310/W | U310/D |

*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| SYMBOL | PARAMETER | U308 | | | U309 | | | U310 | | | UNIT | TEST CONDITIONS |
|---------------|---|---------------------------|------|------|------|------|------|------|------|------|--------------------------------------|--|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | | |
| I_{GSSR} | Gate Reverse Current | | | -150 | | | -150 | | | -150 | pA | $V_{GS} = -15\text{V}$ |
| | | $T_A = 125^\circ\text{C}$ | | -150 | | -150 | | -150 | | -150 | nA | $V_{GS} = 0$ |
| BV_{GSS} | Gate-Source Breakdown Voltage | -25 | | -25 | | | -25 | | | | V | $I_G = -1\ \mu\text{A}, V_{DS} = 0$ |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | -1.0 | | -6.0 | -1.0 | | -4.0 | -2.5 | | -6.0 | V | $V_{DS} = 10\text{V}, I_D = 1\ \text{nA}^*$ |
| I_{DSS} | Saturation Drain Current (Note 1) | 12 | | 60 | 12 | | 30 | 24 | | 60 | mA | $V_{DS} = 10\text{V}, V_{GS} = 0$ |
| $V_{GS(f)}$ | Gate-Source Forward Voltage | | | 1.0 | | | 1.0 | | | 1.0 | V | $I_G = 10\ \text{mA}, V_{DS} = 0$ |
| g_{fg} | Common-Gate Forward Transconductance (Note 1) | 10 | | 20 | 10 | | 20 | 10 | | 18 | mmho | $V_{DS} = 10\text{V}, I_D = 10\ \text{mA}$ $f = 1\ \text{kHz}$ |
| g_{ogs} | Common-Gate Output Conductance | | | 150 | | | 150 | | | 150 | μmho | |
| C_{gd} | Drain-Gate Capacitance | | | 2.5 | | | 2.5 | | | 2.5 | pF | $V_{GS} = -10\text{V}, V_{DS} = 10\text{V}$ $f = 1\ \text{MHz}$ |
| C_{gs} | Gate-Source Capacitance | | | 5.0 | | | 5.0 | | | 5.0 | | |
| \bar{e}_n | Equivalent Short Circuit Input Noise Voltage | | 10 | | | 10 | | | 10 | | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ | $V_{DS} = 10\text{V}, I_D = 10\ \text{mA}$ $f = 100\ \text{Hz}$ |
| g_{fg} | Common-Gate Forward Transconductance | | 15 | | | 15 | | | 15 | | mmho | $f = 100\ \text{MHz}$ |
| | | | 14 | | | 14 | | | 14 | | | $f = 450\ \text{MHz}$ |
| g_{ogs} | Common-Gate Output Conductance | | 0.18 | | | 0.18 | | | 0.18 | | mmho | $f = 100\ \text{MHz}$ |
| | | | 0.32 | | | 0.32 | | | 0.32 | | | $f = 450\ \text{MHz}$ |
| G_{pg} | Common-Gate Power Gain | | 16 | | | 16 | | | 16 | | dB | $f = 100\ \text{MHz}$ |
| | | | 11 | | | 11 | | | 11 | | | $f = 450\ \text{MHz}$ |
| NF | Noise Figure | | 1.5 | | | 1.5 | | | 1.5 | | dB | $f = 100\ \text{MHz}$ |
| | | | 2.7 | | | 2.7 | | | 2.7 | | | $f = 450\ \text{MHz}$ |

NOTE: Pulse test duration = 2 ms.

U401-U406 Monolithic Dual N-Channel JFET

1

FEATURES

- Minimum System Error and Calibration
- Low Drift with Temperature
- Operates from Low Power Supply Voltages
- High Output Impedance

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | |
|--|---|
| Gate-Drain or Gate-Source Voltage (Note 1) | 50V |
| Gate Current (Note 1) | 10 mA |
| Storage Temperature Range | -65°C to $+200^\circ\text{C}$ |
| Operating Temperature Range | -55°C to $+150^\circ\text{C}$ |
| Lead Temperature (Soldering, 10 sec) | $+300^\circ\text{C}$ |

| | ONE SIDE | BOTH SIDES |
|---------------------------------|--------------------------|------------------------|
| Power Dissipation | 300 mW | 500 mW |
| Derate above 25°C | 2.6 mW/ $^\circ\text{C}$ | 5 mW/ $^\circ\text{C}$ |

PIN CONFIGURATION

TO-71

CHIP TOPOGRAPHY

6037

ALL BOND PADS ARE 4 x 4 MIL.

ORDERING INFORMATION*

| TO-71 | WAFER | DICE |
|-------|--------|--------|
| U40X | U40X/W | U40X/D |

ELECTRICAL CHARACTERISTICS

TEST CONDITIONS: 25° unless otherwise noted.

*When ordering wafer/dice refer to Appendix B-23.

| Parameters | | U401 | | U402 | | U403 | | U404 | | U405 | | U406 | | Unit | Test Conditions |
|--|---|----------|------|----------|------|----------|------|----------|------|----------|------|----------|------|--------------------------------------|---|
| | | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | Min | Max | | |
| BV_{GS} | Gate-Source Breakdown Voltage | -50 | | -50 | | -50 | | -50 | | -50 | | -50 | | V | $V_{DS} = 0, I_G = -1\mu\text{A}$ |
| I_{GSS} | Gate Reverse Current (Note 2) | | -25 | | -25 | | -25 | | -25 | | -25 | | -25 | pA | $V_{DS} = 0, V_{GS} = -30\text{V}$ |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | -5 | -2.5 | -5 | -2.5 | -5 | -2.5 | -5 | -2.5 | -5 | -2.5 | -5 | -2.5 | V | $V_{DS} = 15\text{V}, I_D = 1\text{nA}$ |
| $V_{GS(on)}$ | Gate-Source Voltage (on) | | -2.3 | | -2.3 | | -2.3 | | -2.3 | | -2.3 | | -2.3 | V | $V_{DG} = 15\text{V}, I_D = 200\mu\text{A}$ |
| I_{DSS} | Saturation Drain Current (Note 3) | 0.5 | 10.0 | 0.5 | 10.0 | 0.5 | 10.0 | 0.5 | 10.0 | 0.5 | 10.0 | 0.5 | 10.0 | mA | $V_{DS} = 10\text{V}, V_{GS} = 0$ |
| I_G | Operating Gate Current (Note 2) $T_A = 125^\circ\text{C}$ | | -15 | | -15 | | -15 | | -15 | | -15 | | -15 | pA | $V_{DG} = 15\text{V}, I_D = 200\mu\text{A}$ |
| BV_{G1-G2} | Gate-Gate Breakdown Voltage | ± 50 | | ± 50 | | ± 50 | | ± 50 | | ± 50 | | ± 50 | | V | $V_{DS} = 0, V_{GS} = 0, I_G = \pm 1\mu\text{A}$ |
| g_{fs} | Common-Source Forward Transconductance (Note 3) | 2000 | 7000 | 2000 | 7000 | 2000 | 7000 | 2000 | 7000 | 2000 | 7000 | 2000 | 7000 | μmho | $V_{DS} = 10\text{V}, V_{GS} = 0, f = 1\text{kHz}$ |
| g_{os} | Common-Source Output Conductance | | 20 | | 20 | | 20 | | 20 | | 20 | | 20 | μmho | $V_{DG} = 15\text{V}, I_D = 200\mu\text{A}, f = 1\text{kHz}$ |
| g_{fs} | Common-Source Forward Transconductance | 1000 | 1600 | 1000 | 1600 | 1000 | 1600 | 1000 | 1600 | 1000 | 1600 | 1000 | 1600 | μmho | $V_{DG} = 15\text{V}, I_D = 200\mu\text{A}, f = 1\text{kHz}$ |
| g_{os} | Common-Source Output Conductance | | 2.0 | | 2.0 | | 2.0 | | 2.0 | | 2.0 | | 2.0 | μmho | $V_{DG} = 15\text{V}, I_D = 200\mu\text{A}, f = 1\text{MHz}$ |
| C_{iss} | Common-Source Input Capacitance | | 8.0 | | 8.0 | | 8.0 | | 8.0 | | 8.0 | | 8.0 | pF | $V_{DS} = 15\text{V}, V_{GS} = 0, f = 1\text{MHz}$ |
| C_{rss} | Common-Source Reverse Transfer Capacitance | | 3.0 | | 3.0 | | 3.0 | | 3.0 | | 3.0 | | 3.0 | pF | $V_{DS} = 15\text{V}, V_{GS} = 0, f = 1\text{MHz}$ |
| e_n | Equivalent Short-Circuit Input Noise Voltage | | 20 | | 20 | | 20 | | 20 | | 20 | | 20 | $\frac{\text{nV}}{\sqrt{\text{Hz}}}$ | $V_{DS} = 15\text{V}, V_{GS} = 0, f = 10\text{Hz}$ |
| CMRR | Common-Mode Rejection Ratio (Note 4) | 95 | | 95 | | 95 | | 95 | | 90 | | | | dB | $V_{DG} = 10\text{ to }20\text{V}, I_D = 200\mu\text{A}$ |
| $ V_{GS1}-V_{GS2} $ | Differential Gate-Source Voltage | | 5 | | 10 | | 10 | | 15 | | 20 | | 40 | mV | $V_{DG} = 10\text{V}, I_D = 200\mu\text{A}$ |
| $\frac{\Delta V_{GS1}-V_{GS2} }{\Delta T}$ | Gate-Source Voltage Differential Drift (Note 5) | | 10 | | 10 | | 25 | | 25 | | 40 | | 80 | $\mu\text{V}/^\circ\text{C}$ | $V_{DG} = 10\text{V}, I_D = 200\mu\text{A}, T_A = -55^\circ\text{C}, T_B = +25^\circ\text{C}, I_D = 200\mu\text{A}, T_C = +125^\circ\text{C}$ |

NOTES:

1. Per transistor.
2. Approximately doubles for every 10°C increase in T_A .
3. Pulse test duration = 300 μsec ; duty cycle $\leq 3\%$.
4. Measured at end points, T_A and T_B .

$$5. \text{CMRR} = 20 \log_{10} \left[\frac{\Delta V_{DD}}{\Delta |V_{GS1}-V_{GS2}|} \right], \Delta V_{DD} = 10\text{V.}$$

FEATURES

- Low Insertion Loss
- No Error or Offset Voltage Generated by Closed Switch

APPLICATIONS

Analog Switches, Choppers

ABSOLUTE MAXIMUM RATINGS

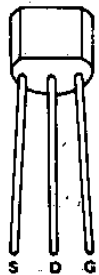
($T_A = 25^\circ\text{C}$ unless otherwise noted)

| | | |
|---------------------------------------|-------|-----------------|
| Gate-Drain or Gate-Source Voltage | | -40V |
| Forward Gate Current | | 10 mA |
| Storage Temperature Range | .. | -65°C to +200°C |
| Operating Temperature Range | .. | -55°C to +150°C |
| Lead Temperature (Soldering, 10 sec.) | .. | +300°C |
| Power Dissipation | | 350 mW |
| Derate above 25°C | | 3.5 mW/°C |

ELECTRICAL CHARACTERISTICS

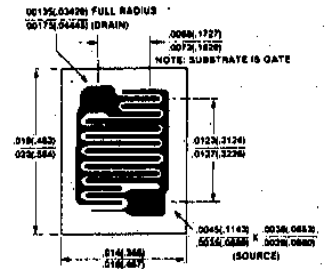
TEST CONDITIONS: 25°C unless otherwise noted

PIN CONFIGURATION
TO-92



S D G

CHIP TOPOGRAPHY
5001



NOTE: SUBSTRATE IS GATE

ORDERING INFORMATION*

| TO-92 | TO-92-18 | WAFER | DICE |
|-------|----------|---------|---------|
| U1897 | U1897-18 | U1897/W | U1897/D |
| U1898 | U1898-18 | U1898/W | U1898/D |
| U1899 | U1899-18 | U1899/W | U1899/D |

*When ordering wafer/dice refer to Appendix B-23.

| PARAMETERS | | U1897 | | U1898 | | U1899 | | UNIT | TEST CONDITIONS | | | | | | | | | | | | | | | | | | | | |
|----------------------|--|-------|-------|-------|------|-------|------|------|--|-----------------|-------|-------|-------|---------------------|----|----|----|----------------------|---|---|---|----------------|------|------|-------|--------------------|-------|-----|-------|
| | | MIN | MAX | MIN | MAX | MIN | MAX | | | | | | | | | | | | | | | | | | | | | | |
| BV _{GSS} | Gate-Source Breakdown Voltage | -40 | | -40 | | -40 | | V | I _G = -1μA, V _{DS} = 0 | | | | | | | | | | | | | | | | | | | | |
| I _{GSSR} | Gate Reverse Current | | -400 | | -400 | | -400 | | V _{GS} = -20V, V _{DS} = 0 | | | | | | | | | | | | | | | | | | | | |
| I _{DGO} | Drain-Gate Leakage Current | | 200 | | 200 | | 200 | | V _{DG} = 20V, I _S = 0 | | | | | | | | | | | | | | | | | | | | |
| I _{SGO} | Source-Gate Leakage Current | | 200 | | 200 | | 200 | | V _{SG} = 20V, I _D = 0 | | | | | | | | | | | | | | | | | | | | |
| I _{D(off)} | Drain Cutoff Current | | 200 | | 200 | | 200 | | V _{DS} = 20V, V _{GS} = -12V (U1897) | | | | | | | | | | | | | | | | | | | | |
| | | | 10 | | 10 | | 10 | | V _{GS} = -8V (U1898) V _{GS} = -6V (U1899) | | | | | | | | | | | | | | | | | | | | |
| | | | | | | | | | T _A = 85°C | | | | | | | | | | | | | | | | | | | | |
| V _{GS(off)} | Gate-Source Cutoff Voltage | -5.0 | -10 | -2.0 | -7.0 | -1.0 | -5.0 | V | V _{DS} = 20V, I _D = 1 na | | | | | | | | | | | | | | | | | | | | |
| I _{DSS} | Saturation Drain Current (Note 1) | 30 | | 15 | | 8.0 | | mA | V _{DS} = 20V, V _{GS} = 0 | | | | | | | | | | | | | | | | | | | | |
| V _{DS(on)} | Drain-Source ON Voltage | | 0.2 | | 0.2 | | 0.2 | V | V _{GS} = 0, I _D = 6.6mA (U1897) | | | | | | | | | | | | | | | | | | | | |
| | | | | | | | | | I _D = 4.0mA (U1898) I _D = 2.5mA (U1899) | | | | | | | | | | | | | | | | | | | | |
| r _{DS(on)} | Static Drain-Source ON Resistance | | 30 | | 50 | | 80 | Ω | I _D = 1mA, V _{GS} = 0 | | | | | | | | | | | | | | | | | | | | |
| C _{dg} | Drain-Gate Capacitance | | 5 | | 5 | | 5 | | V _{DG} = 20V, I _S = 0 | | | | | | | | | | | | | | | | | | | | |
| C _{sg} | Source-Gate Capacitance | | 5 | | 5 | | 5 | | V _{SG} = 20V, I _D = 0 | | | | | | | | | | | | | | | | | | | | |
| C _{iss} | Common-Source Input Capacitance | | 16 | | 16 | | 16 | | V _{DS} = 20V, V _{GS} = 0 | | | | | | | | | | | | | | | | | | | | |
| C _{rss} | Common-Source Reverse Transfer Capacitance | | 3.5 | | 3.5 | | 3.5 | | f = 1 MHz | | | | | | | | | | | | | | | | | | | | |
| t _{d(on)} | Turn ON Delay Time | | 15 | | 15 | | 20 | | Switching Time Test Conditions | | | | | | | | | | | | | | | | | | | | |
| t _r | Rise Time | | 10 | | 20 | | 40 | | | | | | | | | | | | | | | | | | | | | | |
| t _{off} | Turn OFF Time | | 40 | | 60 | | 80 | | | | | | | | | | | | | | | | | | | | | | |
| | | | | | | | | | <table border="0" style="width: 100%;"> <tr> <td>V_{DD}</td> <td>U1897</td> <td>U1898</td> <td>U1899</td> </tr> <tr> <td>V_{GS(on)}</td> <td>3V</td> <td>3V</td> <td>3V</td> </tr> <tr> <td>V_{GS(off)}</td> <td>0</td> <td>0</td> <td>0</td> </tr> <tr> <td>R_L</td> <td>425Ω</td> <td>770Ω</td> <td>1120Ω</td> </tr> <tr> <td>I_{D(on)}</td> <td>6.6mA</td> <td>4mA</td> <td>2.5mA</td> </tr> </table> | V _{DD} | U1897 | U1898 | U1899 | V _{GS(on)} | 3V | 3V | 3V | V _{GS(off)} | 0 | 0 | 0 | R _L | 425Ω | 770Ω | 1120Ω | I _{D(on)} | 6.6mA | 4mA | 2.5mA |
| V _{DD} | U1897 | U1898 | U1899 | | | | | | | | | | | | | | | | | | | | | | | | | | |
| V _{GS(on)} | 3V | 3V | 3V | | | | | | | | | | | | | | | | | | | | | | | | | | |
| V _{GS(off)} | 0 | 0 | 0 | | | | | | | | | | | | | | | | | | | | | | | | | | |
| R _L | 425Ω | 770Ω | 1120Ω | | | | | | | | | | | | | | | | | | | | | | | | | | |
| I _{D(on)} | 6.6mA | 4mA | 2.5mA | | | | | | | | | | | | | | | | | | | | | | | | | | |

NOTE: 1. Pulse test pulsewidth = 300 μs; duty cycle < 3%

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VCR2N/3P/4N/7N Voltage Controlled Resistors

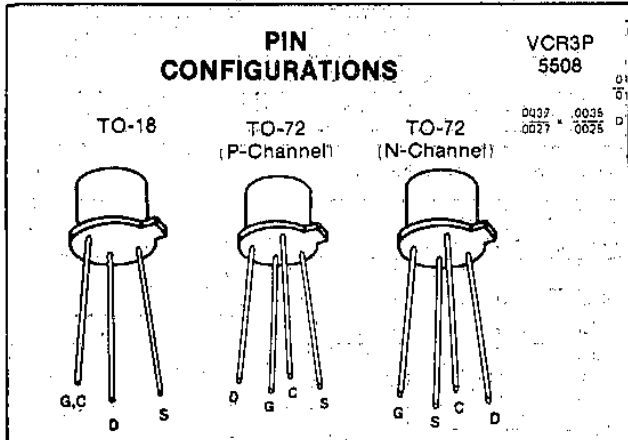
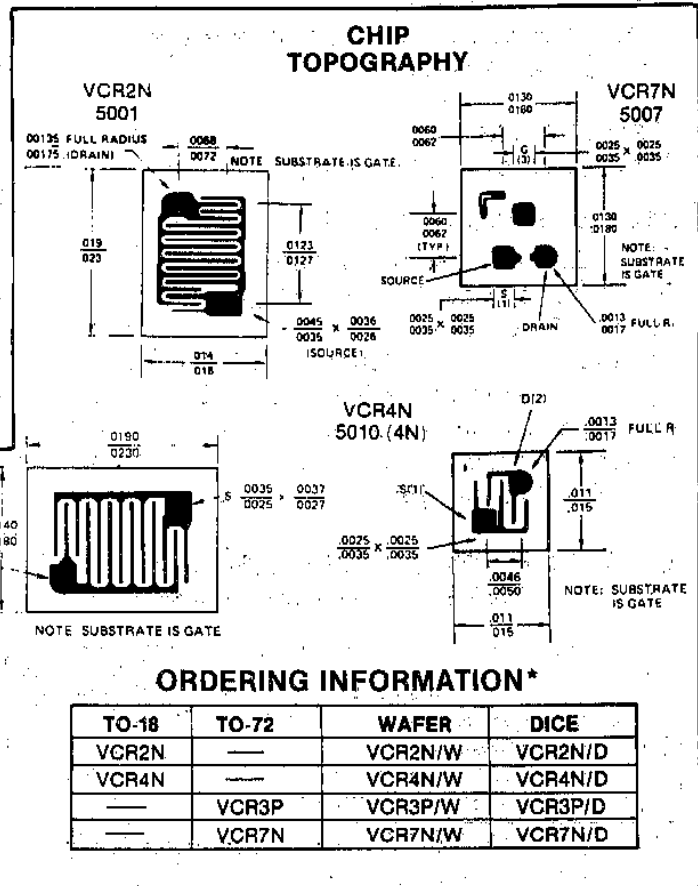
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APPLICATIONS

- Small Signal Attenuators
- Filters
- Amplifier Gain Control
- Oscillator Amplitude Control

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise noted)
 Gate-Drain or Gate-Source Voltage 15V
 Gate Current 10 mA
 Storage Temperature Range .. -65°C to $+200^\circ\text{C}$
 Operating Temperature Range -55°C to $+150^\circ\text{C}$
 Lead Temperature (Soldering, 10 sec.)... $+300^\circ\text{C}$
 Power Dissipation 300 mW
 Derate above 25°C 2 mW/ $^\circ\text{C}$



*When ordering wafer/dice refer to Appendix B-23.

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

N-Channel VCR FETS

| Parameter | VCR2N | | VCR4N | | VCR7N | | Unit | Test Conditions |
|---|-------|-----|-------|------|-------|-------|----------|------------------------------------|
| | Min | Max | Min | Max | Min | Max | | |
| S I_{GSS} Gate Reverse Current | | -5 | | -0.2 | | -0.1 | nA | $V_{GS} = -15V, V_{DS} = 0$ |
| A BV_{GSS} Gate-Source Breakdown Voltage | -15 | | -15 | | -15 | | V | $I_G = -1 \mu A, V_{DS} = 0$ |
| T $V_{GS(off)}$ Gate-Source Cutoff Voltage | -3.5 | -7 | -3.5 | -7 | -2.5 | -5 | | $I_D = 1 \mu A, V_{DS} = 10V$ |
| I $r_{ds(on)}$ Drain Source ON Resistance | 20 | 60 | 200 | 600 | 4,000 | 8,000 | Ω | $V_{GS} = 0, I_D = 0$ f = 1 kHz |
| D C_{dgo} Drain-Gate Capacitance | | 7.5 | | 3 | | 1.5 | pF | $V_{GD} = -10V, I_S = 0$ f = 1 MHz |
| Y C_{sgo} Source-Gate Capacitance | | 7.5 | | 3 | | 1.5 | pF | $V_{GS} = -10V, I_D = 0$ |

P-Channel VCR FETS

| Parameter | VCR3P | | Unit | Test Conditions |
|---|-------|-----|----------|-----------------------------------|
| S I_{GSS} Gate Reverse Current | | 20 | nA | $V_{GS} = 15V, V_{DS} = 0$ |
| A BV_{GSS} Gate-Source Breakdown Voltage | 15 | | V | $I_G = 1 \mu A, V_{DS} = 0$ |
| T $V_{GS(off)}$ Gate-Source Cutoff Voltage | 3.5 | 7 | | $I_D = -1 \mu A, V_{DS} = -10V$ |
| I $r_{ds(on)}$ Drain-Source ON Resistance | 70 | 200 | Ω | $V_{GS} = 0, I_D = 0$ f = 1 kHz |
| D C_{dgo} Drain-Gate Capacitance | | 6 | pF | $V_{GD} = 10V, I_S = 0$ f = 1 MHz |
| Y C_{sgo} Source-Gate Capacitance | | 6 | pF | $V_{GS} = 10V, I_D = 0$ |

JFETS AS VOLTAGE CONTROLLED RESISTORS

The voltage controlled resistor is a junction field effect transistor whose drain to source ON resistance is controlled by gate to source voltage.

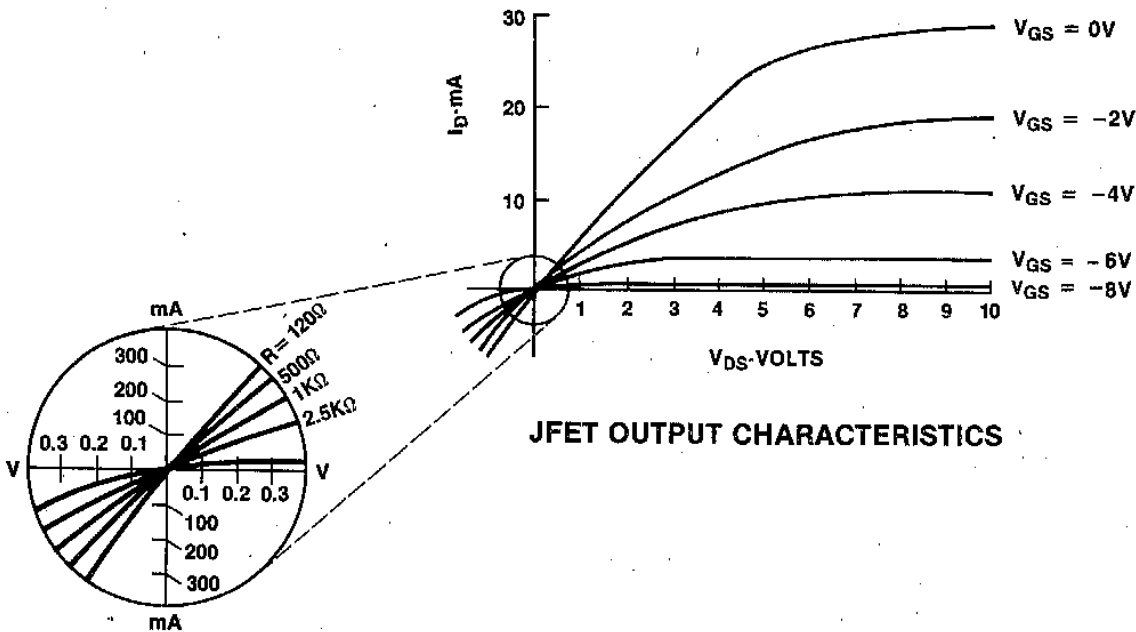
The gate control terminal is high impedance thereby allowing negligible control current. The gate voltage is zero for minimum resistance, and increases as the gate voltage approaches the pinch-off voltage.

This VCR is intended for use on applications using low level AC signals. Figure 1 shows the output characteristics, with an enlarged graph of $V_{DS} = 0$ for AC signals with no DC component. Operation is in the first and third quadrants; the device will operate in the first quadrant only if a constant current is applied to the drain and the input signal level is kept low.

Figure 1 also shows that certain combinations of gate control voltage and signal levels will cause resistance modulation. This distortion may be improved by introducing local feedback as shown in figure 2 for best frequency response and impedance levels; eliminating the feedback capacitor will require the gate control voltage to be double for the same ON resistance. The resistor values should be equal, and about $100k\Omega$.

Best gate control voltage for best linearity is up to about $0.8V_{PK}$; ON resistance increases rapidly beyond this point.

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JFET OUTPUT CHARACTERISTICS

JFET OUTPUT CHARACTERISTICS ENLARGED AROUND $V_{DS} = 0$

FIGURE 1

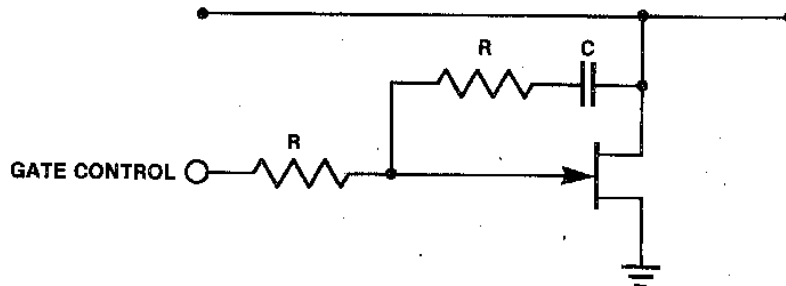


FIGURE 2

